

# Fusion Family of Mixed Signal FPGAs

## **Features and Benefits**

### High-Performance Reprogrammable Flash Technology

- Advanced 130-nm, 7-Layer Metal, Flash-Based CMOS Process
- Nonvolatile, Retains Program when Powered Off
- Instant On Single-Chip Solution 350 MHz System Performance

#### **Embedded Flash Memory**

- User Flash Memory 2 Mbits to 8 Mbits Configurable 8-, 16-, or 32-Bit Datapath 10 ns Access in Read-Ahead Mode
- 1 Kbit of Additional FlashROM

#### Integrated A/D Converter (ADC) and Analog I/O

- Up to 12-Bit Resolution and up to 600 Ksps
- Internal 2.56 V or External Reference Voltage
- ADC: Up to 30 Scalable Analog Input Channels High-Voltage Input Tolerance: –10.5 V to +12 V
- Current Monitor and Temperature Monitor Blocks
- Up to 10 MOSFET Gate Driver Outputs
- P- and N-Channel Power MOSFET Support Programmable 1, 3, 10, 30  $\mu$ A, and 20 mA Drive Strengths
- ADC Accuracy is Better than 1%

#### On-Chip Clocking Support

- Internal 100 MHz RC Oscillator (accurate to 1%)
- Crystal Oscillator Support (32 KHz to 20 MHz)
- Programmable Real-Time Counter (RTC) 6 Clock Conditioning Circuits (CCCs) with 1 or 2 Integrated PLLs
  - Phase Shift, Multiply/Divide, and Delay Capabilities
     Frequency: Input 1.5–350 MHz, Output 0.75–350 MHz

#### Low Power Consumption

- Single 3.3 V Power Supply with On-Chip 1.5 V Regulator
- Sleep and Standby Low-Power Modes

#### In-System Programming (ISP) and Security

- ISP with 128-Bit AES via JTAG FlashLock<sup>®</sup> Designed to Protect FPGA Contents

#### Advanced Digital I/O

- 1.5 V, 1.8 V, 2.5 V, and 3.3 V Mixed-Voltage Operation
- Bank-Selectable I/O Voltages Up to 5 Banks per Chip Single-Ended I/O Standards: LVTTL, LVCMOS 3.3 V / 2.5 V / 1.8 V / 1.5 V, 3.3 V PCI / 3.3 V PCI-X, and LVCMOS 2.5 V / 5.0 V Input
- Differential I/O Standards: LVPECL, LVDS, B-LVDS, M-LVDS
  - Built-In I/O Registers
  - 700 Mbps DDR Operation
- Hot-Swappable I/Os
- Programmable Output Slew Rate, Drive Strength, and Weak Pull-Up/Down Resistor
- Pin-Compatible Packages across the Fusion<sup>®</sup> Family

#### SRAMs and FIFOs

- Variable-Aspect-Ratio 4,608-Bit SRAM Blocks (×1, ×2, ×4, ×9, and ×18 organizations available)
- True Dual-Port SRAM (except ×18)
- Programmable Embedded FIFO Control Logic

#### Soft ARM Cortex-M1 Fusion Devices (M1)

ARM<sup>®</sup> Cortex<sup>®</sup>-M1–Enabled

#### Pigeon Point ATCA IP Support (P1)

- Targeted to Pigeon Point® Board Management Reference (BMR) Starter Kits
- Designed in Partnership with Pigeon Point Systems
- ARM Cortex-M1 Enabled

### MicroBlade Advanced Mezzanine Card Support (U1)

- Targeted to Advanced Mezzanine Card (AdvancedMC™ Designs)
- Designed in Partnership with MicroBlade
- 8051-Based Module Management Controller (MMC)

Table 1 • Fusion Family

Fusion Devices		AFS090	AFS250	AFS600	AFS1500
ARM Cortex-M1*	Devices		M1AFS250	M1AFS600	M1AFS1500
Pigeon Point De	vices			P1AFS600	P1AFS1500
MicroBlade Devi	ces		U1AFS250	U1AFS600	U1AFS1500
	System Gates	90,000	250,000	600,000	1,500,000
	Tiles (D-flip-flops)	2,304	6,144	13,824	38,400
General Information	Secure (AES) ISP	Yes	Yes	Yes	Yes
	PLLs	1	1	2	2
	Globals	18	18	18	18
	Flash Memory Blocks (2 Mbits)	1	1	2	4
	Total Flash Memory Bits	2M	2M	4M	M8
Memory	FlashROM Bits	1,024	1,024	1,024	1,024
	RAM Blocks (4,608 bits)	6	8	24	60
	RAM kbits	27	36	108	270
	Analog Quads	5	6	10	10
	Analog Input Channels	15	18	30	30
Analan and I/Oa	Gate Driver Outputs	5	6	10	10
Analog and I/Os	I/O Banks (+ JTAG)	4	4	5	5
	Maximum Digital I/Os	75	114	172	252
	Analog I/Os	20	24	40	40

\*Refer to the Cortex-M1 product brief for more information.

Downloaded from **Arrow.com**.



## **Fusion Device Architecture Overview**

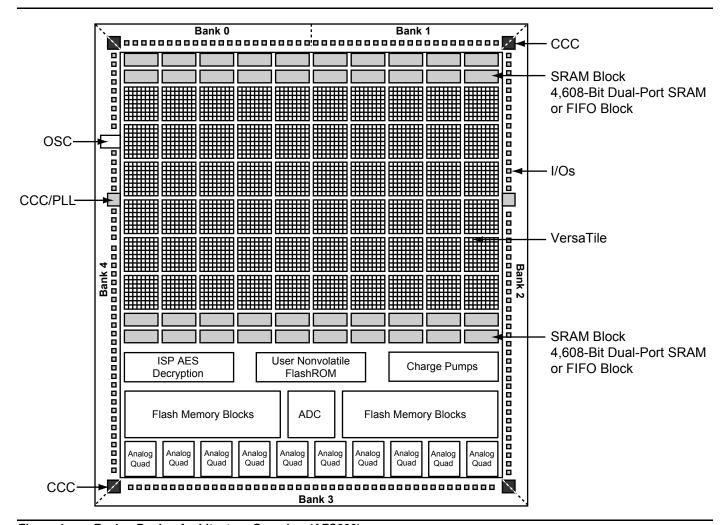


Figure 1 • Fusion Device Architecture Overview (AFS600)

# Package I/Os: Single-/Double-Ended (Analog)

Fusion Devices	AFS090	AFS250	AFS600	AFS1500
ARM Cortex-M1 Devices		M1AFS250	M1AFS600	M1AFS1500
Pigeon Point Devices			P1AFS600 <sup>1</sup>	P1AFS1500 <sup>1</sup>
MicroBlade Devices		U1AFS250 <sup>2</sup>	U1AFS600 <sup>2</sup>	U1AFS1500 <sup>2</sup>
QN108 <sup>3</sup>	37/9 (16)			
QN180 <sup>3</sup>	60/16 (20)	65/15 (24)		
PQ208 <sup>4, 5</sup>		93/26 (24)	95/46 (40)	
FG256	75/22 (20)	114/37 (24)	119/58 (40)	119/58 (40)
FG484			172/86 (40)	223/109 (40)
FG676				252/126 (40)
	1			

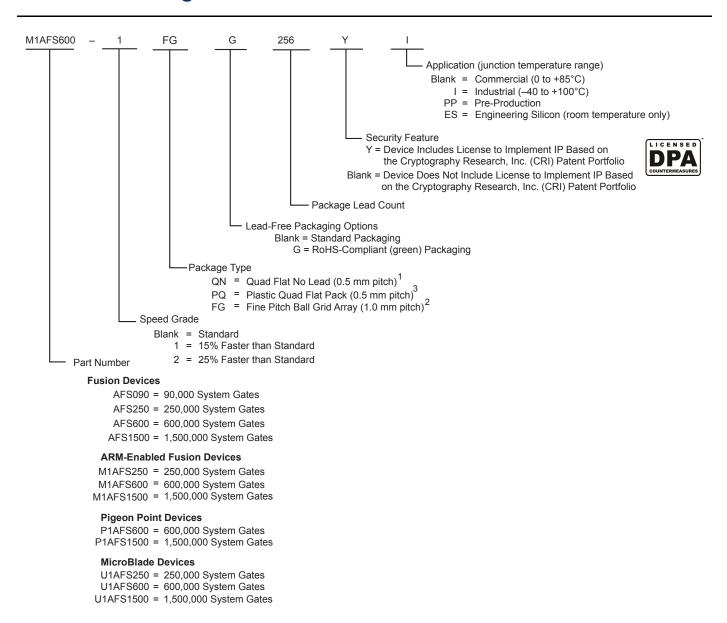
#### Notes:

- 1. Pigeon Point devices are only offered in FG484 and FG256.
- MicroBlade devices are only offered in FG256.
- 3. Package not available.
- 4. Fusion devices in the same package are pin compatible with the exception of the PQ208 package (AFS250 and AFS600).
- 5. PQ208 package is discontinued.

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## **Product Ordering Codes**



#### Notes:

- 1. For Fusion devices, Quad Flat No Lead packages are only offered as RoHS compliant, QNG packages.
- 2. MicroBlade and Pigeon Point devices only support FG packages.
- Package is discontinued.

## **Fusion Device Status**

Fusion	Status	Cortex-M1	Status	Pigeon Point	Status	MicroBlade	Status
AFS090	Production						
AFS250	Production	M1AFS250	Production			U1AFS250	Production
AFS600	Production	M1AFS600	Production	P1AFS600	Production	U1AFS600	Production
AFS1500	Production	M1AFS1500	Production	P1AFS1500	Production	U1AFS1500	Production

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## **Temperature Grade Offerings**

Fusion Devices	AFS090	AFS250	AFS600	AFS1500
ARM Cortex-M1 Devices		M1AFS250	M1AFS600	M1AFS1500
Pigeon Point Devices			P1AFS600 <sup>3</sup>	P1AFS1500 <sup>3</sup>
MicroBlade Devices		U1AFS250 <sup>4</sup>	U1AFS600 <sup>4</sup>	U1AFS1500 <sup>4</sup>
QN108 <sup>5</sup>	C, I	-	-	-
QN180 <sup>5</sup>	C, I	C, I	-	_
PQ208 <sup>6</sup>	-	C, I	C, I	_
FG256	C, I	C, I	C, I	C, I
FG484	_	-	C, I	C, I
FG676	_	-	_	C, I

#### Notes:

- 1. C = Commercial Temperature Range: 0°C to 85°C Junction
- 2. I = Industrial Temperature Range: -40°C to 100°C Junction
- 3. Pigeon Point devices are only offered in FG484 and FG256.
- 4. MicroBlade devices are only offered in FG256.
- 5. Package not available.
- Package is discontinued.

## **Speed Grade and Temperature Grade Matrix**

	Std. <sup>1</sup>	-1	<b>-2</b> <sup>2</sup>
$C^3$	✓	✓	✓
14	✓	<b>√</b>	✓

#### Notes:

- 1. MicroBlade devices are only offered in standard speed grade.
- 2. Pigeon Point devices are only offered in -2 speed grade.
- 3. C = Commercial Temperature Range: 0°C to 85°C Junction
- 4. I = Industrial Temperature Range: -40°C to 100°C Junction

Contact your local Microsemi SoC Products Group representative for device availability:

http://www.microsemi.com/index.php?option=com content&id=137&lang=en&view=article.

## Cortex-M1, Pigeon Point, and MicroBlade Fusion Device Information

This datasheet provides information for all Fusion (AFS), Cortex-M1 (M1), Pigeon Point (P1), and MicroBlade (U1) devices. The remainder of the document will only list the Fusion (AFS) devices. Please apply relevant information to M1, P1, and U1 devices when appropriate. Please note the following:

- · Cortex-M1 devices are offered in the same speed grades and packages as basic Fusion devices.
- Pigeon Point devices are only offered in –2 speed grade and FG484 and FG256 packages.
- MicroBlade devices are only offered in standard speed grade and the FG256 package.

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# 1 – Fusion Device Family Overview

## Introduction

The Fusion mixed signal FPGA satisfies the demand from system architects for a device that simplifies design and unleashes their creativity. As the world's first mixed signal programmable logic family, Fusion integrates mixed signal analog, flash memory, and FPGA fabric in a monolithic device. Fusion devices enable designers to quickly move from concept to completed design and then deliver feature-rich systems to market. This new technology takes advantage of the unique properties of Microsemi flash-based FPGAs, including a high-isolation, triple-well process and the ability to support high-voltage transistors to meet the demanding requirements of mixed signal system design.

Fusion mixed signal FPGAs bring the benefits of programmable logic to many application areas, including power management, smart battery charging, clock generation and management, and motor control. Until now, these applications have only been implemented with costly and space-consuming discrete analog components or mixed signal ASIC solutions. Fusion mixed signal FPGAs present new capabilities for system development by allowing designers to integrate a wide range of functionality into a single device, while at the same time offering the flexibility of upgrades late in the manufacturing process or after the device is in the field. Fusion devices provide an excellent alternative to costly and time-consuming mixed signal ASIC designs. In addition, when used in conjunction with the ARM Cortex-M1 processor, Fusion technology represents the definitive mixed signal FPGA platform.

Flash-based Fusion devices are Instant On. As soon as system power is applied and within normal operating specifications, Fusion devices are working. Fusion devices have a 128-bit flash-based lock and industry-leading AES decryption, used to secure programmed intellectual property (IP) and configuration data. Fusion devices are the most comprehensive single-chip analog and digital programmable logic solution available today.

To support this new ground-breaking technology, Microsemi has developed a series of major tool innovations to help maximize designer productivity. Implemented as extensions to the popular Microsemi Libero<sup>®</sup> System-on-Chip (SoC) software, these new tools allow designers to easily instantiate and configure peripherals within a design, establish links between peripherals, create or import building blocks or reference designs, and perform hardware verification. This tool suite will also add comprehensive hardware/software debug capability as well as a suite of utilities to simplify development of embedded soft-processor-based solutions.

## **General Description**

The Fusion family, based on the highly successful ProASIC®3 and ProASIC3E flash FPGA architecture, has been designed as a high-performance, programmable, mixed signal platform. By combining an advanced flash FPGA core with flash memory blocks and analog peripherals, Fusion devices dramatically simplify system design and, as a result, dramatically reduce overall system cost and board space.

The state-of-the-art flash memory technology offers high-density integrated flash memory blocks, enabling savings in cost, power, and board area relative to external flash solutions, while providing increased flexibility and performance. The flash memory blocks and integrated analog peripherals enable true mixed-mode programmable logic designs. Two examples are using an on-chip soft processor to implement a fully functional flash MCU and using high-speed FPGA logic to offer system and power supervisory capabilities. Instant On, and capable of operating from a single 3.3 V supply, the Fusion family is ideally suited for system management and control applications.

The devices in the Fusion family are categorized by FPGA core density. Each family member contains many peripherals, including flash memory blocks, an analog-to-digital-converter (ADC), high-drive outputs, both RC and crystal oscillators, and a real-time counter (RTC). This provides the user with a high level of flexibility and integration to support a wide variety of mixed signal applications. The flash memory block capacity ranges from 2 Mbits to 8 Mbits. The integrated 12-bit ADC supports up to 30 independently configurable input channels.



The on-chip crystal and RC oscillators work in conjunction with the integrated phase-locked loops (PLLs) to provide clocking support to the FPGA array and on-chip resources. In addition to supporting typical RTC uses such as watchdog timer, the Fusion RTC can control the on-chip voltage regulator to power down the device (FPGA fabric, flash memory block, and ADC), enabling a low power standby mode.

The Fusion family offers revolutionary features, never before available in an FPGA. The nonvolatile flash technology gives the Fusion solution the advantage of being a highly secure, low power, single-chip solution that is Instant On. Fusion is reprogrammable and offers time-to-market benefits at an ASIC-level unit cost. These features enable designers to create high-density systems using existing ASIC or FPGA design flows and tools.

## Flash Advantages

### Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, high performance, and ease of use. Flash-based Fusion devices are Instant On and do not need to be loaded from an external boot PROM. On-board security mechanisms prevent access to the programming information and enable remote updates of the FPGA logic that are protected with high level security. Designers can perform remote insystem reprogramming to support future design iterations and field upgrades, with confidence that valuable IP is highly unlikely to be compromised or copied. ISP can be performed using the industry-standard AES algorithm with MAC data authentication on the device. The Fusion family device architecture mitigates the need for ASIC migration at higher user volumes. This makes the Fusion family a cost-effective ASIC replacement solution for applications in the consumer, networking and communications, computing, and avionics markets.

### Security

As the nonvolatile, flash-based Fusion family requires no boot PROM, there is no vulnerable external bitstream. Fusion devices incorporate FlashLock, which provides a unique combination of reprogrammability and design security without external overhead, advantages that only an FPGA with nonvolatile flash programming can offer.

Fusion devices utilize a 128-bit flash-based key lock and a separate AES key to provide the highest level of protection in the FPGA industry for programmed IP and configuration data. The FlashROM data in Fusion devices can also be encrypted prior to loading. Additionally, the flash memory blocks can be programmed during runtime using the industry-leading AES-128 block cipher encryption standard (FIPS Publication 192). The AES standard was adopted by the National Institute of Standards and Technology (NIST) in 2000 and replaces the DES standard, which was adopted in 1977. Fusion devices have a built-in AES decryption engine and a flash-based AES key that make Fusion devices the most comprehensive programmable logic device security solution available today. Fusion devices with AES-based security provide a high level of protection for remote field updates over public networks, such as the Internet, and are designed to ensure that valuable IP remains out of the hands of system overbuilders, system cloners, and IP thieves. As an additional security measure, the FPGA configuration data of a programmed Fusion device cannot be read back, although secure design verification is possible. During design, the user controls and defines both internal and external access to the flash memory blocks.

Security, built into the FPGA fabric, is an inherent component of the Fusion family. The flash cells are located beneath seven metal layers, and many device design and layout techniques have been used to make invasive attacks extremely difficult. Fusion with FlashLock and AES security is unique in being highly resistant to both invasive and noninvasive attacks. Your valuable IP is protected with industry-standard security, making remote ISP possible. A Fusion device provides the best available security for programmable logic designs.

### Single Chip

Flash-based FPGAs store their configuration information in on-chip flash cells. Once programmed, the configuration data is an inherent part of the FPGA structure, and no external configuration data needs to be loaded at system power-up (unlike SRAM-based FPGAs). Therefore, flash-based Fusion FPGAs do not require system configuration components such as EEPROMs or microcontrollers to load device configuration data. This reduces bill-of-materials costs and PCB area, and increases security and system reliability.



#### Instant On

Flash-based Fusion devices are Level 0 Instant On. Instant On Fusion devices greatly simplify total system design and reduce total system cost by eliminating the need for CPLDs. The Fusion Instant On clocking (PLLs) replaces off-chip clocking resources. The Fusion mix of Instant On clocking and analog resources makes these devices an excellent choice for both system supervisor and system management functions. Instant On from a single 3.3 V source enables Fusion devices to initiate, control, and monitor multiple voltage supplies while also providing system clocks. In addition, glitches and brownouts in system power will not corrupt the Fusion device flash configuration. Unlike SRAM-based FPGAs, the device will not have to be reloaded when system power is restored. This enables reduction or complete removal of expensive voltage monitor and brownout detection devices from the PCB design.

Flash-based Fusion devices simplify total system design and reduce cost and design risk, while increasing system reliability.

#### Firm Errors

Firm errors occur most commonly when high-energy neutrons, generated in the upper atmosphere, strike a configuration cell of an SRAM FPGA. The energy of the collision can change the state of the configuration cell and thus change the logic, routing, or I/O behavior in an unpredictable way. Another source of radiation-induced firm errors is alpha particles. For an alpha to cause a soft or firm error, its source must be in very close proximity to the affected circuit. The alpha source must be in the package molding compound or in the die itself. While low-alpha molding compounds are being used increasingly, this helps reduce but does not entirely eliminate alpha-induced firm errors.

Firm errors are impossible to prevent in SRAM FPGAs. The consequence of this type of error can be a complete system failure. Firm errors do not occur in Fusion flash-based FPGAs. Once it is programmed, the flash cell configuration element of Fusion FPGAs cannot be altered by high-energy neutrons and is therefore immune to errors from them.

Recoverable (or soft) errors occur in the user data SRAMs of all FPGA devices. These can easily be mitigated by using error detection and correction (EDAC) circuitry built into the FPGA fabric.

#### Low Power

Flash-based Fusion devices exhibit power characteristics similar to those of an ASIC, making them an ideal choice for power-sensitive applications. With Fusion devices, there is no power-on current surge and no high current transition, both of which occur on many FPGAs.

Fusion devices also have low dynamic power consumption and support both low power standby mode and very low power sleep mode, offering further power savings.

## **Advanced Flash Technology**

The Fusion family offers many benefits, including nonvolatility and reprogrammability through an advanced flash-based, 130-nm LVCMOS process with seven layers of metal. Standard CMOS design techniques are used to implement logic and control functions. The combination of fine granularity, enhanced flexible routing resources, and abundant flash switches allows very high logic utilization (much higher than competing SRAM technologies) without compromising device routability or performance. Logic functions within the device are interconnected through a four-level routing hierarchy.

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### **Advanced Architecture**

The proprietary Fusion architecture provides granularity comparable to standard-cell ASICs. The Fusion device consists of several distinct and programmable architectural features, including the following (Figure 1-1 on page 1-5):

- · Embedded memories
  - Flash memory blocks
  - FlashROM
  - SRAM and FIFO
- · Clocking resources
  - PLL and CCC
  - RC oscillator
  - Crystal oscillator
  - No-Glitch MUX (NGMUX)
- Digital I/Os with advanced I/O standards
- FPGA VersaTiles
- · Analog components
  - ADC
  - Analog I/Os supporting voltage, current, and temperature monitoring
  - 1.5 V on-board voltage regulator
  - Real-time counter

The FPGA core consists of a sea of VersaTiles. Each VersaTile can be configured as a three-input logic lookup table (LUT) equivalent or a D-flip-flop or latch (with or without enable) by programming the appropriate flash switch interconnections. This versatility allows efficient use of the FPGA fabric. The VersaTile capability is unique to the Microsemi families of flash-based FPGAs. VersaTiles and larger functions are connected with any of the four levels of routing hierarchy. Flash switches are distributed throughout the device to provide nonvolatile, reconfigurable interconnect programming. Maximum core utilization is possible for virtually any design.

In addition, extensive on-chip programming circuitry allows for rapid (3.3 V) single-voltage programming of Fusion devices via an IEEE 1532 JTAG interface.

## **Unprecedented Integration**

## Integrated Analog Blocks and Analog I/Os

Fusion devices offer robust and flexible analog mixed signal capability in addition to the high-performance flash FPGA fabric and flash memory block. The many built-in analog peripherals include a configurable 32:1 input analog MUX, up to 10 independent MOSFET gate driver outputs, and a configurable ADC. The ADC supports 8-, 10-, and 12-bit modes of operation with a cumulative sample rate up to 600 k samples per second (Ksps), differential nonlinearity (DNL) < 1.0 LSB, and Total Unadjusted Error (TUE) of 0.72 LSB in 10-bit mode. The TUE is used for characterization of the conversion error and includes errors from all sources, such as offset and linearity. Internal bandgap circuitry offers 1% voltage reference accuracy with the flexibility of utilizing an external reference voltage. The ADC channel sampling sequence and sampling rate are programmable and implemented in the FPGA logic using Designer and Libero SoC software tool support.

Two channels of the 32-channel ADCMUX are dedicated. Channel 0 is connected internally to VCC and can be used to monitor core power supply. Channel 31 is connected to an internal temperature diode which can be used to monitor device temperature. The 30 remaining channels can be connected to external analog signals. The exact number of I/Os available for external connection signals is device-dependent (refer to the "Fusion Family" table on page I for details).



With Fusion, Microsemi also introduces the Analog Quad I/O structure (Figure 1-1). Each quad consists of three analog inputs and one gate driver. Each quad can be configured in various built-in circuit combinations, such as three prescaler circuits, three digital input circuits, a current monitor circuit, or a temperature monitor circuit. Each prescaler has multiple scaling factors programmed by FPGA signals to support a large range of analog inputs with positive or negative polarity. When the current monitor circuit is selected, two adjacent analog inputs measure the voltage drop across a small external sense resistor. For more information, refer to the "Analog System Characteristics" section on page 2-117. Built-in operational amplifiers amplify small voltage signals for accurate current measurement. One analog input in each quad can be connected to an external temperature monitor diode. In addition to the external temperature monitor diode(s), a Fusion device can monitor an internal temperature diode using dedicated channel 31 of the ADCMUX.

Figure 1-1 on page 1-5 illustrates a typical use of the Analog Quad I/O structure. The Analog Quad shown is configured to monitor and control an external power supply. The AV pad measures the source of the power supply. The AC pad measures the voltage drop across an external sense resistor to calculate current. The AG MOSFET gate driver pad turns the external MOSFET on and off. The AT pad measures the load-side voltage level.

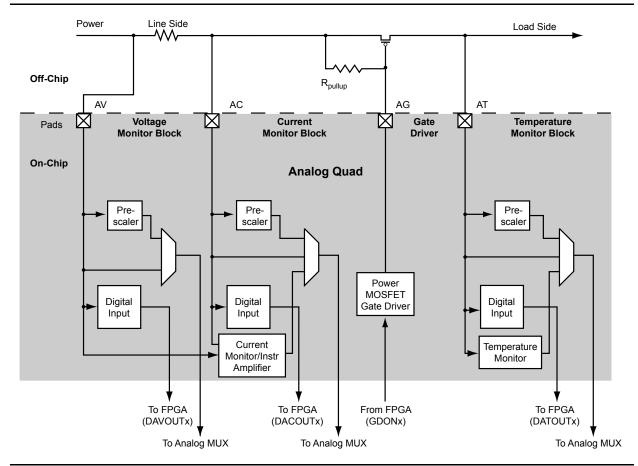


Figure 1-1 • Analog Quad

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## **Embedded Memories**

## Flash Memory Blocks

The flash memory available in each Fusion device is composed of one to four flash blocks, each 2 Mbits in density. Each block operates independently with a dedicated flash controller and interface. Fusion flash memory blocks combine fast access times (60 ns random access and 10 ns access in Read-Ahead mode) with a configurable 8-, 16-, or 32-bit datapath, enabling high-speed flash operation without wait states. The memory block is organized in pages and sectors. Each page has 128 bytes, with 33 pages comprising one sector and 64 sectors per block. The flash block can support multiple partitions. The only constraint on size is that partition boundaries must coincide with page boundaries. The flexibility and granularity enable many use models and allow added granularity in programming updates.

Fusion devices support two methods of external access to the flash memory blocks. The first method is a serial interface that features a built-in JTAG-compliant port, which allows in-system programmability during user or monitor/test modes. This serial interface supports programming of an AES-encrypted stream. Data protected with security measures can be passed through the JTAG interface, decrypted, and then programmed in the flash block. The second method is a soft parallel interface.

FPGA logic or an on-chip soft microprocessor can access flash memory through the parallel interface. Since the flash parallel interface is implemented in the FPGA fabric, it can potentially be customized to meet special user requirements. For more information, refer to the *CoreCFI Handbook*. The flash memory parallel interface provides configurable byte-wide (×8), word-wide (×16), or dual-word-wide (×32) data-port options. Through the programmable flash parallel interface, the on-chip and off-chip memories can be cascaded for wider or deeper configurations.

The flash memory has built-in security. The user can configure either the entire flash block or the small blocks to protect against unintentional or intrusive attempts to change or destroy the storage contents. Each on-chip flash memory block has a dedicated controller, enabling each block to operate independently.

The flash block logic consists of the following sub-blocks:

- Flash block Contains all stored data. The flash block contains 64 sectors and each sector contains 33 pages of data.
- Page Buffer Contains the contents of the current page being modified. A page contains 8 blocks of data.
- Block Buffer Contains the contents of the last block accessed. A block contains 128 data bits.
- ECC Logic The flash memory stores error correction information with each block to perform single-bit error correction and double-bit error detection on all data blocks.

#### User Nonvolatile FlashROM

In addition to the flash blocks, Fusion devices have 1 Kbit of user-accessible, nonvolatile FlashROM on-chip. The FlashROM is organized as 8×128-bit pages. The FlashROM can be used in diverse system applications:

- Internet protocol addressing (wireless or fixed)
- System calibration settings
- · Device serialization and/or inventory control
- Subscription-based business models (for example, set-top boxes)
- Secure key storage for communications algorithms protected by security
- Asset management/tracking
- · Date stamping
- Version management

The FlashROM is written using the standard IEEE 1532 JTAG programming interface. Pages can be individually programmed (erased and written). On-chip AES decryption can be used selectively over public networks to load data such as security keys stored in the FlashROM for a user design.

The FlashROM can be programmed (erased and written) via the JTAG programming interface, and its contents can be read back either through the JTAG programming interface or via direct FPGA core addressing.



The FlashPoint tool in the Fusion development software solutions, Libero SoC and Designer, has extensive support for flash memory blocks and FlashROM. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature allows the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using the Libero SoC and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.

#### SRAM and FIFO

Fusion devices have embedded SRAM blocks along the north and south sides of the device. Each variable-aspect-ratio SRAM block is 4,608 bits in size. Available memory configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1 bits. The individual blocks have independent read and write ports that can be configured with different bit widths on each port. For example, data can be written through a 4-bit port and read as a single bitstream. The SRAM blocks can be initialized from the flash memory blocks or via the device JTAG port (ROM emulation mode), using the UJTAG macro.

In addition, every SRAM block has an embedded FIFO control unit. The control unit allows the SRAM block to be configured as a synchronous FIFO without using additional core VersaTiles. The FIFO width and depth are programmable. The FIFO also features programmable Almost Empty (AEMPTY) and Almost Full (AFULL) flags in addition to the normal EMPTY and FULL flags. The embedded FIFO control unit contains the counters necessary for the generation of the read and write address pointers. The SRAM/FIFO blocks can be cascaded to create larger configurations.

### **Clock Resources**

### PLLs and Clock Conditioning Circuits (CCCs)

Fusion devices provide designers with very flexible clock conditioning capabilities. Each member of the Fusion family contains six CCCs. In the two larger family members, two of these CCCs also include a PLL; the smaller devices support one PLL.

The inputs of the CCC blocks are accessible from the FPGA core or from one of several inputs with dedicated CCC block connections.

The CCC block has the following key features:

- Wide input frequency range (f<sub>IN CCC</sub>) = 1.5 MHz to 350 MHz
- Output frequency range (f<sub>OUT CCC</sub>) = 0.75 MHz to 350 MHz
- Clock phase adjustment via programmable and fixed delays from –6.275 ns to +8.75 ns
- · Clock skew minimization (PLL)
- · Clock frequency synthesis (PLL)
- · On-chip analog clocking resources usable as inputs:
  - 100 MHz on-chip RC oscillator
  - Crystal oscillator

#### Additional CCC specifications:

- Internal phase shift = 0°, 90°, 180°, and 270°
- Output duty cycle = 50% ± 1.5%
- Low output jitter. Samples of peak-to-peak period jitter when a single global network is used:
  - 70 ps at 350 MHz
  - 90 ps at 100 MHz
  - 180 ps at 24 MHz
  - Worst case < 2.5% × clock period</li>
- Maximum acquisition time = 150 μs
- Low power consumption of 5 mW

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### **Global Clocking**

Fusion devices have extensive support for multiple clocking domains. In addition to the CCC and PLL support described above, there are on-chip oscillators as well as a comprehensive global clock distribution network.

The integrated RC oscillator generates a 100 MHz clock. It is used internally to provide a known clock source to the flash memory read and write control. It can also be used as a source for the PLLs.

The crystal oscillator supports the following operating modes:

- Crystal (32.768 KHz to 20 MHz)
- Ceramic (500 KHz to 8 MHz)
- RC (32.768 KHz to 4 MHz)

Each VersaTile input and output port has access to nine VersaNets: six main and three quadrant global networks. The VersaNets can be driven by the CCC or directly accessed from the core via MUXes. The VersaNets can be used to distribute low-skew clock signals or for rapid distribution of high-fanout nets.

## Digital I/Os with Advanced I/O Standards

The Fusion family of FPGAs features a flexible digital I/O structure, supporting a range of voltages (1.5 V, 1.8 V, 2.5 V, and 3.3 V). Fusion FPGAs support many different digital I/O standards, both single-ended and differential.

The I/Os are organized into banks, with four or five banks per device. The configuration of these banks determines the I/O standards supported. The banks along the east and west sides of the device support the full range of I/O standards (single-ended and differential). The south bank supports the Analog Quads (analog I/O). In the family's two smaller devices, the north bank supports multiple single-ended digital I/O standards. In the family's larger devices, the north bank is divided into two banks of digital Pro I/Os, supporting a wide variety of single-ended, differential, and voltage-referenced I/O standards.

Each I/O module contains several input, output, and enable registers. These registers allow the implementation of the following applications:

- · Single-Data-Rate (SDR) applications
- Double-Data-Rate (DDR) applications—DDR LVDS I/O for chip-to-chip communications
- Fusion banks support LVPECL, LVDS, BLVDS, and M-LVDS with 20 multi-drop points.

#### VersaTiles

The Fusion core consists of VersaTiles, which are also used in the successful ProASIC3 family. The Fusion VersaTile supports the following:

- All 3-input logic functions—LUT-3 equivalent
- · Latch with clear or set
- D-flip-flop with clear or set and optional enable

Refer to Figure 1-2 for the VersaTile configuration arrangement.

LUT-3 Equivalent D-Flip-Flop with Clear or Set Enable D-Flip-Flop with Clear or Set

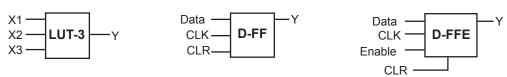


Figure 1-2 • VersaTile Configurations



## Specifying I/O States During Programming

You can modify the I/O states during programming in FlashPro. In FlashPro, this feature is supported for PDB files generated from Designer v8.5 or greater. See the *FlashPro User Guide* for more information.

Note: PDB files generated from Designer v8.1 to Designer v8.4 (including all service packs) have limited display of Pin Numbers only.

The I/Os are controlled by the JTAG Boundary Scan register during programming, except for the analog pins (AC, AT and AV). The Boundary Scan register of the AG pin can be used to enable/disable the gate driver in Libero SoC.

- Load a PDB from the FlashPro GUI. You must have a PDB loaded to modify the I/O states during programming.
- From the FlashPro GUI, click PDB Configuration. A FlashPoint Programming File Generator window appears.
- Click the Specify I/O States During Programming button to display the Specify I/O States During Programming dialog box.
- 4. Sort the pins as desired by clicking any of the column headers to sort the entries by that header. Select the I/Os you wish to modify (Figure 1-3).
- 5. Set the I/O Output State. You can set Basic I/O settings if you want to use the default I/O settings for your pins, or use Custom I/O settings to customize the settings for each pin. Basic I/O state settings:
  - 1 I/O is set to drive out logic High
  - 0 I/O is set to drive out logic Low

Last Known State – I/O is set to the last value that was driven out prior to entering the programming mode, and then held at that value during programming

Z -Tri-State: I/O is tristated

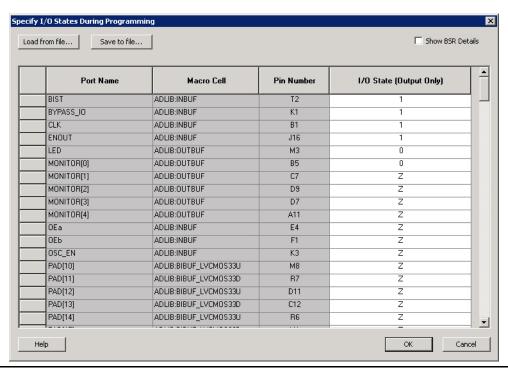


Figure 1-3 • I/O States During Programming Window

6. Click **OK** to return to the FlashPoint – Programming File Generator window.

 $\ensuremath{\mathsf{I/O}}$  States During programming are saved to the ADB and resulting programming files after completing programming file generation.

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## **Related Documents**

### **Datasheet**

Core8051

www.microsemi.com/soc/ipdocs/Core8051 DS.pdf

## **Application Notes**

Fusion FlashROM

http://www.microsemi.com/soc/documents/Fusion FROM AN.pdf

Fusion SRAM/FIFO Blocks

http://www.microsemi.com/soc/documents/Fusion\_RAM\_FIFO\_AN.pdf

Using DDR in Fusion Devices

http://www.microsemi.com/index.php?option=com\_docman&task=doc\_download&gid=129938

Fusion Security

http://www.microsemi.com/soc/documents/Fusion Security AN.pdf

Using Fusion RAM as Multipliers

http://www.microsemi.com/index.php?option=com\_docman&task=doc\_download&gid=129940

#### Handbook

Cortex-M1 Handbook

www.microsemi.com/soc/documents/CortexM1\_HB.pdf

#### **User Guides**

Designer User Guide

http://www.microsemi.com/soc/documents/designer\_UG.pdf

Fusion FPGA Fabric User Guide

http://www.microsemi.com/index.php?option=com\_docman&task=doc\_download&gid=130817

IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide

http://www.microsemi.com/soc/documents/pa3\_libguide\_ug.pdf

SmartGen, FlashROM, Flash Memory System Builder, and Analog System Builder User Guide http://www.microsemi.com/soc/documents/genguide\_ug.pdf

## **White Papers**

Fusion Technology

http://www.microsemi.com/soc/documents/Fusion\_Tech\_WP.pdf



## 2 – Device Architecture

## **Fusion Stack Architecture**

To manage the unprecedented level of integration in Fusion devices, Microsemi developed the Fusion technology stack (Figure 2-1). This layered model offers a flexible design environment, enabling design at very high and very low levels of abstraction. Fusion peripherals include hard analog IP and hard and soft digital IP. Peripherals communicate across the FPGA fabric via a layer of soft gates—the Fusion backbone. Much more than a common bus interface, this Fusion backbone integrates a micro-sequencer within the FPGA fabric and configures the individual peripherals and supports low-level processing of peripheral data. Fusion applets are application building blocks that can control and respond to peripherals and other system signals. Applets can be rapidly combined to create large applications. The technology is scalable across devices, families, design types, and user expertise, and supports a well-defined interface for external IP and tool integration.

At the lowest level, Level 0, are Fusion peripherals. These are configurable functional blocks that can be hardwired structures such as a PLL or analog input channel, or soft (FPGA gate) blocks such as a UART or two-wire serial interface. The Fusion peripherals are configurable and support a standard interface to facilitate communication and implementation.

Connecting and controlling access to the peripherals is the Fusion backbone, Level 1. The backbone is a soft-gate structure, scalable to any number of peripherals. The backbone is a bus and much more; it manages peripheral configuration to ensure proper operation. Leveraging the common peripheral interface and a low-level state machine, the backbone efficiently offloads peripheral management from the system design. The backbone can set and clear flags based upon peripheral behavior and can define performance criteria. The flexibility of the stack enables a designer to configure the silicon, directly bypassing the backbone if that level of control is desired.

One step up from the backbone is the Fusion applet, Level 2. The applet is an application building block that implements a specific function in FPGA gates. It can react to stimuli and board-level events coming through the backbone or from other sources, and responds to these stimuli by accessing and manipulating peripherals via the backbone or initiating some other action. An applet controls or responds to the peripheral(s). Applets can be easily imported or exported from the design environment. The applet structure is open and well-defined, enabling users to import applets from Microsemi, system developers, third parties, and user groups.

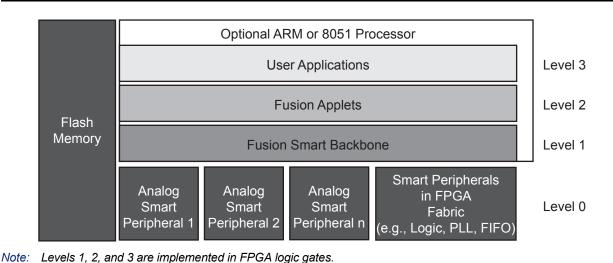


Figure 2-1 • Fusion Architecture Stack



The system application, Level 3, is the larger user application that utilizes one or more applets. Designing at the highest level of abstraction supported by the Fusion technology stack, the application can be easily created in FPGA gates by importing and configuring multiple applets.

In fact, in some cases an entire FPGA system design can be created without any HDL coding.

An optional MCU enables a combination of software and HDL-based design methodologies. The MCU can be on-chip or off-chip as system requirements dictate. System portioning is very flexible, allowing the MCU to reside above the applets or to absorb applets, or applets and backbone, if desired.

The Fusion technology stack enables a very flexible design environment. Users can engage in design across a continuum of abstraction from very low to very high.

## **Core Architecture**

## **VersaTile**

Based upon successful ProASIC3/E logic architecture, Fusion devices provide granularity comparable to gate arrays. The Fusion device core consists of a sea-of-VersaTiles architecture.

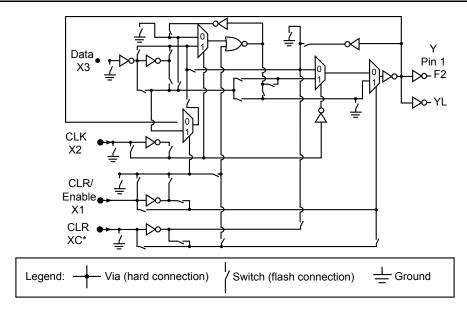
As illustrated in Figure 2-2, there are four inputs in a logic VersaTile cell, and each VersaTile can be configured using the appropriate flash switch connections:

- Any 3-input logic function
- Latch with clear or set
- · D-flip-flop with clear or set
- · Enable D-flip-flop with clear or set (on a 4th input)

VersaTiles can flexibly map the logic and sequential gates of a design. The inputs of the VersaTile can be inverted (allowing bubble pushing), and the output of the tile can connect to high-speed, very-long-line routing resources. VersaTiles and larger functions are connected with any of the four levels of routing hierarchy.

When the VersaTile is used as an enable D-flip-flop, the SET/CLR signal is supported by a fourth input, which can only be routed to the core cell over the VersaNet (global) network.

The output of the Versatile is F2 when the connection is to the ultra-fast local lines, or YL when the connection is to the efficient long-line or very-long-line resources (Figure 2-2).



Note: \*This input can only be connected to the global clock distribution network.

Figure 2-2 • Fusion Core VersaTile



### VersaTile Characteristics

## Sample VersaTile Specifications—Combinatorial Module

The Fusion library offers all combinations of LUT-3 combinatorial functions. In this section, timing characteristics are presented for a sample of the library (Figure 2-3). For more details, refer to the IGLOO, ProASIC3, SmartFusion, and Fusion Macro Library Guide.

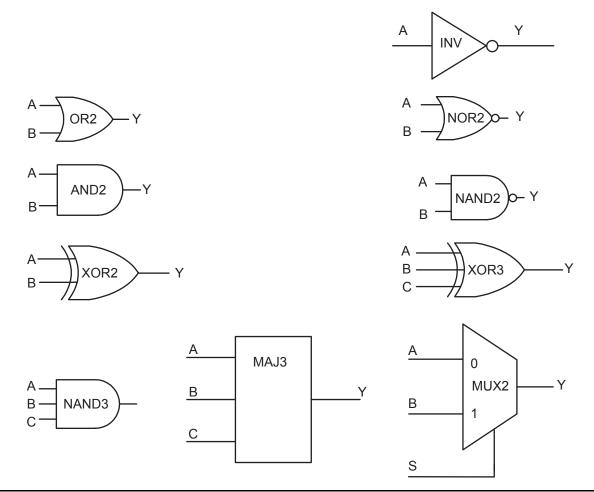
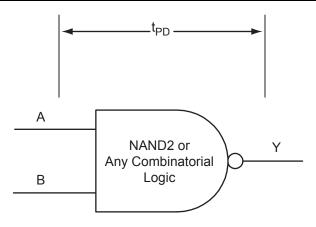


Figure 2-3 • Sample of Combinatorial Cells

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 $t_{PD}$  = MAX( $t_{PD(RR)}$ ,  $t_{PD(RF)}$ ,  $t_{PD(FF)}$ ,  $t_{PD(FR)}$ ) where edges are applicable for the particular combinatorial cell

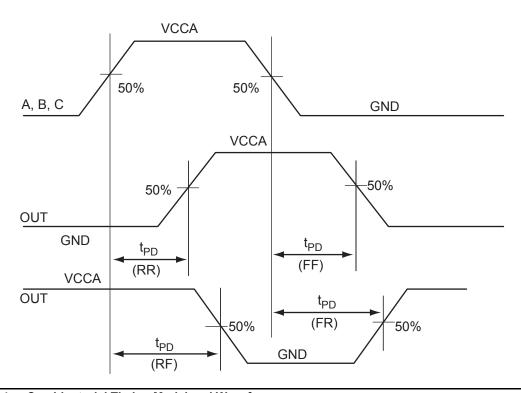


Figure 2-4 • Combinatorial Timing Model and Waveforms



#### **Timing Characteristics**

Table 2-1 • Combinatorial Cell Propagation Delays
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Combinatorial Cell	Equation	Parameter	-2	-1	Std.	Units
INV	Y = !A	t <sub>PD</sub>	0.40	0.46	0.54	ns
AND2	Y = A · B	t <sub>PD</sub>	0.47	0.54	0.63	ns
NAND2	Y = !(A · B)	t <sub>PD</sub>	0.47	0.54	0.63	ns
OR2	Y = A + B	t <sub>PD</sub>	0.49	0.55	0.65	ns
NOR2	Y = !(A + B)	t <sub>PD</sub>	0.49	0.55	0.65	ns
XOR2	Y = A ⊕ B	t <sub>PD</sub>	0.74	0.84	0.99	ns
MAJ3	Y = MAJ(A, B, C)	t <sub>PD</sub>	0.70	0.79	0.93	ns
XOR3	$Y = A \oplus B \oplus C$	t <sub>PD</sub>	0.87	1.00	1.17	ns
MUX2	Y = A !S + B S	t <sub>PD</sub>	0.51	0.58	0.68	ns
AND3	$Y = A \cdot B \cdot C$	t <sub>PD</sub>	0.56	0.64	0.75	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

#### Sample VersaTile Specifications—Sequential Module

The Fusion library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library (Figure 2-5). For more details, refer to the *IGLOO*, *ProASIC3*, *SmartFusion and Fusion Macro Library Guide*.

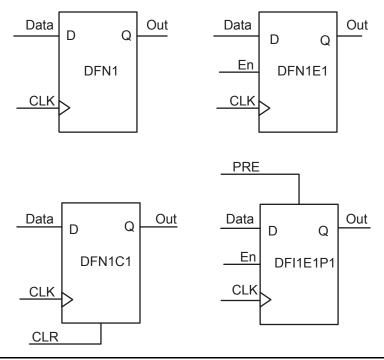


Figure 2-5 • Sample of Sequential Cells

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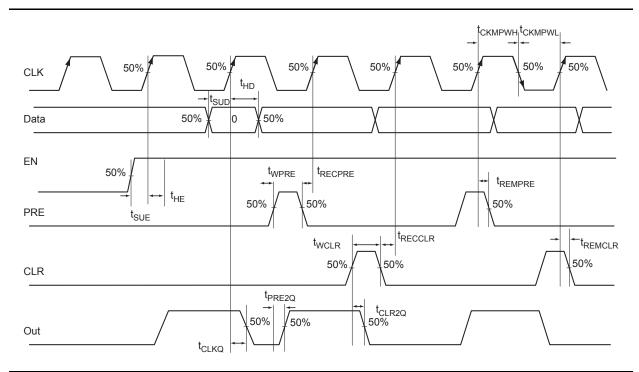


Figure 2-6 • Sequential Timing Model and Waveforms

### Sequential Timing Characteristics

Table 2-2 • Register Delays
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>CLKQ</sub>	Clock-to-Q of the Core Register	0.55	0.63	0.74	ns
t <sub>SUD</sub>	Data Setup Time for the Core Register	0.43	0.49	0.57	ns
t <sub>HD</sub>	Data Hold Time for the Core Register	0.00	0.00	0.00	ns
t <sub>SUE</sub>	Enable Setup Time for the Core Register	0.45	0.52	0.61	ns
t <sub>HE</sub>	Enable Hold Time for the Core Register	0.00	0.00	0.00	ns
t <sub>CLR2Q</sub>	Asynchronous Clear-to-Q of the Core Register	0.40	0.45	0.53	ns
t <sub>PRE2Q</sub>	Asynchronous Preset-to-Q of the Core Register	0.40	0.45	0.53	ns
t <sub>REMCLR</sub>	Asynchronous Clear Removal Time for the Core Register	0.00	0.00	0.00	ns
t <sub>RECCLR</sub>	Asynchronous Clear Recovery Time for the Core Register	0.22	0.25	0.30	ns
t <sub>REMPRE</sub>	Asynchronous Preset Removal Time for the Core Register	0.00	0.00	0.00	ns
t <sub>RECPRE</sub>	Asynchronous Preset Recovery Time for the Core Register	0.22	0.25	0.30	ns
t <sub>WCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Core Register	0.22	0.25	0.30	ns
t <sub>WPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Core Register	0.22	0.25	0.30	ns
t <sub>CKMPWH</sub>	Clock Minimum Pulse Width High for the Core Register	0.32	0.37	0.43	ns
t <sub>CKMPWL</sub>	Clock Minimum Pulse Width Low for the Core Register	0.36	0.41	0.48	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



## **Array Coordinates**

During many place-and-route operations in the Microsemi Designer software tool, it is possible to set constraints that require array coordinates. Table 2-3 is provided as a reference. The array coordinates are measured from the lower left (0, 0). They can be used in region constraints for specific logic groups/blocks, designated by a wild card, and can contain core cells, memories, and I/Os.

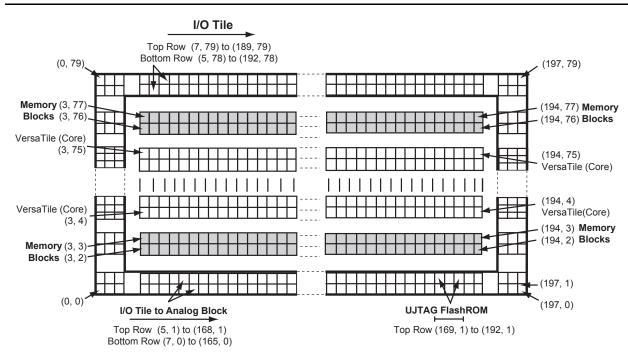
Table 2-3 provides array coordinates of core cells and memory blocks.

I/O and cell coordinates are used for placement constraints. Two coordinate systems are needed because there is not a one-to-one correspondence between I/O cells and edge core cells. In addition, the I/O coordinate system changes depending on the die/package combination. It is not listed in Table 2-3. The Designer ChipPlanner tool provides array coordinates of all I/O locations. I/O and cell coordinates are used for placement constraints. However, I/O placement is easier by package pin assignment.

Figure 2-7 illustrates the array coordinates of an AFS600 device. For more information on how to use array coordinates for region/placement constraints, see the *Designer User's Guide* or online help (available in the software) for Fusion software tools.

Table 2-3 • Array Coordinates

		Vers	aTiles		Memor	y Rows	All		
Device	Mi	Min.		Max.		Тор	Min.	Max.	
	х	у	х	у	(x, y)	(x, y)	(x, y)	(x, y)	
AFS090	3	2	98	25	None	None (3, 26)		(101, 29)	
AFS250	3	2	130	49	None	(3, 50)	(0, 0)	(133, 53)	
AFS600	3	4	194	75	(3, 2)	(3, 76)	(0, 0)	(197, 79)	
AFS1500	3	4	322	123	(3, 2)	(3, 124)	(0, 0)	(325, 129)	



Note: The vertical I/O tile coordinates are not shown. West side coordinates are {(0, 2) to (2, 2)} to {(0, 77) to (2, 77)}; east side coordinates are {(195, 2) to (197, 2)} to {(195, 77) to (197, 77)}.

Figure 2-7 • Array Coordinates for AFS600

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## **Routing Architecture**

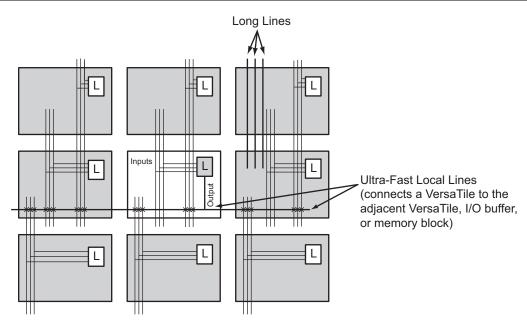
The routing structure of Fusion devices is designed to provide high performance through a flexible four-level hierarchy of routing resources: ultra-fast local resources; efficient long-line resources; high-speed very-long-line resources; and the high-performance VersaNet networks.

The ultra-fast local resources are dedicated lines that allow the output of each VersaTile to connect directly to every input of the eight surrounding VersaTiles (Figure 2-8). The exception to this is that the SET/CLR input of a VersaTile configured as a D-flip-flop is driven only by the VersaNet global network.

The efficient long-line resources provide routing for longer distances and higher-fanout connections. These resources vary in length (spanning one, two, or four VersaTiles), run both vertically and horizontally, and cover the entire Fusion device (Figure 2-9 on page 2-9). Each VersaTile can drive signals onto the efficient long-line resources, which can access every input of every VersaTile. Active buffers are inserted automatically by routing software to limit loading effects.

The high-speed very-long-line resources, which span the entire device with minimal delay, are used to route very long or high-fanout nets: length ±12 VersaTiles in the vertical direction and length ±16 in the horizontal direction from a given core VersaTile (Figure 2-10 on page 2-10). Very long lines in Fusion devices, like those in ProASIC3 devices, have been enhanced. This provides a significant performance boost for long-reach signals.

The high-performance VersaNet global networks are low-skew, high-fanout nets that are accessible from external pins or from internal logic (Figure 2-11 on page 2-11). These nets are typically used to distribute clocks, reset signals, and other high-fanout nets requiring minimum skew. The VersaNet networks are implemented as clock trees, and signals can be introduced at any junction. These can be employed hierarchically, with signals accessing every input on all VersaTiles.



Note: Input to the core cell for the D-flip-flop set and reset is only available via the VersaNet global network connection.

Figure 2-8 • Ultra-Fast Local Lines Connected to the Eight Nearest Neighbors



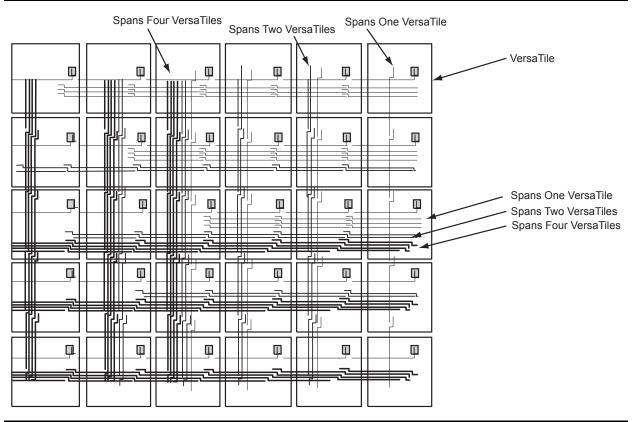


Figure 2-9 • Efficient Long-Line Resources

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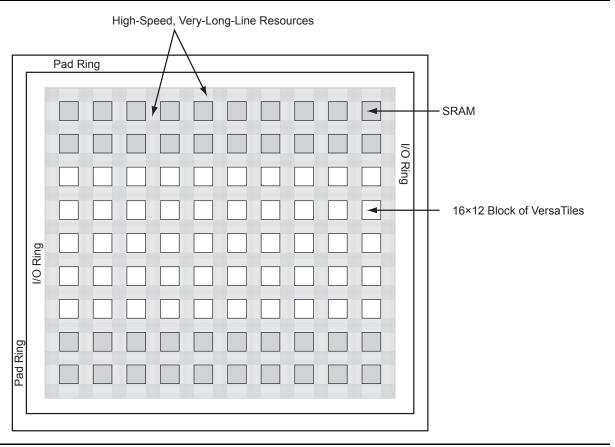


Figure 2-10 • Very-Long-Line Resources



## **Global Resources (VersaNets)**

Fusion devices offer powerful and flexible control of circuit timing through the use of analog circuitry. Each chip has six CCCs. The west CCC also contains a PLL core. In the two larger devices (AFS600 and AFS1500), the west and the east CCCs each contain a PLL. The PLLs include delay lines, a phase shifter (0°, 90°, 180°, 270°), and clock multipliers/dividers. Each CCC has all the circuitry needed for the selection and interconnection of inputs to the VersaNet global network. The east and west CCCs each have access to three VersaNet global lines on each side of the chip (six lines total). The CCCs at the four corners each have access to three quadrant global lines on each quadrant of the chip.

## Advantages of the VersaNet Approach

One of the architectural benefits of Fusion is the set of powerful and low-delay VersaNet global networks. Fusion offers six chip (main) global networks that are distributed from the center of the FPGA array (Figure 2-11). In addition, Fusion devices have three regional globals (quadrant globals) in each of the four chip quadrants. Each core VersaTile has access to nine global network resources: three quadrant and six chip (main) global networks. There are a total of 18 global networks on the device. Each of these networks contains spines and ribs that reach all VersaTiles in all quadrants (Figure 2-12 on page 2-12). This flexible VersaNet global network architecture allows users to map up to 180 different internal/external clocks in a Fusion device. Details on the VersaNet networks are given in Table 2-4 on page 2-12. The flexibility of the Fusion VersaNet global network allows the designer to address several design requirements. User applications that are clock-resource-intensive can easily route external or gated internal clocks using VersaNet global routing networks. Designers can also drastically reduce delay penalties and minimize resource usage by mapping critical, high-fanout nets to the VersaNet global network.

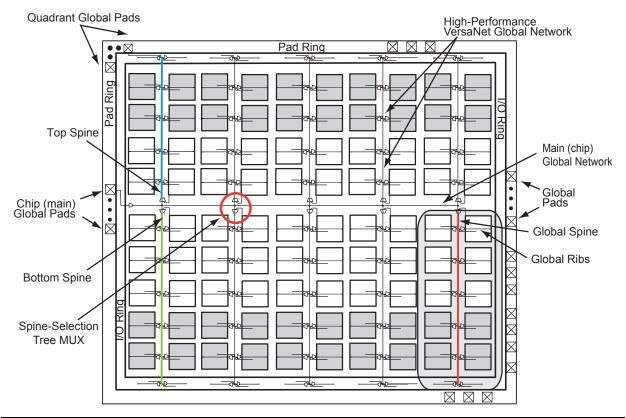


Figure 2-11 • Overview of Fusion VersaNet Global Network

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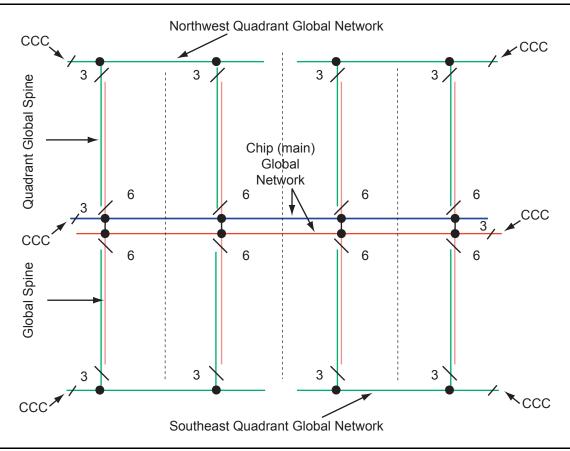


Figure 2-12 • Global Network Architecture

Table 2-4 • Globals/Spines/Rows by Device

	AFS090	AFS250	AFS600	AFS1500
Global VersaNets (trees)*	9	9	9	9
VersaNet Spines/Tree	4	8	12	20
Total Spines	36	72	108	180
VersaTiles in Each Top or Bottom Spine	384	768	1,152	1,920
Total VersaTiles	2,304	6,144	13,824	38,400

Note: \*There are six chip (main) globals and three globals per quadrant.



## VersaNet Global Networks and Spine Access

The Fusion architecture contains a total of 18 segmented global networks that can access the VersaTiles, SRAM, and I/O tiles on the Fusion device. There are 6 chip (main) global networks that access the entire device and 12 quadrant networks (3 in each quadrant). Each device has a total of 18 globals. These VersaNet global networks offer fast, low-skew routing resources for high-fanout nets, including clock signals. In addition, these highly segmented global networks offer users the flexibility to create low-skew local networks using spines for up to 180 internal/external clocks (in an AFS1500 device) or other high-fanout nets in Fusion devices. Optimal usage of these low-skew networks can result in significant improvement in design performance on Fusion devices.

The nine spines available in a vertical column reside in global networks with two separate regions of scope: the quadrant global network, which has three spines, and the chip (main) global network, which has six spines. Note that there are three quadrant spines in each quadrant of the device. There are four quadrant global network regions per device (Figure 2-12 on page 2-12).

The spines are the vertical branches of the global network tree, shown in Figure 2-11 on page 2-11. Each spine in a vertical column of a chip (main) global network is further divided into two equal-length spine segments: one in the top and one in the bottom half of the die.

Each spine and its associated ribs cover a certain area of the Fusion device (the "scope" of the spine; see Figure 2-11 on page 2-11). Each spine is accessed by the dedicated global network MUX tree architecture, which defines how a particular spine is driven—either by the signal on the global network from a CCC, for example, or another net defined by the user (Figure 2-13). Quadrant spines can be driven from user I/Os on the north and south sides of the die, via analog I/Os configured as direct digital inputs. The ability to drive spines in the quadrant global networks can have a significant effect on system performance for high-fanout inputs to a design.

Details of the chip (main) global network spine-selection MUX are presented in Figure 2-13. The spine drivers for each spine are located in the middle of the die.

Quadrant spines are driven from a north or south rib. Access to the top and bottom ribs is from the corner CCC or from the I/Os on the north and south sides of the device. For details on using spines in Fusion devices, see the application note *Using Global Resources in Actel Fusion Devices*.

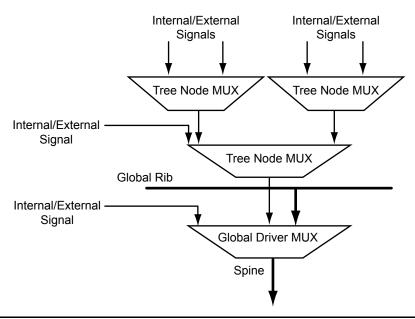


Figure 2-13 • Spine-Selection MUX of Global Tree

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## Clock Aggregation

Clock aggregation allows for multi-spine clock domains. A MUX tree provides the necessary flexibility to allow long lines or I/Os to access domains of one, two, or four global spines. Signal access to the clock aggregation system is achieved through long-line resources in the central rib, and also through local resources in the north and south ribs, allowing I/Os to feed directly into the clock system. As Figure 2-14 indicates, this access system is contiguous.

There is no break in the middle of the chip for north and south I/O VersaNet access. This is different from the quadrant clocks, located in these ribs, which only reach the middle of the rib. Refer to the *Using Global Resources in Actel Fusion Devices* application note.

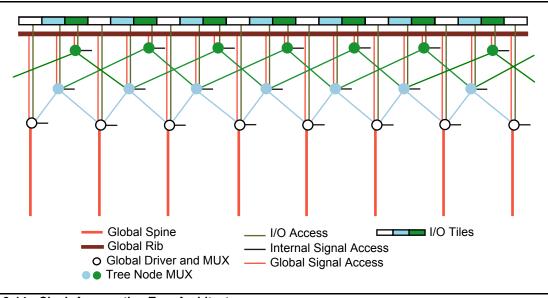


Figure 2-14 • Clock Aggregation Tree Architecture



## Global Resource Characteristics

### AFS600 VersaNet Topology

Clock delays are device-specific. Figure 2-15 is an example of a global tree used for clock routing. The global tree presented in Figure 2-15 is driven by a CCC located on the west side of the AFS600 device. It is used to drive all D-flip-flops in the device.

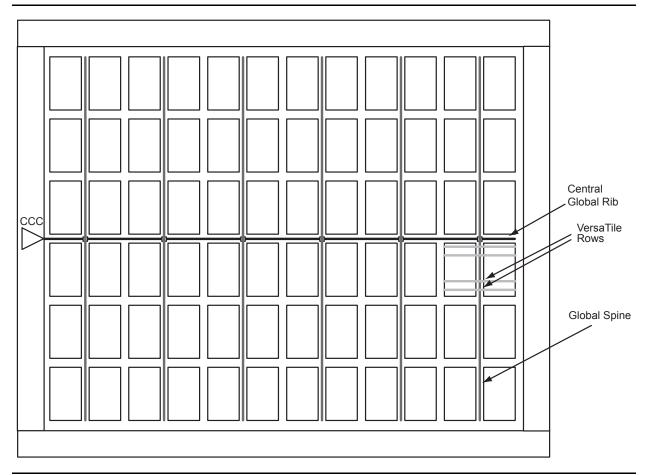


Figure 2-15 • Example of Global Tree Use in an AFS600 Device for Clock Routing

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### VersaNet Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are dependent upon I/O standard, and the clock may be driven and conditioned internally by the CCC module. Table 2-5, Table 2-6, Table 2-7, and Table 2-8 on page 2-17 present minimum and maximum global clock delays within the device Minimum and maximum delays are measured with minimum and maximum loading, respectively.

#### **Timing Characteristics**

Table 2-5 • AFS1500 Global Resource Timing

Commercial Temperature Range Conditions: T<sub>.I</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	_	-2		-1		Std.	
	Description		Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	1.53	1.75	1.74	1.99	2.05	2.34	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	1.53	1.79	1.75	2.04	2.05	2.40	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.26		0.29		0.34	ns

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Table 2-6 • AFS600 Global Resource Timing

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	_	-2		-1		Std.	
	Description		Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	1.27	1.49	1.44	1.70	1.69	2.00	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	1.26	1.54	1.44	1.75	1.69	2.06	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.27		0.31		0.36	ns

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



Table 2-7 • AFS250 Global Resource Timing

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	_	-2		<b>-1</b>		Std.	
	Description		Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	0.89	1.12	1.02	1.27	1.20	1.50	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	0.88	1.14	1.00	1.30	1.17	1.53	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.26		0.30		0.35	ns

#### Notes:

- Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Table 2-8 • AFS090 Global Resource Timing

Commercial Temperature Range Conditions: T<sub>,I</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2		-1		Std.		Units
	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Ullits
t <sub>RCKL</sub>	Input Low Delay for Global Clock	0.84	1.07	0.96	1.21	1.13	1.43	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	0.83	1.10	0.95	1.25	1.12	1.47	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.27		0.30		0.36	ns

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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## **Clocking Resources**

The Fusion family has a robust collection of clocking peripherals, as shown in the block diagram in Figure 2-16. These on-chip resources enable the creation, manipulation, and distribution of many clock signals. The Fusion integrated RC oscillator produces a 100 MHz clock source with no external components. For systems requiring more precise clock signals, the Fusion family supports an on-chip crystal oscillator circuit. The integrated PLLs in each Fusion device can use the RC oscillator, crystal oscillator, or another on-chip clock signal as a source. These PLLs offer a variety of capabilities to modify the clock source (multiply, divide, synchronize, advance, or delay). Utilizing the CCC found in the popular ProASIC3 family, Fusion incorporates six CCC blocks. The CCCs allow access to Fusion global and local clock distribution nets, as described in the "Global Resources (VersaNets)" section on page 2-11.

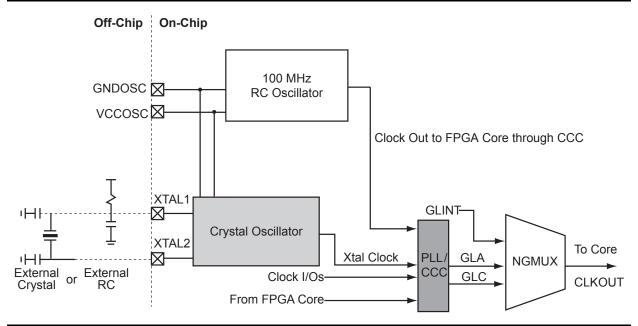


Figure 2-16 • Fusion Clocking Options



### **RC** Oscillator

The RC oscillator is an on-chip free-running clock source generating a 100 MHz clock. It can be used as a source clock for both on-chip and off-chip resources. When used in conjunction with the Fusion PLL and CCC circuits, the RC oscillator clock source can be used to generate clocks of varying frequency and phase.

The Fusion RC oscillator is very accurate at  $\pm 1\%$  over commercial temperature ranges and  $\pm 3\%$  over industrial temperature ranges. It is an automated clock, requiring no setup or configuration by the user. It requires only that the power and GNDOSC pins be connected; no external components are required. The RC oscillator can be used to drive either a PLL or another internal signal.

#### RC Oscillator Characteristics

Table 2-9 • Electrical Characteristics of RC Oscillator

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
F <sub>RC</sub>	Operating Frequency			100		MHz
	Accuracy	Temperature: 0°C to 85°C Voltage: 3.3 V ± 5%		1		%
		Temperature: –40°C to 125°C Voltage: 3.3 V ± 5%		3		%
	Output Jitter	Period Jitter (at 5 k cycles)		100		ps
		Cycle–Cycle Jitter (at 5 k cycles)		100		ps
		Period Jitter (at 5 k cycles) with 1 KHz / 300 mV peak-to-peak noise on power supply		150		ps
		Cycle–Cycle Jitter (at 5 k cycles) with 1 KHz / 300 mV peak-to-peak noise on power supply		150		ps
	Output Duty Cycle			50		%
I <sub>DYNRC</sub>	Operating Current			1		mA

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## **Crystal Oscillator**

The Crystal Oscillator (XTLOSC) is source that generates the clock from an external crystal. The output of XTLOSC CLKOUT signal can be selected as an input to the PLL. Refer to the "Clock Conditioning Circuits" section for more details. The XTLOSC can operate in normal operations and Standby mode (RTC is running and 1.5 V is not present).

In normal operation, the internal FPGA\_EN signal is '1' as long as 1.5 V is present for VCC. As such, the internal enable signal, XTL\_EN, for Crystal Oscillator is enabled since FPGA\_EN is asserted. The XTL\_MODE has the option of using MODE or RTC\_MODE, depending on SELMODE.

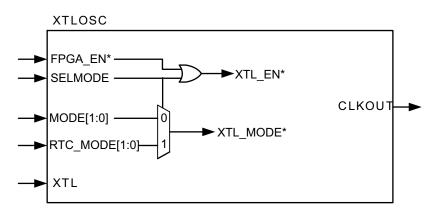
During Standby, 1.5 V is not available, as such, and FPGA\_EN is '0'. SELMODE must be asserted in order for XTL\_EN to be enabled; hence XTL\_MODE relies on RTC\_MODE. SELMODE and RTC\_MODE must be connected to RTCXTLSEL and RTCXTLMODE from the AB respectively for correct operation during Standby (refer to the "Real-Time Counter System" section on page 2-31 for a detailed description).

The Crystal Oscillator can be configured in one of four modes:

- · RC network, 32 KHz to 4 MHz
- Low gain, 32 to 200 KHz
- Medium gain, 0.20 to 2.0 MHz
- High gain, 2.0 to 20.0 MHz

In RC network mode, the XTAL1 pin is connected to an RC circuit, as shown in Figure 2-16 on page 2-18. The XTAL2 pin should be left floating. The RC value can be chosen based on Figure 2-18 for any desired frequency between 32 KHz and 4 MHz. The RC network mode can also accommodate an external clock source on XTAL1 instead of an RC circuit.

In Low gain, Medium gain, and High gain, an external crystal component or ceramic resonator can be added onto XTAL1 and XTAL2, as shown in Figure 2-16 on page 2-18. In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating.



Note: \*Internal signal—does not exist in macro.

Figure 2-17 • XTLOSC Macro



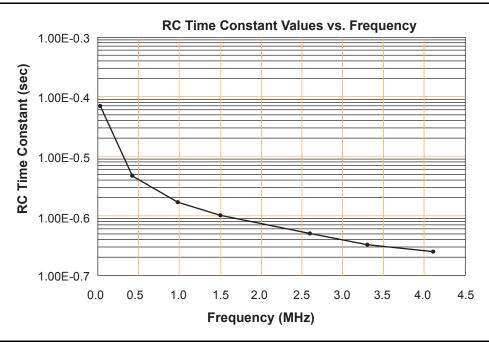


Figure 2-18 • Crystal Oscillator: RC Time Constant Values vs. Frequency (typical)

Table 2-10 • XTLOSC Signals Descriptions

Signal Name	Width	Direction	Function					
XTL_EN*	1		Enables the crystal. Active high.					
XTL_MODE*	2		Settings for the crystal clock for different frequency.					
			Value	Modes	Frequency Range			
			b'00	RC network	32 KHz to 4 MHz			
			b'01	Low gain	32 to 200 KHz			
			b'10	Medium gain	0.20 to 2.0 MHz			
			b'11	High gain	2.0 to 20.0 MHz			
SELMODE	1	IN	Selects the source of XTL_MODE and also enables the XTL_EN. Connect from RTCXTLSEL from AB.					
			0	For normal operation or sleep mode, XTL_EN depends on FPGA_EN, XTL_MODE depends on MODE				
			1	For Standby mode, XTL_EN is enabled, XTL_MODE depends on RTC_MODE				
RTC_MODE[1:0]	2	IN	Settings for the crystal clock for different frequency ranges. XTL_MODE uses RTC_MODE when SELMODE is '1'.					
MODE[1:0]	2	IN	Settings for the crystal clock for different frequency ranges. XTL_MODE uses MODE when SELMODE is '0'. In Standby, MODE inputs will be 0's.					
FPGA_EN*	1	IN	0 when 1.5 V is not present for VCC 1 when 1.5 V is present for VCC					
XTL	1	IN	Crystal Clock source					
CLKOUT	1	OUT	Crystal Clock output					

Note: \*Internal signal—does not exist in macro.

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# **Clock Conditioning Circuits**

In Fusion devices, the CCCs are used to implement frequency division, frequency multiplication, phase shifting, and delay operations.

The CCCs are available in six chip locations—each of the four chip corners and the middle of the east and west chip sides.

Each CCC can implement up to three independent global buffers (with or without programmable delay), or a PLL function (programmable frequency division/multiplication, phase shift, and delays) with up to three global outputs. Unused global outputs of a PLL can be used to implement independent global buffers, up to a maximum of three global outputs for a given CCC.

A global buffer can be placed in any of the three global locations (CLKA-GLA, CLKB-GLB, and CLKC-GLC) of a given CCC.

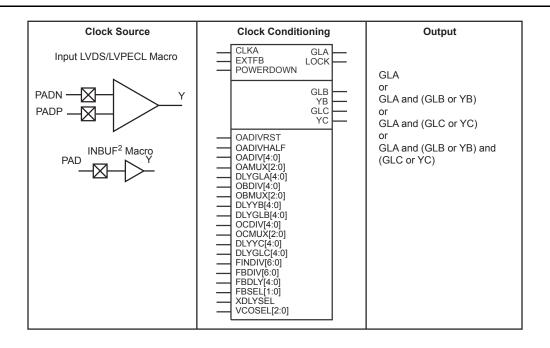
A PLL macro uses the CLKA CCC input to drive its reference clock. It uses the GLA and, optionally, the GLB and GLC global outputs to drive the global networks. A PLL macro can also drive the YB and YC regular core outputs. The GLB (or GLC) global output cannot be reused if the YB (or YC) output is used (Figure 2-19). Refer to the "PLL Macro" section on page 2-27 for more information.

Each global buffer, as well as the PLL reference clock, can be driven from one of the following:

- 3 dedicated single-ended I/Os using a hardwired connection
- · 2 dedicated differential I/Os using a hardwired connection
- · The FPGA core

The CCC block is fully configurable, either via flash configuration bits set in the programming bitstream or through an asynchronous interface. This asynchronous interface is dynamically accessible from inside the Fusion device to permit changes of parameters (such as divide ratios) during device operation. To increase the versatility and flexibility of the clock conditioning system, the CCC configuration is determined either by the user during the design process, with configuration data being stored in flash memory as part of the device programming procedure, or by writing data into a dedicated shift register during normal device operation. This latter mode allows the user to dynamically reconfigure the CCC without the need for core programming. The shift register is accessed through a simple serial interface. Refer to the "UJTAG Applications in Micro-semi's Low-Power Flash Devices" chapter of the *Fusion FPGA Fabric User Guide* and the "CCC and PLL Characteristics" section on page 2-28 for more information.





#### Notes:

- 1. Visit the Microsemi SoC Products Group website for application notes concerning dynamic PLL reconfiguration. Refer to the "PLL Macro" section on page 2-27 for signal descriptions.
- 2. Many specific INBUF macros support the wide variety of single-ended and differential I/O standards for the Fusion family.
- 3. Refer to the IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide for more information.

Figure 2-19 • Fusion CCC Options: Global Buffers with the PLL Macro

Table 2-11 • Available Selections of I/O Standards within CLKBUF and CLKBUF\_LVDS/LVPECL Macros

CLKBUF Macros
CLKBUF_LVCMOS5
CLKBUF_LVCMOS33 <sup>1</sup>
CLKBUF_LVCMOS18
CLKBUF_LVCMOS15
CLKBUF_PCI
CLKBUF_LVDS <sup>2</sup>
CLKBUF_LVPECL

#### Notes:

- 1. This is the default macro. For more details, refer to the IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide.
- 2. The B-LVDS and M-LVDS standards are supported with CLKBUF\_LVDS.

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## Global Buffers with No Programmable Delays

The CLKBUF and CLKBUF\_LVPECL/LVDS macros are composite macros that include an I/O macro driving a global buffer, hardwired together (Figure 2-20).

The CLKINT macro provides a global buffer function driven by the FPGA core.

The CLKBUF, CLKBUF\_LVPECL/LVDS, and CLKINT macros are pass-through clock sources and do not use the PLL or provide any programmable delay functionality.

Many specific CLKBUF macros support the wide variety of single-ended and differential I/O standards supported by Fusion devices. The available CLKBUF macros are described in the IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide.

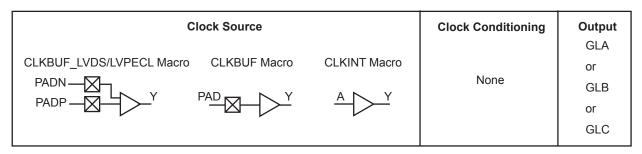


Figure 2-20 • Global Buffers with No Programmable Delay

## Global Buffers with Programmable Delay

The CLKDLY macro is a pass-through clock source that does not use the PLL, but provides the ability to delay the clock input using a programmable delay (Figure 2-21 on page 2-25). The CLKDLY macro takes the selected clock input and adds a user-defined delay element. This macro generates an output clock phase shift from the input clock.

The CLKDLY macro can be driven by an INBUF macro to create a composite macro, where the I/O macro drives the global buffer (with programmable delay) using a hardwired connection. In this case, the I/O must be placed in one of the dedicated global I/O locations.

Many specific INBUF macros support the wide variety of single-ended and differential I/O standards supported by the Fusion family. The available INBUF macros are described in the IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide.

The CLKDLY macro can be driven directly from the FPGA core.

The CLKDLY macro can also be driven from an I/O that is routed through the FPGA regular routing fabric. In this case, users must instantiate a special macro, PLLINT, to differentiate from the hardwired I/O connection described earlier.

The visual CLKDLY configuration in the SmartGen part of the Libero SoC and Designer tools allows the user to select the desired amount of delay and configures the delay elements appropriately. SmartGen also allows the user to select the input clock source. SmartGen will automatically instantiate the special macro, PLLINT, when needed.



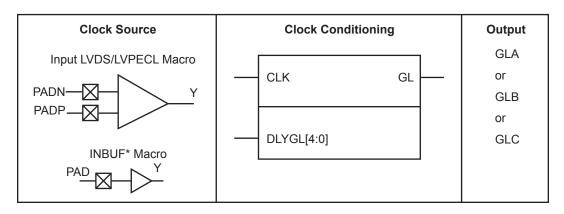
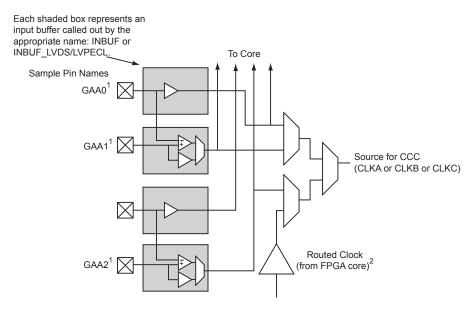


Figure 2-21 • Fusion CCC Options: Global Buffers with Programmable Delay

# **Global Input Selections**

Each global buffer, as well as the PLL reference clock, can be driven from one of the following (Figure 2-22):

- · 3 dedicated single-ended I/Os using a hardwired connection
- · 2 dedicated differential I/Os using a hardwired connection
- The FPGA core



GAA[0:2]: GA represents global in the northwest corner of the device. A[0:2]: designates specific A clock source.

### Notes:

- 1. Represents the global input pins. Globals have direct access to the clock conditioning block and are not routed via the FPGA fabric. Refer to the "User I/O Naming Convention" section on page 2-158 for more information.
- 2. Instantiate the routed clock source input as follows:
  - a) Connect the output of a logic element to the clock input of the PLL, CLKDLY, or CLKINT macro.
  - b) Do not place a clock source I/O (INBUF or INBUF\_LVPECL/LVDS) in a relevant global pin location.
- 3. LVDS-based clock sources are available in the east and west banks on all Fusion devices.

Figure 2-22 • Clock Input Sources Including CLKBUF, CLKBUF\_LVDS/LVPECL, and CLKINT

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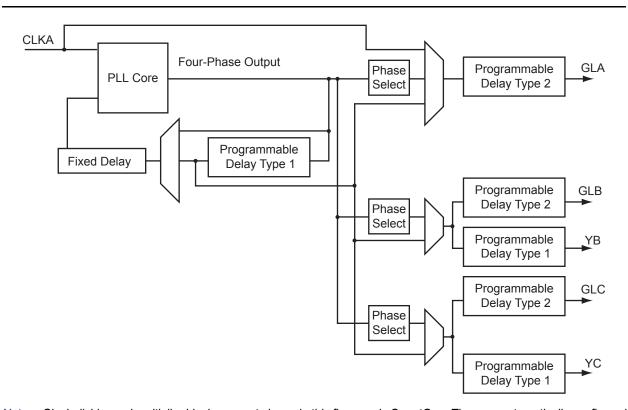
## **CCC Physical Implementation**

The CCC circuit is composed of the following (Figure 2-23):

- PLL core
- · 3 phase selectors
- · 6 programmable delays and 1 fixed delay
- 5 programmable frequency dividers that provide frequency multiplication/division (not shown in Figure 2-23 because they are automatically configured based on the user's required frequencies)
- 1 dynamic shift register that provides CCC dynamic reconfiguration capability (not shown)

### **CCC Programming**

The CCC block is fully configurable. It is configured via static flash configuration bits in the array, set by the user in the programming bitstream, or configured through an asynchronous dedicated shift register, dynamically accessible from inside the Fusion device. The dedicated shift register permits changes of parameters such as PLL divide ratios and delays during device operation. This latter mode allows the user to dynamically reconfigure the PLL without the need for core programming. The register file is accessed through a simple serial interface.



Note: Clock divider and multiplier blocks are not shown in this figure or in SmartGen. They are automatically configured based on the user's required frequencies.

Figure 2-23 • PLL Block



### PLL Macro

The PLL functionality of the clock conditioning block is supported by the PLL macro. Note that the PLL macro reference clock uses the CLKA input of the CCC block, which is only accessible from the global A[2:0] package pins. Refer to Figure 2-22 on page 2-25 for more information.

The PLL macro provides five derived clocks (three independent) from a single reference clock. The PLL feedback loop can be driven either internally or externally. The PLL macro also provides power-down input and lock output signals. During power-up, POWERDOWN should be asserted Low until VCC is up. See Figure 2-19 on page 2-23 for more information.

#### Inputs:

- · CLKA: selected clock input
- POWERDOWN (active low): disables PLLs. The default state is power-down on (active low).

#### Outputs:

- LOCK (active high): indicates that PLL output has locked on the input reference signal
- · GLA, GLB, GLC: outputs to respective global networks
- · YB, YC: allows output from the CCC to be routed back to the FPGA core

As previously described, the PLL allows up to five flexible and independently configurable clock outputs. Figure 2-23 on page 2-26 illustrates the various clock output options and delay elements.

As illustrated, the PLL supports three distinct output frequencies from a given input clock. Two of these (GLB and GLC) can be routed to the B and C global networks, respectively, and/or routed to the device core (YB and YC).

There are five delay elements to support phase control on all five outputs (GLA, GLB, GLC, YB, and YC). There is also a delay element in the feedback loop that can be used to advance the clock relative to the reference clock.

The PLL macro reference clock can be driven by an INBUF macro to create a composite macro, where the I/O macro drives the global buffer (with programmable delay) using a hardwired connection. In this case, the I/O must be placed in one of the dedicated global I/O locations.

The PLL macro reference clock can be driven directly from the FPGA core.

The PLL macro reference clock can also be driven from an I/O routed through the FPGA regular routing fabric. In this case, users must instantiate a special macro, PLLINT, to differentiate it from the hardwired I/O connection described earlier.

The visual PLL configuration in SmartGen, available with the Libero SoC and Designer tools, will derive the necessary internal divider ratios based on the input frequency and desired output frequencies selected by the user. SmartGen allows the user to select the various delays and phase shift values necessary to adjust the phases between the reference clock (CLKA) and the derived clocks (GLA, GLB, GLC, YB, and YC). SmartGen also allows the user to select where the input clock is coming from. SmartGen automatically instantiates the special macro, PLLINT, when needed.

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## CCC and PLL Characteristics

## **Timing Characteristics**

## Table 2-12 • Fusion CCC/PLL Specification

Parameter	Min.	Тур.	Max.	Unit
Clock Conditioning Circuitry Input Frequency f <sub>IN_CCC</sub>	1.5		350	MHz
Clock Conditioning Circuitry Output Frequency f <sub>OUT_CCC</sub>	0.75		350	MHz
Delay Increments in Programmable Delay Blocks <sup>1, 2</sup>		160 <sup>3</sup>		ps
Number of Programmable Values in Each Programmable Delay Block			32	
Input Period Jitter			1.5	ns
CCC Output Peak-to-Peak Period Jitter F <sub>CCC_OUT</sub>	Max Pea	k-to-Peak Po	eriod Jitter	
	1 Global Network Used		3 Global Networks Used	
0.75 MHz to 24 MHz	1.00%		1.00%	
24 MHz to 100 MHz	1.50%		1.50%	
100 MHz to 250 MHz	2.25%		2.25%	
250 MHz to 350 MHz	3.50%		3.50%	
Acquisition Time LockControl = 0			300	μs
LockControl = 1			6.0	ms
Tracking Jitter <sup>4</sup> LockControl = 0			1.6	ns
LockControl = 1			0.8	ns
Output Duty Cycle	48.5		51.5	%
Delay Range in Block: Programmable Delay 1 <sup>1, 2</sup>	0.6		5.56	ns
Delay Range in Block: Programmable Delay 2 1, 2	0.025		5.56	ns
Delay Range in Block: Fixed Delay <sup>1, 2</sup>		2.2		ns

#### Notes:

- 1. This delay is a function of voltage and temperature. See Table 3-7 on page 3-9 for deratings.
- 2.  $T_J = 25^{\circ}C$ , VCC = 1.5 V
- 3. When the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available. Refer to the Libero SoC Online Help associated with the core for more information.
- 4. Tracking jitter is defined as the variation in clock edge position of PLL outputs with reference to PLL input clock edge. Tracking jitter does not measure the variation in PLL output period, which is covered by period jitter parameter.



## **No-Glitch MUX (NGMUX)**

Positioned downstream from the PLL/CCC blocks, the NGMUX provides a special switching sequence between two asynchronous clock domains that prevents generating any unwanted narrow clock pulses. The NGMUX is used to switch the source of a global between three different clock sources. Allowable inputs are either two PLL/CCC outputs or a PLL/CCC output and a regular net, as shown in Figure 2-24. The GLMUXCFG[1:0] configuration bits determine the source of the CLK inputs (i.e., internal signal or GLC). These are set by SmartGen during design but can also be changed by dynamically reconfiguring the PLL. The GLMUXSEL[1:0] bits control which clock source is passed through the NGMUX to the global network (GL). See Table 2-13.

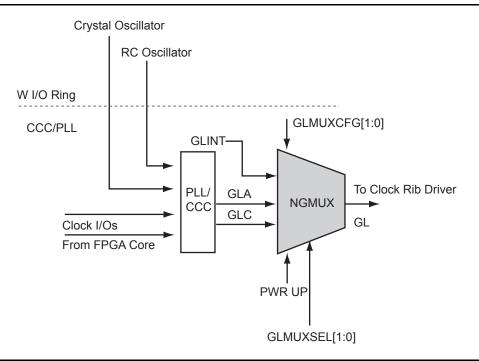


Figure 2-24 • NGMUX

Table 2-13 • NGMUX Configuration and Selection Table

GLMUXCFG[1:0]	GLMUXSEL[1:0]		Selected Input Signal	MUX Type
00	Х	0	GLA	2-to-1 GLMUX
00	Х	1	GLC	2-to-1 GLIVIOX
01	Х	0	GLA	2-to-1 GLMUX
01	Х	1	GLINT	2-10-1 GLIVIOX

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The NGMUX macro is simplified to show the two clock options that have been selected by the GLMUXCFG[1:0] bits. Figure 2-25 illustrates the NGMUX macro. During design, the two clock sources are connected to CLK0 and CLK1 and are controlled by GLMUXSEL[1:0] to determine which signal is to be passed through the MUX.

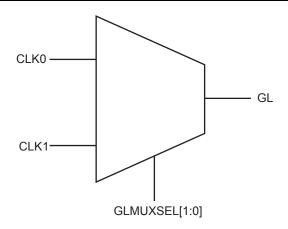


Figure 2-25 • NGMUX Macro

The sequence of switching between two clock sources (from CLK0 to CLK1) is as follows (Figure 2-26):

- GLMUXSEL[1:0] transitions to initiate a switch.
- GL drives one last complete CLK0 positive pulse (i.e., one rising edge followed by one falling edge).
- From that point, GL stays Low until the second rising edge of CLK1 occurs.
- · At the second CLK1 rising edge, GL will begin to continuously deliver the CLK1 signal.
- Minimum t<sub>sw</sub> = 0.05 ns at 25°C (typical conditions)

For examples of NGMUX operation, refer to the Fusion FPGA Fabric User Guide.

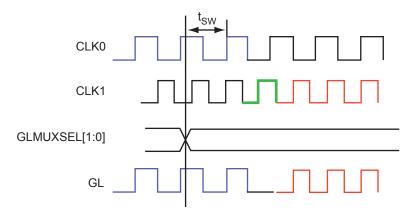


Figure 2-26 • NGMUX Waveform



# **Real-Time Counter System**

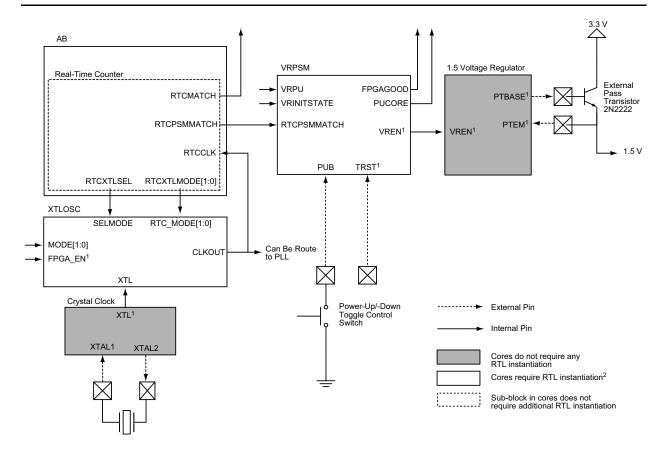
The RTC system enables Fusion devices to support standby and sleep modes of operation to reduce power consumption in many applications.

- Sleep mode, typical 10 μA
- Standby mode (RTC running), typical 3 mA with 20 MHz

The RTC system is composed of five cores:

- RTC sub-block inside Analog Block (AB)
- Voltage Regulator and Power System Monitor (VRPSM)
- Crystal oscillator (XTLOSC); refer to the "Crystal Oscillator" section in the Fusion Clock Resources chapter of the Fusion FPGA Fabric User Guide for more detail.
- Crystal clock; does not require instantiation in RTL
- · 1.5 V voltage regulator; does not require instantiation in RTL

All cores are powered by 3.3 V supplies, so the RTC system is operational without a 1.5 V supply during standby mode. Figure 2-27 shows their connection.



#### Notes:

- 1. Signals are hardwired internally and do not exist in the macro core.
- 2. User is only required to instantiate the VRPSM macro if the user wishes to specify PUPO behavior of the voltage regulator to be different from the default, or employ user logic to shut the voltage regulator off.

Figure 2-27 • Real-Time Counter System (not all the signals are shown for the AB macro)

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## **Modes of Operation**

## Standby Mode

Standby mode allows periodic power-up and power-down of the FPGA fabric. In standby mode, the real-time counter and crystal block are ON. The FPGA is not powered by disabling the 1.5 V voltage regulator. The 1.5 V voltage regulator can be enabled when the preset count is matched. Refer to the "Real-Time Counter (part of AB macro)" section for details. To enter standby mode, the RTC must be first configured and enabled. Then VRPSM is shut off by deasserting the VRPU signal. The 1.5 V voltage regulator is then disabled, and shuts off the 1.5 V output.

## Sleep Mode

In sleep mode, the real-time counter and crystal blocks are OFF. The 1.5 V voltage regulator inside the VRPSM can only be enabled by the PUB or TRST pin. Refer to the "Voltage Regulator and Power System Monitor (VRPSM)" section on page 2-36 for details on power-up and power-down of the 1.5 V voltage regulator.

# Standby and Sleep Mode Circuit Implementation

For extra power savings, VJTAG and VPUMP should be at the same voltage as VCC, floated or ground, during standby and sleep modes. Note that when VJTAG is not powered, the 1.5 V voltage regulator cannot be enabled through TRST.

VPUMP and VJTAG can be controlled through an external switch. Microsemi recommends ADG839, ADG849, or ADG841 as possible switches. Figure 2-28 shows the implementation for controlling VPUMP. The IN signal of the switch can be connected to PTBASE of the Fusion device. VJTAG can be controlled in same manner.

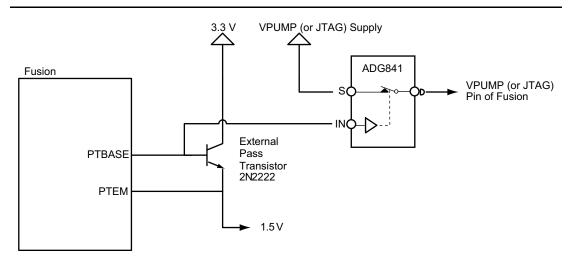


Figure 2-28 • Implementation to Control VPUMP



# **Real-Time Counter (part of AB macro)**

The RTC is a 40-bit loadable counter and used as the primary timekeeping element (Figure 2-29). The clock source, RTCCLK, must come from the CLKOUT signal of the crystal oscillator. The RTC can be configured to reset itself when a count value reaches the match value set in the Match Register.

The RTC is part of the Analog Block (AB) macro. The RTC is configured by the analog configuration MUX (ACM). Each address contains one byte of data. The circuitry in the RTC is powered by VCC33A, so the RTC can be used in standby mode when the 1.5 V supply is not present.

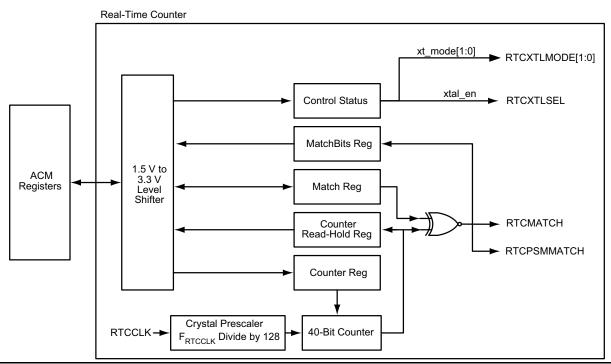


Figure 2-29 • RTC Block Diagram

Table 2-14 • RTC Signal Description

Signal Name	Width	Direction	Function
RTCCLK	1	In	Must come from CLKOUT of XTLOSC.
RTCXTLMODE[1:0]	2	Out	Controlled by xt_mode in CTRL_STAT. Signal must connect to the RTC_MODE signal in XTLOSC, as shown in Figure 2-27.
RTCXTLSEL	1	Out	Controlled by xtal_en from CTRL_STAT register. Signal must connect to RTC_MODE signal in XTLOSC in Figure 2-27.
RTCMATCH	1	Out	Match signal for FPGA
			0 – Counter value does not equal the Match Register value.
			1 – Counter value equals the Match Register value.
RTCPSMMATCH	1	Out	Same signal as RTCMATCH. Signal must connect to RTCPSMMATCH in VRPSM, as shown in Figure 2-27.

The 40-bit counter can be preloaded with an initial value as a starting point by the Counter Register. The count from the 40-bit counter can be read through the same set of address space. The count comes from a Read-Hold Register to avoid data changing during read. When the counter value equals the Match Register value, all Match Bits Register values will be 0xFFFFFFFFF. The RTCMATCH and RTCPSMMATCH signals will assert. The 40-bit counter can be configured to automatically reset to 0x0000000000 when the counter value equals the Match Register value. The automatic reset does not apply if the Match Register value is 0x0000000000. The RTCCLK has a prescaler to divide the clock by 128 before it is used for the 40-bit counter. Below is an example of how to calculate the OFF time.

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## **Example: Calculation for Match Count**

To put the Fusion device on standby for one hour using an external crystal of 32.768 KHz:

The period of the crystal oscillator is  $T_{crystal}$ :

 $T_{crystal}$  = 1 / 32.768 KHz = 30.518  $\mu s$ 

The period of the counter is  $T_{counter}$ :

 $T_{counter}$  = 30.518 us X 128 = 3.90625 ms

The Match Count for 1 hour is  $\Delta t$ match:

 $\Delta$ tmatch / T<sub>counter</sub> = (1 hr X 60 min/hr X 60 sec/min) / 3.90625 ms = 921600 or 0xE1000

Using a 32.768 KHz crystal, the maximum standby time of the 40-bit counter is 4,294,967,296 seconds, which is 136 years.

Table 2-15 • Memory Map for RTC in ACM Register and Description

ACMADDR	Register Name	Description	Use	Default Value
0x40	COUNTER0	Counter bits 7:0	Used to preload the counter to a specified start point.	0x00
0x41	COUNTER1	Counter bits 15:8		0x00
0x42	COUNTER2	Counter bits 23:16		0x00
0x43	COUNTER3	Counter bits 31:24		0x00
0x44	COUNTER4	Counter bits 39:32		0x00
0x48	MATCHREG0	Match register bits 7:0	The RTC comparison bits	0x00
0x49	MATCHREG1	Match register bits 15:8		0x00
0x4A	MATCHREG2	Match register bits 23:16		0x00
0x4B	MATCHREG3	Match register bits 31:24		0x00
0x4C	MATCHREG4	Match register bits 39:32		0x00
0x50	MATCHBIT0	Individual match bits 7:0	The output of the XNOR gates 0 – Not matched 1 – Matched	0x00
0x51	MATCHBIT1	Individual match bits 15:8		0x00
0x52	MATCHBIT2	Individual match bits 23:16		0x00
0x53	MATCHBIT3	Individual match bits 31:24		0x00
0x54	MATCHBIT4	Individual match bits 29:32		0x00
0x58	CTRL_STAT	Control (write/read) / Status (read only) register bits	Refer to Table 2-16 on page 2-35 for details.	0x00



## Table 2-16 • RTC Control/Status Register

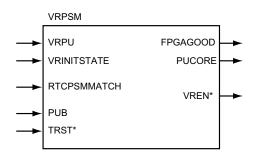
Bit	Name	Description	Default Value
7	rtc_rst	RTC Reset	
		1 – Resets the RTC	
		0 – Deassert reset on after two ACM_CLK cycle.	
6	cntr_en	Counter Enable	0
		1 – Enables the counter; rtc_rst must be deasserted as well. First counter increments after 64 RTCCLK positive edges.	
		0 – Disables the crystal prescaler but does not reset the counter value. Counter value can only be updated when the counter is disabled.	
5	vr_en_mat	Voltage Regulator Enable on Match	0
		1 – Enables RTCMATCH and RTCPSMMATCH to output 1 when the counter value equals the Match Register value. This enables the 1.5 V voltage regulator when RTCPSMMATCH connects to the RTCPSMMATCH signal in VRPSM.	
		0 – RTCMATCH and RTCPSMMATCH output 0 at all times.	
4:3	xt_mode[1:0]	Crystal Mode	00
		Controls RTCXTLMODE[1:0]. Connects to RTC_MODE signal in XTLOSC. XTL_MODE uses this value when xtal_en is 1. See the "Crystal Oscillator" section on page 2-20 for mode configuration.	
2	rst_cnt_omat	Reset Counter on Match	0
		<ul> <li>1 - Enables the sync clear of the counter when the counter value equals the Match Register value. The counter clears on the rising edge of the clock. If all the Match Registers are set to 0, the clear is disabled.</li> <li>0 - Counter increments indefinitely</li> </ul>	
1	rstb cnt	Counter Reset, active Low	0
	_	0 - Resets the 40-bit counter value	
0	xtal_en	Crystal Enable	0
	_	Controls RTCXTLSEL. Connects to SELMODE signal in XTLOSC.	
		0 – XTLOSC enables control by FPGA_EN; xt_mode is not used. Sleep mode requires this bit to equal 0.	
		1 – Enables XTLOSC, XTL_MODE control by xt_mode	
		Standby mode requires this bit to be set to 1.	
		See the "Crystal Oscillator" section on page 2-20 for further details on SELMODE configuration.	

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# **Voltage Regulator and Power System Monitor (VRPSM)**

The VRPSM macro controls the power-up state of the FPGA. The power-up bar (PUB) pin can turn on the voltage regulator when set to 0. TRST can enable the voltage regulator when deasserted, allowing the FPGA to power-up when user want access to JTAG ports. The inputs VRINITSTATE and RTCPSMMATCH come from the flash bits and RTC, and can also power up the FPGA.



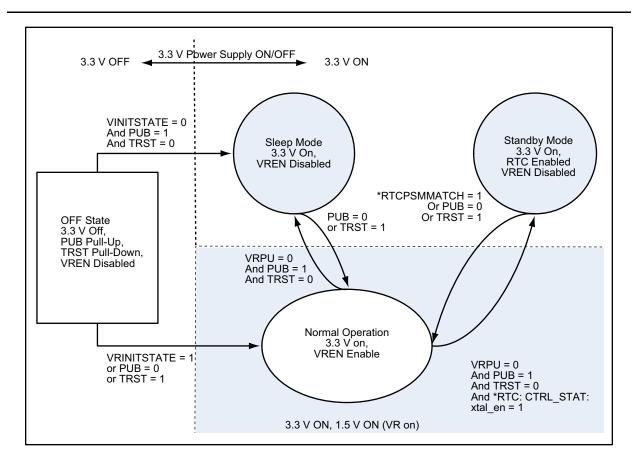
Note: \*Signals are hardwired internally and do not exist in the macro core.

Figure 2-30 • VRPSM Macro

Table 2-17 • VRPSM Signal Descriptions

Signal Name	Width	Direction	Function
VRPU	1	In	Voltage Regulator Power-Up
			0 – Voltage regulator disabled. PUB must be floated or pulled up, and the TRST pin must be grounded to disable the voltage regulator.
			1 – Voltage regulator enabled
VRINITSTATE	1	In	Voltage Regulator Initial State
			Defines the voltage Regulator status upon power-up of the 3.3 V. The signal is configured by Libero SoC when the VRPSM macro is generated.
			Tie off to 1 – Voltage regulator enables when 3.3 V is powered.
			Tie off to 0 – Voltage regulator disables when 3.3 V is powered.
RTCPSMMATCH	1	In	RTC Power System Management Match
			Connect from RTCPSMATCH signal from RTC in AB
			0 transition to 1 turns on the voltage regulator
PUB	1	In	External pin, built-in weak pull-up
			Power-Up Bar
			0 – Enables voltage regulator at all times
TRST*	1	In	External pin, JTAG Test Reset
			1 – Enables voltage regulator at all times
FPGAGOOD	1	Out	Indicator that the FPGA is powered and functional
			No need to connect if it is not used.
			1 – Indicates that the FPGA is powered up and functional.
			0 – Not possible to read by FPGA since it has already powered off.
PUCORE	1	Out	Power-Up Core
			Inverted signal of PUB. No need to connect if it is not used.
VREN*	1	Out	Voltage Regulator Enable
			Connected to 1.5 V voltage regulator in Fusion device internally.
			0 – Voltage regulator disables
			1 – Voltage regulator enables
Note: *Signals a	re hardı	wired intern	ally and do not exist in the macro core.





Note: \* To enter and exit standby mode without any external stimulus on PUB or TRST, the vr\_en\_mat in the CTRL\_STAT register must also be set to 1, so that RTCPSMMATCH will assert when a match occurs; hence the device exits standby mode.

Figure 2-31 • State Diagram for All Different Power Modes

When TRST is 1 or PUB is 0, the 1.5 V voltage regulator is always ON, putting the Fusion device in normal operation at all times. Therefore, when the JTAG port is not in reset, the Fusion device cannot enter sleep mode or standby mode.

To enter standby mode, the Fusion device must first power-up into normal operation. The RTC is enabled through the RTC Control/Status Register described in the "Real-Time Counter (part of AB macro)" section on page 2-33. A match value corresponding to the wake-up time is loaded into the Match Register. The 1.5 V voltage regulator is disabled by setting VRPU to 0 to allow the Fusion device to enter standby mode, when the 1.5 V supply is off but the RTC remains on.

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# 1.5 V Voltage Regulator

The  $1.5\,\mathrm{V}$  voltage regulator uses an external pass transistor to generate  $1.5\,\mathrm{V}$  from a  $3.3\,\mathrm{V}$  supply. The base of the pass transistor is tied to PTBASE, the collector is tied to  $3.3\,\mathrm{V}$ , and an emitter is tied to PTBASE and the  $1.5\,\mathrm{V}$  supplies of the Fusion device. Figure 2-27 on page 2-31 shows the hook-up of the  $1.5\,\mathrm{V}$  voltage regulator to an external pass transistor.

Microsemi recommends using a PN2222A or 2N2222A transistor. The gain of such a transistor is approximately 25, with a maximum base current of 20 mA. The maximum current that can be supported is 0.5 A. Transistors with different gain can also be used for different current requirements.

Table 2-18 • Electrical Characteristics VCC33A = 3.3 V

Symbol	Parameter	Condition		Min	Typical	Max	Units
VOUT	Output Voltage	Tj = 25°C		1.425	1.5	1.575	V
ICC33A	Operation Current	Tj = 25°C	ILOAD = 1 mA		11		mA
			ILOAD = 100 mA		11		mA
			ILOAD = 0.5 A		30		mA
ΔVOUT	Load Regulation	Tj = 25°C	ILOAD = 1 mA to 0.5 A		90		mV
	Line Regulation	Tj = 25°C	VCC33A = 2.97 V to 3.63 V				
			ILOAD = 1 mA		10.6		mV/V
			VCC33A = 2.97 V to 3.63 V				
			ILOAD = 100 mA		12.1		mV/V
$\Delta VOUT$			VCC33A = 2.97 V to 3.63 V		40.0		
			ILOAD = 500 mA		10.6		mV/V
	Dropout Voltage*	Tj = 25°C	ILOAD = 1 mA		0.63		V
			ILOAD = 100 mA		0.84		V
			ILOAD = 0.5 A		1.35		V
IPTBASE	PTBase Current	Tj = 25°C	ILOAD = 1 mA		48		μA
			ILOAD = 100 mA		736		μA
			ILOAD = 0.5 A		12	20	mA

Note: \*Data collected with 2N2222A.



# **Embedded Memories**

Fusion devices include four types of embedded memory: flash block, FlashROM, SRAM, and FIFO.

# Flash Memory Block

Fusion is the first FPGA that offers a flash memory block (FB). Each FB block stores 2 Mbits of data. The flash memory block macro is illustrated in Figure 2-32. The port pin name and descriptions are detailed on Table 2-19 on page 2-40. All flash memory block signals are active high, except for CLK and active low RESET. All flash memory operations are synchronous to the rising edge of CLK.

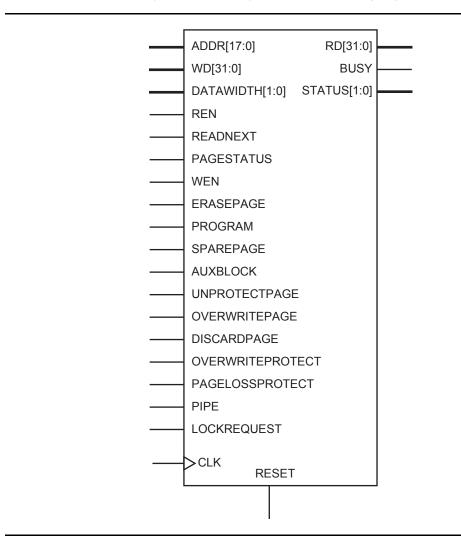


Figure 2-32 • Flash Memory Block

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# Flash Memory Block Pin Names

Table 2-19 • Flash Memory Block Pin Names

Interface Name	Width	Direction	Description	
ADDR[17:0]	18	In	Byte offset into the FB. Byte-based address.	
AUXBLOCK	1	In	When asserted, the page addressed is used to access the auxiliary block within that page.	
BUSY	1	Out	When asserted, indicates that the FB is performing an operation.	
CLK	1	ln	User interface clock. All operations and status are synchronous to the rising edge of this clock.	
DATAWIDTH[1:0]	2	In	Data width  00 = 1 byte in RD/WD[7:0]  01 = 2 bytes in RD/WD[15:0]  1x = 4 bytes in RD/WD[31:0]	
DISCARDPAGE	1	ln	When asserted, the contents of the Page Buffer are discarded so that a new page write can be started.	
ERASEPAGE	1	In	When asserted, the address page is to be programmed with all zer ERASEPAGE must transition synchronously with the rising edge CLK.	
LOCKREQUEST	1	ln	When asserted, indicates to the JTAG controller that the FPG interface is accessing the FB.	
OVERWRITEPAGE	1	ln	When asserted, the page addressed is overwritten with the contents of the Page Buffer if the page is writable.	
OVERWRITEPROTECT	1	In	When asserted, all program operations will set the overwrite protect bit of the page being programmed.	
PAGESTATUS	1	In	When asserted with REN, initiates a read page status operation.	
PAGELOSSPROTECT	1	In	When asserted, a modified Page Buffer must be programmed or discarded before accessing a new page.	
PIPE	1	In	Adds a pipeline stage to the output for operation above 50 MHz.	
PROGRAM	1	In	When asserted, writes the contents of the Page Buffer into the FB page addressed.	
RD[31:0]	32	Out	Read data; data will be valid from the first non-busy cycle (BUSY = 0) after REN has been asserted.	
READNEXT	1	ln	When asserted with REN, initiates a read-next operation.	
REN	1	In	When asserted, initiates a read operation.	
RESET	1	In	When asserted, resets the state of the FB (active low).	
SPAREPAGE	1	In	When asserted, the sector addressed is used to access the spare page within that sector.	



Table 2-19 • Flash Memory Block Pin Names (continued)

Interface Name	Width	Direction	Description
STATUS[1:0]	2	Out	Status of the last operation completed:
			00: Successful completion
			01: Read-/Unprotect-Page: single error detected and corrected
			Write: operation addressed a write-protected page Erase-Page: protection violation Program: Page Buffer is unmodified Protection violation
			10: Read-/Unprotect-Page: two or more errors detected
			11: Write: attempt to write to another page before programming current page
			Erase-Page/Program: page write count has exceeded the 10-year retention threshold
UNPROTECTPAGE	1	In	When asserted, the page addressed is copied into the Page Buffer and the Page Buffer is made writable.
WD[31:0]	32	In	Write data
WEN	1	In	When asserted, stores WD in the page buffer.

All flash memory block input signals are active high, except for RESET.

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# Flash Memory Block Diagram

A simplified diagram of the flash memory block is shown in Figure 2-33.

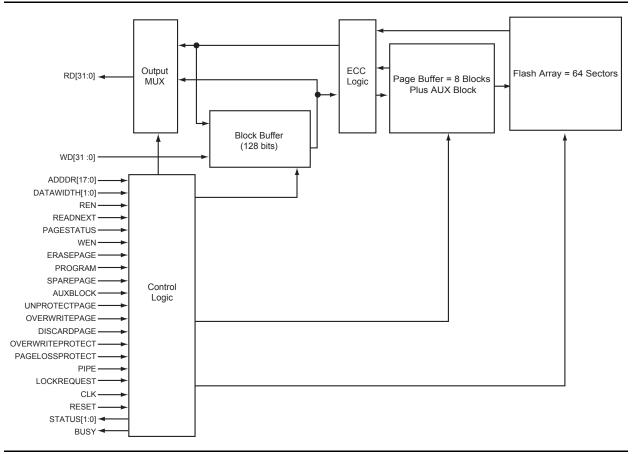


Figure 2-33 • Flash Memory Block Diagram

The logic consists of the following sub-blocks:

- · Flash Array
  - Contains all stored data. The flash array contains 64 sectors, and each sector contains 33 pages of data.
- Page Buffer
  - A page-wide volatile register. A page contains 8 blocks of data and an AUX block.
- Block Buffer
  - Contains the contents of the last block accessed. A block contains 128 data bits.
- ECC Logic

The FB stores error correction information with each block to perform single-bit error correction and double-bit error detection on all data blocks.



## Flash Memory Block Addressing

Figure 2-34 shows a graphical representation of the flash memory block.

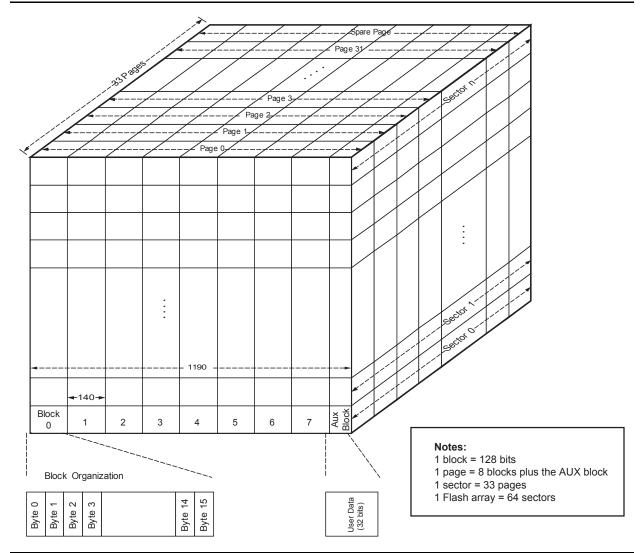


Figure 2-34 • Flash Memory Block Organization

Each FB is partitioned into sectors, pages, blocks, and bytes. There are 64 sectors in an FB, and each sector contains 32 pages and 1 spare page. Each page contains 8 data blocks and 1 auxiliary block. Each data block contains 16 bytes of user data, and the auxiliary block contains 4 bytes of user data. Addressing for the FB is shown in Table 2-20.

Table 2-20 • FB Address Bit Allocation ADDR[17:0]

17	12	11	7	6	4	3	0
Sec	ctor	Page		Blo	ock	Ву	/te

When the spare page of a sector is addressed (SPAREPAGE active), ADDR[11:7] are ignored.

When the Auxiliary block is addressed (AUXBLOCK active), ADDR[6:2] are ignored.

Note: The spare page of sector 0 is unavailable for any user data. Writes to this page will return an error, and reads will return all zeroes.

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Data operations are performed in widths of 1 to 4 bytes. A write to a location in a page that is not already in the Page Buffer will cause the page to be read from the FB Array and stored in the Page Buffer. The block that was addressed during the write will be put into the Block Buffer, and the data written by WD will overwrite the data in the Block Buffer. After the data is written to the Block Buffer, the Block Buffer is then written to the Page Buffer to keep both buffers in sync. Subsequent writes to the same block will overwrite the Block Buffer and the Page Buffer. A write to another block in the page will cause the addressed block to be loaded from the Page Buffer, and the write will be performed as described previously.

The data width can be selected dynamically via the DATAWIDTH input bus. The truth table for the data width settings is detailed in Table 2-21. The minimum resolvable address is one 8-bit byte. For data widths greater than 8 bits, the corresponding address bits are ignored—when DATAWIDTH = 0 (2 bytes), ADDR[0] is ignored, and when DATAWIDTH = '10' or '11' (4 bytes), ADDR[1:0] are ignored. Data pins are LSB-oriented and unused WD data pins must be grounded.

Table 2-21 • Data Width Settings

DATAWIDTH[1:0]	Data Width
00	1 byte [7:0]
01	2 byte [15:0]
10, 11	4 bytes [31:0]

## Flash Memory Block Protection

### Page Loss Protection

When the PAGELOSSPROTECT pin is set to logic 1, it prevents writes to any page other than the current page in the Page Buffer until the page is either discarded or programmed.

A write to another page while the current page is Page Loss Protected will return a STATUS of '11'.

#### **Overwrite Protection**

Any page that is Overwrite Protected will result in the STATUS being set to '01' when an attempt is made to either write, program, or erase it. To set the Overwrite Protection state for a page, set the OVERWRITEPROTECT pin when a Program operation is undertaken. To clear the Overwrite Protect state for a given page, an Unprotect Page operation must be performed on the page, and then the page must be programmed with the OVERWRITEPROTECT pin cleared to save the new page.

### **LOCKREQUEST**

LOCKREQUEST indicates to the JTAG controller that the FPGA interface is accessing the Flash memory Block. For the JTAG master LOCKREQUEST check is optional and can be ignored.

### Flash Memory Block Operations

#### FB Operation Priority

The FB provides for priority of operations when multiple actions are requested simultaneously. Table 2-22 shows the priority order (priority 0 is the highest).

Table 2-22 • FB Operation Priority

Operation	Priority
System Initialization	0
FB Reset	1
Read	2
Write	3
Erase Page	4
Program	5
Unprotect Page	6
Discard Page	7



Access to the FB is controlled by the BUSY signal. The BUSY output is synchronous to the CLK signal. FB operations are only accepted in cycles where BUSY is logic 0.

#### Write Operation

Write operations are initiated with the assertion of the WEN signal. Figure 2-35 on page 2-45 illustrates the multiple Write operations.

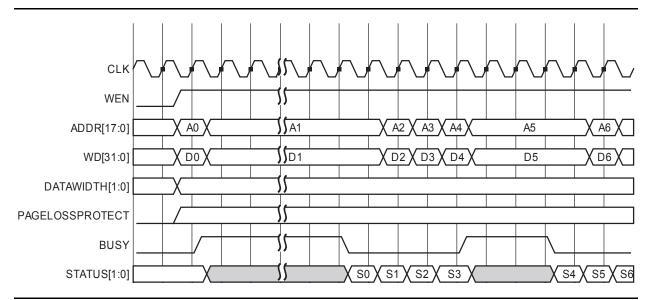


Figure 2-35 • FB Write Waveform

When a Write operation is initiated to a page that is currently not in the Page Buffer, the FB control logic will issue a BUSY signal to the user interface while the page is loaded from the FB Array into the Page Buffer. A Copy Page operation takes no less than 55 cycles and could take more if a Write or Unprotect Page operation is started while the NVM is busy pre-fetching a block. The basic operation is to read a block from the array into the block register (5 cycles) and then write the block register to the page buffer (1 cycle) and if necessary, when the copy is complete, reading the block being written from the page buffer into the block buffer (1 cycle). A page contains 9 blocks, so 9 blocks multiplied by 6 cycles to read/write each block, plus 1 is 55 cycles total. Subsequent writes to the same block of the page will incur no busy cycles. A write to another block in the page will assert BUSY for four cycles (five cycles when PIPE is asserted), to allow the data to be written to the Page Buffer and have the current block loaded into the Block Buffer.

Write operations are considered successful as long as the STATUS output is '00'. A non-zero STATUS indicates that an error was detected during the operation and the write was not performed. Note that the STATUS output is "sticky"; it is unchanged until another operation is started.

Only one word can be written at a time. Write word width is controlled by the DATAWIDTH bus. Users are responsible for keeping track of the contents of the Page Buffer and when to program it to the array. Just like a regular RAM, writing to random addresses is possible. Users can write into the Page Buffer in any order but will incur additional BUSY cycles. It is not necessary to modify the entire Page Buffer before saving it to nonvolatile memory.

Write errors include the following:

- 1. Attempting to write a page that is Overwrite Protected (STATUS = '01'). The write is not performed.
- 2. Attempting to write to a page that is not in the Page Buffer when Page Loss Protection is enabled (STATUS = '11'). The write is not performed.

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### **Program Operation**

A Program operation is initiated by asserting the PROGRAM signal on the interface. Program operations save the contents of the Page Buffer to the FB Array. Due to the technologies inherent in the FB, the total programming (including erase) time per page of the eNVM is 6.8 ms. While the FB is writing the data to the array, the BUSY signal will be asserted.

During a Program operation, the sector and page addresses on ADDR are compared with the stored address for the page (and sector) in the Page Buffer. If there is a mismatch between the two addresses, the Program operation will be aborted and an error will be reported on the STATUS output.

It is possible to write the Page Buffer to a different page in memory. When asserting the PROGRAM pin, if OVERWRITEPAGE is asserted as well, the FB will write the contents of the Page Buffer to the sector and page designated on the ADDR inputs if the destination page is not Overwrite Protected.

A Program operation can be utilized to either modify the contents of the page in the flash memory block or change the protections for the page. Setting the OVERWRITEPROTECT bit on the interface while asserting the PROGRAM pin will put the page addressed into Overwrite Protect Mode. Overwrite Protect Mode safeguards a page from being inadvertently overwritten during subsequent Program or Erase operations.

Program operations that result in a STATUS value of '01' do not modify the addressed page. For all other values of STATUS, the addressed page is modified. Program errors include the following:

- 1. Attempting to program a page that is Overwrite Protected (STATUS = '01')
- Attempting to program a page that is not in the Page Buffer when the Page Buffer has entered Page Loss Protection Mode (STATUS = '01')
- 3. Attempting to perform a program with OVERWRITEPAGE set when the page addressed has been Overwrite Protected (STATUS = '01')
- 4. The Write Count of the page programmed exceeding the Write Threshold defined in the part specification (STATUS = '11')
- 5. The ECC Logic determining that there is an uncorrectable error within the programmed page (STATUS = '10')
- 6. Attempting to program a page that is **not** in the Page Buffer when OVERWRITEPAGE is not set and the page in the Page Buffer is modified (STATUS = '01')
- 7. Attempting to program the page in the Page Buffer when the Page Buffer is **not** modified

The waveform for a Program operation is shown in Figure 2-36.

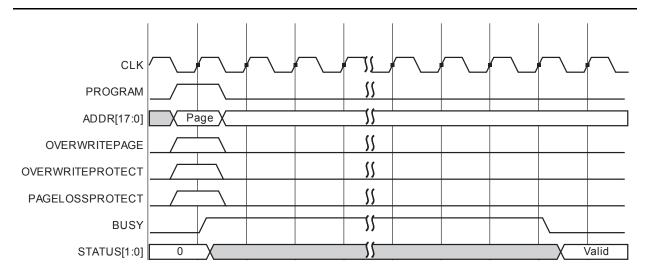


Figure 2-36 • FB Program Waveform

Note: OVERWRITEPAGE is only sampled when the PROGRAM or ERASEPAGE pins are asserted. OVERWRITEPAGE is ignored in all other operations.



## **Erase Page Operation**

The Erase Page operation is initiated when the ERASEPAGE pin is asserted. The Erase Page operation allows the user to erase (set user data to zero) any page within the FB.

The use of the OVERWRITEPAGE and PAGELOSSPROTECT pins is the same for erase as for a Program Page operation.

As with the Program Page operation, a STATUS of '01' indicates that the addressed page is not erased. A waveform for an Erase Page operation is shown in Figure 2-37.

Erase errors include the following:

- 1. Attempting to erase a page that is Overwrite Protected (STATUS = '01')
- 2. Attempting to erase a page that is not in the Page Buffer when the Page Buffer has entered Page Loss Protection mode (STATUS = '01')
- 3. The Write Count of the erased page exceeding the Write Threshold defined in the part specification (STATUS = '11')
- 4. The ECC Logic determining that there is an uncorrectable error within the erased page (STATUS = '10')

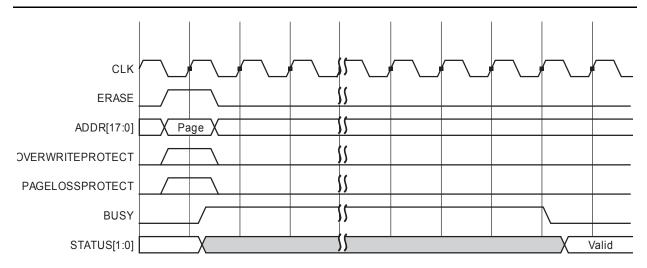


Figure 2-37 • FB Erase Page Waveform

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## **Read Operation**

Read operations are designed to read data from the FB Array, Page Buffer, Block Buffer, or status registers. Read operations support a normal read and a read-ahead mode (done by asserting READNEXT). Also, the timing for Read operations is dependent on the setting of PIPE.

The following diagrams illustrate representative timing for Non-Pipe Mode (Figure 2-38) and Pipe Mode (Figure 2-39) reads of the flash memory block interface.

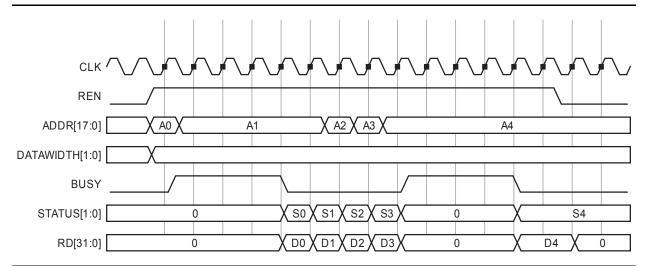


Figure 2-38 • Read Waveform (Non-Pipe Mode, 32-bit access)

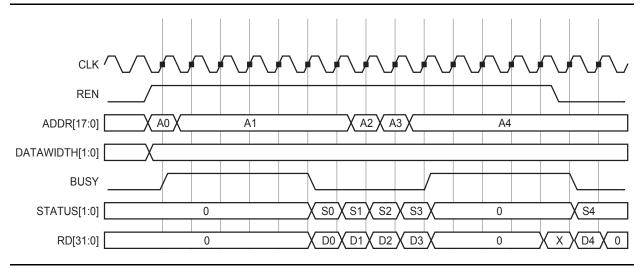


Figure 2-39 • Read Waveform (Pipe Mode, 32-bit access)



The following error indications are possible for Read operations:

- 1. STATUS = '01' when a single-bit data error was detected and corrected within the block addressed.
- 2. STATUS = '10' when a double-bit error was detected in the block addressed (note that the error is uncorrected).

In addition to data reads, users can read the status of any page in the FB by asserting PAGESTATUS along with REN. The format of the data returned by a page status read is shown in Table 2-23, and the definition of the page status bits is shown in Table 2-24.

#### Table 2-23 • Page Status Read Data Format

31	8	7	4	3	2	1	0	
Write 0	Count	Rese	erved	Over Threshold	Read Protected	Write Protected	Overwrite Protected	

### Table 2-24 • Page Status Bit Definition

Page Status Bit(s)	Definition
31–8	The number of times the page addressed has been programmed/erased
7–4	Reserved; read as 0
3	Over Threshold indicator (see the "Program Operation" section on page 2-46)
2	Read Protected; read protect bit for page, which is set via the JTAG interface and only affects JTAG operations. This bit can be overridden by using the correct user key value.
1	Write Protected; write protect bit for page, which is set via the JTAG interface and only affects JTAG operations. This bit can be overridden by using the correct user key value.
0	Overwrite Protected; designates that the user has set the OVERWRITEPROTECT bit on the interface while doing a Program operation. The page cannot be written without first performing an Unprotect Page operation.

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### **Read Next Operation**

The Read Next operation is a feature by which the next block relative to the block in the Block Buffer is read from the FB Array while performing reads from the Block Buffer. The goal is to minimize wait states during consecutive sequential Read operations.

The Read Next operation is performed in a predetermined manner because it does look-ahead reads. The general look-ahead function is as follows:

- · Within a page, the next block fetched will be the next in linear address.
- When reading the last data block of a page, it will fetch the first block of the next page.
- When reading spare pages, it will read the first block of the next sector's spare page.
- · Reads of the last sector will wrap around to sector 0.
- · Reads of Auxiliary blocks will read the next linear page's Auxiliary block.

When an address on the ADDR input does not agree with the predetermined look-ahead address, there is a time penalty for this access. The FB will be busy finishing the current look-ahead read before it can start the next read. The worst case is a total of nine BUSY cycles before data is delivered.

The Non-Pipe Mode and Pipe Mode waveforms for Read Next operations are illustrated in Figure 2-40 and Figure 2-41.

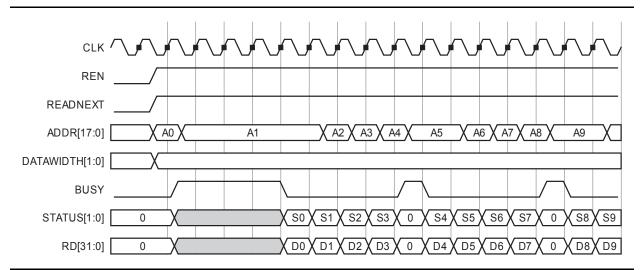


Figure 2-40 • Read Next Waveform (Non-Pipe Mode, 32-bit access)

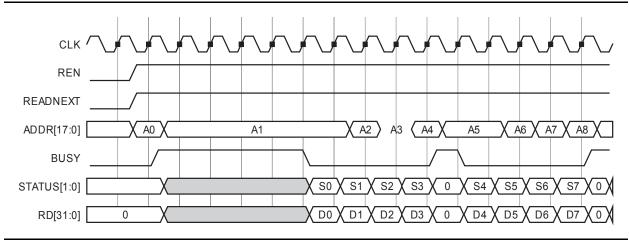


Figure 2-41 • Read Next WaveForm (Pipe Mode, 32-bit access)



### **Unprotect Page Operation**

An Unprotect Page operation will clear the protection for a page addressed on the ADDR input. It is initiated by setting the UNPROTECTPAGE signal on the interface along with the page address on ADDR.

If the page is not in the Page Buffer, the Unprotect Page operation will copy the page into the Page Buffer. The Copy Page operation occurs only if the current page in the Page Buffer is not Page Loss Protected.

The waveform for an Unprotect Page operation is shown in Figure 2-42.

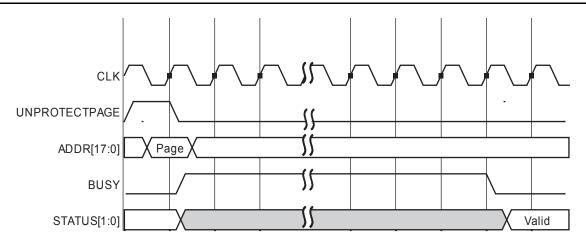


Figure 2-42 • FB Unprotected Page Waveform

The Unprotect Page operation can incur the following error conditions:

- 1. If the copy of the page to the Page Buffer determines that the page has a single-bit correctable error in the data, it will report a STATUS = '01'.
- 2. If the address on ADDR does not match the address of the Page Buffer, PAGELOSSPROTECT is asserted, and the Page Buffer has been modified, then STATUS = '11' and the addressed page is not loaded into the Page Buffer.
- 3. If the copy of the page to the Page Buffer determines that at least one block in the page has a double-bit uncorrectable error, STATUS = '10' and the Page Buffer will contain the corrupted data.

### **Discard Page Operation**

If the contents of the modified Page Buffer have to be discarded, the DISCARDPAGE signal should be asserted. This command results in the Page Buffer being marked as unmodified.

The timing for the operation is shown in Figure 2-43. The BUSY signal will remain asserted until the operation has completed.

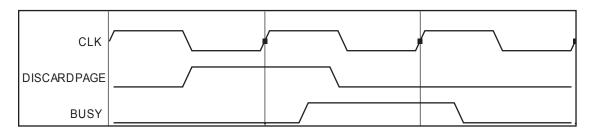


Figure 2-43 • FB Discard Page Waveform

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# Flash Memory Block Characteristics

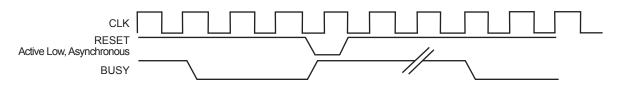


Figure 2-44 • Reset Timing Diagram

Table 2-25 • Flash Memory Block Timing
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units					
+.	Clock-to-Q in 5-cycle read mode of the Read Data	7.99	9.10	10.70	ns					
<sup>t</sup> CLK2RD	Clock-to-Q in 6-cycle read mode of the Read Data	5.03	5.73	6.74	ns					
4	Clock-to-Q in 5-cycle read mode of BUSY	4.95	5.63	6.62	ns					
<sup>t</sup> CLK2BUSY	Clock-to-Q in 6-cycle read mode of BUSY	4.45	5.07	5.96	ns					
+	Clock-to-Status in 5-cycle read mode	11.24	12.81	15.06	ns					
<sup>T</sup> CLK2STATUS	Clock-to-Status in 6-cycle read mode	4.48	5.10	6.00	ns					
t <sub>DSUNVM</sub>	Data Input Setup time for the Control Logic	1.92	2.19	2.57	ns					
t <sub>DHNVM</sub>	Data Input Hold time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>ASUNVM</sub>	Address Input Setup time for the Control Logic	2.76	3.14	3.69	ns					
t <sub>AHNVM</sub>	Address Input Hold time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUDWNVM</sub>	Data Width Setup time for the Control Logic	1.85	2.11	2.48	ns					
t <sub>HDDWNVM</sub>	Data Width Hold time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SURENNVM</sub>	Read Enable Setup time for the Control Logic	3.85	4.39	5.16	ns					
t <sub>HDRENNVM</sub>	Read Enable Hold Time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUWENNVM</sub>	Write Enable Setup time for the Control Logic	2.37	2.69	3.17	ns					
t <sub>HDWENNVM</sub>	Write Enable Hold Time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUPROGNVM</sub>	Program Setup time for the Control Logic	2.16	2.46	2.89	ns					
t <sub>HDPROGNVM</sub>	Program Hold time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUSPAREPAGE</sub>	SparePage Setup time for the Control Logic	3.74	4.26	5.01	ns					
t <sub>HDSPAREPAGE</sub>	SparePage Hold time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUAUXBLK</sub>	Auxiliary Block Setup Time for the Control Logic	3.74	4.26	5.00	ns					
t <sub>HDAUXBLK</sub>	Auxiliary Block Hold Time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SURDNEXT</sub>	ReadNext Setup Time for the Control Logic	2.17	2.47	2.90	ns					
t <sub>HDRDNEXT</sub>	ReadNext Hold Time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUERASEPG</sub>	Erase Page Setup Time for the Control Logic	3.76	4.28	5.03	ns					
t <sub>HDERASEPG</sub>	Erase Page Hold Time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUUNPROTECTPG</sub>	Unprotect Page Setup Time for the Control Logic	2.01	2.29	2.69	ns					
t <sub>HDUNPROTECTPG</sub>	Unprotect Page Hold Time for the Control Logic	0.00	0.00	0.00	ns					
t <sub>SUDISCARDPG</sub>	Discard Page Setup Time for the Control Logic	1.88	2.14	2.52	ns					
t <sub>HDDISCARDPG</sub>	Discard Page Hold Time for the Control Logic	0.00	0.00	0.00	ns					
tsuoverwrpro	Overwrite Protect Setup Time for the Control Logic	1.64	1.86	2.19	ns					
t <sub>HDOVERWRPRO</sub>	Overwrite Protect Hold Time for the Control Logic	0.00	0.00	0.00	ns					



Table 2-25 • Flash Memory Block Timing (continued)

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>SUPGLOSSPRO</sub>	Page Loss Protect Setup Time for the Control Logic	1.69	1.93	2.27	ns
t <sub>HDPGLOSSPRO</sub>	Page Loss Protect Hold Time for the Control Logic	0.00	0.00	0.00	ns
t <sub>SUPGSTAT</sub>	Page Status Setup Time for the Control Logic	2.49	2.83	3.33	ns
t <sub>HDPGSTAT</sub>	Page Status Hold Time for the Control Logic	0.00	0.00	0.00	ns
tsuoverwrpg	Over Write Page Setup Time for the Control Logic	1.88	2.14	2.52	ns
t <sub>HDOVERWRPG</sub>	Over Write Page Hold Time for the Control Logic	0.00	0.00	0.00	ns
tsulockrequest	Lock Request Setup Time for the Control Logic	0.87	0.99	1.16	ns
t <sub>HDLOCKREQUEST</sub>	Lock Request Hold Time for the Control Logic	0.00	0.00	0.00	ns
t <sub>RECARNVM</sub>	Reset Recovery Time	0.94	1.07	1.25	ns
t <sub>REMARNVM</sub>	Reset Removal Time	0.00	0.00	0.00	ns
t <sub>MPWARNVM</sub>	Asynchronous Reset Minimum Pulse Width for the Control Logic		12.50	12.50	ns
t <sub>MPWCLKNVM</sub>	Clock Minimum Pulse Width for the Control Logic	4.00	5.00	5.00	ns
	Maximum Frequency for Clock for the Control Logic – for AFS1500/AFS600	80.00	80.00	80.00	MHz
<sup>T</sup> FMAXCLKNVM	Maximum Frequency for Clock for the Control Logic – for AFS250/AFS090	100.00	80.00	80.00	MHz

### **FlashROM**

Fusion devices have 1 kbit of on-chip nonvolatile flash memory that can be read from the FPGA core fabric. The FlashROM is arranged in eight banks of 128 bits during programming. The 128 bits in each bank are addressable as 16 bytes during the read-back of the FlashROM from the FPGA core (Figure 2-45).

The FlashROM can only be programmed via the IEEE 1532 JTAG port. It cannot be programmed directly from the FPGA core. When programming, each of the eight 128-bit banks can be selectively reprogrammed. The FlashROM can only be reprogrammed on a bank boundary. Programming involves an automatic, on-chip bank erase prior to reprogramming the bank. The FlashROM supports a synchronous read and can be read on byte boundaries. The upper three bits of the FlashROM address from the FPGA core define the bank that is being accessed. The lower four bits of the FlashROM address from the FPGA core define which of the 16 bytes in the bank is being accessed.

The maximum FlashROM access clock is given in Table 2-26 on page 2-54. Figure 2-46 shows the timing behavior of the FlashROM access cycle—the address has to be set up on the rising edge of the clock for DOUT to be valid on the next falling edge of the clock.

If the address is unchanged for two cycles:

- D0 becomes invalid t<sub>CK2Q</sub> ns after the second rising edge of the clock.
- D0 becomes valid again t<sub>CK2Q</sub> ns after the second falling edge.

If the address unchanged for three cycles:

- D0 becomes invalid t<sub>CK2O</sub> ns after the second rising edge of the clock.
- D0 becomes valid again t<sub>CK2Q</sub> ns after the second falling edge.
- D0 becomes invalid t<sub>CK2Q</sub> ns after the third rising edge of the clock.
- D0 becomes valid again t<sub>CK2Q</sub> ns after the third falling edge.

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Byte Number in Bank					4 LSB of ADDR (READ)												
		15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
3 Ba	7																
Bank N 3 MSB	6																
Number B of ADE	5																
A nb	4																
🖁 🕆	3																
nber ADDR (READ)	2																
₩	1																
ا کا	0																

Figure 2-45 • FlashROM Architecture

## FlashROM Characteristics

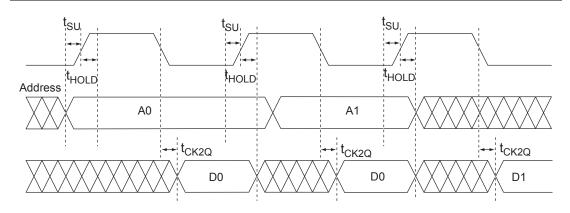


Figure 2-46 • FlashROM Timing Diagram

Table 2-26 • FlashROM Access Time Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	<b>–2</b>	<b>-1</b>	Std.	Units
t <sub>SU</sub>	Address Setup Time	0.53	0.61	0.71	ns
t <sub>HOLD</sub>	Address Hold Time	0.00	0.00	0.00	ns
t <sub>CK2Q</sub>	Clock to Out	21.42	24.40	28.68	ns
F <sub>MAX</sub>	Maximum Clock frequency	15.00	15.00	15.00	MHz



### **SRAM and FIFO**

All Fusion devices have SRAM blocks along the north side of the device. Additionally, AFS600 and AFS1500 devices have an SRAM block on the south side of the device. To meet the needs of high-performance designs, the memory blocks operate strictly in synchronous mode for both read and write operations. The read and write clocks are completely independent, and each may operate at any desired frequency less than or equal to 350 MHz. The following configurations are available:

- 4k×1, 2k×2, 1k×4, 512×9 (dual-port RAM—two read, two write or one read, one write)
- 512×9, 256×18 (two-port RAM—one read and one write)
- Sync write, sync pipelined/nonpipelined read

The Fusion SRAM memory block includes dedicated FIFO control logic to generate internal addresses and external flag logic (FULL, EMPTY, AFULL, AEMPTY).

During RAM operation, addresses are sourced by the user logic, and the FIFO controller is ignored. In FIFO mode, the internal addresses are generated by the FIFO controller and routed to the RAM array by internal MUXes. Refer to Figure 2-47 for more information about the implementation of the embedded FIFO controller.

The Fusion architecture enables the read and write sizes of RAMs to be organized independently, allowing for bus conversion. This is done with the WW (write width) and RW (read width) pins. The different D×W configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1. For example, the write size can be set to 256×18 and the read size to 512×9.

Both the write and read widths for the RAM blocks can be specified independently with the WW (write width) and RW (read width) pins. The different D×W configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1.

Refer to the allowable RW and WW values supported for each of the RAM macro types in Table 2-27 on page 2-58.

When a width of one, two, or four is selected, the ninth bit is unused. For example, when writing 9-bit values and reading 4-bit values, only the first four bits and the second four bits of each 9-bit value are addressable for read operations. The ninth bit is not accessible.

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Conversely, when writing 4-bit values and reading 9-bit values, the ninth bit of a read operation will be undefined. The RAM blocks employ little-endian byte order for read and write operations.

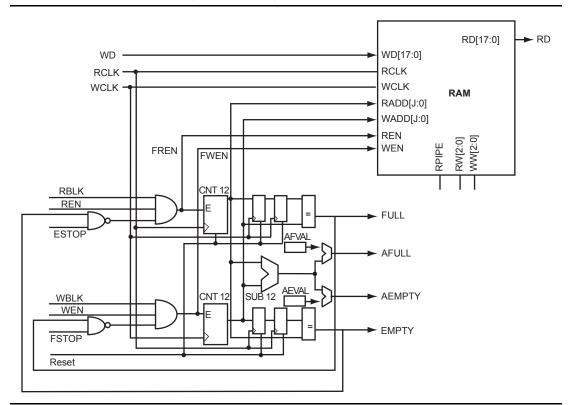


Figure 2-47 • Fusion RAM Block with Embedded FIFO Controller



# **RAM4K9 Description**

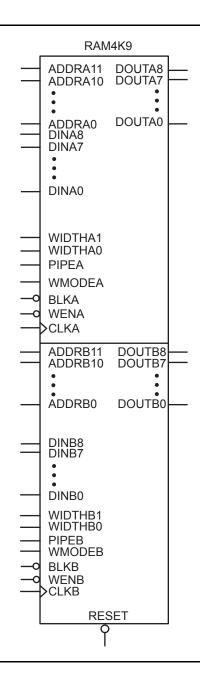


Figure 2-48 • RAM4K9

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The following signals are used to configure the RAM4K9 memory element.

#### WIDTHA and WIDTHB

These signals enable the RAM to be configured in one of four allowable aspect ratios (Table 2-27).

Table 2-27 • Allowable Aspect Ratio Settings for WIDTHA[1:0]

WIDTHA1, WIDTHA0	WIDTHB1, WIDTHB0	D×W	
00	00	4k×1	
01	01	2k×2	
10	10	1k×4	
11	11	512×9	

#### **BLKA and BLKB**

These signals are active low and will enable the respective ports when asserted. When a BLKx signal is deasserted, the corresponding port's outputs hold the previous value.

#### WENA and WENB

These signals switch the RAM between read and write mode for the respective ports. A Low on these signals indicates a write operation, and a High indicates a read.

#### CLKA and CLKB

These are the clock signals for the synchronous read and write operations. These can be driven independently or with the same driver.

#### PIPEA and PIPEB

These signals are used to specify pipelined read on the output. A Low on PIPEA or PIPEB indicates a nonpipelined read, and the data appears on the corresponding output in the same clock cycle. A High indicates a pipelined, read and data appears on the corresponding output in the next clock cycle.

## WMODEA and WMODEB

These signals are used to configure the behavior of the output when the RAM is in write mode. A Low on these signals makes the output retain data from the previous read. A High indicates pass-through behavior, wherein the data being written will appear immediately on the output. This signal is overridden when the RAM is being read.

### RESET

This active low signal resets the output to zero, disables reads and writes from the SRAM block, and clears the data hold registers when asserted. It does not reset the contents of the memory.

## ADDRA and ADDRB

These are used as read or write addresses, and they are 12 bits wide. When a depth of less than 4 k is specified, the unused high-order bits must be grounded (Table 2-28).

Table 2-28 • Address Pins Unused/Used for Various Supported Bus Widths

D×W	ADDRx				
D~**	Unused	Used			
4k×1	None	[11:0]			
2k×2	[11]	[10:0]			
1k×4	[11:10]	[9:0]			
512×9	[11:9]	[8:0]			

Note: The "x" in ADDRx implies A or B.



# **DINA** and **DINB**

These are the input data signals, and they are nine bits wide. Not all nine bits are valid in all configurations. When a data width less than nine is specified, unused high-order signals must be grounded (Table 2-29).

# **DOUTA and DOUTB**

These are the nine-bit output data signals. Not all nine bits are valid in all configurations. As with DINA and DINB, high-order bits may not be used (Table 2-29). The output data on unused pins is undefined.

Table 2-29 • Unused/Used Input and Output Data Pins for Various Supported Bus Widths

D×W	DINx/DOUTx				
D^44	Unused	Used			
4k×1	[8:1]	[0]			
2k×2	[8:2]	[1:0]			
1k×4	[8:4]	[3:0]			
512×9	None	[8:0]			

Note: The "x" in DINx and DOUTx implies A or B.

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# RAM512X18 Description

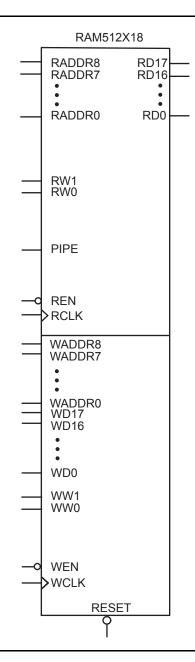


Figure 2-49 • RAM512X18



RAM512X18 exhibits slightly different behavior from RAM4K9, as it has dedicated read and write ports.

#### WW and RW

These signals enable the RAM to be configured in one of the two allowable aspect ratios (Table 2-30).

Table 2-30 • Aspect Ratio Settings for WW[1:0]

WW[1:0]	RW[1:0]	D×W
01	01	512×9
10	10	256×18
00, 11	00, 11	Reserved

#### WD and RD

These are the input and output data signals, and they are 18 bits wide. When a 512×9 aspect ratio is used for write, WD[17:9] are unused and must be grounded. If this aspect ratio is used for read, then RD[17:9] are undefined.

### WADDR and RADDR

These are read and write addresses, and they are nine bits wide. When the 256×18 aspect ratio is used for write or read, WADDR[8] or RADDR[8] are unused and must be grounded.

#### WCLK and RCLK

These signals are the write and read clocks, respectively. They are both active high.

#### WEN and REN

These signals are the write and read enables, respectively. They are both active low by default. These signals can be configured as active high.

#### RESET

This active low signal resets the output to zero, disables reads and/or writes from the SRAM block, and clears the data hold registers when asserted. It does not reset the contents of the memory.

## **PIPE**

This signal is used to specify pipelined read on the output. A Low on PIPE indicates a nonpipelined read, and the data appears on the output in the same clock cycle. A High indicates a pipelined read, and data appears on the output in the next clock cycle.

#### Clocking

The dual-port SRAM blocks are only clocked on the rising edge. SmartGen allows falling-edge-triggered clocks by adding inverters to the netlist, hence achieving dual-port SRAM blocks that are clocked on either edge (rising or falling). For dual-port SRAM, each port can be clocked on either edge or by separate clocks, by port.

Fusion devices support inversion (bubble pushing) throughout the FPGA architecture, including the clock input to the SRAM modules. Inversions added to the SRAM clock pin on the design schematic or in the HDL code will be automatically accounted for during design compile without incurring additional delay in the clock path.

The two-port SRAM can be clocked on the rising edge or falling edge of WCLK and RCLK.

If negative-edge RAM and FIFO clocking is selected for memory macros, clock edge inversion management (bubble pushing) is automatically used within the Fusion development tools, without performance penalty.

Note: Data in the SRAM block can be corrupted during a read operation, when the read address does not meet setup and hold requirements with respect to the clock for that port. The data corruption occurs when the read address (RADDR) changes almost simultaneously with read clock (RCLK) edge (that is, RADDR violates the timing requirement of the memory). Users must always meet the setup and hold time requirements on the RAM inputs; to have reliable and predictable results for reads and writes. To avoid data corruption due to asynchronous clocking for read address and read clock of the RAM, users must implement a proper synchronizer circuit. For more information, see, Fusion and Extended Temperature Fusion FPGA Fabric User's Guide

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## **Modes of Operation**

There are two read modes and one write mode:

- Read Nonpipelined (synchronous—1 clock edge): In the standard read mode, new data is driven
  onto the RD bus in the same clock cycle following RA and REN valid. The read address is
  registered on the read port clock active edge, and data appears at RD after the RAM access time.
  Setting PIPE to OFF enables this mode.
- Read Pipelined (synchronous—2 clock edges): The pipelined mode incurs an additional clock
  delay from the address to the data but enables operation at a much higher frequency. The read
  address is registered on the read port active clock edge, and the read data is registered and
  appears at RD after the second read clock edge. Setting PIPE to ON enables this mode.
- Write (synchronous—1 clock edge): On the write clock active edge, the write data is written into
  the SRAM at the write address when WEN is High. The setup times of the write address, write
  enables, and write data are minimal with respect to the write clock. Write and read transfers are
  described with timing requirements in the "SRAM Characteristics" section on page 2-63 and the
  "FIFO Characteristics" section on page 2-72.

#### RAM Initialization

Each SRAM block can be individually initialized on power-up by means of the JTAG port using the UJTAG mechanism (refer to the "JTAG IEEE 1532" section on page 2-229 and the *Fusion SRAM/FIFO Blocks* application note). The shift register for a target block can be selected and loaded with the proper bit configuration to enable serial loading. The 4,608 bits of data can be loaded in a single operation.



# **SRAM Characteristics**

# **Timing Waveforms**

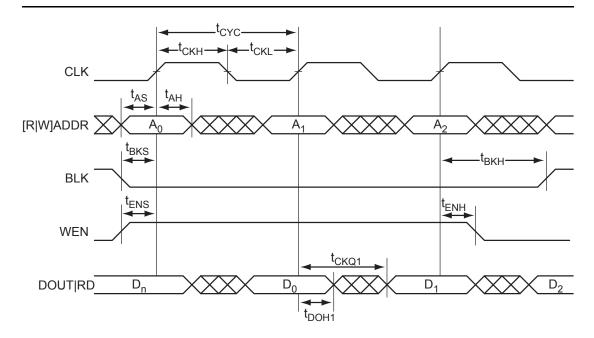


Figure 2-50 • RAM Read for Flow-Through Output. Applicable to both RAM4K9 and RAM512x18.

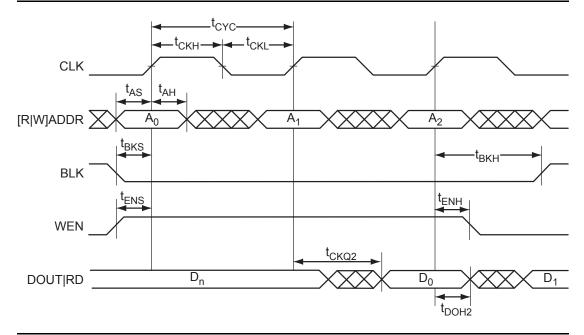


Figure 2-51 • RAM Read for Pipelined Output. Applicable to both RAM4K9 and RAM512x18.

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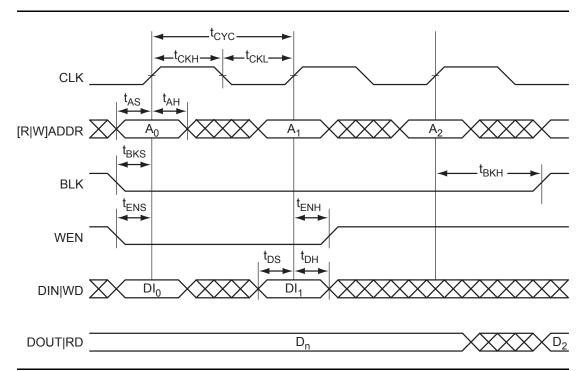


Figure 2-52 • RAM Write, Output Retained. Applicable to both RAM4K9 and RAM512x18.

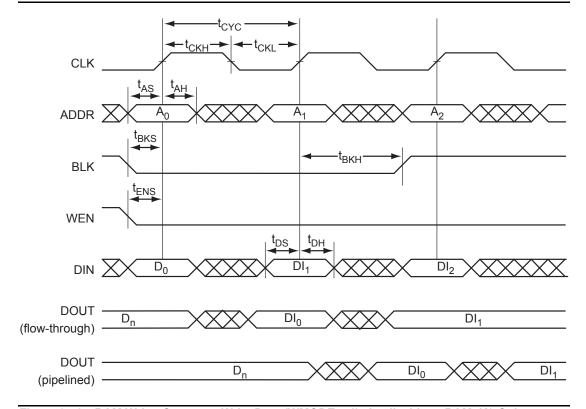


Figure 2-53 • RAM Write, Output as Write Data (WMODE = 1). Applicable to RAM4K9 Only.



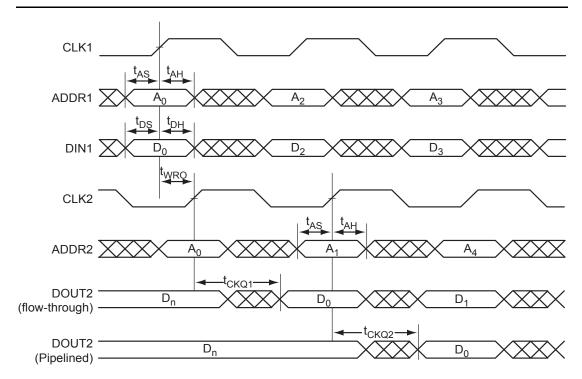


Figure 2-54 • One Port Write / Other Port Read Same

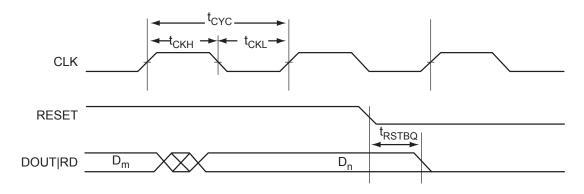


Figure 2-55 • RAM Reset. Applicable to both RAM4K9 and RAM512x18.

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# Timing Characteristics

Table 2-31 • RAM4K9

Commercial Temperature Range Conditions:  $T_J = 70^{\circ}C$ , Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>AS</sub>	Address setup time	0.25	0.28	0.33	ns
t <sub>AH</sub>	Address hold time	0.00	0.00	0.00	ns
t <sub>ENS</sub>	REN, WEN setup time	0.14	0.16	0.19	ns
t <sub>ENH</sub>	REN, WEN hold time	0.10	0.11	0.13	ns
t <sub>BKS</sub>	BLK setup time	0.23	0.27	0.31	ns
t <sub>BKH</sub>	BL hold time	0.02	0.02	0.02	ns
t <sub>DS</sub>	Input data (DIN) setup time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input data (DIN) hold time	0.00	0.00	0.00	ns
	Clock High to new data valid on DOUT (output retained, WMODE = 0)	1.79	2.03	2.39	ns
t <sub>CKQ1</sub>	Clock High to new data valid on DOUT (flow-through, WMODE = 1)	2.36	2.68	3.15	ns
t <sub>CKQ2</sub>	Clock High to new data valid on DOUT (pipelined)	0.89	1.02	1.20	ns
t <sub>C2CWWH</sub> <sup>1</sup>	Address collision clk-to-clk delay for reliable write after write on same address—Applicable to Rising Edge	0.30	0.26	0.23	ns
t <sub>C2CRWH</sub> 1	Address collision clk-to-clk delay for reliable read access after write on same address—Applicable to Opening Edge	0.45	0.38	0.34	ns
t <sub>C2CWRH</sub> 1	Address collision clk-to-clk delay for reliable write access after read on same address— Applicable to Opening Edge	0.49	0.42	0.37	ns
	RESET Low to data out Low on DOUT (flow-through)	0.92	1.05	1.23	ns
t <sub>RSTBQ</sub>	RESET Low to Data Out Low on DOUT (pipelined)	0.92	1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET removal	0.29	0.33	0.38	ns
t <sub>RECRSTB</sub>	RESET recovery	1.50	1.71	2.01	ns
t <sub>MPWRSTB</sub>	RESET minimum pulse width	0.21	0.24	0.29	ns
t <sub>CYC</sub>	Clock cycle time	3.23	3.68	4.32	ns
F <sub>MAX</sub>	Maximum frequency	310	272	231	MHz

# Notes:

2. For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.



Table 2-32 • RAM512X18

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>AS</sub>	Address setup time	0.25	0.28	0.33	ns
t <sub>AH</sub>	Address hold time	0.00	0.00	0.00	ns
t <sub>ENS</sub>	REN, WEN setup time	0.09	0.10	0.12	ns
t <sub>ENH</sub>	REN, WEN hold time	0.06	0.07	0.08	ns
t <sub>DS</sub>	Input data (WD) setup time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input data (WD) hold time	0.00	0.00	0.00	ns
t <sub>CKQ1</sub>	Clock High to new data valid on RD (output retained)	2.16	2.46	2.89	ns
t <sub>CKQ2</sub>	Clock High to new data valid on RD (pipelined)	0.90	1.02	1.20	ns
t <sub>C2CRWH</sub> 1	Address collision clk-to-clk delay for reliable read access after write on same address—Applicable to Opening Edge	0.50	0.43	0.38	ns
t <sub>C2CWRH</sub> 1	Address collision clk-to-clk delay for reliable write access after read on same address—Applicable to Opening Edge		0.50	0.44	ns
<b>,</b> 1	RESET Low to data out Low on RD (flow-through)	0.92	1.05	1.23	ns
t <sub>RSTBQ</sub> 1	RESET Low to data out Low on RD (pipelined)	0.92	1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET removal	0.29	0.33	0.38	ns
t <sub>RECRSTB</sub>	RESET recovery	1.50	1.71	2.01	ns
t <sub>MPWRSTB</sub>	RESET minimum pulse width	0.21	0.24	0.29	ns
t <sub>CYC</sub>	Clock cycle time	3.23	3.68	4.32	ns
F <sub>MAX</sub>	Maximum frequency	310	272	231	MHz

#### Notes:

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<sup>1.</sup> For more information, refer to the application note Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs.

<sup>2.</sup> For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# FIFO4K18 Description

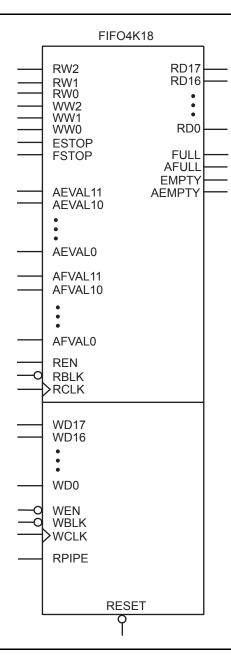


Figure 2-56 • FIFO4KX18



The following signals are used to configure the FIFO4K18 memory element.

#### WW and RW

These signals enable the FIFO to be configured in one of the five allowable aspect ratios (Table 2-33).

Table 2-33 • Aspect Ratio Settings for WW[2:0]

WW2, WW1, WW0	RW2, RW1, RW0	D×W
000	000	4k×1
001	001	2k×2
010	010	1k×4
011	011	512×9
100	100	256×18
101, 110, 111	101, 110, 111	Reserved

#### WBLK and RBLK

These signals are active low and will enable the respective ports when Low. When the RBLK signal is High, the corresponding port's outputs hold the previous value.

#### **WEN** and **REN**

Read and write enables. WEN is active low and REN is active high by default. These signals can be configured as active high or low.

#### WCLK and RCLK

These are the clock signals for the synchronous read and write operations. These can be driven independently or with the same driver.

#### **RPIPE**

This signal is used to specify pipelined read on the output. A Low on RPIPE indicates a nonpipelined read, and the data appears on the output in the same clock cycle. A High indicates a pipelined read, and data appears on the output in the next clock cycle.

#### RESET

This active low signal resets the output to zero when asserted. It resets the FIFO counters. It also sets all the RD pins Low, the FULL and AFULL pins Low, and the EMPTY and AEMPTY pins High (Table 2-34).

Table 2-34 • Input Data Signal Usage for Different Aspect Ratios

D×W	WD/RD Unused
4k×1	WD[17:1], RD[17:1]
2k×2	WD[17:2], RD[17:2]
1k×4	WD[17:4], RD[17:4]
512×9	WD[17:9], RD[17:9]
256×18	-

## WD

This is the input data bus and is 18 bits wide. Not all 18 bits are valid in all configurations. When a data width less than 18 is specified, unused higher-order signals must be grounded (Table 2-34).

#### RD

This is the output data bus and is 18 bits wide. Not all 18 bits are valid in all configurations. Like the WD bus, high-order bits become unusable if the data width is less than 18. The output data on unused pins is undefined (Table 2-34).

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## ESTOP, FSTOP

ESTOP is used to stop the FIFO read counter from further counting once the FIFO is empty (i.e., the EMPTY flag goes High). A High on this signal inhibits the counting.

FSTOP is used to stop the FIFO write counter from further counting once the FIFO is full (i.e., the FULL flag goes High). A High on this signal inhibits the counting.

For more information on these signals, refer to the "ESTOP and FSTOP Usage" section on page 2-70.

## **FULL, EMPTY**

When the FIFO is full and no more data can be written, the FULL flag asserts High. The FULL flag is synchronous to WCLK to inhibit writing immediately upon detection of a full condition and to prevent overflows. Since the write address is compared to a resynchronized (and thus time-delayed) version of the read address, the FULL flag will remain asserted until two WCLK active edges after a read operation eliminates the full condition.

When the FIFO is empty and no more data can be read, the EMPTY flag asserts High. The EMPTY flag is synchronous to RCLK to inhibit reading immediately upon detection of an empty condition and to prevent underflows. Since the read address is compared to a resynchronized (and thus time-delayed) version of the write address, the EMPTY flag will remain asserted until two RCLK active edges after a write operation removes the empty condition.

For more information on these signals, refer to the "FIFO Flag Usage Considerations" section on page 2-70.

## AFULL, AEMPTY

These are programmable flags and will be asserted on the threshold specified by AFVAL and AEVAL, respectively.

When the number of words stored in the FIFO reaches the amount specified by AEVAL while reading, the AEMPTY output will go High. Likewise, when the number of words stored in the FIFO reaches the amount specified by AFVAL while writing, the AFULL output will go High.

### AFVAL, AEVAL

The AEVAL and AFVAL pins are used to specify the almost-empty and almost-full threshold values, respectively. They are 12-bit signals. For more information on these signals, refer to "FIFO Flag Usage Considerations" section.

# ESTOP and FSTOP Usage

The ESTOP pin is used to stop the read counter from counting any further once the FIFO is empty (i.e., the EMPTY flag goes High). Likewise, the FSTOP pin is used to stop the write counter from counting any further once the FIFO is full (i.e., the FULL flag goes High).

The FIFO counters in the Fusion device start the count at 0, reach the maximum depth for the configuration (e.g., 511 for a 512×9 configuration), and then restart at 0. An example application for the ESTOP, where the read counter keeps counting, would be writing to the FIFO once and reading the same content over and over without doing another write.

#### FIFO Flag Usage Considerations

The AEVAL and AFVAL pins are used to specify the 12-bit AEMPTY and AFULL threshold values, respectively. The FIFO contains separate 12-bit write address (WADDR) and read address (RADDR) counters. WADDR is incremented every time a write operation is performed, and RADDR is incremented every time a read operation is performed. Whenever the difference between WADDR and RADDR is greater than or equal to AFVAL, the AFULL output is asserted. Likewise, whenever the difference between WADDR and RADDR is less than or equal to AEVAL, the AEMPTY output is asserted. To handle different read and write aspect ratios, AFVAL and AEVAL are expressed in terms of total data bits instead of total data words. When users specify AFVAL and AEVAL in terms of read or write words, the SmartGen tool translates them into bit addresses and configures these signals automatically. SmartGen configures the AFULL flag to assert when the write address exceeds the read address by at least a predefined value. In a 2k×8 FIFO, for example, a value of 1,500 for AFVAL means that the AFULL flag will be asserted after a write when the difference between the write address and the read address reaches 1,500 (there have been at least 1500 more writes than reads). It will stay asserted until the difference between the write and read addresses drops below 1,500.



The AEMPTY flag is asserted when the difference between the write address and the read address is less than a predefined value. In the example above, a value of 200 for AEVAL means that the AEMPTY flag will be asserted when a read causes the difference between the write address and the read address to drop to 200. It will stay asserted until that difference rises above 200. Note that the FIFO can be configured with different read and write widths; in this case, the AFVAL setting is based on the number of write data entries and the AEVAL setting is based on the number of read data entries. For aspect ratios of 512×9 and 256×18, only 4,096 bits can be addressed by the 12 bits of AFVAL and AEVAL. The number of words must be multiplied by 8 and 16, instead of 9 and 18. The SmartGen tool automatically uses the proper values. To avoid halfwords being written or read, which could happen if different read and write aspect ratios are specified, the FIFO will assert FULL or EMPTY as soon as at least a minimum of one word cannot be written or read. For example, if a two-bit word is written and a four-bit word is being read, the FIFO will remain in the empty state when the first word is written. This occurs even if the FIFO is not completely empty, because in this case, a complete word cannot be read. The same is applicable in the full state. If a four-bit word is written and a two-bit word is read, the FIFO is full and one word is read. The FULL flag will remain asserted because a complete word cannot be written at this point.

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# FIFO Characteristics

# **Timing Waveforms**

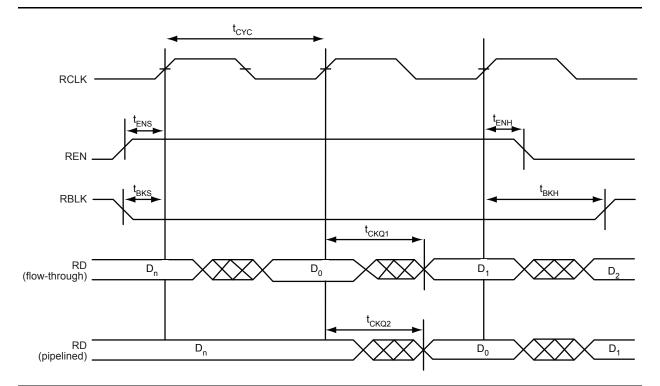


Figure 2-57 • FIFO Read

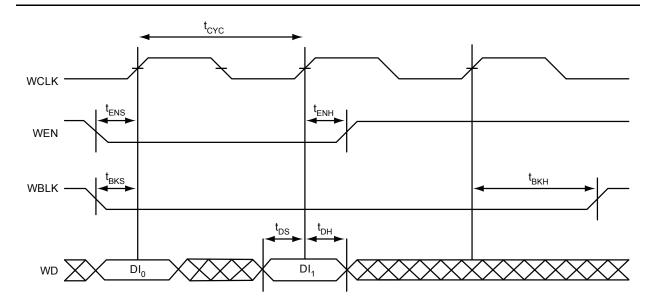


Figure 2-58 • FIFO Write



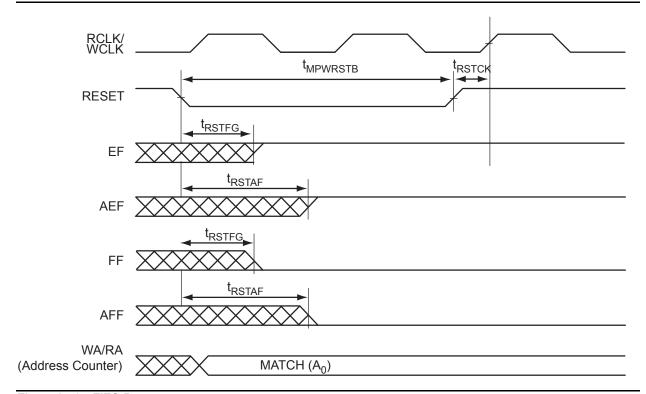


Figure 2-59 • FIFO Reset

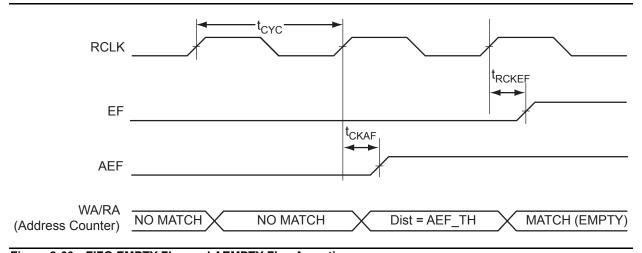


Figure 2-60 • FIFO EMPTY Flag and AEMPTY Flag Assertion

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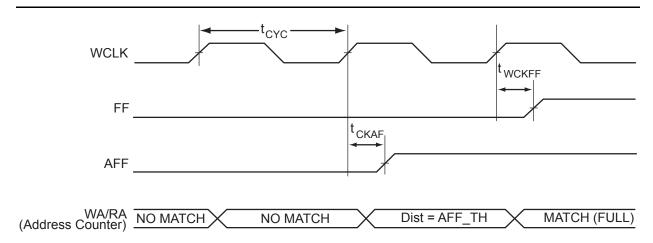


Figure 2-61 • FIFO FULL and AFULL Flag Assertion

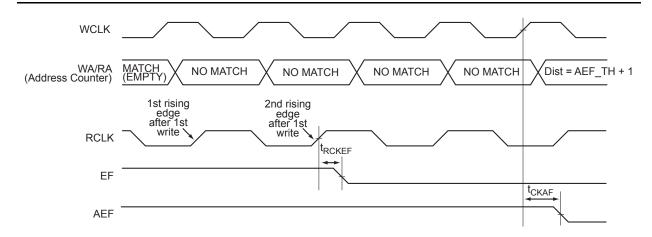


Figure 2-62 • FIFO EMPTY Flag and AEMPTY Flag Deassertion

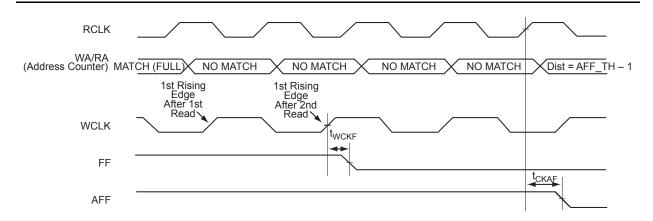


Figure 2-63 • FIFO FULL Flag and AFULL Flag Deassertion



# **Timing Characteristics**

Table 2-35 • FIFO Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	<b>-1</b>	Std.	Units
t <sub>ENS</sub>	REN, WEN Setup time	1.34	1.52	1.79	ns
t <sub>ENH</sub>	REN, WEN Hold time	0.00	0.00	0.00	ns
t <sub>BKS</sub>	BLK Setup time	0.19	0.22	0.26	ns
t <sub>BKH</sub>	BLK Hold time	0.00	0.00	0.00	ns
t <sub>DS</sub>	Input data (WD) Setup time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input data (WD) Hold time	0.00	0.00	0.00	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on RD (flow-through)	2.17	2.47	2.90	ns
t <sub>CKQ2</sub>	Clock High to New Data Valid on RD (pipelined)	0.94	1.07	1.26	ns
t <sub>RCKEF</sub>	RCLK High to Empty Flag Valid	1.72	1.96	2.30	ns
t <sub>WCKFF</sub>	WCLK High to Full Flag Valid	1.63	1.86	2.18	ns
t <sub>CKAF</sub>	Clock High to Almost Empty/Full Flag Valid	6.19	7.05	8.29	ns
t <sub>RSTFG</sub>	RESET Low to Empty/Full Flag Valid	1.69	1.93	2.27	ns
t <sub>RSTAF</sub>	RESET Low to Almost-Empty/Full Flag Valid	6.13	6.98	8.20	ns
+	RESET Low to Data out Low on RD (flow-through)	0.92	1.05	1.23	ns
t <sub>RSTBQ</sub>	RESET Low to Data out Low on RD (pipelined)	0.92	1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET Removal	0.29	0.33	0.38	ns
t <sub>RECRSTB</sub>	RESET Recovery	1.50	1.71	2.01	ns
t <sub>MPWRSTB</sub>	RESET Minimum Pulse Width	0.21	0.24	0.29	ns
t <sub>CYC</sub>	Clock Cycle time	3.23	3.68	4.32	ns
F <sub>MAX</sub>	Maximum Frequency for FIFO	310	272	231	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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# **Analog Block**

With the Fusion family, Microsemi has introduced the world's first mixed-mode FPGA solution. Supporting a robust analog peripheral mix, Fusion devices will support a wide variety of applications. It is this Analog Block that separates Fusion from all other FPGA solutions on the market today.

By combining both flash and high-speed CMOS processes in a single chip, these devices offer the best of both worlds. The high-performance CMOS is used for building RAM resources. These high-performance structures support device operation up to 350 MHz. Additionally, the advanced Microsemi 0.13 µm flash process incorporates high-voltage transistors and a high-isolation, triple-well process. Both of these are suited for the flash-based programmable logic and nonvolatile memory structures.

High-voltage transistors support the integration of analog technology in several ways. They aid in noise immunity so that the analog portions of the chip can be better isolated from the digital portions, increasing analog accuracy. Because they support high voltages, Microsemi flash FPGAs can be connected directly to high-voltage input signals, eliminating the need for external resistor divider networks, reducing component count, and increasing accuracy. By supporting higher internal voltages, the Microsemi advanced flash process enables high dynamic range on analog circuitry, increasing precision and signal—noise ratio. Microsemi flash FPGAs also drive high-voltage outputs, eliminating the need for external level shifters and drivers.

The unique triple-well process enables the integration of high-performance analog features with increased noise immunity and better isolation. By increasing the efficiency of analog design, the triple-well process also enables a smaller overall design size, reducing die size and cost.

The Analog Block consists of the Analog Quad I/O structure, RTC (for details refer to the "Real-Time Counter System" section on page 2-31), ADC, and ACM. All of these elements are combined in the single Analog Block macro, with which the user implements this functionality (Figure 2-64).

The Analog Block needs to be reset/reinitialized after the core powers up or the device is programmed. An external reset/initialize signal, which can come from the internal voltage regulator when it powers up, must be applied.



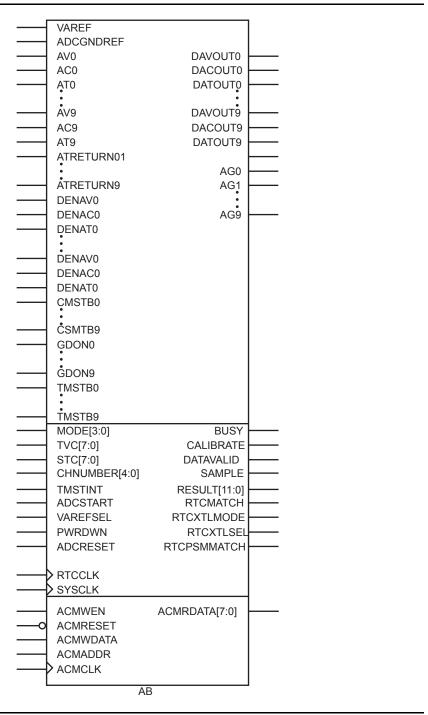


Figure 2-64 • Analog Block Macro

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Table 2-36 describes each pin in the Analog Block. Each function within the Analog Block will be explained in detail in the following sections.

Table 2-36 • Analog Block Pin Description

Signal Name	Number of Bits	Direction	Function	Location of Details
VAREF	1	Input/Output	Voltage reference for ADC	ADC
ADCGNDREF	1	Input	External ground reference	ADC
MODE[3:0]	4	Input	ADC operating mode	ADC
SYSCLK	1	Input	External system clock	
TVC[7:0]	8	Input	Clock divide control	ADC
STC[7:0]	8	Input	Sample time control	ADC
ADCSTART	1	Input	Start of conversion	ADC
PWRDWN	1	Input	ADC comparator power-down if 1. When asserted, the ADC will stop functioning, and the digital portion of the analog block will continue operating. This may result in invalid status flags from the analog block. Therefore, Microsemi does not recommend asserting the PWRDWN pin.	
ADCRESET	1	Input	ADC resets and disables Analog Quad – active high	ADC
BUSY	1	Output	1 – Running conversion	ADC
CALIBRATE	1	Output	1 – Power-up calibration	ADC
DATAVALID	1	Output	1 – Valid conversion result	ADC
RESULT[11:0]	12	Output	Conversion result	ADC
TMSTBINT	1	Input	Internal temp. monitor strobe	ADC
SAMPLE	1	Output	<ul><li>1 – An analog signal is actively being sampled (stays high during signal acquisition only)</li><li>0 – No analog signal is being sampled</li></ul>	ADC
VAREFSEL	1	Input	0 = Output internal voltage reference (2.56 V) to VAREF	ADC
			1 = Input external voltage reference from VAREF and ADCGNDREF	
CHNUMBER[4:0]	5	Input	Analog input channel select	Input multiplexer
ACMCLK	1	Input	ACM clock	ACM
ACMWEN	1	Input	ACM write enable – active high	ACM
ACMRESET	1	Input	ACM reset – active low	ACM
ACMWDATA[7:0]	8	Input	ACM write data	ACM
ACMRDATA[7:0]	8	Output	ACM read data	ACM
ACMADDR[7:0]	8	Input	ACM address	ACM
CMSTB0 to CMSTB9	10	Input	Current monitor strobe – 1 per quad, active high	Analog Quad



Table 2-36 • Analog Block Pin Description (continued)

Signal Name	Number of Bits	Direction	Function	Location of Details
GDON0 to GDON9	10	Input	Control to power MOS – 1 per quad	Analog Quad
TMSTB0 to TMSTB9	10	Input	Temperature monitor strobe – 1 per quad; active high	Analog Quad
DAVOUTO, DACOUTO, DATOUTO	30	Output	Digital outputs – 3 per quad	Analog Quad
to DAVOUT9, DACOUT9, DATOUT9				
DENAV0, DENAC0, DENAT0 to DENAV9, DENAC9, DENAT9	30	Input	Digital input enables – 3 per quad	Analog Quad
AV0	1	Input	Analog Quad 0	Analog Quad
AC0	1	Input		Analog Quad
AG0	1	Output		Analog Quad
AT0	1	Input		Analog Quad
ATRETURN01	1	Input	Temperature monitor return shared by Analog Quads 0 and 1	Analog Quad
AV1	1	Input	Analog Quad 1	Analog Quad
AC1	1	Input		Analog Quad
AG1	1	Output		Analog Quad
AT1	1	Input		Analog Quad
AV2	1	Input	Analog Quad 2	Analog Quad
AC2	1	Input		Analog Quad
AG2	1	Output		Analog Quad
AT2	1	Input		Analog Quad
ATRETURN23	1	Input	Temperature monitor return shared by Analog Quads 2 and 3	Analog Quad
AV3	1	Input	Analog Quad 3	Analog Quad
AC3	1	Input		Analog Quad
AG3	1	Output		Analog Quad
AT3	1	Input		Analog Quad
AV4	1	Input	Analog Quad 4	Analog Quad
AC4	1	Input		Analog Quad
AG4	1	Output		Analog Quad
AT4	1	Input		Analog Quad
ATRETURN45	1	Input	Temperature monitor return shared by Analog Quads 4 and 5	Analog Quad
AV5	1	Input	Analog Quad 5	Analog Quad
AC5	1	Input		Analog Quad
AG5	1	Output		Analog Quad
AT5	1	Input		Analog Quad
AV6	1	Input	Analog Quad 6	Analog Quad
AC6	1	Input		Analog Quad

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Table 2-36 • Analog Block Pin Description (continued)

Signal Name	Number of Bits	Direction	Function	Location of Details
AG6	1	Output		Analog Quad
AT6	1	Input		Analog Quad
ATRETURN67	1	Input	Temperature monitor return shared by Analog Quads 6 and 7	Analog Quad
AV7	1	Input	Analog Quad 7	Analog Quad
AC7	1	Input		Analog Quad
AG7	1	Output		Analog Quad
AT7	1	Input		Analog Quad
AV8	1	Input	Analog Quad 8	Analog Quad
AC8	1	Input		Analog Quad
AG8	1	Output		Analog Quad
AT8	1	Input		Analog Quad
ATRETURN89	1	Input	Temperature monitor return shared by Analog Quads 8 and 9	Analog Quad
AV9	1	Input	Analog Quad 9	Analog Quad
AC9	1	Input		Analog Quad
AG9	1	Output		Analog Quad
AT9	1	Input		Analog Quad
RTCMATCH	1	Output	MATCH	RTC
RTCPSMMATCH	1	Output	MATCH connected to VRPSM	RTC
RTCXTLMODE[1:0]	2	Output	Drives XTLOSC RTCMODE[1:0] pins	RTC
RTCXTLSEL	1	Output	Drives XTLOSC MODESEL pin	RTC
RTCCLK	1	Input	RTC clock input	RTC

# **Analog Quad**

With the Fusion family, Microsemi introduces the Analog Quad, shown in Figure 2-65 on page 2-81, as the basic analog I/O structure. The Analog Quad is a four-channel system used to precondition a set of analog signals before sending it to the ADC for conversion into a digital signal. To maximize the usefulness of the Analog Quad, the analog input signals can also be configured as LVTTL digital input signals. The Analog Quad is divided into four sections.

The first section is called the Voltage Monitor Block, and its input pin is named AV. It contains a two-channel analog multiplexer that allows an incoming analog signal to be routed directly to the ADC or allows the signal to be routed to a prescaler circuit before being sent to the ADC. The prescaler can be configured to accept analog signals between –12 V and 0 or between 0 and +12 V. The prescaler circuit scales the voltage applied to the ADC input pad such that it is compatible with the ADC input voltage range. The AV pin can also be used as a digital input pin.

The second section of the Analog Quad is called the Current Monitor Block. Its input pin is named AC. The Current Monitor Block contains all the same functions as the Voltage Monitor Block with one addition, which is a current monitoring function. A small external current sensing resistor (typically less than 1  $\Omega$ ) is connected between the AV and AC pins and is in series with a power source. The Current Monitor Block contains a current monitor circuit that converts the current through the external resistor to a voltage that can then be read using the ADC.



The third part of the Analog Quad is called the Gate Driver Block, and its output pin is named AG. This section is used to drive an external FET. There are two modes available: a High Current Drive mode and a Current Source Control mode. Both negative and positive voltage polarities are available, and in the current source control mode, four different current levels are available.

The fourth section of the Analog Quad is called the Temperature Monitor Block, and its input pin name is AT. This block is similar to the Voltage Monitor Block, except that it has an additional function: it can be used to monitor the temperature of an external diode-connected transistor. It has a modified prescaler and is limited to positive voltages only.

The Analog Quad can be configured during design time by Libero SoC; however, the ACM can be used to change the parameters of any of these I/Os during runtime. This type of change is referred to as a context switch. The Analog Quad is a modular structure that is replicated to generate the analog I/O resources. Each Fusion device supports between 5 and 10 Analog Quads.

The analog pads are numbered to clearly identify both the type of pad (voltage, current, gate driver, or temperature pad) and its corresponding Analog Quad (AV0, AC0, AG0, AT0, AV1, ..., AC9, AG9, and AT9). There are three types of input pads (AVx, ACx, and ATx) and one type of analog output pad (AGx). Since there can be up to 10 Analog Quads on a device, there can be a maximum of 30 analog input pads and 10 analog output pads.

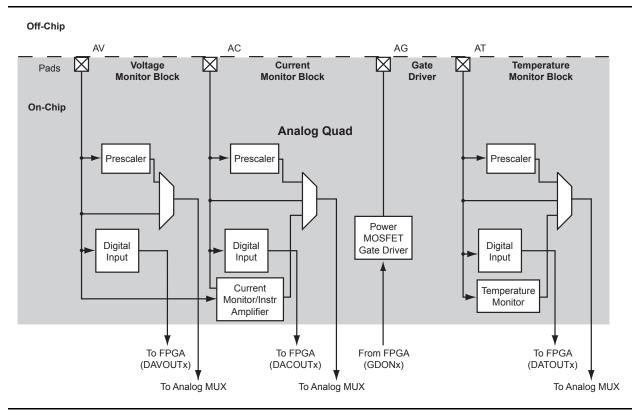


Figure 2-65 • Analog Quad

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# Voltage Monitor

The Fusion Analog Quad offers a robust set of voltage-monitoring capabilities unique in the FPGA industry. The Analog Quad comprises three analog input pads— Analog Voltage (AV), Analog Current (AC), and Analog Temperature (AT)—and a single gate driver output pad, Analog Gate (AG). There are many common characteristics among the analog input pads. Each analog input can be configured to connect directly to the input MUX of the ADC. When configured in this manner (Figure 2-66), there will be no prescaling of the input signal. Care must be taken in this mode not to drive the ADC into saturation by applying an input voltage greater than the reference voltage. The internal reference voltage of the ADC is 2.56 V. Optionally, an external reference can be supplied by the user. The external reference can be a maximum of 3.3 V DC.

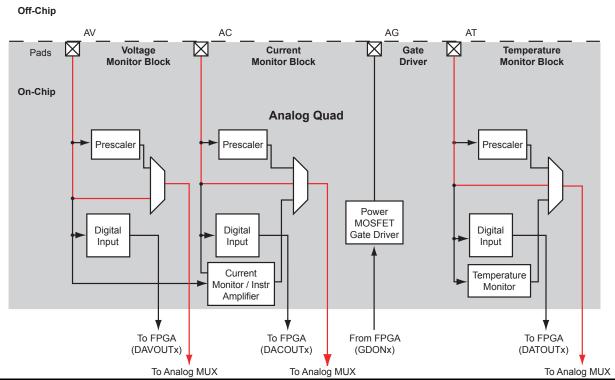


Figure 2-66 • Analog Quad Direct Connect

The Analog Quad offers a wide variety of prescaling options to enable the ADC to resolve the input signals. Figure 2-67 shows the path through the Analog Quad for a signal that is to be prescaled prior to conversion. The ADC internal reference voltage and the prescaler factors were selected to make both prescaling and postscaling of the signals easy binary calculations (refer to Table 2-57 on page 2-130 for details). When an analog input pad is configured with a prescaler, there will be a 1 M $\Omega$  resistor to ground. This occurs even when the device is in power-down mode. In low power standby or sleep mode (VCC is OFF, VCC33A is ON, VCCI is ON) or when the resource is not used, analog inputs are pulled down to ground through a 1 M $\Omega$  resistor. The gate driver output is floating (or tristated), and there is no extra current on VCC33A.

These scaling factors hold true whether the particular pad is configured to accept a positive or negative voltage. Note that whereas the AV and AC pads support the same prescaling factors, the AT pad supports a reduced set of prescaling factors and supports positive voltages only.



Typical scaling factors are given in Table 2-57 on page 2-130, and the gain error (which contributes to the minimum and maximum) is in Table 2-49 on page 2-117.

Off-Chip

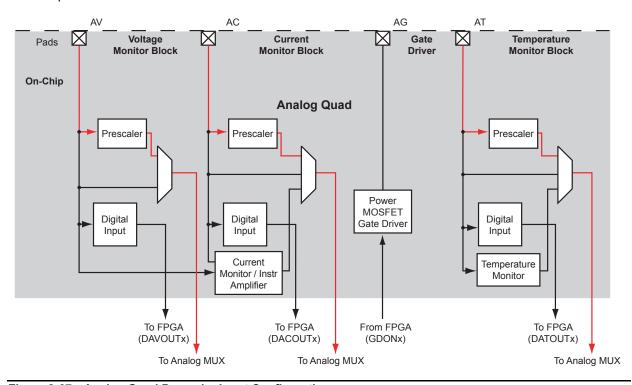


Figure 2-67 • Analog Quad Prescaler Input Configuration

# **Terminology**

## BW - Bandwidth

BW is a range of frequencies that a Channel can handle.

#### Channe

A channel is define as an analog input configured as one of the Prescaler range shown in Table 2-57 on page 2-130. The channel includes the Prescaler circuit and the ADC.

### Channel Gain

Channel Gain is a measured of the deviation of the actual slope from the ideal slope. The slope is measured from the 20% and 80% point.

$$Gain = \frac{Gain_{actual}}{Gain_{ideal}}$$

EQ1

# **Channel Gain Error**

Channel Gain Error is a deviation from the ideal slope of the transfer function. The Prescaler Gain Error is expressed as the percent difference between the actual and ideal, as shown in EQ 2.

$$Error_{Gain} = (1-Gain) \times 100\%$$

EQ 2

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# Channel Input Offset Error

Channel Offset error is measured as the input voltage that causes the transition from zero to a count of one. An Ideal Prescaler will have offset equal to  $\frac{1}{2}$  of LSB voltage. Offset error is a positive or negative when the first transition point is higher or lower than ideal. Offset error is expressed in LSB or input voltage.

## **Total Channel Error**

Total Channel Error is defined as the total error measured compared to the ideal value. Total Channel Error is the sum of gain error and offset error combined. Figure 2-68 shows how Total Channel Error is measured.

Total Channel Error is defined as the difference between the actual ADC output and ideal ADC output. In the example shown in Figure 2-68, the Total Channel Error would be a negative number.

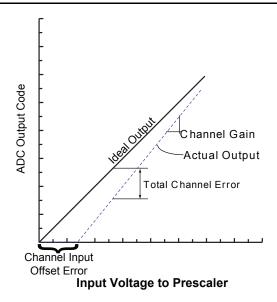


Figure 2-68 • Total Channel Error Example



# **Direct Digital Input**

The AV, AC, and AT pads can also be configured as high-voltage digital inputs (Figure 2-69). As these pads are 12 V-tolerant, the digital input can also be up to 12 V. However, the frequency at which these pads can operate is limited to 10 MHz.

To enable one of these analog input pads to operate as a digital input, its corresponding Digital Input Enable (DENAxy) pin on the Analog Block must be pulled High, where x is either V, C, or T (for AV, AC, or AT pads, respectively) and y is in the range 0 to 9, corresponding to the appropriate Analog Quad.

When the pad is configured as a digital input, the signal will come out of the Analog Block macro on the appropriate DAxOUTy pin, where x represents the pad type (V for AV pad, C for AC pad, or T for AT pad) and y represents the appropriate Analog Quad number. Example: If the AT pad in Analog Quad 5 is configured as a digital input, it will come out on the DATOUT5 pin of the Analog Block macro.

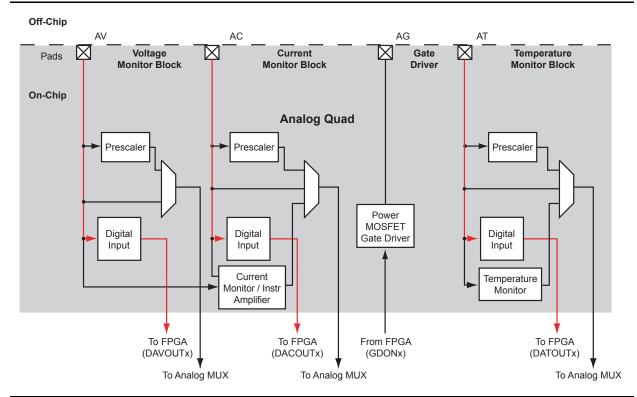


Figure 2-69 • Analog Quad Direct Digital Input Configuration

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# **Current Monitor**

The Fusion Analog Quad is an excellent element for voltage- and current-monitoring applications. In addition to supporting the same functionality offered by the AV pad, the AC pad can be configured to monitor current across an external sense resistor (Figure 2-70). To support this current monitor function, a differential amplifier with 10x gain passes the amplified voltage drop between the AV and AC pads to the ADC. The amplifier enables the user to use very small resistor values, thereby limiting any impact on the circuit. This function of the AC pad does not limit AV pad operation. The AV pad can still be configured for use as a direct voltage input or scaled through the AV prescaler independently of it's use as an input to the AC pad's differential amplifier.

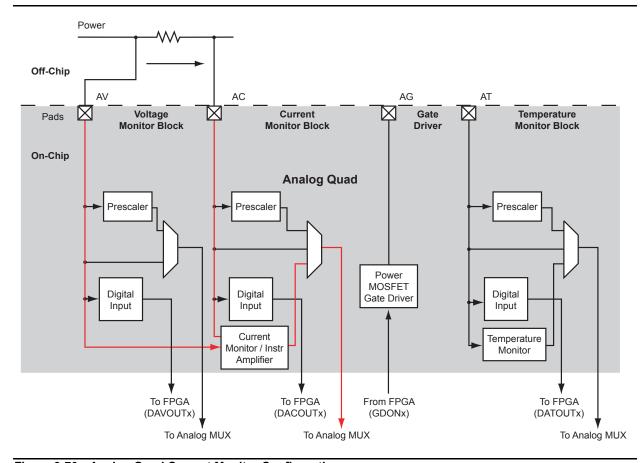


Figure 2-70 • Analog Quad Current Monitor Configuration



To initiate a current measurement, the appropriate Current Monitor Strobe (CMSTB) signal on the AB macro must be asserted low for at least  $t_{CMSLO}$  in order to discharge the previous measurement. Then CMSTB must be asserted high for at least  $t_{CMSET}$  prior to asserting the ADCSTART signal. The CMSTB must remain high until after the SAMPLE signal is de-asserted by the AB macro. Note that the minimum sample time cannot be less than  $t_{CMSHI}$ . Figure 2-71 shows the timing diagram of CMSTB in relationship with the ADC control signals.

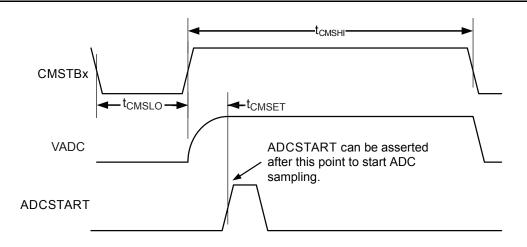


Figure 2-71 • Timing Diagram for Current Monitor Strobe

Figure 2-72 illustrates positive current monitor operation. The differential voltage between AV and AC goes into the 10× amplifier and is then converted by the ADC. For example, a current of 1.5 A is drawn from a 10 V supply and is measured by the voltage drop across a 0.050  $\Omega$  sense resistor, The voltage drop is amplified by ten times by the amplifier and then measured by the ADC. The 1.5 A current creates a differential voltage across the sense resistor of 75 mV. This becomes 750 mV after amplification. Thus, the ADC measures a current of 1.5 A as 750 mV. Using an ADC with 8-bit resolution and VAREF of 2.56 V, the ADC result is decimal 75. EQ 3 shows how to compute the current from the ADC result.

$$|\mathbf{I}| = (ADC \times V_{AREF})/(10 \times 2^{N} \times R_{sense})$$

EQ3

where

I is the current flowing through the sense resistor

ADC is the result from the ADC

VAREF is the Reference voltage

N is the number of bits

Rsense is the resistance of the sense resistor

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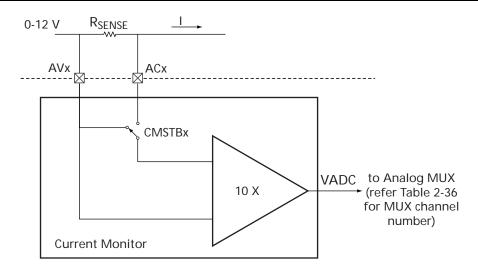


Figure 2-72 • Positive Current Monitor

Care must be taken when choosing the right resistor for current measurement application. Note that because of the  $10\times$  amplification, the maximum measurable difference between the AV and AC pads is  $V_{AREF}$  / 10. A larger AV-to-AC voltage drop will result in ADC saturation; that is, the digital code put out by the ADC will stay fixed at the full scale value. Therefore, the user must select the external sense resistor appropriately. Table 2-38 shows recommended resistor values for different current measurement ranges. When choosing resistor values for a system, there is a trade-off between measurement accuracy and power consumption. Choosing a large resistor will increase the voltage drop and hence increase accuracy of the measurement; however the larger voltage drop dissipates more power (P =  $1^2 \times R$ ).

The Current Monitor is a unipolar system, meaning that the differential voltage swing must be from 0 V to  $V_{AREF}/10$ . Therefore, the Current Monitor only supports differential voltage where  $|V_{AV}-V_{AC}|$  is greater than 0 V. This results in the requirement that the potential of the AV pad must be larger than the potential of the AC pad. This is straightforward for positive voltage systems. For a negative voltage system, it means that the AV pad must be "more negative" than the AC pad. This is shown in Figure 2-73.

In this case, both the AV pad and the AC pad are configured for negative operations and the output of the differential amplifier still falls between 0 V and  $V_{ARFF}$  as required.

Table 2-37 • Recommended Resistor for Different Current Range Measurement

Current Range	Recommended Minimum Resistor Value (Ohms)
> 5 mA – 10 mA	10 – 20
> 10 mA – 20 mA	5 – 10
> 20 mA – 50 mA	2.5 – 5
> 50 mA – 100 mA	1 – 2
> 100 mA – 200 mA	0.5 – 1
> 200 mA – 500 mA	0.3 – 0.5
> 500 mA – 1 A	0.1 – 0.2
> 1 A – 2 A	0.05 – 0.1
> 2 A – 4 A	0.025 - 0.05
> 4 A – 8 A	0.0125 - 0.025
> 8 A – 12 A	0.00625 - 0.02



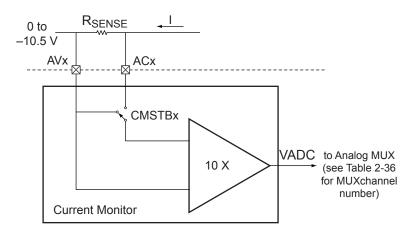


Figure 2-73 • Negative Current Monitor

# **Terminology**

# Accuracy

The accuracy of Fusion Current Monitor is  $\pm 2$  mV minimum plus 5% of the differential voltage at the input. The input accuracy can be translated to error at the ADC output by using EQ 4. The 10 V/V gain is the gain of the Current Monitor Circuit, as described in the "Current Monitor" section on page 2-86. For 8-bit mode, N = 8,  $V_{AREF} = 2.56$  V, zero differential voltage between AV and AC, the Error ( $E_{ADC}$ ) is equal to 2 LSBs.

$$E_{ADC} = (2mV + 0.05 | V_{AV} - V_{AC}|) \times (10V) / V \times \frac{2^{N}}{V_{AREF}}$$

EQ4

where

N is the number of bits

 $V_{AREF}$  is the Reference voltage

 $V_{AV}$  is the voltage at AV pad

 $V_{AC}$  is the voltage at AC pad

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## **Gate Driver**

The Fusion Analog Quad includes a Gate Driver connected to the Quad's AG pin (Figure 2-74). Designed to work with external p- or n-channel MOSFETs, the Gate driver is a configurable current sink or source and requires an external pull-up or pull-down resistor. The AG supports 4 selectable gate drive levels: 1  $\mu$ A, 3  $\mu$ A, 10  $\mu$ A, and 30  $\mu$ A (Figure 2-75 on page 2-91). The AG also supports a High Current Drive mode in which it can sink 20 mA; in this mode the switching rate is approximately 1.3 MHz with 100 ns turn-on time and 600 ns turn-off time. Modeled on an open-drain-style output, it does not output a voltage level without an appropriate pull-up or pull-down resistor. If 1 V is forced on the drain, the current sinking/sourcing will exceed the ability of the transistor, and the device could be damaged.

The AG pad is turned on via the corresponding GDONx pin in the Analog Block macro, where x is the number of the corresponding Analog Quad for the AG pad to be enabled (GDON0 to GDON9).

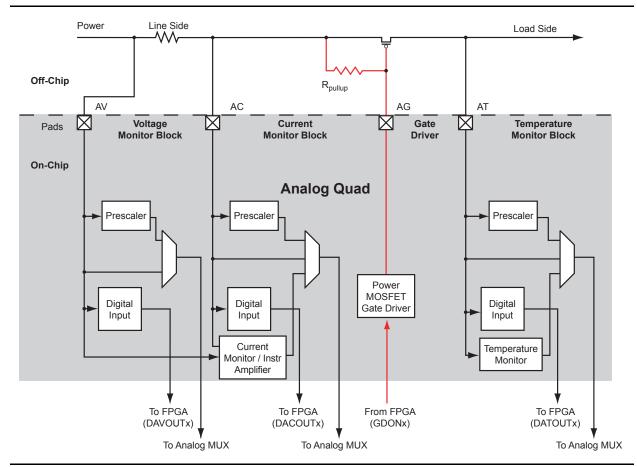


Figure 2-74 • Gate Driver

The gate-to-source voltage ( $V_{gs}$ ) of the external MOSFET is limited to the programmable drive current times the external pull-up or pull-down resistor value (EQ 5).

$$V_{gs} \le I_g \times (R_{pullup} \text{ or } R_{pulldown})$$

EQ 5



The rate at which the gate voltage of the external MOSFET slews is determined by the current,  $I_g$ , sourced or sunk by the AG pin and the gate-to-source capacitance,  $C_{GS}$ , of the external MOSFET. As an approximation, the slew rate is given by EQ 6.

$$dv/dt = I_g / C_{GS}$$

EQ6

 $C_{GS}$  is not a fixed capacitance but, depending on the circuitry connected to its drain terminal, can vary significantly during the course of a turn-on or turn-off transient. Thus, EQ 6 on page 2-91 can only be used for a first-order estimate of the switching speed of the external MOSFET.

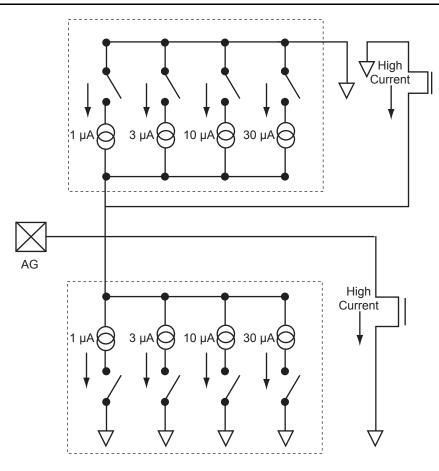


Figure 2-75 • Gate Driver Example

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# **Temperature Monitor**

The final pin in the Analog Quad is the Analog Temperature (AT) pin. The AT pin is used to implement an accurate temperature monitor in conjunction with an external diode-connected bipolar transistor (Figure 2-76). For improved temperature measurement accuracy, it is important to use the ATRTN pin for the return path of the current sourced by the AT pin. Each ATRTN pin is shared between two adjacent Analog Quads. Additionally, if not used for temperature monitoring, the AT pin can provide functionality similar to that of the AV pad. However, in this mode only positive voltages can be applied to the AT pin, and only two prescaler factors are available (16 V and 4 V ranges—refer to Table 2-57 on page 2-130).

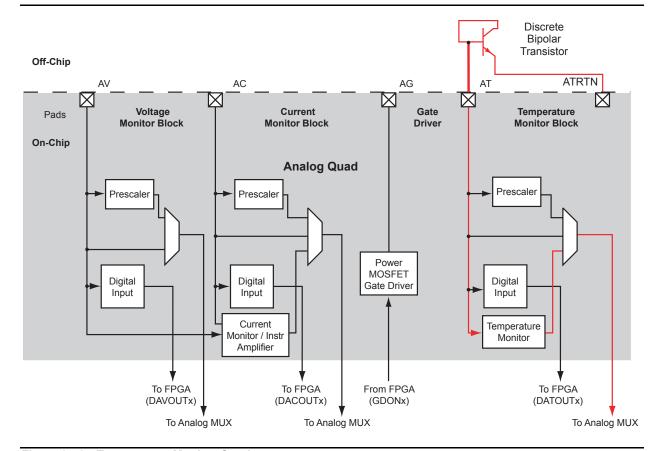


Figure 2-76 • Temperature Monitor Quad



Fusion uses a remote diode as a temperature sensor. The Fusion Temperature Monitor uses a differential input; the AT pin and ATRTN (AT Return) pin are the differential inputs to the Temperature Monitor. There is one Temperature Monitor in each Quad. A simplified block diagram is shown in Figure 2-77.

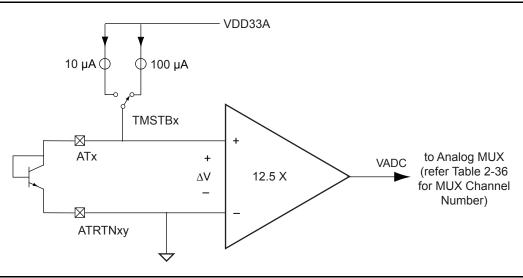


Figure 2-77 • Block Diagram for Temperature Monitor Circuit

The Fusion approach to measuring temperature is forcing two different currents through the diode with a ratio of 10:1. The switch that controls the different currents is controlled by the Temperature Monitor Strobe signal, TMSTB. Setting TMSTB to '1' will initiate a Temperature reading. The TMSTB should remain '1' until the ADC finishes sampling the voltage from the Temperature Monitor. The minimum sample time for the Temperature Monitor cannot be less than the minimum strobe high time minus the setup time. Figure 2-78 shows the timing diagram.

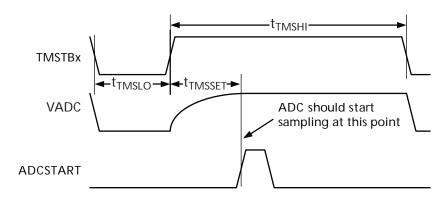


Figure 2-78 • Timing Diagram for the Temperature Monitor Strobe Signal

Note: When the IEEE 1149.1 Boundary Scan EXTEST instruction is executed, the AG pad drive strength ceases and becomes a 1 µA sink into the Fusion device.

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The diode's voltage is measured at each current level and the temperature is calculated based on EQ 7.

$$V_{\text{TMSLO}} - V_{\text{TMSHI}} = n \frac{kT}{q} \left( \ln \frac{I_{\text{TMSLO}}}{I_{\text{TMSHI}}} \right)$$

EQ7

where

 $I_{TMSLO}$  is the current when the Temperature Strobe is Low, typically 100  $\mu$ A

 $I_{TMSHI}$  is the current when the Temperature Strobe is High, typically 10  $\mu$ A

V<sub>TMSLO</sub> is diode voltage while Temperature Strobe is Low

*V*<sub>TMSHI</sub> is diode voltage while Temperature Strobe is High

*n* is the non-ideality factor of the diode-connected transistor. It is typically 1.004 for the Microsemi-recommended transistor type 2N3904.

 $K = 1.3806 \times 10^{-23} \text{ J/K}$  is the Boltzman constant

 $Q = 1.602 \times 10^{-19} C$  is the charge of a proton

When  $I_{TMSLO} / I_{TMSHI} = 10$ , the equation can be simplified as shown in EQ 8.

$$\Delta V = V_{\text{TMSLO}} - V_{\text{TMSHI}} = 1.986 \times 10^{-4} nT$$

EQ8

In the Fusion TMB, the ideality factor n for 2N3904 is 1.004 and  $\Delta V$  is amplified 12.5 times by an internal amplifier; hence the voltage before entering the ADC is as given in EQ 9.

$$V_{ADC} = \Delta V \times 12.5 = 2.5 \text{ mV}/(K \times T)$$

EQ9

This means the temperature to voltage relationship is 2.5 mV per degree Kelvin. The unique design of Fusion has made the Temperature Monitor System simple for the user. When the 10-bit mode ADC is used, each LSB represents 1 degree Kelvin, as shown in EQ 10. That is, e. 25°C is equal to 293°K and is represented by decimal 293 counts from the ADC.

$$1K = 2.5 \text{ mV} \times \frac{2^{10}}{2.56 \text{ V}} = 1 \text{ LSB}$$

EQ 10

If 8-bit mode is used for the ADC resolution, each LSB represents 4 degrees Kelvin; however, the resolution remains as 1 degree Kelvin per LSB, even for 12-bit mode, due to the Temperature Monitor design. An example of the temperature data format for 10-bit mode is shown in Table 2-38.

Table 2-38 • Temperature Data Format

Temperature	Temperature (K)	Digital Output (ADC 10-bit mode)
-40°C	233	00 1110 1001
–20°C	253	00 1111 1101
0°C	273	01 0001 0001
1°C	274	01 0001 0010
10 °C	283	01 0001 1011
25°C	298	01 0010 1010
50 °C	323	01 0100 0011
85 °C	358	01 0110 0110



# Terminology

# Resolution

Resolution defines the smallest temperature change Fusion Temperature Monitor can resolve. For ADC configured as 8-bit mode, each LSB represents 4°C, and 1°C per LSB for 10-bit mode. With 12-bit mode, the Temperature Monitor can still only resolve 1°C due to Temperature Monitor design.

#### Offset

The Fusion Temperature Monitor has a systematic offset (Table 2-49 on page 2-117), excluding error due to board resistance and ideality factor of the external diode. Microsemi provides an IP block (CalibIP) that is required in order to mitigate the systematic temperature offset. For further details on CalibIP, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.

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# **Analog-to-Digital Converter Block**

At the heart of the Fusion analog system is a programmable Successive Approximation Register (SAR) ADC. The ADC can support 8-, 10-, or 12-bit modes of operation. In 12-bit mode, the ADC can resolve 500 ksps. All results are MSB-justified in the ADC. The input to the ADC is a large 32:1 analog input multiplexer. A simplified block diagram of the Analog Quads, analog input multiplexer, and ADC is shown in Figure 2-79. The ADC offers multiple self-calibrating modes to ensure consistent high performance both at power-up and during runtime.

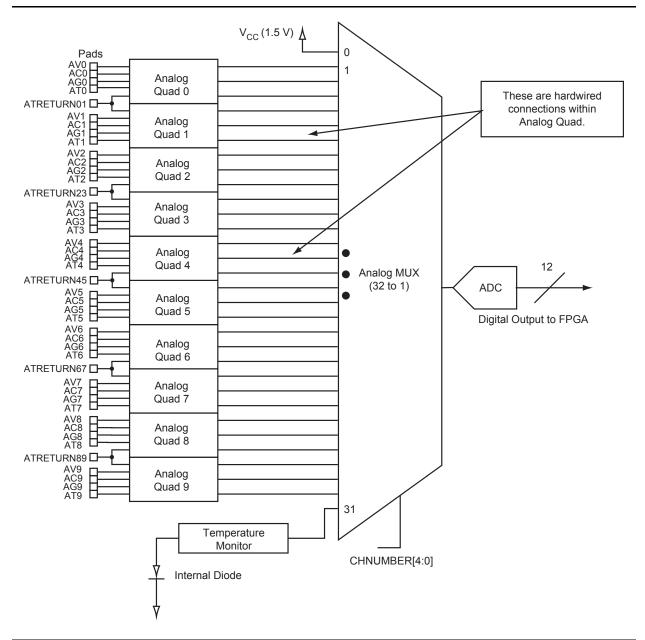


Figure 2-79 • ADC Block Diagram



# **ADC Description**

The Fusion ADC is a 12-bit SAR ADC. It offers a wide variety of features for different use models. Figure 2-80 shows a block diagram of the Fusion ADC.

- · Configurable resolution: 8-bit, 10-bit, and 12-bit mode
- DNL: 0.6 LSB for 10-bit mode
- INL: 0.4 LSB for 10-bit mode
- · No missing code
- Internal VAREF = 2.56 V
- Maximum Sample Rate = 600 Ksps
- Power-up calibration and dynamic calibration after every sample to compensate for temperature drift over time

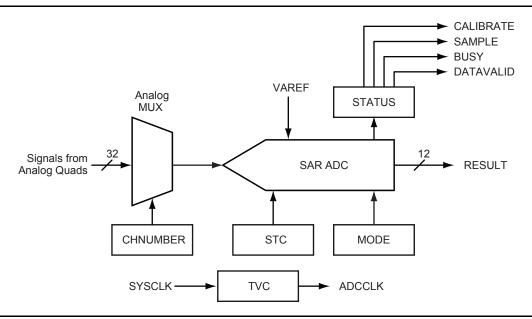


Figure 2-80 • ADC Simplified Block Diagram

# ADC Theory of Operation

An analog-to-digital converter is used to capture discrete samples of a continuous analog voltage and provide a discrete binary representation of the signal. Analog-to-digital converters are generally characterized in three ways:

- · Input voltage range
- · Resolution
- Bandwidth or conversion rate

The input voltage range of an ADC is determined by its reference voltage (VREF). Fusion devices include an internal 2.56~V reference, or the user can supply an external reference of up to 3.3~V. The following examples use the internal 2.56~V reference, so the full-scale input range of the ADC is 0~t0 to 2.56~V.

The resolution (LSB) of the ADC is a function of the number of binary bits in the converter. The ADC approximates the value of the input voltage using 2n steps, where n is the number of bits in the converter. Each step therefore represents VREF $\div$  2n volts. In the case of the Fusion ADC configured for 12-bit operation, the LSB is 2.56 V / 4096 = 0.625 mV.

Finally, bandwidth is an indication of the maximum number of conversions the ADC can perform each second. The bandwidth of an ADC is constrained by its architecture and several key performance characteristics.

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There are several popular ADC architectures, each with advantages and limitations.

The analog-to-digital converter in Fusion devices is a switched-capacitor Successive Approximation Register (SAR) ADC. It supports 8-, 10-, and 12-bit modes of operation with a cumulative sample rate up to 600 k samples per second (ksps). Built-in bandgap circuitry offers 1% internal voltage reference accuracy or an external reference voltage can be used.

As shown in Figure 2-81, a SAR ADC contains N capacitors with binary-weighted values.

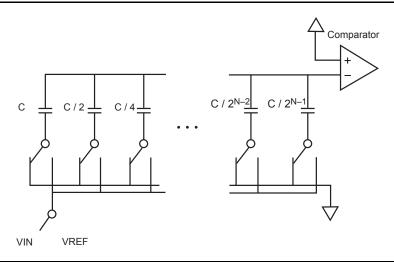


Figure 2-81 • Example SAR ADC Architecture

To begin a conversion, all of the capacitors are quickly discharged. Then VIN is applied to all the capacitors for a period of time (acquisition time) during which the capacitors are charged to a value very close to VIN. Then all of the capacitors are switched to ground, and thus –VIN is applied across the comparator. Now the conversion process begins. First, C is switched to VREF. Because of the binary weighting of the capacitors, the voltage at the input of the comparator is then shown by EQ 11.

Voltage at input of comparator = -VIN + VREF / 2

EQ 11

If VIN is greater than VREF / 2, the output of the comparator is 1; otherwise, the comparator output is 0. A register is clocked to retain this value as the MSB of the result. Next, if the MSB is 0, C is switched back to ground; otherwise, it remains connected to VREF, and C / 2 is connected to VREF. The result at the comparator input is now either -VIN + VREF / 4 or -VIN + 3 VREF / 4 (depending on the state of the MSB), and the comparator output now indicates the value of the next most significant bit. This bit is likewise registered, and the process continues for each subsequent bit until a conversion is completed. The conversion process requires some acquisition time plus N + 1 ADC clock cycles to complete.



This process results in a binary approximation of VIN. Generally, there is a fixed interval T, the sampling period, between the samples. The inverse of the sampling period is often referred to as the sampling frequency  $f_S = 1 / T$ . The combined effect is illustrated in Figure 2-82.

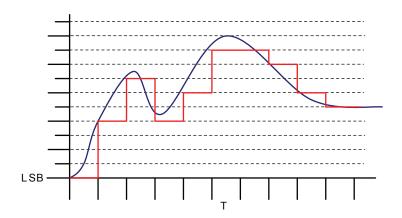


Figure 2-82 • Conversion Example

Figure 2-82 demonstrates that if the signal changes faster than the sampling rate can accommodate, or if the actual value of VIN falls between counts in the result, this information is lost during the conversion. There are several techniques that can be used to address these issues.

First, the sampling rate must be chosen to provide enough samples to adequately represent the input signal. Based on the Nyquist-Shannon Sampling Theorem, the minimum sampling rate must be at least twice the frequency of the highest frequency component in the target signal (Nyquist Frequency). For example, to recreate the frequency content of an audio signal with up to 22 KHz bandwidth, the user must sample it at a minimum of 44 ksps. However, as shown in Figure 2-82, significant post-processing of the data is required to interpolate the value of the waveform during the time between each sample.

Similarly, to re-create the amplitude variation of a signal, the signal must be sampled with adequate resolution. Continuing with the audio example, the dynamic range of the human ear (the ratio of the amplitude of the threshold of hearing to the threshold of pain) is generally accepted to be 135 dB, and the dynamic range of a typical symphony orchestra performance is around 85 dB. Most commercial recording media provide about 96 dB of dynamic range using 16-bit sample resolution. But 16-bit fidelity does not necessarily mean that you need a 16-bit ADC. As long as the input is sampled at or above the Nyquist Frequency, post-processing techniques can be used to interpolate intermediate values and reconstruct the original input signal to within desired tolerances.

If sophisticated digital signal processing (DSP) capabilities are available, the best results are obtained by implementing a reconstruction filter, which is used to interpolate many intermediate values with higher resolution than the original data. Interpolating many intermediate values increases the effective number of samples, and higher resolution increases the effective number of bits in the sample. In many cases, however, it is not cost-effective or necessary to implement such a sophisticated reconstruction algorithm. For applications that do not require extremely fine reproduction of the input signal, alternative methods can enhance digital sampling results with relatively simple post-processing. The details of such techniques are out of the scope of this chapter; refer to the *Improving ADC Results through Oversampling and Post-Processing of Data* white paper for more information.

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# **ADC Terminology**

#### **Conversion Time**

Conversion time is the interval between the release of the hold state (imposed by the input circuitry of a track-and-hold) and the instant at which the voltage on the sampling capacitor settles to within one LSB of a new input value.

#### DNL - Differential Non-Linearity

For an ideal ADC, the analog-input levels that trigger any two successive output codes should differ by one LSB (DNL = 0). Any deviation from one LSB in defined as DNL (Figure 2-83).

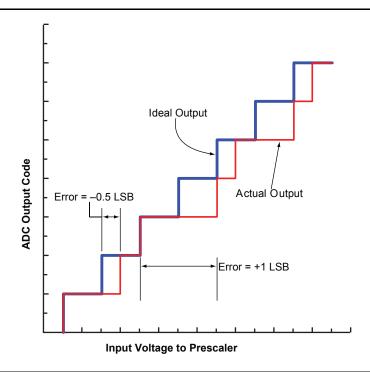


Figure 2-83 • Differential Non-Linearity (DNL)

# **ENOB – Effective Number of Bits**

ENOB specifies the dynamic performance of an ADC at a specific input frequency and sampling rate. An ideal ADC's error consists only of quantization of noise. As the input frequency increases, the overall noise (particularly in the distortion components) also increases, thereby reducing the ENOB and SINAD (also see "Signal-to-Noise and Distortion Ratio (SINAD)".) ENOB for a full-scale, sinusoidal input waveform is computed using EQ 12.

$$ENOB = \frac{SINAD - 1.76}{6.02}$$

EQ 12

# FS Error - Full-Scale Error

Full-scale error is the difference between the actual value that triggers that transition to full-scale and the ideal analog full-scale transition value. Full-scale error equals offset error plus gain error.



# Gain Error

The gain error of an ADC indicates how well the slope of an actual transfer function matches the slope of the ideal transfer function. Gain error is usually expressed in LSB or as a percent of full-scale (%FSR). Gain error is the full-scale error minus the offset error (Figure 2-84).

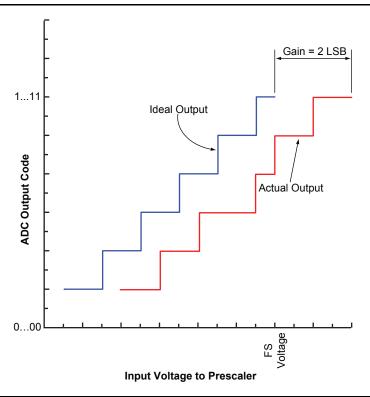


Figure 2-84 • Gain Error

# **Gain Error Drift**

Gain-error drift is the variation in gain error due to a change in ambient temperature, typically expressed in ppm/°C.

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# INL - Integral Non-Linearity

INL is the deviation of an actual transfer function from a straight line. After nullifying offset and gain errors, the straight line is either a best-fit straight line or a line drawn between the end points of the transfer function (Figure 2-85).

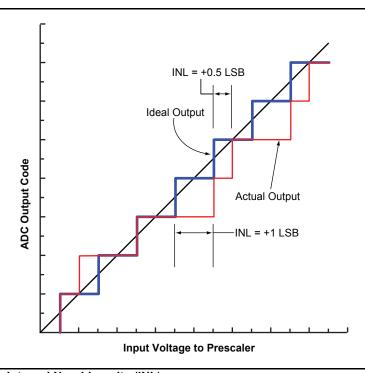


Figure 2-85 • Integral Non-Linearity (INL)

# LSB - Least Significant Bit

In a binary number, the LSB is the least weighted bit in the group. Typically, the LSB is the furthest right bit. For an ADC, the weight of an LSB equals the full-scale voltage range of the converter divided by  $2^N$ , where N is the converter's resolution.

EQ 13 shows the calculation for a 10-bit ADC with a unipolar full-scale voltage of 2.56 V:

$$1 LSB = (2.56 V / 2^{10}) = 2.5 mV$$

EQ 13

# No Missing Codes

An ADC has no missing codes if it produces all possible digital codes in response to a ramp signal applied to the analog input.



#### Offset Error

Offset error indicates how well the actual transfer function matches the ideal transfer function at a single point. For an ideal ADC, the first transition occurs at 0.5 LSB above zero. The offset voltage is measured by applying an analog input such that the ADC outputs all zeroes and increases until the first transition occurs (Figure 2-86).

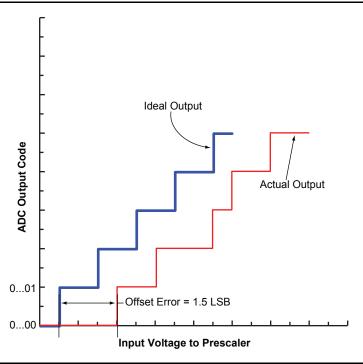


Figure 2-86 • Offset Error

#### Resolution

ADC resolution is the number of bits used to represent an analog input signal. To more accurately replicate the analog signal, resolution needs to be increased.

## Sampling Rate

Sampling rate or sample frequency, specified in samples per second (sps), is the rate at which an ADC acquires (samples) the analog input.

#### SNR - Signal-to-Noise Ratio

SNR is the ratio of the amplitude of the desired signal to the amplitude of the noise signals at a given point in time. For a waveform perfectly reconstructed from digital samples, the theoretical maximum SNR (EQ 14) is the ratio of the full-scale analog input (RMS value) to the RMS quantization error (residual error). The ideal, theoretical minimum ADC noise is caused by quantization error only and results directly from the ADC's resolution (N bits):

$$SNR_{dBIMAX1} = 6.02_{dB} \times N + 1.76_{dB}$$

EQ 14

#### SINAD - Signal-to-Noise and Distortion

SINAD is the ratio of the rms amplitude to the mean value of the root-sum-square of the all other spectral components, including harmonics, but excluding DC. SINAD is a good indication of the overall dynamic performance of an ADC because it includes all components which make up noise and distortion.

#### **Total Harmonic Distortion**

THD measures the distortion content of a signal, and is specified in decibels relative to the carrier (dBc). THD is the ratio of the RMS sum of the selected harmonics of the input signal to the fundamental itself. Only harmonics within the Nyquist limit are included in the measurement.

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## TUE - Total Unadjusted Error

TUE is a comprehensive specification that includes linearity errors, gain error, and offset error. It is the worst-case deviation from the ideal device performance. TUE is a static specification (Figure 2-87).

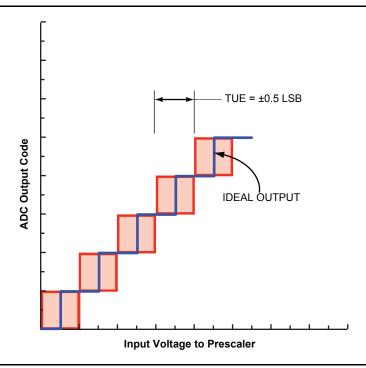


Figure 2-87 • Total Unadjusted Error (TUE)

# ADC Operation

Once the ADC has powered up and been released from reset, ADCRESET, the ADC will initiate a calibration routine designed to provide optimal ADC performance. The Fusion ADC offers a robust calibration scheme to reduce integrated offset and linearity errors. The offset and linearity errors of the main capacitor array are compensated for with an 8-bit calibration capacitor array. The offset/linearity error calibration is carried out in two ways. First, a power-up calibration is carried out when the ADC comes out of reset. This is initiated by the CALIBRATE output of the Analog Block macro and is a fixed number of ADC\_CLK cycles (3,840 cycles), as shown in Figure 2-89 on page 2-111. In this mode, the linearity and offset errors of the capacitors are calibrated.

To further compensate for drift and temperature-dependent effects, every conversion is followed by post-calibration of either the offset or a bit of the main capacitor array. The post-calibration ensures that, over time and with temperature, the ADC remains consistent.

After both calibration and the setting of the appropriate configurations, as explained above, the ADC is ready for operation. Setting the ADCSTART signal high for one clock period will initiate the sample and conversion of the analog signal on the channel as configured by CHNUMBER[4:0]. The status signals SAMPLE and BUSY will show when the ADC is sampling and converting (Figure 2-91 on page 2-112). Both SAMPLE and BUSY will initially go high. After the ADC has sampled and held the analog signal, SAMPLE will go low. After the entire operation has completed and the analog signal is converted, BUSY will go low and DATAVALID will go high. This indicates that the digital result is available on the RESULT[11:0] pins.

DATAVALID will remain high until a subsequent ADCSTART is issued. The DATAVALID goes low on the rising edge of SYSCLK as shown in Figure 2-90 on page 2-112. The RESULT signals will be kept constant until the ADC finishes the subsequent sample. The next sampled RESULT will be available when DATAVALID goes high again. It is ideal to read the RESULT when DATAVALID is '1'. The RESULT is latched and remains unchanged until the next DATAVLAID rising edge.



# **ADC Input Multiplexer**

At the input to the Fusion ADC is a 32:1 multiplexer. Of the 32 input channels, up to 30 are user definable. Two of these channels are hardwired internally. Channel 31 connects to an internal temperature diode so the temperature of the Fusion device itself can be monitored. Channel 0 is wired to the FPGA's 1.5 V VCC supply, enabling the Fusion device to monitor its own power supply. Doing this internally makes it unnecessary to use an analog I/O to support these functions. The balance of the MUX inputs are connected to Analog Quads (see the "Analog Quad" section on page 2-80). Table 2-40 defines which Analog Quad inputs are associated with which specific analog MUX channels. The number of Analog Quads present is device-dependent; refer to the family list in the "Fusion Family" table on page I of this datasheet for the number of quads per device. Regardless of the number of quads populated in a device, the internal connections to both VCC and the internal temperature diode remain on Channels 0 and 31, respectively. To sample the internal temperature monitor, it must be strobed (similar to the AT pads). The TMSTBINT pin on the Analog Block macro is the control for strobing the internal temperature measurement diode.

To determine which channel is selected for conversion, there is a five-pin interface on the Analog Block, CHNUMBER[4:0], defined in Table 2-39.

Table 2-39 • Channel Selection

Channel Number	CHNUMBER[4:0]
0	00000
1	00001
2	00010
3	00011
	·
•	·
30	11110
31	11111

Table 2-40 shows the correlation between the analog MUX input channels and the analog input pins.

#### Table 2-40 • Analog MUX Channels

Analog MUX Channel	Signal	Analog Quad Number
0	Vcc_analog	
1	AV0	
2	AC0	Analog Quad 0
3	AT0	
4	AV1	
5	AC1	Analog Quad 1
6	AT1	
7	AV2	
8	AC2	Analog Quad 2
9	AT2	
10	AV3	
11	AC3	Analog Quad 3
12	AT3	
13	AV4	
14	AC4	Analog Quad 4
15	AT4	
		1

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Table 2-40 • Analog MUX Channels (continued)

Analog MUX Channel	Signal	Analog Quad Number
16	AV5	
17	AC5	Analog Quad 5
18	AT5	
19	AV6	
20	AC6	Analog Quad 6
21	AT6	
22	AV7	
23	AC7	Analog Quad 7
24	AT7	
25	AV8	
26	AC8	Analog Quad 8
27	AT8	
28	AV9	
29	AC9	Analog Quad 9
30	AT9	
31	Internal temperature monitor	

The ADC can be powered down independently of the FPGA core, as an additional control or for power-saving considerations, via the PWRDWN pin of the Analog Block. The PWRDWN pin controls only the comparators in the ADC.

#### **ADC Modes**

The Fusion ADC can be configured to operate in 8-, 10-, or 12-bit modes, power-down after conversion, and dynamic calibration. This is controlled by MODE[3:0], as defined in Table 2-41 on page 2-106.

The output of the ADC is the RESULT[11:0] signal. In 8-bit mode, the Most Significant 8 Bits RESULT[11:4] are used as the ADC value and the Least Significant 4 Bits RESULT[3:0] are logical '0's. In 10-bit mode, RESULT[11:2] are used the ADC value and RESULT[1:0] are logical 0s.

Table 2-41 • Mode Bits Function

Name	Bits	Function
MODE	3	0 – Internal calibration after every conversion; two ADCCLK cycles are used after the conversion.  1 – No calibration after every conversion
MODE	2	0 – Power-down after conversion
		1 – No Power-down after conversion
MODE	1:0	00 – 10-bit
		01 – 12-bit
		10 – 8-bit
		11 – Unused



#### Integrated Voltage Reference

The Fusion device has an integrated on-chip 2.56 V reference voltage for the ADC. The value of this reference voltage was chosen to make the prescaling and postscaling factors for the prescaler blocks change in a binary fashion. However, if desired, an external reference voltage of up to 3.3 V can be connected between the VAREF and ADCGNDREF pins. The VAREFSEL control pin is used to select the reference voltage.

Table 2-42 • VAREF Bit Function

Name	Bit	Function
VAREF	0	Reference voltage selection
		0 – Internal voltage reference selected. VAREF pin outputs 2.56 V.
		1 – Input external voltage reference from VAREF and ADCGNDREF

#### **ADC Clock**

The speed of the ADC depends on its internal clock, ADCCLK, which is not accessible to users. The ADCCLK is derived from SYSCLK. Input signal TVC[7:0], Time Divider Control, determines the speed of the ADCCLK in relationship to SYSCLK, based on EQ 15.

$$t_{ADCCLK} = 4 \times (1 + TVC) \times t_{SYSCLK}$$

EQ 15

TVC: Time Divider Control (0-255)

 $t_{ADCCL\,K}$  is the period of ADCCLK, and must be between 0.5 MHz and 10 MHz

t<sub>SYSCLK</sub> is the period of SYSCLK

Table 2-43 • TVC Bits Function

Name	Bits	Function		
TVC	[7:0]	SYSCLK divider control		

The frequency of ADCCLK, f<sub>ADCCLK</sub>, must be within 0.5 Hz to 10 MHz.

The inputs to the ADC are synchronized to SYSCLK. A conversion is initiated by asserting the ADCSTART signal on a rising edge of SYSCLK. Figure 2-90 on page 2-112 and Figure 2-91 on page 2-112 show the timing diagram for the ADC.

# **Acquisition Time or Sample Time Control**

Acquisition time (t<sub>SAMPLE</sub>) specifies how long an analog input signal has to charge the internal capacitor array. Figure 2-88 shows a simplified internal input sampling mechanism of a SAR ADC.

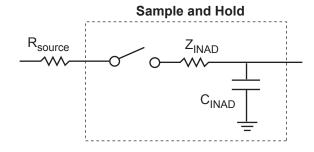


Figure 2-88 • Simplified Sample and Hold Circuitry

The internal impedance ( $Z_{INAD}$ ), external source resistance ( $R_{SOURCE}$ ), and sample capacitor ( $C_{INAD}$ ) form a simple RC network. As a result, the accuracy of the ADC can be affected if the ADC is given insufficient time to charge the capacitor. To resolve this problem, you can either reduce the source resistance or increase the sampling time by changing the acquisition time using the STC signal.

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EQ 16 through EQ 18 can be used to calculate the acquisition time required for a given input. The STC signal gives the number of sample periods in ADCCLK for the acquisition time of the desired signal. If the actual acquisition time is higher than the STC value, the settling time error can affect the accuracy of the ADC, because the sampling capacitor is only partially charged within the given sampling cycle. Example acquisition times are given in Table 2-44 and Table 2-45. When controlling the sample time for the ADC along with the use of the active bipolar prescaler, current monitor, or temperature monitor, the minimum sample time(s) for each must be obeyed. EQ 19 can be used to determine the appropriate value of STC.

$$VOUT = VIN(1 - e^{-t/RC})$$

EQ 16

For 0.5 LSB gain error, VOUT should be replaced with (VIN –(0.5 × LSB Value)):

You can calculate the minimum actual acquisition time by using EQ 16:

$$(VIN - 0.5 \times LSB \ Value) = VIN(1 - e^{-t/RC})$$

EQ 17

where VIN is the ADC reference voltage (VREF)

Solving EQ 17:

$$t = RC \times In (VIN / (0.5 \times LSB \ Value))$$

EQ 18

where  $R = Z_{INAD} + R_{SOURCE}$  and  $C = C_{INAD}$ .

Calculate the value of STC by using EQ 19.

EQ 19

where ADCCLK = ADC clock frequency in MHz.

 $t_{SAMPLE}$  = 0.449 µs from bit resolution in Table 2-44.

ADC Clock frequency = 10 MHz or a 100 ns period.

STC =  $(t_{SAMPLE} / (1 / 10 \text{ MHz})) - 2 = 4.49 - 2 = 2.49.$ 

You must round up to 3 to accommodate the minimum sample time.

Table 2-44 • Acquisition Time Example with VAREF = 2.56 V

VIN = 2.56V, R = 4K (R <sub>SOURCE</sub> ~ 0), C = 18 pF			
Resolution LSB Value (mV) Min. Sample/Hold Time for 0.5 LSB (μs)			
8	10	0.449	
10	2.5	0.549	
12	0.625	0.649	

Table 2-45 • Acquisition Time Example with VAREF = 3.3 V

VIN = 3.3V, R = 4K (R <sub>SOURCE</sub> ~ 0), C = 18 pF			
Resolution LSB Value (mV) Min. Sample/Hold time for 0.5 LSB (μs)			
8	12.891	0.449	
10	3.223	0.549	
12	0.806	0.649	

### Sample Phase

A conversion is performed in three phases. In the first phase, the analog input voltage is sampled on the input capacitor. This phase is called sample phase. During the sample phase, the output signals BUSY and SAMPLE change from '0' to '1', indicating the ADC is busy and sampling the analog signal. The sample time can be controlled by input signals STC[7:0]. The sample time can be calculated by EQ 20. When controlling the sample time for the ADC along with the use of Prescaler or Current Monitor or Temperature Monitor, the minimum sample time for each must be obeyed.



Refer to Table 2-46 on page 2-109 and the "Acquisition Time or Sample Time Control" section on page 2-107

$$t_{\text{sample}} = (2 + STC) \times t_{\text{ADCCLK}}$$

EQ 20

STC: Sample Time Control value (0-255)

t<sub>SAMPLE</sub> is the sample time

# Table 2-46 • STC Bits Function

Name	Bits	Function
STC	[7:0]	Sample time control

Sample time is computed based on the period of ADCCLK.

#### **Distribution Phase**

The second phase is called the distribution phase. During distribution phase, the ADC computes the equivalent digital value from the value stored in the input capacitor. In this phase, the output signal SAMPLE goes back to '0', indicating the sample is completed; but the BUSY signal remains '1', indicating the ADC is still busy for distribution. The distribution time depends strictly on the number of bits. If the ADC is configured as a 10-bit ADC, then 10 ADCCLK cycles are needed. EQ 8 describes the distribution time.

$$t_{distrib} = N \times t_{ADCCLK}$$

EQ 21

N: Number of bits

#### Post-Calibration Phase

The last phase is the post-calibration phase. This is an optional phase. The post-calibration phase takes two ADCCLK cycles. The output BUSY signal will remain '1' until the post-calibration phase is completed. If the post-calibration phase is skipped, then the BUSY signal goes to '0' after distribution phase. As soon as BUSY signal goes to '0', the DATAVALID signal goes to '1', indicating the digital result is available on the RESULT output signals. DATAVAILD will remain '1' until the next ADCSTART is asserted. Microsemi recommends enabling post-calibration to compensate for drift and temperature-dependent effects. This ensures that the ADC remains consistent over time and with temperature. The post-calibration phase is enabled by bit 3 of the Mode register. EQ 9 describes the post-calibration time.

$$t_{post-cal} = MODE[3] \times (2 \times t_{ADCCLK})$$

EQ 22

MODE[3]: Bit 3 of the Mode register, described in Table 2-41 on page 2-106.

The calculation for the conversion time for the ADC is summarized in EQ 23.

EQ 23

t<sub>conv</sub>: conversion time

 $t_{sync\_read}$ : maximum time for a signal to synchronize with SYSCLK. For calculation purposes, the worst case is a period of SYSCLK,  $t_{SYSCLK}$ .

t<sub>sample</sub>: Sample time

t<sub>distrib</sub>: Distribution time

t<sub>post-cal</sub>: Post-calibration time

 $t_{sync\_write}$ : Maximum time for a signal to synchronize with SYSCLK. For calculation purposes, the worst case is a period of SYSCLK,  $t_{SYSCLK}$ .

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#### Intra-Conversion

Performing a conversion during power-up calibration is possible but should be avoided, since the performance is not guaranteed, as shown in Table 2-49 on page 2-117. This is described as intra-conversion. Figure 2-92 on page 2-113 shows intra-conversion, (conversion that starts during power-up calibration).

#### Injected Conversion

A conversion can be interrupted by another conversion. Before the current conversion is finished, a second conversion can be started by issuing a pulse on signal ADCSTART. When a second conversion is issued before the current conversion is completed, the current conversion would be dropped and the ADC would start the second conversion on the rising edge of the SYSCLK. This is known as injected conversion. Since the ADC is synchronous, the minimum time to issue a second conversion is two clock cycles of SYSCLK after the previous one. Figure 2-93 on page 2-113 shows injected conversion, (conversion that starts before a previously started conversion is finished). The total time for calibration still remains 3,840 ADCCLK cycles.

# ADC Example

This example shows how to choose the correct settings to achieve the fastest sample time in 10-bit mode for a system that runs at 66 MHz. Assume the acquisition times defined in Table 2-44 on page 2-108 for 10-bit mode, which gives  $0.549 \mu s$  as a minimum hold time.

The period of SYSCLK:  $t_{SYSCLK}$  = 1/66 MHz = 0.015  $\mu s$ 

Choosing TVC between 1 and 33 will meet the maximum and minimum period for the ADCCLK requirement. A higher TVC leads to a higher ADCCLK period.

The minimum TVC is chosen so that  $t_{distrib}$  and  $t_{post-cal}$  can be run faster. The period of ADCCLK with a TVC of 1 can be computed by EQ 24.

$$t_{ADCCLK} = 4 \times (1 + TVC) \times t_{SYSCLK} = 4 \times (1 + 1) \times 0.015 \ \mu s = 0.12 \ \mu s$$

EQ 24

The STC value can now be computed by using the minimum sample/hold time from Table 2-44 on page 2-108, as shown in EQ 25.

STC = 
$$\frac{t_{sample}}{t_{ADCCLK}} - 2 = \frac{0.549 \,\mu s}{0.12 \,\mu s} - 2 = 4.575 - 2 = 2.575$$

EQ 25

You must round up to 3 to accommodate the minimum sample time requirement. The actual sample time,  $t_{\text{sample}}$ , with an STC of 3, is now equal to 0.6  $\mu$ s, as shown in EQ 26

$$t_{sample} = (2 + STC) \times t_{ADCCLK} = (2 + 3) \times t_{ADCCLK} = 5 \times 0.12 \ \mu s = 0.6 \ \mu s$$

EQ 26

Microsemi recommends post-calibration for temperature drift over time, so post-calibration is enabled.

The post-calibration time,  $t_{\text{post-cal}}$ , can be computed by EQ 27. The post-calibration time is 0.24  $\mu s$ .

$$t_{post-cal} = 2 \times t_{ADCCLK} = 0.24 \mu s$$

EQ 27

The distribution time,  $t_{distrib}$ , is equal to 1.2  $\mu$ s and can be computed as shown in EQ 28 (N is number of bits, referring back to EQ 8 on page 2-94).

$$t_{distrib} = N \times t_{ADCCLK} = 10 \times 0.12 = 1.2 \mu s$$

EQ 28

The total conversion time can now be summated, as shown in EQ 29 (referring to EQ 23 on page 2-109).

$$t_{sync}$$
 read +  $t_{sample}$  +  $t_{distrib}$  +  $t_{post-cal}$  +  $t_{sync}$  write = (0.015 + 0.60 + 1.2 + 0.24 + 0.015)  $\mu s$  = 2.07  $\mu s$ 

EQ 29



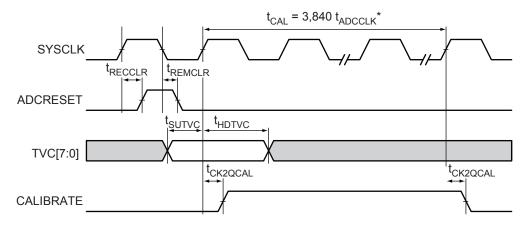
The optimal setting for the system running at 66 MHz with an ADC for 10-bit mode chosen is shown in Table 2-47:

Table 2-47 • Optimal Setting at 66 MHz in 10-Bit Mode

TVC[7:0]	= 1	= 0x01
STC[7:0]	= 3	= 0x03
MODE[3:0]	= b'0100	= 0x4*

*Note:* No power-down after every conversion is chosen in this case; however, if the application is power-sensitive, the MODE[2] can be set to '0', as described above, and it will not affect any performance.

# **Timing Diagrams**



Note: \*Refer to EQ 15 on page 2-107 for the calculation on the period of ADCCLK, t<sub>ADCCLK</sub>.

Figure 2-89 • Power-Up Calibration Status Signal Timing Diagram

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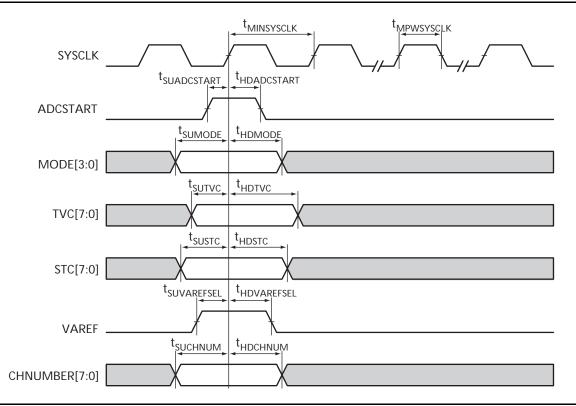
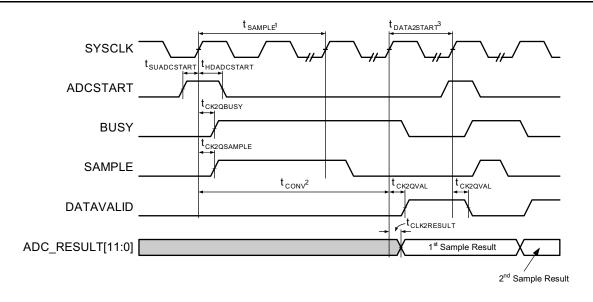


Figure 2-90 • Input Setup Time

## Standard Conversion



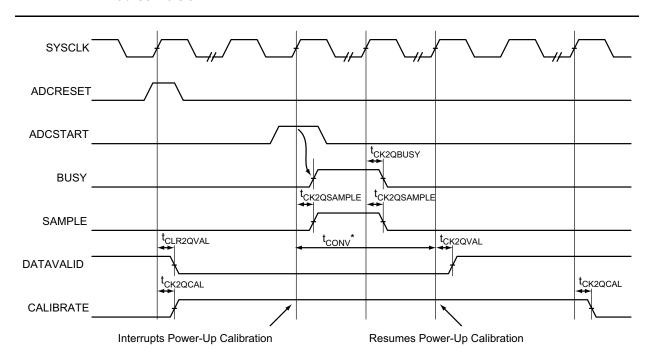
#### Notes:

- 1. Refer to EQ 20 on page 2-109 for the calculation on the sample time,  $t_{\sf SAMPLE}$ .
- 2. See EQ 23 on page 2-109 for calculation of the conversion time,  $t_{CONV}$ .
- 3. Minimum time to issue an ADCSTART after DATAVALID is 1 SYSCLK period

Figure 2-91 • Standard Conversion Status Signal Timing Diagram



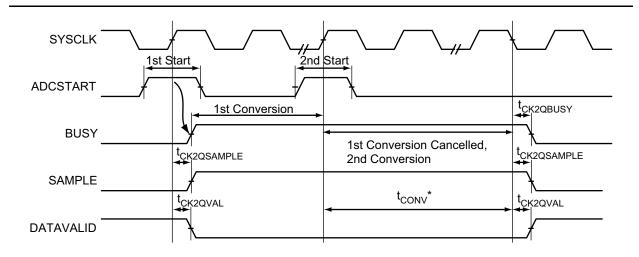
#### Intra-Conversion



Note:  $^*t_{CONV}$  represents the conversion time of the second conversion. See EQ 23 on page 2-109 for calculation of the conversion time,  $t_{CONV}$ .

Figure 2-92 • Intra-Conversion Timing Diagram

# Injected Conversion



Note: \*See EQ 23 on page 2-109 for calculation on the conversion time,  $t_{CONV}$ .

Figure 2-93 • Injected Conversion Timing Diagram



# **ADC Interface Timing**

Table 2-48 • ADC Interface Timing
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>SUMODE</sub>	Mode Pin Setup Time	0.56	0.64	0.75	ns
t <sub>HDMODE</sub>	Mode Pin Hold Time	0.26	0.29	0.34	ns
t <sub>SUTVC</sub>	Clock Divide Control (TVC) Setup Time	0.68	0.77	0.90	ns
t <sub>HDTVC</sub>	Clock Divide Control (TVC) Hold Time	0.32	0.36	0.43	ns
t <sub>sustc</sub>	Sample Time Control (STC) Setup Time	1.58	1.79	2.11	ns
t <sub>HDSTC</sub>	Sample Time Control (STC) Hold Time	1.27	1.45	1.71	ns
t <sub>SUVAREFSEL</sub>	Voltage Reference Select (VAREFSEL) Setup Time	0.00	0.00	0.00	ns
t <sub>HDVAREFSEL</sub>	Voltage Reference Select (VAREFSEL) Hold Time	0.67	0.76	0.89	ns
tsuchnum	Channel Select (CHNUMBER) Setup Time	0.90	1.03	1.21	ns
t <sub>HDCHNUM</sub>	Channel Select (CHNUMBER) Hold Time	0.00	0.00	0.00	ns
t <sub>SUADCSTART</sub>	Start of Conversion (ADCSTART) Setup Time	0.75	0.85	1.00	ns
t <sub>HDADCSTART</sub>	Start of Conversion (ADCSTART) Hold Time	0.43	0.49	0.57	ns
t <sub>CK2QBUSY</sub>	Busy Clock-to-Q	1.33	1.51	1.78	ns
t <sub>CK2QCAL</sub>	Power-Up Calibration Clock-to-Q	0.63	0.71	0.84	ns
t <sub>CK2QVAL</sub>	Valid Conversion Result Clock-to-Q	3.12	3.55	4.17	ns
t <sub>CK2QSAMPLE</sub>	Sample Clock-to-Q	0.22	0.25	0.30	ns
t <sub>CK2QRESULT</sub>	Conversion Result Clock-to-Q	2.53	2.89	3.39	ns
t <sub>CLR2QBUSY</sub>	Busy Clear-to-Q	2.06	2.35	2.76	ns
t <sub>CLR2QCAL</sub>	Power-Up Calibration Clear-to-Q	2.15	2.45	2.88	ns
t <sub>CLR2QVAL</sub>	Valid Conversion Result Clear-to-Q	2.41	2.74	3.22	ns
t <sub>CLR2QSAMPLE</sub>	Sample Clear-to-Q	2.17	2.48	2.91	ns
t <sub>CLR2QRESULT</sub>	Conversion result Clear-to-Q	2.25	2.56	3.01	ns
t <sub>RECCLR</sub>	Recovery Time of Clear	0.00	0.00	0.00	ns
t <sub>REMCLR</sub>	Removal Time of Clear	0.63	0.72	0.84	ns
t <sub>MPWSYSCLK</sub>	Clock Minimum Pulse Width for the ADC	4.00	4.00	4.00	ns
t <sub>FMAXSYSCLK</sub>	Clock Maximum Frequency for the ADC	100.00	100.00	100.00	MHz



# **Typical Performance Characteristics**

# Temperature Errror vs. Die Temperature

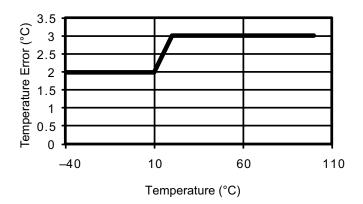


Figure 2-94 • Temperature Error

# Temperature Error vs. Interconnect Capacitance

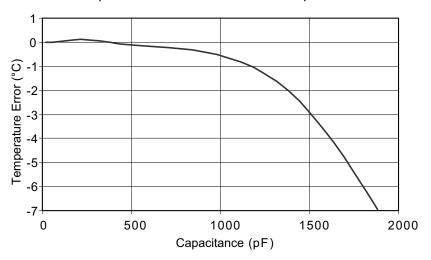


Figure 2-95 • Effect of External Sensor Capacitance

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# Temperature Reading Noise RMS vs. Averaging

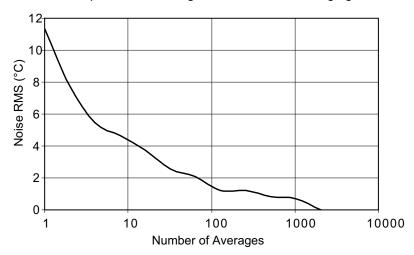


Figure 2-96 • Temperature Reading Noise When Averaging is Used



# **Analog System Characteristics**

Table 2-49 • Analog Channel Specifications

Commercial Temperature Range Conditions,  $T_J$  = 85°C (unless noted otherwise), Typical: VCC33A = 3.3 V, VCC = 1.5 V

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Voltage Monit	tor Using Analog Pads AV,	AC and AT (using prescaler)			•	
	Input Voltage (Prescaler)	Refer to Table 3-2 on page 3-3				
VINAP	Uncalibrated Gain and Offset Errors	Refer to Table 2-51 on page 2-122				
	Calibrated Gain and Offset Errors	Refer to Table 2-52 on page 2-123				
	Bandwidth1				100	KHz
	Input Resistance	Refer to Table 3-3 on page 3-4				
	Scaling Factor	Prescaler modes (Table 2-57 on page 2-130)				
	Sample Time		10			μs
Current Moni	tor Using Analog Pads AV	and AC				
VRSM <sup>1</sup>	Maximum Differential Input Voltage				VAREF / 10	mV
	Resolution	Refer to "Current Monitor" section				
	Common Mode Range				- 10.5 to +12	V
CMRR	Common Mode Rejection Ratio	DC – 1 KHz		60		dB
		1 KHz - 10 KHz		50		dB
		> 10 KHz		30		dB
t <sub>CMSHI</sub>	Strobe High time		ADC conv. time		200	μs
t <sub>CMSHI</sub>	Strobe Low time		5			μs
t <sub>CMSHI</sub>	Settling time		0.02			μs
	Accuracy	Input differential voltage > 50 mV			-2 -(0.05 x VRSM) to +2 + (0.05 x VRSM)	mV

#### Notes:

- 1. VRSM is the maximum voltage drop across the current sense resistor.
- 2. Analog inputs used as digital inputs can tolerate the same voltage limits as the corresponding analog pad. There is no reliability concern on digital inputs as long as VIND does not exceed these limits.
- 3. VIND is limited to VCC33A + 0.2 to allow reaching 10 MHz input frequency.
- 4. An averaging of 1,024 samples (LPF setting in Analog System Builder) is required and the maximum capacitance allowed across the AT pins is 500 pF.
- 5. The temperature offset is a fixed positive value.
- 6. The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.
- 7. When using SmartGen Analog System Builder, CalibIP is required to obtain specified offset. For further details on CalibIP, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.

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Table 2-49 • Analog Channel Specifications (continued)

Commercial Temperature Range Conditions,  $T_J$  = 85°C (unless noted otherwise), Typical: VCC33A = 3.3 V, VCC = 1.5 V

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Temperature Mo	onitor Using Analog Pad	AT		I.	l	<u> </u>
External	Resolution	8-bit ADC		4		
Temperature Monitor		10-bit ADC			1	°C
(external diode		12-bit ADC		C	).25	°C
2N3904, T <sub>J</sub> = 25°C) <sup>4</sup>	Systematic Offset <sup>5</sup>	AFS090, AFS250, AFS600, AFS1500, uncalibrated <sup>7</sup>			5	°C
		AFS090, AFS250, AFS600, AFS1500, calibrated <sup>7</sup>			±5	°C
	Accuracy			±3	±5	°C
	External Sensor Source Current	High level, TMSTBx = 0		10		μA
		Low level, TMSTBx = 1		100		μA
	Max Capacitance on AT pad				1.3	nF
Internal	Resolution	8-bit ADC	4			°C
Temperature Monitor		10-bit ADC	1			°C
Wioriitoi		12-bit ADC	0.25			°C
	Systematic Offset <sup>5</sup>	AFS090 <sup>7</sup>			5	°C
		AFS250, AFS600, AFS1500 <sup>7</sup>			11	°C
	Accuracy			±3	±5	°C
t <sub>TMSHI</sub>	Strobe High time		10		105	μs
t <sub>TMSLO</sub>	Strobe Low time		5			μs
t <sub>TMSSET</sub>	Settling time		5			μs

#### Notes:

- 1. VRSM is the maximum voltage drop across the current sense resistor.
- 2. Analog inputs used as digital inputs can tolerate the same voltage limits as the corresponding analog pad. There is no reliability concern on digital inputs as long as VIND does not exceed these limits.
- 3. VIND is limited to VCC33A + 0.2 to allow reaching 10 MHz input frequency.
- 4. An averaging of 1,024 samples (LPF setting in Analog System Builder) is required and the maximum capacitance allowed across the AT pins is 500 pF.
- 5. The temperature offset is a fixed positive value.
- 6. The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.
- 7. When using SmartGen Analog System Builder, CalibIP is required to obtain specified offset. For further details on CalibIP, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.



Table 2-49 • Analog Channel Specifications (continued)

Commercial Temperature Range Conditions,  $T_J$  = 85°C (unless noted otherwise), Typical: VCC33A = 3.3 V, VCC = 1.5 V

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Digital Input usi	ng Analog Pads AV, AC a	and AT	1			•
VIND <sup>2,3</sup>	Input Voltage	Refer to Table 3-2 on page 3-3				
VHYSDIN	Hysteresis			0.3		V
VIHDIN	Input High			1.2		V
VILDIN	Input Low			0.9		V
VMPWDIN	Minimum Pulse With		50			ns
F <sub>DIN</sub>	Maximum Frequency				10	MHz
ISTBDIN	Input Leakage Current			2		μA
IDYNDIN	Dynamic Current			20		μA
t <sub>INDIN</sub>	Input Delay			10		ns
Gate Driver Out	put Using Analog Pad A	3				
VG	Voltage Range	Refer to Table 3-2 on page 3-3				
IG	Output Current Drive	High Current Mode <sup>6</sup> at 1.0 V			±20	mA
		Low Current Mode: ±1 µA	0.8	1.0	1.3	μA
		Low Current Mode: ±3 μA	2.0	2.7	3.3	μA
		Low Current Mode: ± 10 μA	7.4	9.0	11.5	μA
		Low Current Mode: ± 30 μA	21.0	27.0	32.0	μA
IOFFG	Maximum Off Current				100	nA
F <sub>G</sub>	Maximum switching rate	High Current Mode <sup>6</sup> at 1.0 V, 1 $k\Omega$ resistive load		1.3		MHz
		Low Current Mode: ±1 μA, 3 MΩ resistive load		3		KHz
		Low Current Mode: ±3 μA, 1 MΩ resistive load		7		KHz
		Low Current Mode: ±10 μA, 300 kΩ resistive load		25		KHz
		Low Current Mode: ±30 μA, 105 kΩ resistive load		78		KHz

#### Notes:

- 1. VRSM is the maximum voltage drop across the current sense resistor.
- 2. Analog inputs used as digital inputs can tolerate the same voltage limits as the corresponding analog pad. There is no reliability concern on digital inputs as long as VIND does not exceed these limits.
- 3. VIND is limited to VCC33A + 0.2 to allow reaching 10 MHz input frequency.
- 4. An averaging of 1,024 samples (LPF setting in Analog System Builder) is required and the maximum capacitance allowed across the AT pins is 500 pF.
- 5. The temperature offset is a fixed positive value.
- 6. The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.
- 7. When using SmartGen Analog System Builder, CalibIP is required to obtain specified offset. For further details on CalibIP, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.

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Table 2-50 • ADC Characteristics in Direct Input Mode
Commercial Temperature Range Conditions, T<sub>J</sub> = 85°C (unless noted otherwise),
Typical: VCC33A = 3.3 V, VCC = 1.5 V

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Direct Input	t using Analog Pad AV, AC, A	Ī		•		
VINADC	Input Voltage (Direct Input)	Refer to Table 3-2 on page 3-3				
CINADC	Input Capacitance	Channel not selected		7		pF
		Channel selected but not sampling		8		pF
		Channel selected and sampling		18		pF
ZINADC	Input Impedance	8-bit mode		2		kΩ
		10-bit mode		2		kΩ
		12-bit mode		2		kΩ
Analog Ref	erence Voltage VAREF		•			
VAREF	Accuracy	T <sub>J</sub> = 25°C	2.537	2.56	2.583	V
	Temperature Drift of Internal Reference			65		ppm / °C
	External Reference		2.527		VCC33A + 0.05	V
ADC Accura	acy (using external reference	) 1,2	I		ı	
DC Accurac	су					
TUE	Total Unadjusted Error	8-bit mode	0.29			LSB
		10-bit mode		0.7	72	LSB
		12-bit mode		1.	8	LSB
INL	Integral Non-Linearity	8-bit mode		0.20	0.25	LSB
		10-bit mode		0.32	0.43	LSB
		12-bit mode		1.71	1.80	LSB
DNL	Differential Non-Linearity (no missing code)	8-bit mode		0.20	0.24	LSB
		10-bit mode		0.60	0.65	LSB
		12-bit mode		2.40	2.48	LSB
	Offset Error	8-bit mode		0.01	0.17	LSB
		10-bit mode		0.05	0.20	LSB
		12-bit mode		0.20	0.40	LSB
	Gain Error	8-bit mode		0.0004	0.003	LSB
	1	10-bit mode		0.002	0.011	LSB
		12-bit mode		0.007	0.044	LSB
	Gain Error (with internal reference)	All modes		2		% FSR

#### Notes:

- 1. Accuracy of the external reference is 2.56 V  $\pm$  4.6 mV.
- 2. Data is based on characterization.
- 3. The sample rate is time-shared among active analog inputs.



Table 2-50 • ADC Characteristics in Direct Input Mode (continued)

Commercial Temperature Range Conditions, T<sub>J</sub> = 85°C (unless noted otherwise),

Typical: VCC33A = 3.3 V, VCC = 1.5 V

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Dynamic Po	erformance					
SNR	Signal-to-Noise Ratio	8-bit mode	48.0	49.5		dB
		10-bit mode	58.0	60.0		dB
		12-bit mode	62.9	64.5		dB
SINAD	Signal-to-Noise Distortion	8-bit mode	47.6	49.5		dB
		10-bit mode	57.4	59.8		dB
		12-bit mode	62.0	64.2		dB
THD	Total Harmonic Distortion	8-bit mode		-74.4	-63.0	dBc
		10-bit mode		-78.3	-63.0	dBc
		12-bit mode		-77.9	-64.4	dBc
ENOB	Effective Number of Bits	8-bit mode	7.6	7.9		bits
		10-bit mode	9.5	9.6		bits
		12-bit mode	10.0	10.4		bits
Conversion	Rate					
	Conversion Time	8-bit mode	1.7			μs
		10-bit mode	1.8			μs
		12-bit mode	2			μs
	Sample Rate	8-bit mode			600	Ksps
		10-bit mode			550	Ksps
		12-bit mode			500	Ksps

# Notes:

- 1. Accuracy of the external reference is 2.56 V  $\pm$  4.6 mV.
- 2. Data is based on characterization.
- 3. The sample rate is time-shared among active analog inputs.

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Table 2-51 • Uncalibrated Analog Channel Accuracy\*
Worst-Case Industrial Conditions, T<sub>J</sub> = 85°C

			al Char ror (LS			el Inpu rror (LS	t Offset SB)		nel Input Error (mV		Chan	nel Gaiı (%FSR	
Analog Pad	Prescaler Range (V)	Neg. Max.	Med.	Pos. Max.	Neg Max	Med.	Pos. Max.	Neg. Max.	Med.	Pos. Max.	Min.	Тур.	Max.
Positi	ve Range						ADC in	10-Bit M	lode				
AV, AC	16	-22	-2	12	-11	-2	14	-169	-32	224	3	0	-3
	8	-40	<b>–</b> 5	17	-11	<b>-</b> 5	21	-87	-40	166	2	0	-4
	4	-45	-9	24	-16	-11	36	-63	-43	144	2	0	-4
	2	-70	-19	33	-33	-20	66	-66	-39	131	2	0	-4
	1	-25	<b>-</b> 7	5	-11	-3	26	-11	-3	26	3	-1	-3
	0.5	-41	-12	8	-12	<b>-</b> 7	38	-6	-4	19	3	-1	-3
	0.25	-53	-14	19	-20	-14	40	-5	-3	10	5	0	-4
	0.125	-89	-29	24	-40	-28	88	-5	-4	11	7	0	<b>-</b> 5
AT	16	-3	9	15	-4	0	4	-64	5	64	1	0	-1
	4	-10	2	15	-11	-2	11	-44	-8	44	1	0	-1
Negati	ve Range						ADC in	10-Bit N	lode				
AV, AC	16	-35	-10	9	-24	-6	9	-383	-96	148	5	-1	-6
	8	-65	-19	12	-34	-12	9	-268	-99	75	5	<b>–</b> 1	<b>-</b> 5
	4	-86	-28	21	-64	-24	19	-254	-96	76	5	-1	-6
	2	-136	-53	37	-115	-42	39	-230	-83	78	6	-2	<b>-</b> 7
	1	-98	-35	8	-39	-8	15	-39	-8	15	10	-3	-10
	0.5	-121	-46	7	-54	-14	18	-27	<b>-</b> 7	9	10	-4	-11
	0.25	-149	<b>–49</b>	19	-72	-16	40	-18	-4	10	14	-4	-12
	0.125	-188	-67	38	-112	-27	56	-14	-3	7	16	<b>-</b> 5	-14

Note: \*Channel Accuracy includes prescaler and ADC accuracies. For 12-bit mode, multiply the LSB count by 4. For 8-bit mode, divide the LSB count by 4. Gain remains the same.



Table 2-52 • Calibrated Analog Channel Accuracy <sup>1,2,3</sup>
Worst-Case Industrial Conditions, T<sub>J</sub> = 85°C

		Condition	Total Channel Error (LSB)				
Analog Pad	Prescaler Range (V)	Input Voltage <sup>4</sup> (V)	Negative Max.	Median	Positive Max.		
	Positive Range		Al	DC in 10-Bit Mo	ode		
AV, AC	16	0.300 to 12.0	-6	1	6		
	8	0.250 to 8.00	-6	0	6		
	4	0.200 to 4.00	-7	-1	7		
	2	0.150 to 2.00	-7	0	7		
	1	0.050 to 1.00	-6	-1	6		
AT	16	0.300 to 16.0	-5	0	5		
	4	0.100 to 4.00	<b>-7</b>	-1	7		
ı	Negative Range		Al	DC in 10-Bit Mo	ode		
AV, AC	16	-0.400 to -10.5	-7	1	9		
	8	-0.350 to -8.00	-7	-1	7		
	4	-0.300 to -4.00	-7	-2	9		
	2	-0.250 to -2.00	-7	-2	7		
	1	−0.050 to −1.00	-16	-1	20		

#### Notes:

- 1. Channel Accuracy includes prescaler and ADC accuracies. For 12-bit mode, multiply the LSB count by 4. For 8-bit mode, divide the LSB count by 4. Overall accuracy remains the same.
- 2. Requires enabling Analog Calibration using SmartGen Analog System Builder. For further details, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.
- 3. Calibrated with two-point calibration methodology, using 20% and 80% full-scale points.
- 4. The lower limit of the input voltage is determined by the prescaler input offset.

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Table 2-53 • Analog Channel Accuracy: Monitoring Standard Positive Voltages
Typical Conditions, T<sub>A</sub> = 25°C

	Calik	Direct ADC <sup>2,3</sup> (%FSR)						
Input Voltage (V)	16 V (AT)	16 V (12 V) (AV/AC)	8 V (AV/AC)	4 V (AT)	4 V (AV/AC)	2 V (AV/AC)	1 V (AV/AC)	VAREF = 2.56 V
15	1							
14	1							
12	1	1						
5	2	2	1					
3.3	2	2	1	1	1			
2.5	3	2	1	1	1			1
1.8	4	4	1	1	1	1		1
1.5	5	5	2	2	2	1		1
1.2	7	6	2	2	2	1		1
0.9	9	9	4	3	3	1	1	1

#### Notes:

- 1. Requires enabling Analog Calibration using SmartGen Analog System Builder. For further details, refer to the "Temperature, Voltage, and Current Calibration in Fusion FPGAs" chapter of the Fusion FPGA Fabric User Guide.
- 2. Direct ADC mode using an external VAREF of 2.56V±4.6mV, without Analog Calibration macro.
- 3. For input greater than 2.56 V, the ADC output will saturate. A higher VAREF or prescaler usage is recommended.

# Examples

#### Calculating Accuracy for an Uncalibrated Analog Channel

#### Formula

For a given prescaler range, EQ 30 gives the output voltage.

Output Voltage = (Channel Output Offset in V) + (Input Voltage x Channel Gain)

EQ 30

## where

Channel Output offset in V = Channel Input offset in LSBs x Equivalent voltage per LSB Channel Gain Factor = 1+ (% Channel Gain / 100)

#### Example

Input Voltage = 5 V

Chosen Prescaler range = 8 V range

Refer to Table 2-51 on page 2-122.

Max. Output Voltage = (Max Positive input offset) + (Input Voltage x Max Positive Channel Gain)

Max. Positive input offset = (21 LSB) x (8 mV per LSB in 10-bit mode)

Max. Positive input offset = 166 mV

Max. Positive Gain Error = +3%

Max. Positive Channel Gain = 1 + (+3% / 100)

Max. Positive Channel Gain = 1.03

Max. Output Voltage =  $(166 \text{ mV}) + (5 \text{ V} \times 1.03)$ 

Max. Output Voltage = 5.316 V



Similarly,

Min. Output Voltage = (Max. Negative input offset) + (Input Voltage x Max. Negative Channel Gain) =  $(-88 \text{ mV}) + (5 \text{ V} \times 0.96) = 4.712 \text{ V}$ 

# Calculating Accuracy for a Calibrated Analog Channel

#### Formula

For a given prescaler range, EQ 31 gives the output voltage.

Output Voltage = Channel Error in V + Input Voltage

EQ 31

#### where

Channel Error in V = Total Channel Error in LSBs x Equivalent voltage per LSB

#### Example

Input Voltage = 5 V

Chosen Prescaler range = 8 V range

Refer to Table 2-52 on page 2-123.

Max. Output Voltage = Max. Positive Channel Error in V + Input Voltage

Max. Positive Channel Error in V = (6 LSB) × (8 mV per LSB in 10-bit mode) = 48 mV

Max. Output Voltage = 48 mV + 5 V = **5.048 V** 

Similarly,

Min. Output Voltage = Max. Negative Channel Error in V + Input Voltage = (-48 mV) + 5 V = 4.952 V

# Calculating LSBs from a Given Error Budget

# Formula

For a given prescaler range,

LSB count = ± (Input Voltage × Required% error) / (Equivalent voltage per LSB)

#### Example

Input Voltage = 3.3 V

Required error margin= 1%

Refer to Table 2-52 on page 2-123.

Equivalent voltage per LSB = 16 mV for a 16V prescaler, with ADC in 10-bit mode

LSB Count =  $\pm (5.0 \text{ V} \times 1\%) / (0.016)$ 

LSB Count = ± 3.125

Equivalent voltage per LSB = 8 mV for an 8 V prescaler, with ADC in 10-bit mode

LSB Count =  $\pm (5.0 \text{ V} \times 1\%) / (0.008)$ 

LSB Count = ± 6.25

The 8 V prescaler satisfies the calculated LSB count accuracy requirement (see Table 2-52 on page 2-123).

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# **Analog Configuration MUX**

The ACM is the interface between the FPGA, the Analog Block configurations, and the real-time counter. Microsemi Libero SoC will generate IP that will load and configure the Analog Block via the ACM. However, users are not limited to using the Libero SoC IP. This section provides a detailed description of the ACM's register map, truth tables for proper configuration of the Analog Block and RTC, as well as timing waveforms so users can access and control the ACM directly from their designs.

The Analog Block contains four 8-bit latches per Analog Quad that are initialized through the ACM. These latches act as configuration bits for Analog Quads. The ACM block runs from the core voltage supply (1.5 V).

Access to the ACM is achieved via 8-bit address and data busses with enables. The pin list is provided in Table 2-36 on page 2-78. The ACM clock speed is limited to a maximum of 10 MHz, more than sufficient to handle the low-bandwidth requirements of configuring the Analog Block and the RTC (sub-block of the Analog Block).

Table 2-54 decodes the ACM address space and maps it to the corresponding Analog Quad and configuration byte for that quad.

Table 2-54 • ACM Address Decode Table for Analog Quad

ACMADDR [7:0] in Decimal	Name	Description	Associated Peripheral
0	-	-	Analog Quad
1	AQ0	Byte 0	Analog Quad
2	AQ0	Byte 1	Analog Quad
3	AQ0	Byte 2	Analog Quad
4	AQ0	Byte 3	Analog Quad
5	AQ1	Byte 0	Analog Quad
			Analog Quad
36	AQ8	Byte 3	Analog Quad
37	AQ9	Byte 0	Analog Quad
38	AQ9	Byte 1	Analog Quad
39	AQ9	Byte 2	Analog Quad
40	AQ9	Byte 3	Analog Quad
41		Undefined	Analog Quad
		Undefined	Analog Quad
63		Undefined	RTC
64	COUNTER0	Counter bits 7:0	RTC
65	COUNTER1	Counter bits 15:8	RTC
66	COUNTER2	Counter bits 23:16	RTC
67	COUNTER3	Counter bits 31:24	RTC
68	COUNTER4	Counter bits 39:32	RTC
72	MATCHREG0	Match register bits 7:0	RTC



Table 2-54 • ACM Address Decode Table for Analog Quad (continued)

ACMADDR [7:0] in Decimal	Name	Description	Associated Peripheral
73	MATCHREG1	Match register bits 15:8	RTC
74	MATCHREG2	Match register bits 23:16	RTC
75	MATCHREG3	Match register bits 31:24	RTC
76	MATCHREG4	Match register bits 39:32	RTC
80	MATCHBITS0	Individual match bits 7:0	RTC
81	MATCHBITS1	Individual match bits 15:8	RTC
82	MATCHBITS2	Individual match bits 23:16	RTC
83	MATCHBITS3	Individual match bits 31:24	RTC
84	MATCHBITS4	Individual match bits 39:32	RTC
88	CTRL_STAT	Control (write) / Status (read) register bits 7:0	RTC

# **ACM Characteristics**<sup>1</sup>

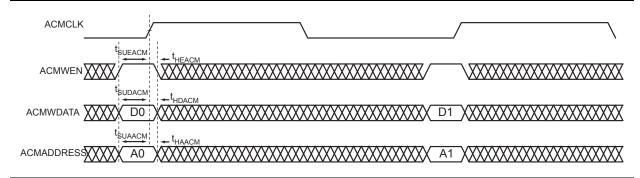


Figure 2-97 • ACM Write Waveform

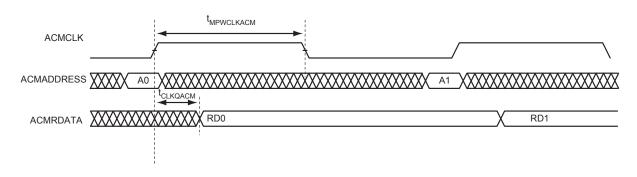


Figure 2-98 • ACM Read Waveform

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<sup>1.</sup> When addressing the RTC addresses (i.e., ACMADDR 64 to 89), there is no timing generator, and the rc\_osc, byte\_en, and aq\_wen signals have no impact.



# **Timing Characteristics**

Table 2-55 • Analog Configuration Multiplexer (ACM) Timing Commercial Temperature Range Conditions:  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>CLKQACM</sub>	Clock-to-Q of the ACM	19.73	22.48	26.42	ns
t <sub>SUDACM</sub>	Data Setup time for the ACM	4.39	5.00	5.88	ns
t <sub>HDACM</sub>	Data Hold time for the ACM	0.00	0.00	0.00	ns
t <sub>SUAACM</sub>	Address Setup time for the ACM	4.73	5.38	6.33	ns
t <sub>HAACM</sub>	Address Hold time for the ACM	0.00	0.00	0.00	ns
t <sub>SUEACM</sub>	Enable Setup time for the ACM	3.93	4.48	5.27	ns
t <sub>HEACM</sub>	Enable Hold time for the ACM	0.00	0.00	0.00	ns
t <sub>MPWARACM</sub>	Asynchronous Reset Minimum Pulse Width for the ACM	10.00	10.00	10.00	ns
t <sub>REMARACM</sub>	Asynchronous Reset Removal time for the ACM	12.98	14.79	17.38	ns
t <sub>RECARACM</sub>	Asynchronous Reset Recovery time for the ACM	12.98	14.79	17.38	ns
t <sub>MPWCLKACM</sub>	Clock Minimum Pulse Width for the ACM		45.00	45.00	ns
t <sub>FMAXCLKACM</sub>	lock Maximum Frequency for the ACM	10.00	10.00	10.00	MHz



# Analog Quad ACM Description

Table 2-56 maps out the ACM space associated with configuration of the Analog Quads within the Analog Block. Table 2-56 shows the byte assignment within each quad and the function of each bit within each byte. Subsequent tables will explain each bit setting and how it corresponds to a particular configuration. After 3.3 V and 1.5 V are applied to Fusion, Analog Quad configuration registers are loaded with default settings until the initialization and configuration state machine changes them to user-defined settings.

Table 2-56 • Analog Quad ACM Byte Assignment

Byte	Bit	Signal (Bx)	Function	Default Setting
Byte 0	0	B0[0]	Scaling factor control – prescaler	Highest voltage range
(AV)	1	B0[1]		
	2	B0[2]		
	3	B0[3]	Analog MUX select	Prescaler
	4	B0[4]	Current monitor switch	Off
	5	B0[5]	Direct analog input switch	Off
	6	B0[6]	Selects V-pad polarity	Positive
	7	B0[7]	Prescaler op amp mode	Power-down
Byte 1	0	B1[0]	Scaling factor control – prescaler	Highest voltage range
(AC)	1	B1[1]		
	2	B1[2]		
	3	B1[3]	Analog MUX select	Prescaler
	4	B1[4]		
	5	B1[5]	Direct analog input switch	Off
	6	B1[6]	Selects C-pad polarity	Positive
	7	B1[7]	Prescaler op amp mode	Power-down
Byte 2	0	B2[0]	Internal chip temperature monitor *	Off
(AG)	1	B2[1]	Spare	-
	2	B2[2]	Current drive control	Lowest current
	3	B2[3]		
	4	B2[4]	Spare	-
	5	B2[5]	Spare	-
	6	B2[6]	Selects G-pad polarity	Positive
	7	B2[7]	Selects low/high drive	Low drive
Byte 3	0	B3[0]	Scaling factor control – prescaler	Highest voltage range
(AT)	1	B3[1]		
	2	B3[2]		
	3	B3[3]	Analog MUX select	Prescaler
	4	B3[4]		
	5	B3[5]	Direct analog input switch	Off
	6	B3[6]	_	-
	7	B3[7]	Prescaler op amp mode	Power-down

Note: \*For the internal temperature monitor to function, Bit 0 of Byte 2 for all 10 Quads must be set.

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Table 2-57 details the settings available to control the prescaler values of the AV, AC, and AT pins. Note that the AT pin has a reduced number of available prescaler values.

Table 2-57 • Prescaler Control Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3)

Control Lines Bx[2:0]	Scaling Factor, Pad to ADC Input	LSB for an 8-Bit Conversion <sup>1</sup> (mV)	LSB for a 10-Bit Conversion <sup>1</sup> (mV)	LSB for a 12-Bit Conversion <sup>1</sup> (mV)	Full-Scale Voltage in 10-Bit Mode <sup>2</sup>	Range Name
000 <sup>3</sup>	0.15625	64	16	4	16.368 V	16 V
001	0.3125	32	8	2	8.184 V	8 V
010 <sup>3</sup>	0.625	16	4	1	4.092 V	4 V
011	1.25	8	2	0.5	2.046 V	2 V
100	2.5	4	1	0.25	1.023 V	1 V
101	5.0	2	0.5	0.125	0.5115 V	0.5 V
110	10.0	1	0.25	0.0625	0.25575 V	0.25 V
111	20.0	0.5	0.125	0.03125	0.127875 V	0.125 V

#### Notes:

- 1. LSB voltage equivalences assume VAREF = 2.56 V.
- 2. Full Scale voltage for n-bit mode: ((2^n) 1) x (LSB for a n-bit Conversion)
- 3. These are the only valid ranges for the Temperature Monitor Block Prescaler.

Table 2-58 details the settings available to control the MUX within each of the AV, AC, and AT circuits. This MUX determines whether the signal routed to the ADC is the direct analog input, prescaled signal, or output of either the Current Monitor Block or the Temperature Monitor Block.

Table 2-58 • Analog Multiplexer Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3)

Control Lines Bx[4]	Control Lines Bx[3]	ADC Connected To
0	0	Prescaler
0	1	Direct input
1	0	Current amplifier temperature monitor
1	1	Not valid

Table 2-59 details the settings available to control the Direct Analog Input switch for the AV, AC, and AT pins.

Table 2-59 • Direct Analog Input Switch Control Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3)

Control Lines Bx[5]	Direct Input Switch
0	Off
1	On

Table 2-60 details the settings available to control the polarity of the signals coming to the AV, AC, and AT pins. Note that the only valid setting for the AT pin is logic 0 to support positive voltages.

Table 2-60 • Voltage Polarity Control Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3)\*

Control Lines Bx[6]	Input Signal Polarity	
0	Positive	
1	Negative	

Note: \*The B3[6] signal for the AT pad should be kept at logic 0 to accept only positive voltages.



Table 2-61 details the settings available to either power down or enable the prescaler associated with the analog inputs AV, AC, and AT.

### Table 2-61 • Prescaler Op Amp Power-Down Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3)

Control Lines Bx[7]	Prescaler Op Amp
0	Power-down
1	Operational

Table 2-62 details the settings available to enable the Current Monitor Block associated with the AC pin.

#### Table 2-62 • Current Monitor Input Switch Control Truth Table—AV (x = 0)

Control Lines B0[4]	Current Monitor Input Switch
0	Off
1	On

Table 2-63 details the settings available to configure the drive strength of the gate drive when not in high-drive mode.

#### Table 2-63 • Low-Drive Gate Driver Current Truth Table (AG)

Control Lines B2[3]	Control Lines B2[2]	Current (μA)	
0	0	1	
0	1	3	
1	0	10	
1	1	30	

Table 2-64 details the settings available to set the polarity of the gate driver (either p-channel- or n-channel-type devices).

### Table 2-64 • Gate Driver Polarity Truth Table (AG)

Control Lines B2[6]	Gate Driver Polarity	
0	Positive	
1	Negative	

Table 2-65 details the settings available to turn on the Gate Driver and set whether high-drive mode is on or off.

### Table 2-65 • Gate Driver Control Truth Table (AG)

Control Lines B2[7]	GDON	Gate Driver
0	0	Off
0	1	Low drive on
1	0	Off
1	1	High drive on

Table 2-66 details the settings available to turn on and off the chip internal temperature monitor.

Note: For the internal temperature monitor to function, Bit 0 of Byte 2 for all 10 Quads must be set.

#### Table 2-66 • Internal Temperature Monitor Control Truth Table

Control Lines B2[0]	PDTMB	Chip Internal Temperature Monitor	
0	0	Off	
1	1	On	

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# User I/Os

### Introduction

Fusion devices feature a flexible I/O structure, supporting a range of mixed voltages (1.5 V, 1.8 V, 2.5 V, and 3.3 V) through a bank-selectable voltage. Table 2-68, Table 2-69, Table 2-70, and Table 2-71 on page 2-135 show the voltages and the compatible I/O standards. I/Os provide programmable slew rates, drive strengths, weak pull-up, and weak pull-down circuits. 3.3 V PCI and 3.3 V PCI-X are 5 V-tolerant. See the "5 V Input Tolerance" section on page 2-144 for possible implementations of 5 V tolerance.

All I/Os are in a known state during power-up, and any power-up sequence is allowed without current impact. Refer to the "I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)" section on page 3-5 for more information. In low power standby or sleep mode (VCC is OFF, VCC33A is ON, VCCI is ON) or when the resource is not used, digital inputs are tristated, digital outputs are tristated, and digital bibufs (input/output) are tristated.

I/O Tile

The Fusion I/O tile provides a flexible, programmable structure for implementing a large number of I/O standards. In addition, the registers available in the I/O tile in selected I/O banks can be used to support high-performance register inputs and outputs, with register enable if desired (Figure 2-99 on page 2-133). The registers can also be used to support the JESD-79C DDR standard within the I/O structure (see the "Double Data Rate (DDR) Support" section on page 2-139 for more information).

As depicted in Figure 2-100 on page 2-138, all I/O registers share one CLR port. The output register and output enable register share one CLK port. Refer to the "I/O Registers" section on page 2-138 for more information.

# I/O Banks and I/O Standards Compatibility

The digital I/Os are grouped into I/O voltage banks. There are three digital I/O banks on the AFS090 and AFS250 devices and four digital I/O banks on the AFS600 and AFS1500 devices. Figure 2-113 on page 2-158 and Figure 2-114 on page 2-159 show the bank configuration by device. The north side of the I/O in the AFS600 and AFS1500 devices comprises two banks of Pro I/Os. The Pro I/Os support a wide number of voltage-referenced I/O standards in addition to the multitude of single-ended and differential I/O standards common throughout all Microsemi digital I/Os. Each I/O voltage bank has dedicated I/O supply and ground voltages (VCCI/GNDQ for input buffers and VCCI/GND for output buffers). Because of these dedicated supplies, only I/Os with compatible standards can be assigned to the same I/O voltage bank. Table 2-69 and Table 2-70 on page 2-134 show the required voltage compatibility values for each of these voltages.

For more information about I/O and global assignments to I/O banks, refer to the specific pin table of the device in the "Package Pin Assignments" on page 4-1 and the "User I/O Naming Convention" section on page 2-158.

Each Pro I/O bank is divided into minibanks. Any user I/O in a VREF minibank (a minibank is the region of scope of a VREF pin) can be configured as a VREF pin (Figure 2-99 on page 2-133). Only one VREF pin is needed to control the entire VREF minibank. The location and scope of the VREF minibanks can be determined by the I/O name. For details, see the "User I/O Naming Convention" section on page 2-158.

Table 2-70 on page 2-134 shows the I/O standards supported by Fusion devices and the corresponding voltage levels.

I/O standards are compatible if the following are true:

- Their VCCI values are identical.
- If both of the standards need a VREF, their VREF values must be identical (Pro I/O only).



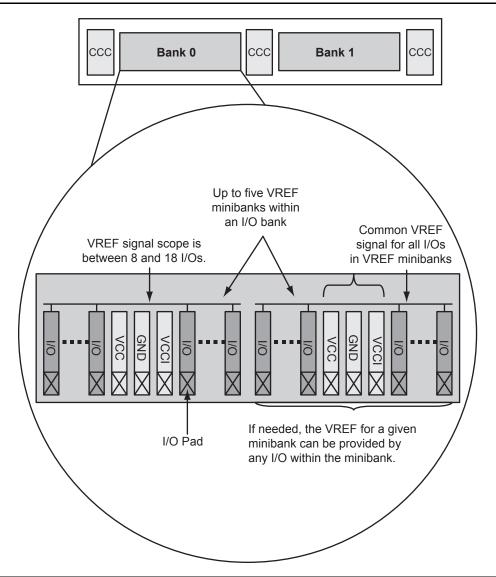


Figure 2-99 • Fusion Pro I/O Bank Detail Showing VREF Minibanks (north side of AFS600 and AFS1500)

Table 2-67 • I/O Standards Supported by Bank Type

I/O Bank	Single-Ended I/O Standards	Differential I/O Standards	Voltage-Referenced	Hot- Swap
Standard I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V / 1.8 V / 1.5 V, LVCMOS 2.5/5.0 V	_	_	Yes
Advanced I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V / 1.8 V / 1.5 V, LVCMOS 2.5/5.0 V, 3.3 V PCI / 3.3 V PCI-X	LVPECL and LVDS	_	ı
Pro I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V / 1.8 V / 1.5 V, LVCMOS 2.5/5.0 V, 3.3 V PCI / 3.3 V PCI-X	LVPECL and LVDS	GTL+ 2.5 V / 3.3 V, GTL 2.5 V / 3.3 V, HSTL Class I and II, SSTL2 Class I and II, SSTL3 Class I and II	Yes

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Table 2-68 • I/O Bank Support by Device

I/O Bank	AFS090	AFS250	AFS600	AFS1500
Standard I/O	N	N	-	_
Advanced I/O	E, W	E, W	E, W	E, W
Pro I/O	_	_	N	N
Analog Quad	S	S	S	S

Note: E = East side of the device W = West side of the device N = North side of the device

S = South side of the device

Table 2-69 • Fusion VCCI Voltages and Compatible Standards

VCCI (typical)	Compatible Standards
3.3 V	LVTTL/LVCMOS 3.3, PCI 3.3, SSTL3 (Class I and II),* GTL+ 3.3, GTL 3.3,* LVPECL
2.5 V	LVCMOS 2.5, LVCMOS 2.5/5.0, SSTL2 (Class I and II),* GTL+ 2.5,* GTL 2.5,* LVDS, BLVDS, M-LVDS
1.8 V	LVCMOS 1.8
1.5 V	LVCMOS 1.5, HSTL (Class I),* HSTL (Class II)*

Note: \*I/O standard supported by Pro I/O banks.

Table 2-70 • Fusion VREF Voltages and Compatible Standards\*

VREF (typical)	Compatible Standards
1.5 V	SSTL3 (Class I and II)
1.25 V	SSTL2 (Class I and II)
1.0 V	GTL+ 2.5, GTL+ 3.3
0.8 V	GTL 2.5, GTL 3.3
0.75 V	HSTL (Class I), HSTL (Class II)

Note: \*I/O standards supported by Pro I/O banks.



Table 2-71 • Fusion Standard and Advanced I/O Features

I/O Bank Voltage (typical)	Minibank Voltage (typical)	LVTTL/LVCMOS 3.3 V	LVCMOS 2.5 V	LVCMOS 1.8 V	LVCMOS 1.5 V	3.3 V PCI / PCI-X	GTL + (3.3 V)	GTL + (2.5 V)	GTL (3.3 V)	GTL (2.5 V)	HSTL Class I and II (1.5 V)	SSTL2 Class I and II (2.5 V)	SSTL3 Class I and II (3.3 V)	LVDS (2.5 V ± 5%)	LVPECL (3.3 V)
3.3 V	_														
	0.80 V														
	1.00 V														
	1.50 V														
2.5 V	_														
	0.80 V														
	1.00 V														
	1.25 V														
1.8 V	_														
1.5 V	_				·										
	0.75 V														

Note: White box: Allowable I/O standard combinations Gray box: Illegal I/O standard combinations

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# Features Supported on Pro I/Os

Table 2-72 lists all features supported by transmitter/receiver for single-ended and differential I/Os.

### Table 2-72 • Fusion Pro I/O Features

Feature	Description				
Single-ended and voltage- referenced transmitter	<ul> <li>Hot insertion in every mode except PCI or 5 V input tolerant (these modes use clamp diodes and do not allow hot insertion)</li> </ul>				
features	Activation of hot insertion (disabling the clamp diode) is selectable by I/Os.				
	Weak pull-up and pull-down				
	Two slew rates				
	<ul> <li>Skew between output buffer enable/disable time: 2 ns delay (rising edge) and 0 ns delay (falling edge); see "Selectable Skew between Output Buffer Enable/Disable Time" on page 2-149 for more information</li> </ul>				
	Five drive strengths				
	5 V-tolerant receiver ("5 V Input Tolerance" section on page 2-144)				
	<ul> <li>LVTTL/LVCMOS 3.3 V outputs compatible with 5 V TTL inputs ("5 V Output Tolerance" section on page 2-148)</li> </ul>				
	High performance (Table 2-76 on page 2-143)				
Single-ended receiver features	Schmitt trigger option				
	ESD protection				
	<ul> <li>Programmable delay: 0 ns if bypassed, 0.625 ns with '000' setting, 6.575 ns with '111' setting, 0.85-ns intermediate delay increments (at 25°C, 1.5 V)</li> </ul>				
	High performance (Table 2-76 on page 2-143)				
	<ul> <li>Separate ground planes, GND/GNDQ, for input buffers only to avoid output- induced noise in the input circuitry</li> </ul>				
Voltage-referenced differential receiver features	<ul> <li>Programmable Delay: 0 ns if bypassed, 0.625 ns with '000' setting, 6.575 ns with '111' setting, 0.85-ns intermediate delay increments (at 25°C, 1.5 V)</li> </ul>				
	High performance (Table 2-76 on page 2-143)				
	<ul> <li>Separate ground planes, GND/GNDQ, for input buffers only to avoid output- induced noise in the input circuitry</li> </ul>				
CMOS-style LVDS, BLVDS, M-LVDS, or LVPECL	<ul> <li>Two I/Os and external resistors are used to provide a CMOS-style LVDS, BLVDS, M-LVDS, or LVPECL transmitter solution.</li> </ul>				
transmitter	Activation of hot insertion (disabling the clamp diode) is selectable by I/Os.				
	Weak pull-up and pull-down				
	Fast slew rate				
LVDS/LVPECL differential	ESD protection				
receiver features	High performance (Table 2-76 on page 2-143)				
	<ul> <li>Programmable delay: 0.625 ns with '000' setting, 6.575 ns with '111' setting, 0.85-ns intermediate delay increments (at 25°C, 1.5 V)</li> </ul>				
	Separate input buffer ground and power planes to avoid output-induced noise in the input circuitry				



Table 2-73 • Maximum I/O Frequency for Single-Ended, Voltage-Referenced, and Differential I/Os; All I/O Bank Types (maximum drive strength and high slew selected)

Specification	Performance Up To
LVTTL/LVCMOS 3.3 V	200 MHz
LVCMOS 2.5 V	250 MHz
LVCMOS 1.8 V	200 MHz
LVCMOS 1.5 V	130 MHz
PCI	200 MHz
PCI-X	200 MHz
HSTL-I	300 MHz
HSTL-II	300 MHz
SSTL2-I	300 MHz
SSTL2-II	300 MHz
SSTL3-I	300 MHz
SSTL3-II	300 MHz
GTL+ 3.3 V	300 MHz
GTL+ 2.5 V	300 MHz
GTL 3.3 V	300 MHz
GTL 2.5 V	300 MHz
LVDS	350 MHz
LVPECL	300 MHz

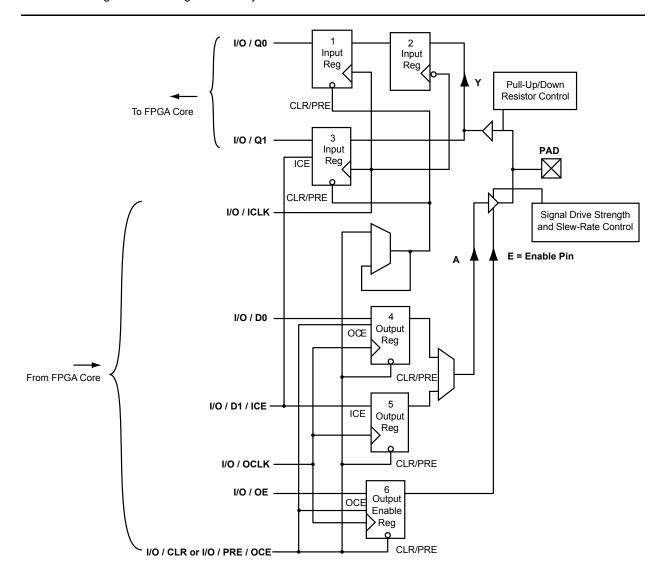


# I/O Registers

Each I/O module contains several input, output, and enable registers. Refer to Figure 2-100 for a simplified representation of the I/O block.

The number of input registers is selected by a set of switches (not shown in Figure 2-100) between registers to implement single or differential data transmission to and from the FPGA core. The Designer software sets these switches for the user.

A common CLR/PRE signal is employed by all I/O registers when I/O register combining is used. Input register 2 does not have a CLR/PRE pin, as this register is used for DDR implementation. The I/O register combining must satisfy some rules.



Note: Fusion I/Os have registers to support DDR functionality (see the "Double Data Rate (DDR) Support" section on page 2-139 for more information).

Figure 2-100 • I/O Block Logical Representation



# **Double Data Rate (DDR) Support**

Fusion Pro I/Os support 350 MHz DDR inputs and outputs. In DDR mode, new data is present on every transition of the clock signal. Clock and data lines have identical bandwidths and signal integrity requirements, making it very efficient for implementing very high-speed systems.

DDR interfaces can be implemented using HSTL, SSTL, LVDS, and LVPECL I/O standards. In addition, high-speed DDR interfaces can be implemented using LVDS I/O.

# Input Support for DDR

The basic structure to support a DDR input is shown in Figure 2-101. Three input registers are used to capture incoming data, which is presented to the core on each rising edge of the I/O register clock. Each I/O tile on Fusion devices supports DDR inputs.

### Output Support for DDR

The basic DDR output structure is shown in Figure 2-102 on page 2-140. New data is presented to the output every half clock cycle. Note: DDR macros and I/O registers do not require additional routing. The combiner automatically recognizes the DDR macro and pushes its registers to the I/O register area at the edge of the chip. The routing delay from the I/O registers to the I/O buffers is already taken into account in the DDR macro.

Refer to the application note *Using DDR for Fusion Devices* for more information.

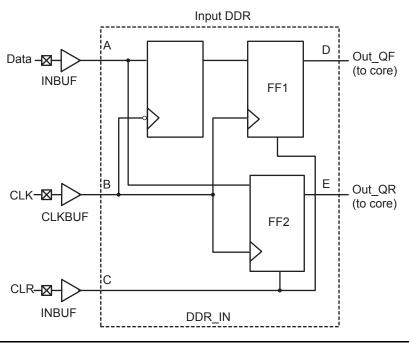


Figure 2-101 • DDR Input Register Support in Fusion Devices

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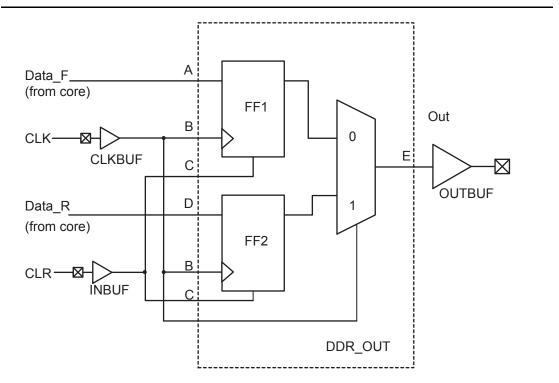


Figure 2-102 • DDR Output Support in Fusion Devices



# **Hot-Swap Support**

Hot-swapping (also called hot plugging) is the operation of hot insertion or hot removal of a card in (or from) a powered-up system. The levels of hot-swap support and examples of related applications are described in Table 2-74. The I/Os also need to be configured in hot insertion mode if hot plugging compliance is required.

Table 2-74 • Levels of Hot-Swap Support

Hot Swapping Level	Description	Power Applied to Device	Bus State	Card Ground Connection	Device Circuitry Connected to Bus Pins		Compliance of Fusion Devices
1	Cold-swap	No	_	_	_	System and card with Microsemi FPGA chip are powered down, then card gets plugged into system, then power supplies are turned on for system but not for FPGA on card.	Compliant I/Os can but do not have to be set to hot insertion mode.
2	Hot-swap while reset	Yes	reset state	Must be made and maintained for 1 ms before, during, and after insertion/ removal	_	In PCI hot plug specification, reset control circuitry isolates the card busses until the card supplies are at their nominal operating levels and stable.	Compliant I/Os can but do not have to be set to hot insertion mode.
3	Hot-swap while bus idle		Held idle (no ongoing I/O processes during insertion/re moval)	Same as Level 2	glitch-free during power-up or	Board bus shared with card bus is "frozen," and there is no toggling activity on bus. It is critical that the logic states set on the bus signal do not get disturbed during card insertion/removal.	set to hot
4	Hot-swap on an active bus		Bus may have active I/O processes ongoing, but device being inserted or removed must be idle.	Same as Level 2	Same as Level 3	signal do not get	

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For Fusion devices requiring Level 3 and/or Level 4 compliance, the board drivers connected to Fusion I/Os need to have 10 k $\Omega$  (or lower) output drive resistance at hot insertion, and 1 k $\Omega$  (or lower) output drive resistance at hot removal. This is the resistance of the transmitter sending a signal to the Fusion I/O, and no additional resistance is needed on the board. If that cannot be assured, three levels of staging can be used to meet Level 3 and/or Level 4 compliance. Cards with two levels of staging should have the following sequence:

- 1. Grounds
- 2. Powers, I/Os, other pins

# **Cold-Sparing Support**

Cold-sparing means that a subsystem with no power applied (usually a circuit board) is electrically connected to the system that is in operation. This means that all input buffers of the subsystem must present very high input impedance with no power applied so as not to disturb the operating portion of the system.

Pro I/O banks and standard I/O banks fully support cold-sparing.

For Pro I/O banks, standards such as PCI that require I/O clamp diodes, can also achieve cold-sparing compliance, since clamp diodes get disconnected internally when the supplies are at 0 V.

For Advanced I/O banks, since the I/O clamp diode is always active, cold-sparing can be accomplished either by employing a bus switch to isolate the device I/Os from the rest of the system or by driving each advanced I/O pin to 0 V.

If Standard I/O banks are used in applications requiring cold-sparing, a discharge path from the power supply to ground should be provided. This can be done with a discharge resistor or a switched resistor. This is necessary because the standard I/O buffers do not have built-in I/O clamp diodes.

If a resistor is chosen, the resistor value must be calculated based on decoupling capacitance on a given power supply on the board (this decoupling capacitor is in parallel with the resistor). The RC time constant should ensure full discharge of supplies before cold-sparing functionality is required. The resistor is necessary to ensure that the power pins are discharged to ground every time there is an interruption of power to the device.

I/O cold-sparing may add additional current if the pin is configured with either a pull-up or pull down resistor and driven in the opposite direction. A small static current is induced on each IO pin when the pin is driven to a voltage opposite to the weak pull resistor. The current is equal to the voltage drop across the input pin divided by the pull resistor. Please refer to Table 2-95 on page 2-169, Table 2-96 on page 2-169, and Table 2-97 on page 2-171 for the specific pull resistor value for the corresponding I/O standard.

For example, assuming an LVTTL 3.3 V input pin is configured with a weak Pull-up resistor, a current will flow through the pull-up resistor if the input pin is driven low. For an LVTTL 3.3 V, pull-up resistor is ~45 k $\Omega$  and the resulting current is equal to 3.3 V / 45 k $\Omega$  = 73  $\mu$ A for the I/O pin. This is true also when a weak pull-down is chosen and the input pin is driven high. Avoiding this current can be done by driving the input low when a weak pull-down resistor is used, and driving it high when a weak pull-up resistor is used.

In Active and Static modes, this current draw can occur in the following cases:

- Input buffers with pull-up, driven low
- · Input buffers with pull-down, driven high
- Bidirectional buffers with pull-up, driven low
- · Bidirectional buffers with pull-down, driven high
- Output buffers with pull-up, driven low
- Output buffers with pull-down, driven high
- Tristate buffers with pull-up, driven low
- Tristate buffers with pull-down, driven high



# **Electrostatic Discharge (ESD) Protection**

Fusion devices are tested per JEDEC Standard JESD22-A114-B.

Fusion devices contain clamp diodes at every I/O, global, and power pad. Clamp diodes protect all device pads against damage from ESD as well as from excessive voltage transients.

Each I/O has two clamp diodes. One diode has its positive (P) side connected to the pad and its negative (N) side connected to VCCI. The second diode has its P side connected to GND and its N side connected to the pad. During operation, these diodes are normally biased in the Off state, except when transient voltage is significantly above VCCI or below GND levels.

By selecting the appropriate I/O configuration, the diode is turned on or off. Refer to Table 2-75 and Table 2-76 on page 2-143 for more information about I/O standards and the clamp diode.

The second diode is always connected to the pad, regardless of the I/O configuration selected.

Table 2-75 • Fusion Standard and Advanced I/O - Hot-Swap and 5 V Input Tolerance Capabilities

	Clamp Diode		Hot In	sertion	5 V Input	Tolerance <sup>1</sup>	Input	Output
I/O Assignment	Standard I/O	Advanced I/O	Standard I/O	Advanced I/O	Standard I/O	Advanced I/O	Buffer	Buffer
3.3 V LVTTL/LVCMOS	No	Yes	Yes	No	Yes <sup>1</sup>	Yes <sup>1</sup>	Enabled/I	Disabled
3.3 V PCI, 3.3 V PCI-X	N/A	Yes	N/A	No	N/A	Yes <sup>1</sup>	Enabled/I	Disabled
LVCMOS 2.5 V	No	Yes	Yes	No	No	No	Enabled/I	Disabled
LVCMOS 2.5 V / 5.0 V	N/A	Yes	N/A	No	N/A	Yes <sup>2</sup>	Enabled/I	Disabled
LVCMOS 1.8 V	No	Yes	Yes	No	No	No	Enabled/I	Disabled
LVCMOS 1.5 V	No	Yes	Yes	No	No	No	Enabled/I	Disabled
Differential, LVDS/BLVDS/M- LVDS/ LVPECL <sup>3</sup>	N/A	Yes	N/A	No	N/A	No	Enabled/l	Disabled

#### Notes:

- 1. Can be implemented with an external IDT bus switch, resistor divider, or Zener with resistor.
- 2. Can be implemented with an external resistor and an internal clamp diode.
- 3. Bidirectional LVPECL buffers are not supported. I/Os can be configured as either input buffers or output buffers.

Table 2-76 • Fusion Pro I/O - Hot-Swap and 5 V Input Tolerance Capabilities

I/O Assignment	Clamp Diode	Hot Insertion	5 V Input Tolerance	Input Buffer	Output Buffer
3.3 V LVTTL/LVCMOS	No	Yes	Yes <sup>1</sup>	Enabled	I/Disabled
3.3 V PCI, 3.3 V PCI-X	Yes	No	Yes <sup>1</sup>	Enabled	I/Disabled
LVCMOS 2.5 V 3	No	Yes	No	Enabled	I/Disabled
LVCMOS 2.5 V / 5.0 V <sup>3</sup>	Yes	No	Yes <sup>2</sup>	Enabled	I/Disabled
LVCMOS 1.8 V	No	Yes	No	Enabled	I/Disabled
LVCMOS 1.5 V	No	Yes	No	Enabled	I/Disabled
Voltage-Referenced Input Buffer	No	Yes	No	Enabled/Disabled	
Differential, LVDS/BLVDS/M-LVDS/LVPECL <sup>4</sup>	No	Yes	No	Enabled	I/Disabled

#### Notes:

- 1. Can be implemented with an external IDT bus switch, resistor divider, or Zener with resistor.
- 2. Can be implemented with an external resistor and an internal clamp diode.
- In the SmartGen, FlashROM, Flash Memory System Builder, and Analog System Builder User Guide, select the LVCMOS5 macro for the LVCMOS 2.5 V / 5.0 V I/O standard or the LVCMOS25 macro for the LVCMOS 2.5 V I/O standard
- 4. Bidirectional LVPECL buffers are not supported. I/Os can be configured as either input buffers or output buffers.

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# **5 V Input Tolerance**

I/Os can support 5 V input tolerance when LVTTL 3.3 V, LVCMOS 3.3 V, LVCMOS 2.5 V / 5 V, and LVCMOS 2.5 V configurations are used (see Table 2-77 on page 2-147 for more details). There are four recommended solutions (see Figure 2-103 to Figure 2-106 on page 2-146 for details of board and macro setups) to achieve 5 V receiver tolerance. All the solutions meet a common requirement of limiting the voltage at the input to 3.6 V or less. In fact, the I/O absolute maximum voltage rating is 3.6 V, and any voltage above 3.6 V may cause long-term gate oxide failures.

#### Solution 1

The board-level design needs to ensure that the reflected waveform at the pad does not exceed the limits provided in Table 3-4 on page 3-4. This is a long-term reliability requirement.

This scheme will also work for a 3.3 V PCI / PCI-X configuration, but the internal diode should not be used for clamping, and the voltage must be limited by the two external resistors, as explained below. Relying on the diode clamping would create an excessive pad DC voltage of 3.3 V + 0.7 V = 4 V.

The following are some examples of possible resistor values (based on a simplified simulation model with no line effects and 10  $\Omega$  transmitter output resistance, where Rtx\_out\_high = (VCCI – VOH) / IOH, Rtx\_out\_low = VOL / IOL).

Example 1 (high speed, high current):

```
Rtx_out_high = Rtx_out_low = 10 \ \Omega R1 = 36 \ \Omega (\pm 5\%), P(r1)min = 0.069 \ \Omega R2 = 82 \ \Omega (\pm 5\%), P(r2)min = 0.158 \ \Omega Imax_tx = 5.5 \ V / (82 \ ^*0.95 \ + 36 \ ^*0.95 \ + 10) = 45.04 \ mA t_{RISE} = t_{FALL} = 0.85 \ ns at C_pad_load = 10 \ pF (includes up to 25\% safety margin) t_{RISE} = t_{FALL} = 4 \ ns at C_pad_load = 50 \ pF (includes up to 25\% safety margin) Example 2 (low-medium speed, medium current): Rtx_out_high = Rtx_out_low = 10 \ \Omega R1 = 220 \ \Omega (\pm 5\%), P(r1)min = 0.018 \ \Omega R2 = 390 \ \Omega (\pm 5\%), P(r2)min = 0.032 \ \Omega Imax_tx = 5.5 \ V / (220 \ ^*0.95 \ + 390 \ ^*0.95 \ + 10) = 9.17 \ mA t_{RISE} = t_{FALL} = 4 \ ns at C_pad_load = 10 \ pF (includes up to 25\% safety margin)
```

 $t_{RISE}$  =  $t_{FALL}$  = 20 ns at C\_pad\_load = 50 pF (includes up to 25% safety margin)

Other values of resistors are also allowed as long as the resistors are sized appropriately to limit the voltage at the receiving end to 2.5 V < Vin(rx) < 3.6 V when the transmitter sends a logic 1. This range of  $\text{Vin\_dc}(rx)$  must be assured for any combination of transmitter supply (5 V  $\pm$  0.5 V), transmitter output resistance, and board resistor tolerances.



Temporary overshoots are allowed according to Table 3-4 on page 3-4.

#### Solution 1

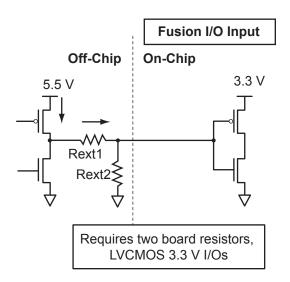


Figure 2-103 • Solution 1

### Solution 2

The board-level design must ensure that the reflected waveform at the pad does not exceed limits provided in Table 3-4 on page 3-4. This is a long-term reliability requirement.

This scheme will also work for a 3.3 V PCI/PCI-X configuration, but the internal diode should not be used for clamping, and the voltage must be limited by the external resistors and Zener, as shown in Figure 2-104. Relying on the diode clamping would create an excessive pad DC voltage of 3.3 V + 0.7 V = 4 V.

#### Solution 2

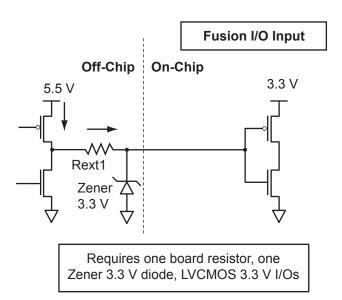


Figure 2-104 • Solution 2

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### Solution 3

The board-level design must ensure that the reflected waveform at the pad does not exceed limits provided in Table 3-4 on page 3-4. This is a long-term reliability requirement.

This scheme will also work for a 3.3 V PCI/PCIX configuration, but the internal diode should not be used for clamping, and the voltage must be limited by the bus switch, as shown in Figure 2-105. Relying on the diode clamping would create an excessive pad DC voltage of 3.3 V + 0.7 V = 4 V.

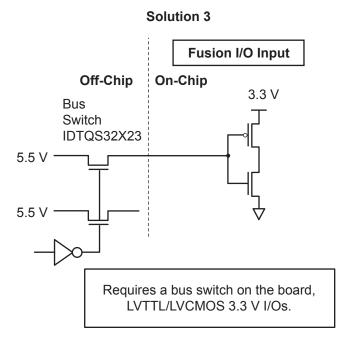


Figure 2-105 • Solution 3

### Solution 4

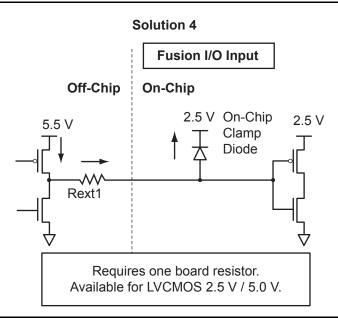


Figure 2-106 • Solution 4



Table 2-77 • Comparison Table for 5 V-Compliant Receiver Scheme

Scheme	Board Components	Speed	Current Limitations
1	Two resistors	Low to high <sup>1</sup>	Limited by transmitter's drive strength
2	Resistor and Zener 3.3 V	Medium	Limited by transmitter's drive strength
3	Bus switch	High	N/A
4	Minimum resistor value <sup>2</sup> R = 47 $\Omega$ at T <sub>J</sub> = 70°C R = 150 $\Omega$ at T <sub>J</sub> = 85°C R = 420 $\Omega$ at T <sub>J</sub> = 100°C	Medium	Maximum diode current at 100% duty cycle, signal constantly at '1' $52.7 \text{ mA at T}_J = 70^{\circ}\text{C} \ / \ 10\text{-year lifetime}$ $16.5 \text{ mA at T}_J = 85^{\circ}\text{C} \ / \ 10\text{-year lifetime}$ $5.9 \text{ mA at T}_J = 100^{\circ}\text{C} \ / \ 10\text{-year lifetime}$ For duty cycles other than 100%, the currents can be increased by a factor = 1 / (duty cycle). Example: 20% duty cycle at $70^{\circ}\text{C}$ Maximum current = $(1 \ / \ 0.2)^{\circ}$ 52.7 mA = 5 * 52.7 mA = 263.5 mA

### Notes:

- 1. Speed and current consumption increase as the board resistance values decrease.
- 2. Resistor values ensure I/O diode long-term reliability.

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# **5 V Output Tolerance**

Fusion I/Os must be set to 3.3 V LVTTL or 3.3 V LVCMOS mode to reliably drive 5 V TTL receivers. It is also critical that there be NO external I/O pull-up resistor to 5 V, since this resistor would pull the I/O pad voltage beyond the 3.6 V absolute maximum value and consequently cause damage to the I/O.

When set to 3.3 V LVTTL or 3.3 V LVCMOS mode, Fusion I/Os can directly drive signals into 5 V TTL receivers. In fact, VOL = 0.4 V and VOH = 2.4 V in both 3.3 V LVTTL and 3.3 V LVCMOS modes exceed the VIL = 0.8 V and VIH = 2 V level requirements of 5 V TTL receivers. Therefore, level '1' and level '0' will be recognized correctly by 5 V TTL receivers.

# Simultaneously Switching Outputs and PCB Layout

- Simultaneously switching outputs (SSOs) can produce signal integrity problems on adjacent signals that are not part of the SSO bus. Both inductive and capacitive coupling parasitics of bond wires inside packages and of traces on PCBs will transfer noise from SSO busses onto signals adjacent to those busses. Additionally, SSOs can produce ground bounce noise and VCCI dip noise. These two noise types are caused by rapidly changing currents through GND and VCCI package pin inductances during switching activities:
- Ground bounce noise voltage = L(GND) \* di/dt
- VCCI dip noise voltage = L(VCCI) \* di/dt

Any group of four or more input pins switching on the same clock edge is considered an SSO bus. The shielding should be done both on the board and inside the package unless otherwise described.

In-package shielding can be achieved in several ways; the required shielding will vary depending on whether pins next to SSO bus are LVTTL/LVCMOS inputs, LVTTL/LVCMOS outputs, or GTL/SSTL/HSTL/LVDS/LVPECL inputs and outputs. Board traces in the vicinity of the SSO bus have to be adequately shielded from mutual coupling and inductive noise that can be generated by the SSO bus. Also, noise generated by the SSO bus needs to be reduced inside the package.

PCBs perform an important function in feeding stable supply voltages to the IC and, at the same time, maintaining signal integrity between devices.

Key issues that need to considered are as follows:

- Power and ground plane design and decoupling network design
- · Transmission line reflections and terminations



# Selectable Skew between Output Buffer Enable/Disable Time

The configurable skew block is used to delay the output buffer assertion (enable) without affecting deassertion (disable) time.

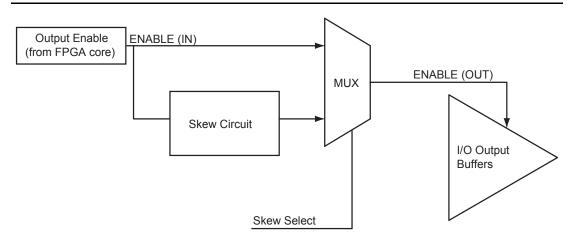


Figure 2-107 • Block Diagram of Output Enable Path

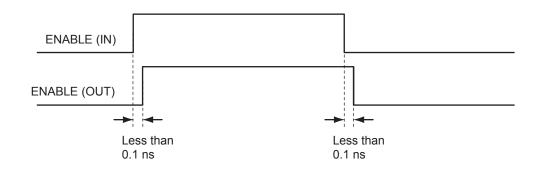


Figure 2-108 • Timing Diagram (option1: bypasses skew circuit)

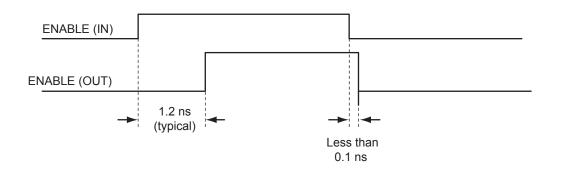


Figure 2-109 • Timing Diagram (option 2: enables skew circuit)

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At the system level, the skew circuit can be used in applications where transmission activities on bidirectional data lines need to be coordinated. This circuit, when selected, provides a timing margin that can prevent bus contention and subsequent data loss or transmitter over-stress due to transmitter-to-transmitter current shorts. Figure 2-110 presents an example of the skew circuit implementation in a bidirectional communication system. Figure 2-111 shows how bus contention is created, and Figure 2-112 on page 2-151 shows how it can be avoided with the skew circuit.

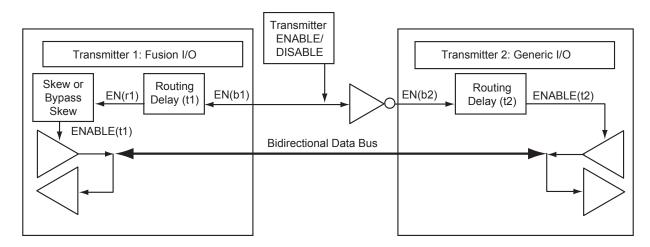


Figure 2-110 • Example of Implementation of Skew Circuits in Bidirectional Transmission Systems Using Fusion Devices

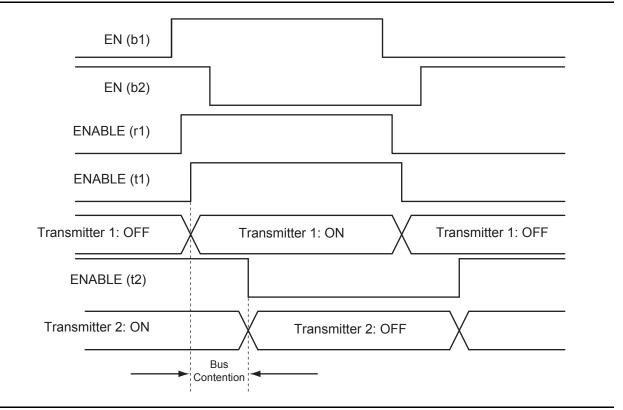


Figure 2-111 • Timing Diagram (bypasses skew circuit)



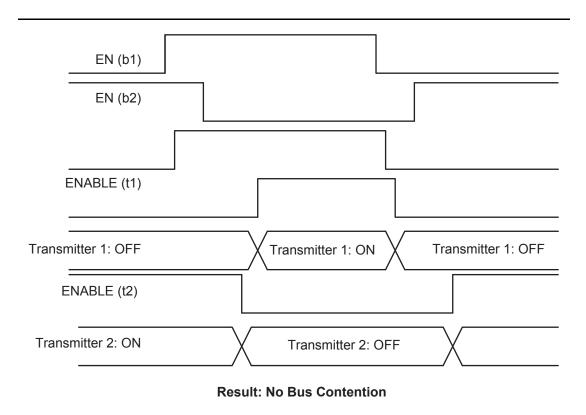


Figure 2-112 • Timing Diagram (with skew circuit selected)

# Weak Pull-Up and Weak Pull-Down Resistors

Fusion devices support optional weak pull-up and pull-down resistors for each I/O pin. When the I/O is pulled up, it is connected to the VCCI of its corresponding I/O bank. When it is pulled down, it is connected to GND. Refer to Table 2-97 on page 2-171 for more information.

# **Slew Rate Control and Drive Strength**

Fusion devices support output slew rate control: high and low. The high slew rate option is recommended to minimize the propagation delay. This high-speed option may introduce noise into the system if appropriate signal integrity measures are not adopted. Selecting a low slew rate reduces this kind of noise but adds some delays in the system. Low slew rate is recommended when bus transients are expected. Drive strength should also be selected according to the design requirements and noise immunity of the system.

The output slew rate and multiple drive strength controls are available in LVTTL/LVCMOS  $3.3\,V$ , LVCMOS  $2.5\,V$ , LVCMOS  $2.5\,V$ /  $5.0\,V$  input, LVCMOS  $1.8\,V$ , and LVCMOS  $1.5\,V$ . All other I/O standards have a high output slew rate by default.

For Fusion slew rate and drive strength specifications, refer to the appropriate I/O bank table:

- Fusion Standard I/O (Table 2-78 on page 2-152)
- Fusion Advanced I/O (Table 2-79 on page 2-152)
- Fusion Pro I/O (Table 2-80 on page 2-152)

Table 2-83 on page 2-155 lists the default values for the above selectable I/O attributes as well as those that are preset for each I/O standard.

Refer to Table 2-78, Table 2-79, and Table 2-80 on page 2-152 for SLEW and OUT\_DRIVE settings. Table 2-81 on page 2-153 and Table 2-82 on page 2-154 list the I/O default attributes. Table 2-83 on page 2-155 lists the voltages for the supported I/O standards.

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## Table 2-78 • Fusion Standard I/O Standards—OUT\_DRIVE Settings

	OUT_DRIVE (mA)								
I/O Standards	2	4	6	8	Sle	ew			
LVTTL/LVCMOS 3.3 V	✓	✓	✓	✓	High	Low			
LVCMOS 2.5 V	✓	✓	✓	✓	High	Low			
LVCMOS 1.8 V	✓	✓	-	-	High	Low			
LVCMOS 1.5 V	✓	_	-	_	High	Low			

## Table 2-79 • Fusion Advanced I/O Standards—SLEW and OUT\_DRIVE Settings

	OUT_DRIVE (mA)									
I/O Standards	2	4	6	8	12	16	SIe	ew		
LVTTL/LVCMOS 3.3 V	✓	✓	✓	✓	✓	✓	High	Low		
LVCMOS 2.5 V	✓	✓	✓	✓	✓	-	High	Low		
LVCMOS 1.8 V	✓	✓	✓	✓	_	_	High	Low		
LVCMOS 1.5 V	<b>√</b>	✓	-	-	_	-	High	Low		

# Table 2-80 • Fusion Pro I/O Standards—SLEW and OUT\_DRIVE Settings

		OUT_DRIVE (mA)							
I/O Standards	2	4	6	8	12	16	24	Sle	w
LVTTL/LVCMOS 3.3 V	<b>√</b>	✓	✓	✓	✓	✓	✓	High	Low
LVCMOS 2.5 V	<b>√</b>	✓	✓	✓	✓	✓	✓	High	Low
LVCMOS 2.5 V/5.0 V	<b>√</b>	✓	✓	✓	✓	✓	✓	High	Low
LVCMOS 1.8 V	<b>√</b>	✓	✓	✓	✓	✓	-	High	Low
LVCMOS 1.5 V	✓	✓	✓	✓	✓	-	-	High	Low



Table 2-81 • Fusion Pro I/O Default Attributes

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (tribuf and bibuf only)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER	IN_DELAY (input only)	IN_DELAY_VAL (input only)	SCHMITT_TRIGGER (input only)
LVTTL/LVCMO S 3.3 V	Refer to the following tables for more information:	Refer to the following tables for more information:	Off	None	35 pF	_	Off	0	Off
LVCMOS 2.5 V	Table 2-78 on page 2-152	Table 2-78 on page 2-152	Off	None	35 pF	_	Off	0	Off
LVCMOS 2.5/5.0 V	Table 2-79 on page 2-152 Table 2-80 on page 2-152	Table 2-79 on page 2-152 Table 2-80 on page 2-152	Off	None	35 pF	_	Off	0	Off
LVCMOS 1.8 V	Table 2-00 on page 2-132	Table 2-00 on page 2-102	Off	None	35 pF	_	Off	0	Off
LVCMOS 1.5 V			Off	None	35 pF	_	Off	0	Off
PCI (3.3 V)			Off	None	10 pF	_	Off	0	Off
PCI-X (3.3 V)			Off	None	10 pF	_	Off	0	Off
GTL+ (3.3 V)			Off	None	10 pF	_	Off	0	Off
GTL+ (2.5 V)			Off	None	10 pF	_	Off	0	Off
GTL (3.3 V)			Off	None	10 pF	_	Off	0	Off
GTL (2.5 V)			Off	None	10 pF	_	Off	0	Off
HSTL Class I			Off	None	20 pF	_	Off	0	Off
HSTL Class II			Off	None	20 pF	_	Off	0	Off
SSTL2 Class I and II			Off	None	30 pF	_	Off	0	Off
SSTL3 Class I and II			Off	None	30 pF	_	Off	0	Off
LVDS, BLVDS, M-LVDS			Off	None	0 pF	_	Off	0	Off
LVPECL			Off	None	0 pF	_	Off	0	Off

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### Table 2-82 • Advanced I/O Default Attributes

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (tribuf and bibuf only)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER
LVTTL/LVCMOS 3.3 V	Refer to the following	Refer to the following tables	Off	None	35 pF	_
LVCMOS 2.5 V	tables for more information:	for more information: Table 2-78 on page 2-152	Off	None	35 pF	_
LVCMOS 2.5/5.0 V	Table 2-78 on page 2-152	Table 2-79 on page 2-152	Off	None	35 pF	_
LVCMOS 1.8 V	Table 2-79 on page 2-152	Table 2-80 on page 2-152	Off	None	35 pF	_
LVCMOS 1.5 V	Table 2-80 on page 2-152		Off	None	35 pF	_
PCI (3.3 V)			Off	None	10 pF	_
PCI-X (3.3 V)			Off	None	10 pF	_
LVDS, BLVDS, M-LVDS			Off	None	_	_
LVPECL			Off	None	_	_



Table 2-83 • Fusion Pro I/O Supported Standards and Corresponding VREF and VTT Voltages

I/O Standard	Input/Output Supply Voltage (VCCI_TYP)	Input Reference Voltage (VREF_TYP)	Board Termination Voltage (VTT_TYP)
LVTTL/LVCMOS 3.3 V	3.30 V	-	-
LVCMOS 2.5 V	2.50 V	-	-
LVCMOS 2.5 V / 5.0 V Input	2.50 V	-	-
LVCMOS 1.8 V	1.80 V	-	-
LVCMOS 1.5 V	1.50 V	-	-
PCI 3.3 V	3.30 V	-	-
PCI-X 3.3 V	3.30 V	-	-
GTL+ 3.3 V	3.30 V	1.00 V	1.50 V
GTL+ 2.5 V	2.50 V	1.00 V	1.50 V
GTL 3.3 V	3.30 V	0.80 V	1.20 V
GTL 2.5 V	2.50 V	0.80 V	1.20 V
HSTL Class I	1.50 V	0.75 V	0.75 V
HSTL Class II	1.50 V	0.75 V	0.75 V
SSTL3 Class I	3.30 V	1.50 V	1.50 V
SSTL3 Class II	3.30 V	1.50 V	1.50 V
SSTL2 Class I	2.50 V	1.25 V	1.25 V
SSTL2 Class II	2.50 V	1.25 V	1.25 V
LVDS, BLVDS, M-LVDS	2.50 V	-	-
LVPECL	3.30 V	-	_

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# I/O Software Support

In the Fusion development software, default settings have been defined for the various I/O standards supported. Changes can be made to the default settings via the use of attributes; however, not all I/O attributes are applicable for all I/O standards. Table 2-84 and Table 2-85 list the valid I/O attributes that can be manipulated by the user for each I/O standard.

Single-ended I/O standards in Fusion support up to five different drive strengths.

Table 2-84 • Fusion Standard and Advanced I/O Attributes vs. I/O Standard Applications

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (all macros with OE)*	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER
LVTTL/LVCMOS 3.3 V	3	3	3	3	3	3
LVCMOS 2.5 V	3	3	3	3	3	3
LVCMOS 2.5/5.0 V	3	3	3	3	3	3
LVCMOS 1.8 V	3	3	3	3	3	3
LVCMOS 1.5 V	3	3	3	3	3	3
PCI (3.3 V)			3		3	3
PCI-X (3.3 V)	3		3		3	3
LVDS, BLVDS, M-LVDS			3			3
LVPECL						3

Note: \* This feature does not apply to the standard I/O banks, which are the north I/O banks of AFS090 and AFS250 devices



Table 2-85 • Fusion Pro I/O Attributes vs. I/O Standard Applications

			, o otana			1				1
I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (all macros with OE)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER	IN_DELAY (input only)	o IN_DELAY_VAL (input only)	SCHMITT_TRIGGER (input only)	HOT_SWAPPABLE
LVTTL/LVCMOS 3.3 V	3	3	3	3	3	3	3	-	3	3
LVCMOS 2.5 V	3	3	3	3	3	3	3	3	3	3
LVCMOS 2.5/5.0 V	3	3	3	3	3	3	3	3	3	3
LVCMOS 1.8 V	3	3	3	3	3	3	3	3	3	3
LVCMOS 1.5 V	3	3	3	3	3	3	3	3	3	3
PCI (3.3 V)			3		3	3	3	3		
PCI-X (3.3 V)	3		3		3	3	3	3		
GTL+ (3.3 V)			3		3	3	3	3		3
GTL+ (2.5 V)			3		3	3	3	3		3
GTL (3.3 V)			3		3	3	3	3		3
GTL (2.5 V)			3		3	3	3	3		3
HSTL Class I			3		3	3	3	3		3
HSTL Class II			3		3	3	3	3		3
SSTL2 Class I and II			3		3	3	3	3		3
SSTL3 Class I and II			3		3	3	3	3		3
LVDS, BLVDS, M-LVDS			3			3	3	3		3
LVPECL						3	3	3		3

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# **User I/O Naming Convention**

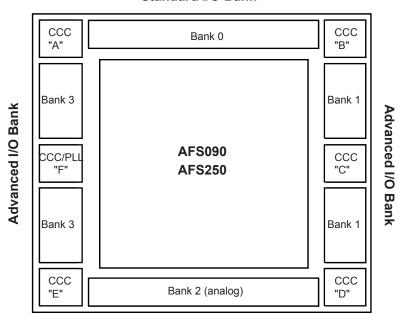
Due to the comprehensive and flexible nature of Fusion device user I/Os, a naming scheme is used to show the details of the I/O (Figure 2-113 on page 2-158 and Figure 2-114 on page 2-159). The name identifies to which I/O bank it belongs, as well as the pairing and pin polarity for differential I/Os.

I/O Nomenclature = Gmn/IOuxwByVz

Gmn is only used for I/Os that also have CCC access—i.e., global pins.

- G = Global
- m = Global pin location associated with each CCC on the device: A (northwest corner), B (northeast corner), C (east middle), D (southeast corner), E (southwest corner), and F (west middle).
- n = Global input MUX and pin number of the associated Global location m, either A0, A1, A2, B0, B1, B2, C0, C1, or C2. Figure 2-22 on page 2-25 shows the three input pins per clock source MUX at CCC location m.
- u = I/O pair number in the bank, starting at 00 from the northwest I/O bank and proceeding in a clockwise direction.
- x = P (Positive) or N (Negative) for differential pairs, or R (Regular single-ended) for the I/Os that support single-ended and voltage-referenced I/O standards only. U (Positive-LVDS only) or V (Negative-LVDS only) restrict the I/O differential pair from being selected as an LVPECL pair.
- w = D (Differential Pair), P (Pair), or S (Single-Ended). D (Differential Pair) if both members of the pair are bonded out to adjacent pins or are separated only by one GND or NC pin; P (Pair) if both members of the pair are bonded out but do not meet the adjacency requirement; or S (Single-Ended) if the I/O pair is not bonded out. For Differential (D) pairs, adjacency for ball grid packages means only vertical or horizontal. Diagonal adjacency does not meet the requirements for a true differential pair.
- B = Bank
- y = Bank number (0-3). The Bank number starts at 0 from the northwest I/O bank and proceeds in a clockwise direction.
- V = Reference voltage
- z = Minibank number

#### Standard I/O Bank



**Analog Quads** 

Figure 2-113 • Naming Conventions of Fusion Devices with Three Digital I/O Banks



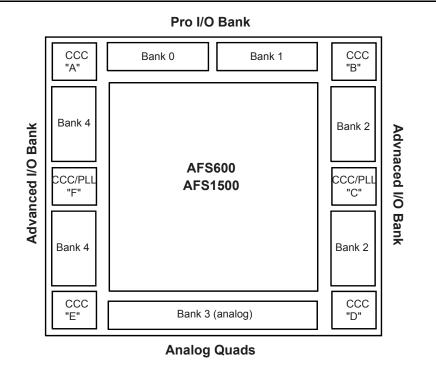


Figure 2-114 • Naming Conventions of Fusion Devices with Four I/O Banks

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### **User I/O Characteristics**

# **Timing Model**

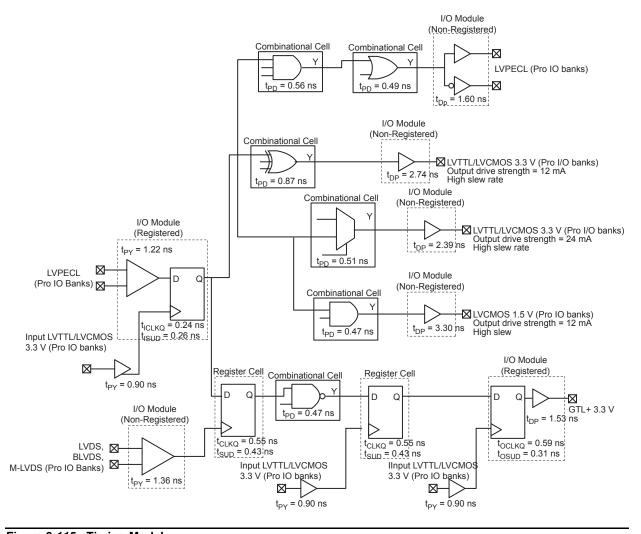
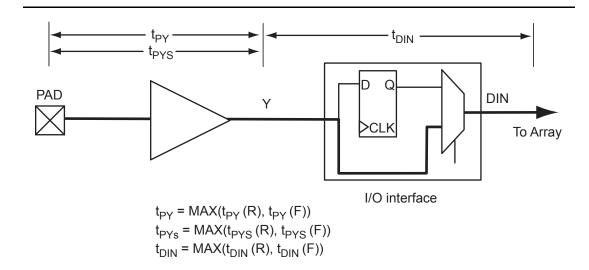


Figure 2-115 • Timing Model
Operating Conditions: –2 Speed, Commercial Temperature Range (T<sub>J</sub> = 70°C),
Worst-Case VCC = 1.425 V





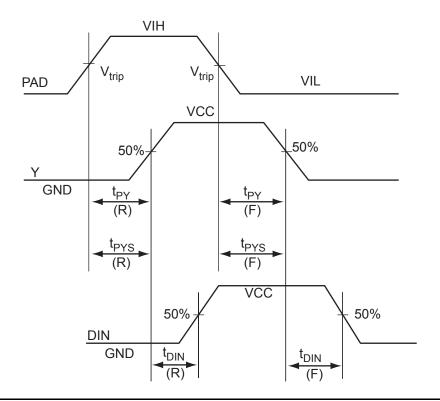


Figure 2-116 • Input Buffer Timing Model and Delays (example)

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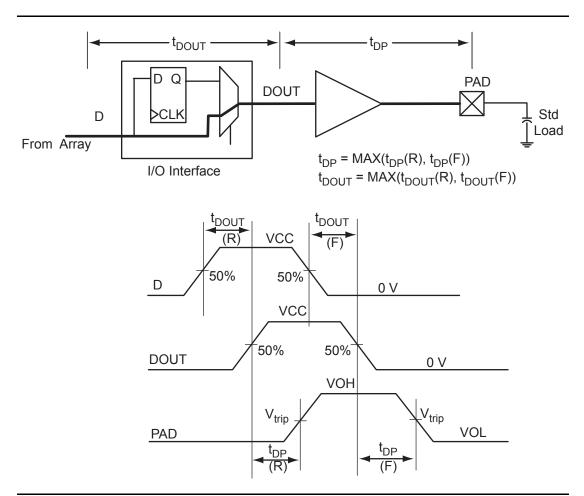


Figure 2-117 • Output Buffer Model and Delays (example)



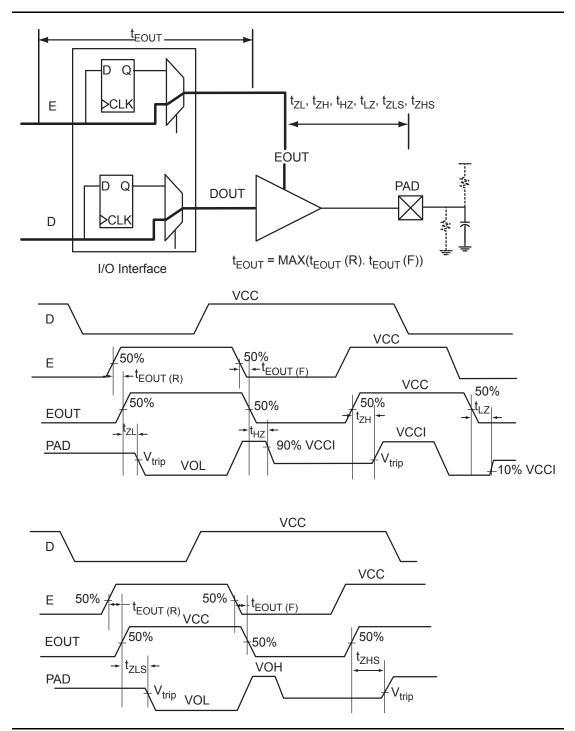


Figure 2-118 • Tristate Output Buffer Timing Model and Delays (example)

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### Overview of I/O Performance

### Summary of I/O DC Input and Output Levels – Default I/O Software Settings

Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions
Applicable to Pro I/Os

				VIL	VIH		VOL	VOH	IOL	ЮН
I/O Standard	Drive Strength	Slew Rate	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	High	-0.3	0.8	2	3.6	0.4	2.4	12	12
2.5 V LVCMOS	12 mA	High	-0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVCMOS	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12
1.5 V LVCMOS	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	12	12
3.3 V PCI			•		Per PCI Spec	ification				
3.3 V PCI-X					Per PCI-X Spe	cification				
3.3 V GTL	20 mA <sup>2</sup>	High	-0.3	VREF-0.05	VREF + 0.05	3.6	0.4	_	20	20
2.5 V GTL	20 mA <sup>2</sup>	High	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	_	20	20
3.3 V GTL+	35 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	_	35	35
2.5 V GTL+	33 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	_	33	33
HSTL (I)	8 mA	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	8	8
HSTL (II)	15 mA <sup>2</sup>	High	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	15	15
SSTL2 (I)	15 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.54	VCCI-0.62	15	15
SSTL2 (II)	18 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.35	VCCI-0.43	18	18
SSTL3 (I)	14 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.7	VCCI - 1.1	14	14
SSTL3 (II)	21 mA	High	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.5	VCCI - 0.9	21	21

#### Notes:

- 1. Currents are measured at 85°C junction temperature.
- 2. Output drive strength is below JEDEC specification.
- 3. Output slew rate can be extracted by the IBIS models.

Table 2-87 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions

Applicable to Advanced I/Os

				VIL	VIH		VOL	VOH	IOL	ЮН
I/O Standard	Drive Strength	Slew Rate	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	High	-0.3	0.8	2	3.6	0.4	2.4	12	12
2.5 V LVCMOS	12 mA	High	-0.3	0.7	1.7	2.7	0.7	1.7	12	12
1.8 V LVCMOS	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI-0.45	12	12
1.5 V LVCMOS	12 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	12	12
3.3 V PCI		•		Per PCI specifications						
3.3 V PCI-X				Р	er PCI-X spec	cification	ns			

Note: Currents are measured at 85°C junction temperature.



Table 2-88 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions

Applicable to Standard I/Os

				VIL	VIH		VOL	VOH	IOL	ЮН
I/O Standard	Drive Strength	Slew Rate	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	High	-0.3	0.8	2	3.6	0.4	2.4	8	8
2.5 V LVCMOS	8 mA	High	-0.3	0.7	1.7	3.6	0.7	1.7	8	8
1.8 V LVCMOS	4 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI-0.45	4	4
1.5 V LVCMOS	2 mA	High	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2

Note: Currents are measured at 85°C junction temperature.

Table 2-89 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions

Applicable to All I/O Bank Types

	Comr	mercial <sup>1</sup>	Indu	strial <sup>2</sup>
	IIL <sup>3</sup>	IIH <sup>4</sup>	IIL <sup>3</sup>	IIH <sup>4</sup>
DC I/O Standards	μΑ	μΑ	μΑ	μΑ
3.3 V LVTTL / 3.3 V LVCMOS	10	10	15	15
2.5 V LVCMOS	10	10	15	15
1.8 V LVCMOS	10	10	15	15
1.5 V LVCMOS	10	10	15	15
3.3 V PCI	10	10	15	15
3.3 V PCI-X	10	10	15	15
3.3 V GTL	10	10	15	15
2.5 V GTL	10	10	15	15
3.3 V GTL+	10	10	15	15
2.5 V GTL+	10	10	15	15
HSTL (I)	10	10	15	15
HSTL (II)	10	10	15	15
SSTL2 (I)	10	10	15	15
SSTL2 (II)	10	10	15	15
SSTL3 (I)	10	10	15	15
SSTL3 (II)	10	10	15	15

#### Notes:

- 1. Commercial range (0°C <  $T_J$  < 85°C)
- 2. Industrial range ( $-40^{\circ}$ C <  $T_J$  <  $100^{\circ}$ C)
- 3. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 4. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.

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# Summary of I/O Timing Characteristics – Default I/O Software Settings

Table 2-90 • Summary of AC Measuring Points
Applicable to All I/O Bank Types

Standard	Input Reference Voltage (VREF_TYP)	Board Termination Voltage (VTT_REF)	Measuring Trip Point (Vtrip)
3.3 V LVTTL / 3.3 V LVCMOS	_	-	1.4 V
2.5 V LVCMOS	-	-	1.2 V
1.8 V LVCMOS	-	-	0.90 V
1.5 V LVCMOS	-	-	0.75 V
3.3 V PCI	-	-	0.285 * VCCI (RR) 0.615 * VCCI (FF))
3.3 V PCI-X	-	-	0.285 * VCCI (RR) 0.615 * VCCI (FF)
3.3 V GTL	0.8 V	1.2 V	VREF
2.5 V GTL	0.8 V	1.2 V	VREF
3.3 V GTL+	1.0 V	1.5 V	VREF
2.5 V GTL+	1.0 V	1.5 V	VREF
HSTL (I)	0.75 V	0.75 V	VREF
HSTL (II)	0.75 V	0.75 V	VREF
SSTL2 (I)	1.25 V	1.25 V	VREF
SSTL2 (II)	1.25 V	1.25 V	VREF
SSTL3 (I)	1.5 V	1.485 V	VREF
SSTL3 (II)	1.5 V	1.485 V	VREF
LVDS	-	-	Cross point
LVPECL	-	-	Cross point

## Table 2-91 • I/O AC Parameter Definitions

Parameter	Definition
t <sub>DP</sub>	Data to Pad delay through the Output Buffer
t <sub>PY</sub>	Pad to Data delay through the Input Buffer with Schmitt trigger disabled
t <sub>DOUT</sub>	Data to Output Buffer delay through the I/O interface
t <sub>EOUT</sub>	Enable to Output Buffer Tristate Control delay through the I/O interface
t <sub>DIN</sub>	Input Buffer to Data delay through the I/O interface
t <sub>PYS</sub>	Pad to Data delay through the Input Buffer with Schmitt trigger enabled
t <sub>HZ</sub>	Enable to Pad delay through the Output Buffer—High to Z
t <sub>ZH</sub>	Enable to Pad delay through the Output Buffer—Z to High
t <sub>LZ</sub>	Enable to Pad delay through the Output Buffer—Low to Z
t <sub>ZL</sub>	Enable to Pad delay through the Output Buffer—Z to Low
t <sub>ZHS</sub>	Enable to Pad delay through the Output Buffer with delayed enable—Z to High
t <sub>ZLS</sub>	Enable to Pad delay through the Output Buffer with delayed enable—Z to Low



Table 2-92 • Summary of I/O Timing Characteristics – Software Default Settings
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = I/O Standard Dependent
Applicable to Pro I/Os

, , , ,	Applicable to FTO IIOS																
I/O Standard	Drive Strength (mA)	Slew Rate	Capacitive Load (pF)	External Resistor (Ohm)	t pour	фр	toin	фү	t <sub>PY</sub> S	<sup>t</sup> Eo∪T	t <sub>ZL</sub>	на	f <sub>L</sub> z	thz	tzLs	sнz <sub>1</sub>	Units
3.3 V LVTTL/ 3.3 V LVCMOS	12 mA	High	35	1	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81	ns
2.5 V LVCMOS	12 mA	High	35	-	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28	ns
1.8 V LVCMOS	12 mA	High	35	-	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98	ns
1.5 V LVCMOS	12 mA	High	35	_	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37	ns
3.3 V PCI	Per PCI spec	High	10	25 <sup>2</sup>	0.49	2.09	0.03	0.78	1.25	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns
3.3 V PCI-X	Per PCI-X spec	High	10	25 <sup>2</sup>	0.49	2.09	0.03	0.77	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns
3.3 V GTL	20 mA	High	10	25	0.49	1.55	0.03	2.19	_	0.32	1.52	1.55	0.00	0.00	3.19	3.22	ns
2.5 V GTL	20 mA	High	10	25	0.49	1.59	0.03	1.83	_	0.32	1.61	1.59	0.00	0.00	3.28	3.26	ns
3.3 V GTL+	35 mA	High	10	25	0.49	1.53	0.03	1.19	_	0.32	1.56	1.53	0.00	0.00	3.23	3.20	ns
2.5 V GTL+	33 mA	High	10	25	0.49	1.65	0.03	1.13	_	0.32	1.68	1.57	0.00	0.00	3.35	3.24	ns
HSTL (I)	8 mA	High	20	50	0.49	2.37	0.03	1.59	_	0.32	2.42	2.35	0.00	0.00	4.09	4.02	ns
HSTL (II)	15 mA	High	20	25	0.49	2.26	0.03	1.59	_	0.32	2.30	2.03	0.00	0.00	3.97	3.70	ns
SSTL2 (I)	17 mA	High	30	50	0.49	1.59	0.03	1.00	_	0.32	1.62	1.38	0.00	0.00	3.29	3.05	ns
SSTL2 (II)	21 mA	High	30	25	0.49	1.62	0.03	1.00	-	0.32	1.65	1.32	0.00	0.00	3.32	2.99	ns
SSTL3 (I)	16 mA	High	30	50	0.49	1.72	0.03	0.93	_	0.32	1.75	1.37	0.00	0.00	3.42	3.04	ns
SSTL3 (II)	24 mA	High	30	25	0.49	1.54	0.03	0.93	_	0.32	1.57	1.25	0.00	0.00	3.24	2.92	ns
LVDS	24 mA	High	_	ı	0.49	1.57	0.03	1.36	-	-	-	1	ı	_	-	_	ns
LVPECL	24 mA	High	_	-	0.49	1.60	0.03	1.22	_	_	_	_	_	_	_	_	ns

# Notes:

- 1. For specific junction temperature and voltage-supply levels, refer to Table 3-6 on page 3-7 for derating values.
- 2. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-123 on page 2-197 for connectivity. This resistor is not required during normal operation.

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Table 2-93 • Summary of I/O Timing Characteristics – Software Default Settings
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = I/O Standard Dependent
Applicable to Advanced I/Os

I/O Standard	Drive Strength (mA)	Slew Rate	Capacitive Load (pF)	External Resistor (Ohm)	tpour	top	t <sub>DIN</sub>	t <sub>р</sub> у	teour	tzL	tzн	tız	t <sub>HZ</sub>	tzıs	tzнs	Units
3.3 V LVTTL/ 3.3 V LVCMOS	12 mA	High	35 pF	-	0.49	2.64	0.03	0.90	0.32	2.69	2.11	2.40	2.68	4.36	3.78	ns
2.5 V LVCMOS	12 mA	High	35 pF	_	0.49	2.66	0.03	0.98	0.32	2.71	2.56	2.47	2.57	4.38	4.23	ns
1.8 V LVCMOS	12 mA	High	35 pF	_	0.49	2.64	0.03	0.91	0.32	2.69	2.27	2.76	3.05	4.36	3.94	ns
1.5 V LVCMOS	12 mA	High	35 pF	_	0.49	3.05	0.03	1.07	0.32	3.10	2.67	2.95	3.14	4.77	4.34	ns
3.3 V PCI	Per PCI spec	High	10 pF	25 <sup>2</sup>	0.49	2.00	0.03	0.65	0.32	2.04	1.46	2.40	2.68	3.71	3.13	ns
3.3 V PCI-X	Per PCI-X spec	High	10 pF	25 <sup>2</sup>	0.49	2.00	0.03	0.62	0.32	2.04	1.46	2.40	2.68	3.71	3.13	ns
LVDS	24 mA	High	_	-	0.49	1.37	0.03	1.20	N/A	N/A	N/A	N/A	N/A	N/A	N/A	ns
LVPECL	24 mA	High	_	-	0.49	1.34	0.03	1.05	N/A	N/A	N/A	N/A	N/A	N/A	N/A	ns

#### Notes:

- 1. For specific junction temperature and voltage-supply levels, refer to Table 3-6 on page 3-7 for derating values.
- 2. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-123 on page 2-197 for connectivity. This resistor is not required during normal operation.

Table 2-94 • Summary of I/O Timing Characteristics – Software Default Settings
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = I/O Standard Dependent
Applicable to Standard I/Os

I/O Standard	Drive Strength (mA)	Slew Rate	Capacitive Load (pF)	External Resistor (Ohm)	tpour	top	t <sub>DIN</sub>	tрү	teour	tzL	tzн	ţrz	ZHj	Units
3.3 V LVTTL/ 3.3 V LVCMOS	8 mA	High	35 pF	-	0.49	3.29	0.03	0.75	0.32	3.36	2.80	1.79	2.01	ns
2.5 V LVCMOS	8 mA	High	35pF	_	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns
1.8 V LVCMOS	4 mA	High	35pF	-	0.49	4.74	0.03	0.90	0.32	4.02	4.74	1.80	1.85	ns
1.5 V LVCMOS	2 mA	High	35pF	_	0.49	5.71	0.03	1.06	0.32	4.71	5.71	1.83	1.83	ns

Note: For specific junction temperature and voltage-supply levels, refer to Table 3-6 on page 3-7 for derating values.



# Detailed I/O DC Characteristics

Table 2-95 • Input Capacitance

Symbol	Definition	Conditions	Min.	Max.	Units
C <sub>IN</sub>	Input capacitance	VIN = 0, f = 1.0 MHz		8	pF
C <sub>INCLK</sub>	Input capacitance on the clock pin	VIN = 0, f = 1.0 MHz		8	pF

# Table 2-96 • I/O Output Buffer Maximum Resistances 1

Standard	Drive Strength	R <sub>PULL-DOWN</sub> (ohms) <sup>2</sup>	R <sub>PULL-UP</sub> (ohms) <sup>3</sup>
Applicable to Pro I/O Banks			1
3.3 V LVTTL / 3.3 V LVCMOS	4 mA	100	300
	8 mA	50	150
	12 mA	25	75
	16 mA	17	50
	24 mA	11	33
2.5 V LVCMOS	4 mA	100	200
	8 mA	50	100
	12 mA	25	50
	16 mA	20	40
	24 mA	11	22
1.8 V LVCMOS	2 mA	200	225
	4 mA	100	112
	6 mA	50	56
	8 mA	50	56
	12 mA	20	22
	16 mA	20	22
1.5 V LVCMOS	2 mA	200	224
	4 mA	100	112
	6 mA	67	75
	8 mA	33	37
	12 mA	33	37
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	25	75
3.3 V GTL	20 mA	11	-
2.5 V GTL	20 mA	14	-
3.3 V GTL+	35 mA	12	-
2.5 V GTL+	33 mA	15	-

# Notes:

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These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCC, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: http://www.microsemi.com/soc/techdocs/models/ibis.html.

<sup>2.</sup>  $R_{(PULL-DOWN-MAX)} = VOLspec / I_{OLspec}$ 

<sup>3.</sup> R<sub>(PULL-UP-MAX)</sub> = (VCCImax – VOHspec) / IOHspec



Table 2-96 • I/O Output Buffer Maximum Resistances <sup>1</sup> (continued)

Standard	Drive Strength	R <sub>PULL-DOWN</sub> (ohms) <sup>2</sup>	R <sub>PULL-UP</sub> (ohms) <sup>3</sup>
HSTL (I)	8 mA	50	50
HSTL (II)	15 mA	25	25
SSTL2 (I)	17 mA	27	31
SSTL2 (II)	21 mA	13	15
SSTL3 (I)	16 mA	44	69
SSTL3 (II)	24 mA	18	32
Applicable to Advanced I/O Ba	nks	I	
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	100	300
	4 mA	100	300
	6 mA	50	150
	8 mA	50	150
	12 mA	25	75
	16 mA	17	50
	24 mA	11	33
2.5 V LVCMOS	2 mA	100	200
	4 mA	100	200
	6 mA	50	100
	8 mA	50	100
	12 mA	25	50
	16 mA	20	40
	24 mA	11	22
1.8 V LVCMOS	2 mA	200	225
	4 mA	100	112
	6 mA	50	56
	8 mA	50	56
	12 mA	20	22
	16 mA	20	22
1.5 V LVCMOS	2 mA	200	224
	4 mA	100	112
	6 mA	67	75
	8 mA	33	37
	12 mA	33	37
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	25	75

## Notes:

- These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCC, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: http://www.microsemi.com/soc/techdocs/models/ibis.html.
- 2.  $R_{(PULL-DOWN-MAX)} = VOLspec / I_{OLspec}$
- 3. R<sub>(PULL-UP-MAX)</sub> = (VCCImax VOHspec) / IOHspec



Table 2-96 • I/O Output Buffer Maximum Resistances 1 (continued)

Standard	Drive Strength	R <sub>PULL-DOWN</sub> (ohms) <sup>2</sup>	R <sub>PULL-UP</sub> (ohms) <sup>3</sup>
Applicable to Standard I/O Banks			
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	100	300
	4 mA	100	300
	6 mA	50	150
	8 mA	50	150
2.5 V LVCMOS	2 mA	100	200
	4 mA	100	200
	6 mA	50	100
	8 mA	50	100
1.8 V LVCMOS	2 mA	200	225
	4 mA	100	112
1.5 V LVCMOS	2 mA	200	224

#### Notes:

- 2.  $R_{(PULL-DOWN-MAX)} = VOLspec / I_{OLspec}$
- 3.  $R_{(PULL-UP-MAX)} = (VCCImax VOHspec) / IOHspec$

Table 2-97 • I/O Weak Pull-Up/Pull-Down Resistances Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

	R <sub>(WEAK</sub>	PULL-UP) nms)	R <sub>(WEAK PULL-DOWN)</sub> <sup>2</sup> (ohms)		
VCCI	Min.	Max.	Min.	Max.	
3.3 V	10 k	45 k	10 k	45 k	
2.5 V	11 k	55 k	12 k	74 k	
1.8 V	18 k	70 k	17 k	110 k	
1.5 V	19 k	90 k	19 k	140 k	

## Notes:

- 1.  $R_{(WEAK\ PULL\ -UP\ -MAX)} = (VCCImax VOHspec) / I_{WEAK\ PULL\ -UP\ -MIN}$ 2.  $R_{(WEAK\ PULL\ -DOWN\ -MAX)} = VOLspec / I_{WEAK\ PULL\ -DOWN\ -MIN}$

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<sup>1.</sup> These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCC, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: http://www.microsemi.com/soc/techdocs/models/ibis.html.



Table 2-98 • I/O Short Currents IOSH/IOSL

	Drive Strength	IOSH (mA)*	IOSL (mA)*
Applicable to Pro I/O Banks			
3.3 V LVTTL / 3.3 V LVCMOS	4 mA	25	27
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181
2.5 V LVCMOS	4 mA	16	18
	8 mA	32	37
	12 mA	65	74
	16 mA	83	87
	24 mA	169	124
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
	6 mA	35	44
	8 mA	45	51
	12 mA	91	74
	16 mA	91	74
1.5 V LVCMOS	2 mA	13	16
	4 mA	25	33
	6 mA	32	39
	8 mA	66	55
	12 mA	66	55
Applicable to Advanced I/O Banks	}		
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181
3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181

Note:  $*T_J = 100$ °C



Table 2-98 • I/O Short Currents IOSH/IOSL (continued)

	Drive Strength	IOSH (mA)*	IOSL (mA)*
2.5 V LVCMOS	2 mA	16	18
	4 mA	16	18
	6 mA	32	37
	8 mA	32	37
	12 mA	65	74
	16 mA	83	87
	24 mA	169	124
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
	6 mA	35	44
	8 mA	45	51
	12 mA	91	74
	16 mA	91	74
1.5 V LVCMOS	2 mA	13	16
	4 mA	25	33
	6 mA	32	39
	8 mA	66	55
	12 mA	66	55
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	103	109
Applicable to Standard I/O Banks			
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	51	54
2.5 V LVCMOS	2 mA	16	18
	4 mA	16	18
	6 mA	32	37
	8 mA	32	37
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
1.5 V LVCMOS	2 mA	13	16

Note:  $*T_J = 100$ °C

The length of time an I/O can withstand IOSH/IOSL events depends on the junction temperature. The reliability data below is based on a 3.3 V, 36 mA I/O setting, which is the worst case for this type of analysis.

For example, at 100°C, the short current condition would have to be sustained for more than six months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

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#### Table 2-99 • Short Current Event Duration before Failure

Temperature	Time Before Failure
-40°C	>20 years
0°C	>20 years
25°C	>20 years
70°C	5 years
85°C	2 years
100°C	6 months

# Table 2-100 • Schmitt Trigger Input Hysteresis Hysteresis Voltage Value (typ.) for Schmitt Mode Input Buffers

Input Buffer Configuration	Hysteresis Value (typ.)
3.3 V LVTTL/LVCMOS/PCI/PCI-X (Schmitt trigger mode)	240 mV
2.5 V LVCMOS (Schmitt trigger mode)	140 mV
1.8 V LVCMOS (Schmitt trigger mode)	80 mV
1.5 V LVCMOS (Schmitt trigger mode)	60 mV

# Table 2-101 • I/O Input Rise Time, Fall Time, and Related I/O Reliability

Input Buffer	Input Rise/Fall Time (min.)	Input Rise/Fall Time (max.)	Reliability
LVTTL/LVCMOS (Schmitt trigger disabled)	No requirement	10 ns*	20 years (100°C)
LVTTL/LVCMOS (Schmitt trigger enabled)	No requirement	No requirement, but input noise voltage cannot exceed Schmitt hysteresis	20 years (100°C)
HSTL/SSTL/GTL	No requirement	10 ns*	10 years (100°C)
LVDS/BLVDS/M-LVDS/LVPECL	No requirement	10 ns*	10 years (100°C)

Note: \* The maximum input rise/fall time is related only to the noise induced into the input buffer trace. If the noise is low, the rise time and fall time of input buffers, when Schmitt trigger is disabled, can be increased beyond the maximum value. The longer the rise/fall times, the more susceptible the input signal is to the board noise. Microsemi recommends signal integrity evaluation/characterization of the system to ensure there is no excessive noise coupling into input signals.



# Single-Ended I/O Characteristics

# 3.3 V LVTTL / 3.3 V LVCMOS

Low-Voltage Transistor-Transistor Logic is a general-purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer. The 3.3 V LVCMOS standard is supported as part of the 3.3 V LVTTL support.

Table 2-102 • Minimum and Maximum DC Input and Output Levels

3.3 V LVTTL / 3.3 V LVCMOS	V	'IL	v	IH	VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
Applicable to P	ro I/O Ba	nks		•	•	•				•		
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	8.0	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	10	10
24 mA	-0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10
Applicable to A	dvanced	I/O Bank	S									
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	10	10
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	10	10
24 mA	-0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10
Applicable to S	tandard	/O Banks										
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	10	10
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10

## Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

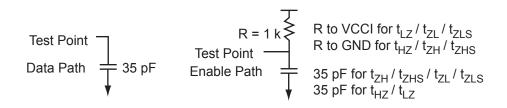


Figure 2-119 • AC Loading

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Table 2-103 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	1.4	-	35

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

## **Timing Characteristics**

Table 2-104 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V

Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
4 mA	Std.	0.66	11.01	0.04	1.20	1.57	0.43	11.21	9.05	2.69	2.44	13.45	11.29	ns
	-1	0.56	9.36	0.04	1.02	1.33	0.36	9.54	7.70	2.29	2.08	11.44	9.60	ns
	-2	0.49	8.22	0.03	0.90	1.17	0.32	8.37	6.76	2.01	1.82	10.04	8.43	ns
8 mA	Std.	0.66	7.86	0.04	1.20	1.57	0.43	8.01	6.44	3.04	3.06	10.24	8.68	ns
	-1	0.56	6.69	0.04	1.02	1.33	0.36	6.81	5.48	2.58	2.61	8.71	7.38	ns
	-2	0.49	5.87	0.03	0.90	1.17	0.32	5.98	4.81	2.27	2.29	7.65	6.48	ns
12 mA	Std.	0.66	6.03	0.04	1.20	1.57	0.43	6.14	5.02	3.28	3.47	8.37	7.26	ns
	-1	0.56	5.13	0.04	1.02	1.33	0.36	5.22	4.27	2.79	2.95	7.12	6.17	ns
	-2	0.49	4.50	0.03	0.90	1.17	0.32	4.58	3.75	2.45	2.59	6.25	5.42	ns
16 mA	Std.	0.66	5.62	0.04	1.20	1.57	0.43	5.72	4.72	3.32	3.58	7.96	6.96	ns
	-1	0.56	4.78	0.04	1.02	1.33	0.36	4.87	4.02	2.83	3.04	6.77	5.92	ns
	-2	0.49	4.20	0.03	0.90	1.17	0.32	4.27	3.53	2.48	2.67	5.94	5.20	ns
24 mA	Std.	0.66	5.24	0.04	1.20	1.57	0.43	5.34	4.69	3.39	3.96	7.58	6.93	ns
	-1	0.56	4.46	0.04	1.02	1.33	0.36	4.54	3.99	2.88	3.37	6.44	5.89	ns
	-2	0.49	3.92	0.03	0.90	1.17	0.32	3.99	3.50	2.53	2.96	5.66	5.17	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



Table 2-105 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V
Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOU</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
4 mA	Std.	0.66	7.88	0.04	1.20	1.57	0.43	8.03	6.70	2.69	2.59	10.26	8.94	ns
	-1	0.56	6.71	0.04	1.02	1.33	0.36	6.83	5.70	2.29	2.20	8.73	7.60	ns
	-2	0.49	5.89	0.03	0.90	1.17	0.32	6.00	5.01	2.01	1.93	7.67	6.67	ns
8 mA	Std.	0.66	5.08	0.04	1.20	1.57	0.43	5.17	4.14	3.05	3.21	7.41	6.38	ns
	-1	0.56	4.32	0.04	1.02	1.33	0.36	4.40	3.52	2.59	2.73	6.30	5.43	ns
	-2	0.49	3.79	0.03	0.90	1.17	0.32	3.86	3.09	2.28	2.40	5.53	4.76	ns
12 mA	Std.	0.66	3.67	0.04	1.20	1.57	0.43	3.74	2.87	3.28	3.61	5.97	5.11	ns
	-1	0.56	3.12	0.04	1.02	1.33	0.36	3.18	2.44	2.79	3.07	5.08	4.34	ns
	-2	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81	ns
16 mA	Std.	0.66	3.46	0.04	1.20	1.57	0.43	3.53	2.61	3.33	3.72	5.76	4.84	ns
	-1	0.56	2.95	0.04	1.02	1.33	0.36	3.00	2.22	2.83	3.17	4.90	4.12	ns
	-2	0.49	2.59	0.03	0.90	1.17	0.32	2.63	1.95	2.49	2.78	4.30	3.62	ns
24 mA	Std.	0.66	3.21	0.04	1.20	1.57	0.43	3.27	2.16	3.39	4.13	5.50	4.39	ns
	<b>–</b> 1	0.56	2.73	0.04	1.02	1.33	0.36	2.78	1.83	2.88	3.51	4.68	3.74	ns
	-2	0.49	2.39	0.03	0.90	1.17	0.32	2.44	1.61	2.53	3.08	4.11	3.28	ns

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Table 2-106 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V
Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zHS</sub>	Units
4 mA	Std.	0.66	10.26	0.04	1.20	0.43	10.45	8.90	2.64	2.46	12.68	11.13	ns
	-1	0.56	8.72	0.04	1.02	0.36	8.89	7.57	2.25	2.09	10.79	9.47	ns
	-2	0.49	7.66	0.03	0.90	0.32	7.80	6.64	1.98	1.83	9.47	8.31	ns
8 mA	Std.	0.66	7.27	0.04	1.20	0.43	7.41	6.28	2.98	3.04	9.65	8.52	ns
	-1	0.56	6.19	0.04	1.02	0.36	6.30	5.35	2.54	2.59	8.20	7.25	ns
	-2	0.49	5.43	0.03	0.90	0.32	5.53	4.69	2.23	2.27	7.20	6.36	ns
12 mA	Std.	0.66	5.58	0.04	1.20	0.43	5.68	4.87	3.21	3.42	7.92	7.11	ns
	-1	0.56	4.75	0.04	1.02	0.36	4.84	4.14	2.73	2.91	6.74	6.05	ns
	-2	0.49	4.17	0.03	0.90	0.32	4.24	3.64	2.39	2.55	5.91	5.31	ns
16 mA	Std.	0.66	5.21	0.04	1.20	0.43	5.30	4.56	3.26	3.51	7.54	6.80	ns
	-1	0.56	4.43	0.04	1.02	0.36	4.51	3.88	2.77	2.99	6.41	5.79	ns
	-2	0.49	3.89	0.03	0.90	0.32	3.96	3.41	2.43	2.62	5.63	5.08	ns
24 mA	Std.	0.66	4.85	0.04	1.20	0.43	4.94	4.54	3.32	3.88	7.18	6.78	ns
	-1	0.56	4.13	0.04	1.02	0.36	4.20	3.87	2.82	3.30	6.10	5.77	ns
	-2	0.49	3.62	0.03	0.90	0.32	3.69	3.39	2.48	2.90	5.36	5.06	ns



Table 2-107 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V
Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
4 mA	Std.	0.66	7.66	0.04	1.20	0.43	7.80	6.59	2.65	2.61	10.03	8.82	ns
	-1	0.56	6.51	0.04	1.02	0.36	6.63	5.60	2.25	2.22	8.54	7.51	ns
	-2	0.49	5.72	0.03	0.90	0.32	5.82	4.92	1.98	1.95	7.49	6.59	ns
8 mA	Std.	0.66	4.91	0.04	1.20	0.43	5.00	4.07	2.99	3.20	7.23	6.31	ns
	-1	0.56	4.17	0.04	1.02	0.36	4.25	3.46	2.54	2.73	6.15	5.36	ns
	-2	0.49	3.66	0.03	0.90	0.32	3.73	3.04	2.23	2.39	5.40	4.71	ns
12 mA	Std.	0.66	3.53	0.04	1.20	0.43	3.60	2.82	3.21	3.58	5.83	5.06	ns
	<b>–</b> 1	0.56	3.00	0.04	1.02	0.36	3.06	2.40	2.73	3.05	4.96	4.30	ns
	-2	0.49	2.64	0.03	0.90	0.32	2.69	2.11	2.40	2.68	4.36	3.78	ns
16 mA	Std.	0.66	3.33	0.04	1.20	0.43	3.39	2.56	3.26	3.68	5.63	4.80	ns
	<b>–</b> 1	0.56	2.83	0.04	1.02	0.36	2.89	2.18	2.77	3.13	4.79	4.08	ns
	-2	0.49	2.49	0.03	0.90	0.32	2.53	1.91	2.44	2.75	4.20	3.58	ns
24 mA	Std.	0.66	3.08	0.04	1.20	0.43	3.13	2.12	3.32	4.06	5.37	4.35	ns
	<b>–1</b>	0.56	2.62	0.04	1.02	0.36	2.66	1.80	2.83	3.45	4.57	3.70	ns
	-2	0.49	2.30	0.03	0.90	0.32	2.34	1.58	2.48	3.03	4.01	3.25	ns

Table 2-108 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V
Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	9.46	0.04	1.00	0.43	9.64	8.54	2.07	2.04	ns
	-1	0.56	8.05	0.04	0.85	0.36	8.20	7.27	1.76	1.73	ns
	-2	0.49	7.07	0.03	0.75	0.32	7.20	6.38	1.55	1.52	ns
4 mA	Std.	0.66	9.46	0.04	1.00	0.43	9.64	8.54	2.07	2.04	ns
	-1	0.56	8.05	0.04	0.85	0.36	8.20	7.27	1.76	1.73	ns
	-2	0.49	7.07	0.03	0.75	0.32	7.20	6.38	1.55	1.52	ns
6 mA	Std.	0.66	6.57	0.04	1.00	0.43	6.69	5.98	2.40	2.57	ns
	-1	0.56	5.59	0.04	0.85	0.36	5.69	5.09	2.04	2.19	ns
	-2	0.49	4.91	0.03	0.75	0.32	5.00	4.47	1.79	1.92	ns
8 mA	Std.	0.66	6.57	0.04	1.00	0.43	6.69	5.98	2.40	2.57	ns
	-1	0.56	5.59	0.04	0.85	0.36	5.69	5.09	2.04	2.19	ns
	-2	0.49	4.91	0.03	0.75	0.32	5.00	4.47	1.79	1.92	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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Table 2-109 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V
Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zh</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	7.07	0.04	1.00	0.43	7.20	6.23	2.07	2.15	ns
	-1	0.56	6.01	0.04	0.85	0.36	6.12	5.30	1.76	1.83	ns
	-2 <sup>2</sup>	0.49	5.28	0.03	0.75	0.32	5.37	4.65	1.55	1.60	ns
4 mA	Std.	0.66	7.07	0.04	1.00	0.43	7.20	6.23	2.07	2.15	ns
	-1	0.56	6.01	0.04	0.85	0.36	6.12	5.30	1.76	1.83	ns
	-2	0.49	5.28	0.03	0.75	0.32	5.37	4.65	1.55	1.60	ns
6 mA	Std.	0.66	4.41	0.04	1.00	0.43	4.49	3.75	2.39	2.69	ns
	-1	0.56	3.75	0.04	0.85	0.36	3.82	3.19	2.04	2.29	ns
	-2	0.49	3.29	0.03	0.75	0.32	3.36	2.80	1.79	2.01	ns
8 mA	Std.	0.66	4.41	0.04	1.00	0.43	4.49	3.75	2.39	2.69	ns
	-1	0.56	3.75	0.04	0.85	0.36	3.82	3.19	2.04	2.29	ns
	-2	0.49	3.29	0.03	0.75	0.32	3.36	2.80	1.79	2.01	ns



## 2.5 V LVCMOS

Low-Voltage CMOS for 2.5 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 2.5 V applications.

Table 2-110 • Minimum and Maximum DC Input and Output Levels

2.5 V LVCMOS	v	IL	v	TH .	VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
Applicable to	Pro I/O Ba	nks										
4 mA	-0.3	0.7	1.7	3.6	0.7	1.7	4	4	18	16	10	10
8 mA	-0.3	0.7	1.7	3.6	0.7	1.7	8	8	37	32	10	10
12 mA	-0.3	0.7	1.7	3.6	0.7	1.7	12	12	74	65	10	10
16 mA	-0.3	0.7	1.7	3.6	0.7	1.7	16	16	87	83	10	10
24 mA	-0.3	0.7	1.7	3.6	0.7	1.7	24	24	124	169	10	10
Applicable to	Advanced	I/O Bank	s	•	•	•				•		
2 mA	-0.3	0.7	1.7	2.7	0.7	1.7	2	2	18	16	10	10
4 mA	-0.3	0.7	1.7	2.7	0.7	1.7	4	4	18	16	10	10
6 mA	-0.3	0.7	1.7	2.7	0.7	1.7	6	6	37	32	10	10
8 mA	-0.3	0.7	1.7	2.7	0.7	1.7	8	8	37	32	10	10
12 mA	-0.3	0.7	1.7	2.7	0.7	1.7	12	12	74	65	10	10
16 mA	-0.3	0.7	1.7	2.7	0.7	1.7	16	16	87	83	10	10
24 mA	-0.3	0.7	1.7	2.7	0.7	1.7	24	24	124	169	10	10
Applicable to	Standard	I/O Banks	,						L	<b>.</b>		
2 mA	-0.3	0.7	1.7	3.6	0.7	1.7	2	2	18	16	10	10
4 mA	-0.3	0.7	1.7	3.6	0.7	1.7	4	4	18	16	10	10
6 mA	-0.3	0.7	1.7	3.6	0.7	1.7	6	6	37	32	10	10
8 mA	-0.3	0.7	1.7	3.6	0.7	1.7	8	8	37	32	10	10
Motor												

### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

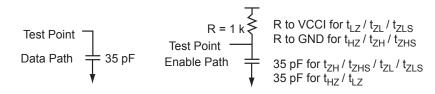


Figure 2-120 • AC Loading

Table 2-111 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	2.5	1.2	_	35

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

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# **Timing Characteristics**

# Table 2-112 • 2.5 V LVCMOS Low Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V Applicable to Pro I/Os

Drive	Speed													
Strength	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	$t_{ZL}$	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.60	12.00	0.04	1.51	1.66	0.43	12.23	11.61	2.72	2.20	14.46	13.85	ns
	-1	0.51	10.21	0.04	1.29	1.41	0.36	10.40	9.88	2.31	1.87	12.30	11.78	ns
	-2	0.45	8.96	0.03	1.13	1.24	0.32	9.13	8.67	2.03	1.64	10.80	10.34	ns
8 mA	Std.	0.60	8.73	0.04	1.51	1.66	0.43	8.89	8.01	3.10	2.93	11.13	10.25	ns
	-1	0.51	7.43	0.04	1.29	1.41	0.36	7.57	6.82	2.64	2.49	9.47	8.72	ns
	-2	0.45	6.52	0.03	1.13	1.24	0.32	6.64	5.98	2.32	2.19	8.31	7.65	ns
12 mA	Std.	0.66	6.77	0.04	1.51	1.66	0.43	6.90	6.11	3.37	3.39	9.14	8.34	ns
	-1	0.56	5.76	0.04	1.29	1.41	0.36	5.87	5.20	2.86	2.89	7.77	7.10	ns
	-2	0.49	5.06	0.03	1.13	1.24	0.32	5.15	4.56	2.51	2.53	6.82	6.23	ns
16 mA	Std.	0.66	6.31	0.04	1.51	1.66	0.43	6.42	5.73	3.42	3.52	8.66	7.96	ns
	-1	0.56	5.37	0.04	1.29	1.41	0.36	5.46	4.87	2.91	3.00	7.37	6.77	ns
	-2	0.49	4.71	0.03	1.13	1.24	0.32	4.80	4.28	2.56	2.63	6.47	5.95	ns
24 mA	Std.	0.66	5.93	0.04	1.51	1.66	0.43	6.04	5.70	3.49	4.00	8.28	7.94	ns
	-1	0.56	5.05	0.04	1.29	1.41	0.36	5.14	4.85	2.97	3.40	7.04	6.75	ns
	-2	0.49	4.43	0.03	1.13	1.24	0.32	4.51	4.26	2.61	2.99	6.18	5.93	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



Table 2-113 • 2.5 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V
Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.60	8.82	0.04	1.51	1.66	0.43	8.13	8.82	2.72	2.29	10.37	11.05	ns
	-1	0.51	7.50	0.04	1.29	1.41	0.36	6.92	7.50	2.31	1.95	8.82	9.40	ns
	-2	0.45	6.58	0.03	1.13	1.24	0.32	6.07	6.58	2.03	1.71	7.74	8.25	ns
8 mA	Std.	0.60	5.27	0.04	1.51	1.66	0.43	5.27	5.27	3.10	3.03	7.50	7.51	ns
	-1	0.51	4.48	0.04	1.29	1.41	0.36	4.48	4.48	2.64	2.58	6.38	6.38	ns
	-2	0.45	3.94	0.03	1.13	1.24	0.32	3.93	3.94	2.32	2.26	5.60	5.61	ns
12 mA	Std.	0.66	3.74	0.04	1.51	1.66	0.43	3.81	3.49	3.37	3.49	6.05	5.73	ns
	<b>–</b> 1	0.56	3.18	0.04	1.29	1.41	0.36	3.24	2.97	2.86	2.97	5.15	4.87	ns
	-2	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28	ns
16 mA	Std.	0.66	3.53	0.04	1.51	1.66	0.43	3.59	3.12	3.42	3.62	5.83	5.35	ns
	-1	0.56	3.00	0.04	1.29	1.41	0.36	3.06	2.65	2.91	3.08	4.96	4.55	ns
	-2	0.49	2.63	0.03	1.13	1.24	0.32	2.68	2.33	2.56	2.71	4.35	4.00	ns
24 mA	Std.	0.66	3.26	0.04	1.51	1.66	0.43	3.32	2.48	3.49	4.11	5.56	4.72	ns
	-1	0.56	2.77	0.04	1.29	1.41	0.36	2.83	2.11	2.97	3.49	4.73	4.01	ns
	-2	0.49	2.44	0.03	1.13	1.24	0.32	2.48	1.85	2.61	3.07	4.15	3.52	ns

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Table 2-114 • 2.5 V LVCMOS Low Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V
Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
4 mA	Std.	0.66	11.40	0.04	1.31	0.43	11.22	11.40	2.68	2.20	13.45	13.63	ns
	-1	0.56	9.69	0.04	1.11	0.36	9.54	9.69	2.28	1.88	11.44	11.60	ns
	-2	0.49	8.51	0.03	0.98	0.32	8.38	8.51	2.00	1.65	10.05	10.18	ns
8 mA	Std.	0.66	7.96	0.04	1.31	0.43	8.11	7.81	3.05	2.89	10.34	10.05	ns
	-1	0.56	6.77	0.04	1.11	0.36	6.90	6.65	2.59	2.46	8.80	8.55	ns
	-2	0.49	5.94	0.03	0.98	0.32	6.05	5.84	2.28	2.16	7.72	7.50	ns
12 mA	Std.	0.66	6.18	0.04	1.31	0.43	6.29	5.92	3.30	3.32	8.53	8.15	ns
	-1	0.56	5.26	0.04	1.11	0.36	5.35	5.03	2.81	2.83	7.26	6.94	ns
	-2	0.49	4.61	0.03	0.98	0.32	4.70	4.42	2.47	2.48	6.37	6.09	ns
16 mA	Std.	0.66	6.18	0.04	1.31	0.43	6.29	5.92	3.30	3.32	8.53	8.15	ns
	-1	0.56	5.26	0.04	1.11	0.36	5.35	5.03	2.81	2.83	7.26	6.94	ns
	-2	0.49	4.61	0.03	0.98	0.32	4.70	4.42	2.47	2.48	6.37	6.09	ns
24 mA	Std.	0.66	6.18	0.04	1.31	0.43	6.29	5.92	3.30	3.32	8.53	8.15	ns
	-1	0.56	5.26	0.04	1.11	0.36	5.35	5.03	2.81	2.83	7.26	6.94	ns
	-2	0.49	4.61	0.03	0.98	0.32	4.70	4.42	2.47	2.48	6.37	6.09	ns



Table 2-115 • 2.5 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V
Applicable to Advanced I/Os

Drive Strongth	Speed		4							٠	4		Units
Strength	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	tzLS	tzHS	Ullits
4 mA	Std.	0.66	8.66	0.04	1.31	0.43	7.83	8.66	2.68	2.30	10.07	10.90	ns
	-1	0.56	7.37	0.04	1.11	0.36	6.66	7.37	2.28	1.96	8.56	9.27	ns
	-2	0.49	6.47	0.03	0.98	0.32	5.85	6.47	2.00	1.72	7.52	8.14	ns
8 mA	Std.	0.66	5.17	0.04	1.31	0.43	5.04	5.17	3.05	3.00	7.27	7.40	ns
	-1	0.56	4.39	0.04	1.11	0.36	4.28	4.39	2.59	2.55	6.19	6.30	ns
	-2	0.49	3.86	0.03	0.98	0.32	3.76	3.86	2.28	2.24	5.43	5.53	ns
12 mA	Std.	0.66	3.56	0.04	1.31	0.43	3.63	3.43	3.30	3.44	5.86	5.67	ns
	-1	0.56	3.03	0.04	1.11	0.36	3.08	2.92	2.81	2.92	4.99	4.82	ns
	-2	0.49	2.66	0.03	0.98	0.32	2.71	2.56	2.47	2.57	4.38	4.23	ns
16 mA	Std.	0.66	3.35	0.04	1.31	0.43	3.41	3.06	3.36	3.55	5.65	5.30	ns
	-1	0.56	2.85	0.04	1.11	0.36	2.90	2.60	2.86	3.02	4.81	4.51	ns
	-2	0.49	2.50	0.03	0.98	0.32	2.55	2.29	2.51	2.65	4.22	3.96	ns
24 mA	Std.	0.66	3.56	0.04	1.31	0.43	3.63	3.43	3.30	3.44	5.86	5.67	ns
	-1	0.56	3.03	0.04	1.11	0.36	3.08	2.92	2.81	2.92	4.99	4.82	ns
	-2	0.49	2.66	0.03	0.98	0.32	2.71	2.56	2.47	2.57	4.38	4.23	ns

Table 2-116 • 2.5 V LVCMOS Low Slew

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,

Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	11.00	0.04	1.29	0.43	10.37	11.00	2.03	1.83	ns
	<b>–</b> 1	0.56	9.35	0.04	1.10	0.36	8.83	9.35	1.73	1.56	ns
	-2	0.49	8.21	0.03	0.96	0.32	7.75	8.21	1.52	1.37	ns
4 mA	Std.	0.66	11.00	0.04	1.29	0.43	10.37	11.00	2.03	1.83	ns
	<b>–</b> 1	0.56	9.35	0.04	1.10	0.36	8.83	9.35	1.73	1.56	ns
	-2	0.49	8.21	0.03	0.96	0.32	7.75	8.21	1.52	1.37	ns
6 mA	Std.	0.66	7.50	0.04	1.29	0.43	7.36	7.50	2.39	2.46	ns
	<b>–</b> 1	0.56	6.38	0.04	1.10	0.36	6.26	6.38	2.03	2.10	ns
	-2	0.49	5.60	0.03	0.96	0.32	5.49	5.60	1.78	1.84	ns
8 mA	Std.	0.66	7.50	0.04	1.29	0.43	7.36	7.50	2.39	2.46	ns
	<b>–</b> 1	0.56	6.38	0.04	1.10	0.36	6.26	6.38	2.03	2.10	ns
	-2	0.49	5.60	0.03	0.96	0.32	5.49	5.60	1.78	1.84	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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Applicable to Standard I/Os



Table 2-117 • 2.5 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 2.3 V
Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	-1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
4 mA	Std.	0.66	8.20	0.04	1.29	0.43	7.24	8.20	2.03	1.91	ns
	-1	0.56	6.98	0.04	1.10	0.36	6.16	6.98	1.73	1.62	ns
	-2	0.49	6.13	0.03	0.96	0.32	5.41	6.13	1.52	1.43	ns
6 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns
8 mA	Std.	0.66	4.77	0.04	1.29	0.43	4.55	4.77	2.38	2.55	ns
	-1	0.56	4.05	0.04	1.10	0.36	3.87	4.05	2.03	2.17	ns
	-2	0.49	3.56	0.03	0.96	0.32	3.40	3.56	1.78	1.91	ns



## 1.8 V LVCMOS

Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and push-pull output buffer.

Table 2-118 • Minimum and Maximum DC Input and Output Levels

1.8 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
Applicable	to Pro I/0	O Banks									•	
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4	22	17	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	6	6	44	35	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	8	8	51	45	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI-0.45	12	12	74	91	10	10
16 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	16	16	74	91	10	10
Applicable	to Advar	nced I/O Bank	(S							•	•	
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI - 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI - 0.45	4	4	22	17	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI - 0.45	6	6	44	35	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI - 0.45	8	8	51	45	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI-0.45	12	12	74	91	10	10
16 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI - 0.45	16	16	74	91	10	10
Applicable	to Stand	ard I/O Banks	S		•	•				_		
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI-0.45	4	4	22	17	10	10
Notes:												

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

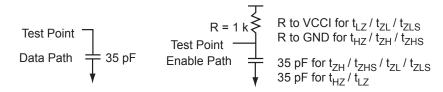


Figure 2-121 • AC Loading

Table 2-119 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input Low (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.8	0.9	_	35

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

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# **Timing Characteristics**

Table 2-120 • 1.8 V LVCMOS Low Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	15.84	0.04	1.45	1.91	0.43	15.65	15.84	2.78	1.58	17.89	18.07	ns
	<b>–1</b>	0.56	13.47	0.04	1.23	1.62	0.36	13.31	13.47	2.37	1.35	15.22	15.37	ns
	-2	0.49	11.83	0.03	1.08	1.42	0.32	11.69	11.83	2.08	1.18	13.36	13.50	ns
4 mA	Std.	0.66	11.39	0.04	1.45	1.91	0.43	11.60	10.76	3.26	2.77	13.84	12.99	ns
	-1	0.56	9.69	0.04	1.23	1.62	0.36	9.87	9.15	2.77	2.36	11.77	11.05	ns
	-2	0.49	8.51	0.03	1.08	1.42	0.32	8.66	8.03	2.43	2.07	10.33	9.70	ns
8 mA	Std.	0.66	8.97	0.04	1.45	1.91	0.43	9.14	8.10	3.57	3.36	11.37	10.33	ns
	<b>–1</b>	0.56	7.63	0.04	1.23	1.62	0.36	7.77	6.89	3.04	2.86	9.67	8.79	ns
	-2	0.49	6.70	0.03	1.08	1.42	0.32	6.82	6.05	2.66	2.51	8.49	7.72	ns
12 mA	Std.	0.66	8.35	0.04	1.45	1.91	0.43	8.50	7.59	3.64	3.52	10.74	9.82	ns
	-1	0.56	7.10	0.04	1.23	1.62	0.36	7.23	6.45	3.10	3.00	9.14	8.35	ns
	-2	0.49	6.24	0.03	1.08	1.42	0.32	6.35	5.66	2.72	2.63	8.02	7.33	ns
16 mA	Std.	0.66	7.94	0.04	1.45	1.91	0.43	8.09	7.56	3.74	4.11	10.32	9.80	ns
	-1	0.56	6.75	0.04	1.23	1.62	0.36	6.88	6.43	3.18	3.49	8.78	8.33	ns
	-2	0.49	5.93	0.03	1.08	1.42	0.32	6.04	5.65	2.79	3.07	7.71	7.32	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



Table 2-121 • 1.8 V LVCMOS High Slew
Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 1.7 V
Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
2 mA	Std.	0.66	12.10	0.04	1.45	1.91	0.43	9.59	12.10	2.78	1.64	11.83	14.34	ns
	-1	0.56	10.30	0.04	1.23	1.62	0.36	8.16	10.30	2.37	1.39	10.06	12.20	ns
	-2	0.49	9.04	0.03	1.08	1.42	0.32	7.16	9.04	2.08	1.22	8.83	10.71	ns
4 mA	Std.	0.66	7.05	0.04	1.45	1.91	0.43	6.20	7.05	3.25	2.86	8.44	9.29	ns
	-1	0.56	6.00	0.04	1.23	1.62	0.36	5.28	6.00	2.76	2.44	7.18	7.90	ns
	-2	0.49	5.27	0.03	1.08	1.42	0.32	4.63	5.27	2.43	2.14	6.30	6.94	ns
8 mA	Std.	0.66	4.52	0.04	1.45	1.91	0.43	4.47	4.52	3.57	3.47	6.70	6.76	ns
	<b>-</b> 1	0.56	3.85	0.04	1.23	1.62	0.36	3.80	3.85	3.04	2.95	5.70	5.75	ns
	-2	0.49	3.38	0.03	1.08	1.42	0.32	3.33	3.38	2.66	2.59	5.00	5.05	ns
12 mA	Std.	0.66	4.12	0.04	1.45	1.91	0.43	4.20	3.99	3.63	3.62	6.43	6.23	ns
	-1	0.56	3.51	0.04	1.23	1.62	0.36	3.57	3.40	3.09	3.08	5.47	5.30	ns
	-2	0.49	3.08	0.03	1.08	1.42	0.32	3.14	2.98	2.71	2.71	4.81	4.65	ns
16 mA	Std.	0.66	3.80	0.04	1.45	1.91	0.43	3.87	3.09	3.73	4.24	6.10	5.32	ns
	-1	0.56	3.23	0.04	1.23	1.62	0.36	3.29	2.63	3.18	3.60	5.19	4.53	ns
	-2	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98	ns

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Table 2-122 • 1.8 V LVCMOS Low Slew Commercial Temperature Range Conditions:  $T_J = 70^{\circ}\text{C}$ , Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V

Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
2 mA	Std.	0.66	15.53	0.04	1.31	0.43	14.11	15.53	2.78	1.60	16.35	17.77	ns
	-1	0.56	13.21	0.04	1.11	0.36	12.01	13.21	2.36	1.36	13.91	15.11	ns
	-2 <sup>2</sup>	0.49	11.60	0.03	0.98	0.32	10.54	11.60	2.07	1.19	12.21	13.27	ns
4 mA	Std.	0.66	10.48	0.04	1.31	0.43	10.41	10.48	3.23	2.73	12.65	12.71	ns
	-1	0.56	8.91	0.04	1.11	0.36	8.86	8.91	2.75	2.33	10.76	10.81	ns
	-2	0.49	7.82	0.03	0.98	0.32	7.77	7.82	2.41	2.04	9.44	9.49	ns
8 mA	Std.	0.66	8.05	0.04	1.31	0.43	8.20	7.84	3.54	3.27	10.43	10.08	ns
	-1	0.56	6.85	0.04	1.11	0.36	6.97	6.67	3.01	2.78	8.88	8.57	ns
	-2	0.49	6.01	0.03	0.98	0.32	6.12	5.86	2.64	2.44	7.79	7.53	ns
12 mA	Std.	0.66	7.50	0.04	1.31	0.43	7.64	7.30	3.61	3.41	9.88	9.53	ns
	-1	0.56	6.38	0.04	1.11	0.36	6.50	6.21	3.07	2.90	8.40	8.11	ns
	-2	0.49	5.60	0.03	0.98	0.32	5.71	5.45	2.69	2.55	7.38	7.12	ns
16 mA	Std.	0.66	7.29	0.04	1.31	0.43	7.23	7.29	3.71	3.95	9.47	9.53	ns
	-1	0.56	6.20	0.04	1.11	0.36	6.15	6.20	3.15	3.36	8.06	8.11	ns
	-2	0.49	5.45	0.03	0.98	0.32	5.40	5.45	2.77	2.95	7.07	7.12	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



Table 2-123 • 1.8 V LVCMOS High Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	11.86	0.04	1.22	0.43	9.14	11.86	2.77	1.66	11.37	14.10	ns
	-1	0.56	10.09	0.04	1.04	0.36	7.77	10.09	2.36	1.41	9.67	11.99	ns
	-2	0.49	8.86	0.03	0.91	0.32	6.82	8.86	2.07	1.24	8.49	10.53	ns
4 mA	Std.	0.66	6.91	0.04	1.22	0.43	5.86	6.91	3.22	2.84	8.10	9.15	ns
	<b>–1</b>	0.56	5.88	0.04	1.04	0.36	4.99	5.88	2.74	2.41	6.89	7.78	ns
	-2	0.49	5.16	0.03	0.91	0.32	4.38	5.16	2.41	2.12	6.05	6.83	ns
8 mA	Std.	0.66	4.45	0.04	1.22	0.43	4.18	4.45	3.53	3.38	6.42	6.68	ns
	<b>–1</b>	0.56	3.78	0.04	1.04	0.36	3.56	3.78	3.00	2.88	5.46	5.69	ns
	-2	0.49	3.32	0.03	0.91	0.32	3.12	3.32	2.64	2.53	4.79	4.99	ns
12 mA	Std.	0.66	3.92	0.04	1.22	0.43	3.93	3.92	3.60	3.52	6.16	6.16	ns
	-1	0.56	3.34	0.04	1.04	0.36	3.34	3.34	3.06	3.00	5.24	5.24	ns
	-2	0.49	2.93	0.03	0.91	0.32	2.93	2.93	2.69	2.63	4.60	4.60	ns
16 mA	Std.	0.66	3.53	0.04	1.22	0.43	3.60	3.04	3.70	4.08	5.84	5.28	ns
	<b>–</b> 1	0.56	3.01	0.04	1.04	0.36	3.06	2.59	3.15	3.47	4.96	4.49	ns
	-2	0.49	2.64	0.03	0.91	0.32	2.69	2.27	2.76	3.05	4.36	3.94	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Table 2-124 • 1.8 V LVCMOS Low Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	15.01	0.04	1.20	0.43	13.15	15.01	1.99	1.99	ns
	-1	0.56	12.77	0.04	1.02	0.36	11.19	12.77	1.70	1.70	ns
	-2	0.49	11.21	0.03	0.90	0.32	9.82	11.21	1.49	1.49	ns
4 mA	Std.	0.66	10.10	0.04	1.20	0.43	9.55	10.10	2.41	2.37	ns
	<b>–</b> 1	0.56	8.59	0.04	1.02	0.36	8.13	8.59	2.05	2.02	ns
	-2	0.49	7.54	0.03	0.90	0.32	7.13	7.54	1.80	1.77	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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Table 2-125 • 1.8 V LVCMOS High Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	11.21	0.04	1.20	0.43	8.53	11.21	1.99	1.21	ns
	-1	0.56	9.54	0.04	1.02	0.36	7.26	9.54	1.69	1.03	ns
	-2	0.49	8.37	0.03	0.90	0.32	6.37	8.37	1.49	0.90	ns
4 mA	Std.	0.66	6.34	0.04	1.20	0.43	5.38	6.34	2.41	2.48	ns
	-1	0.56	5.40	0.04	1.02	0.36	4.58	5.40	2.05	2.11	ns
	-2	0.49	4.74	0.03	0.90	0.32	4.02	4.74	1.80	1.85	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



## 1.5 V LVCMOS (JESD8-11)

Low-Voltage CMOS for 1.5 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.5 V applications. It uses a 1.5 V input buffer and push-pull output buffer.

Table 2-126 • Minimum and Maximum DC Input and Output Levels

1.5 V LVCMOS		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	юзн	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
Applicable	to Pro I	/O Banks										
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2	16	13	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	4	4	33	25	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	6	6	39	32	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	8	8	55	66	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	12	12	55	66	10	10
Applicable	to Adva	nced I/O Ban	ks									
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	2	2	16	13	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	4	4	33	25	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	6	6	39	32	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	8	8	55	66	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	1.575	0.25 * VCCI	0.75 * VCCI	12	12	55	66	10	10
Applicable	to Pro I	/O Banks										
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2	16	13	10	10
Notes:												

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. I<sub>IH</sub> is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

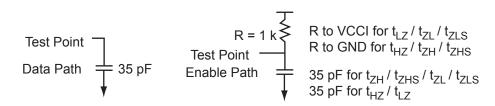


Figure 2-122 • AC Loading

Table 2-127 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	1.5	0.75	_	35

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

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## **Timing Characteristics**

Table 2-128 • 1.5 V LVCMOS Low Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	14.11	0.04	1.70	2.14	0.43	14.37	13.14	3.40	2.68	16.61	15.37	ns
	-1	0.56	12.00	0.04	1.44	1.82	0.36	12.22	11.17	2.90	2.28	14.13	13.08	ns
	-2	0.49	10.54	0.03	1.27	1.60	0.32	10.73	9.81	2.54	2.00	12.40	11.48	ns
4 mA	Std.	0.66	11.23	0.04	1.70	2.14	0.43	11.44	9.87	3.77	3.36	13.68	12.10	ns
	-1	0.56	9.55	0.04	1.44	1.82	0.36	9.73	8.39	3.21	2.86	11.63	10.29	ns
	-2	0.49	8.39	0.03	1.27	1.60	0.32	8.54	7.37	2.81	2.51	10.21	9.04	ns
8 mA	Std.	0.66	10.45	0.04	1.70	2.14	0.43	10.65	9.24	3.84	3.55	12.88	11.48	ns
	<b>–</b> 1	0.56	8.89	0.04	1.44	1.82	0.36	9.06	7.86	3.27	3.02	10.96	9.76	ns
	-2	0.49	7.81	0.03	1.27	1.60	0.32	7.95	6.90	2.87	2.65	9.62	8.57	ns
12 mA	Std.	0.66	10.02	0.04	1.70	2.14	0.43	10.20	9.23	3.97	4.22	12.44	11.47	ns
	<b>–</b> 1	0.56	8.52	0.04	1.44	1.82	0.36	8.68	7.85	3.38	3.59	10.58	9.75	ns
	-2	0.49	7.48	0.03	1.27	1.60	0.32	7.62	6.89	2.97	3.15	9.29	8.56	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Table 2-129 • 1.5 V LVCMOS High Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V Applicable to Pro I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOU</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zHS</sub>	Units
2 mA	Std.	0.66	8.53	0.04	1.70	2.14	0.43	7.26	8.53	3.39	2.79	9.50	10.77	ns
	-1	0.56	7.26	0.04	1.44	1.82	0.36	6.18	7.26	2.89	2.37	8.08	9.16	ns
	-2	0.49	6.37	0.03	1.27	1.60	0.32	5.42	6.37	2.53	2.08	7.09	8.04	ns
4 mA	Std.	0.66	5.41	0.04	1.70	2.14	0.43	5.22	5.41	3.75	3.48	7.45	7.65	ns
	-1	0.56	4.60	0.04	1.44	1.82	0.36	4.44	4.60	3.19	2.96	6.34	6.50	ns
	-2	0.49	4.04	0.03	1.27	1.60	0.32	3.89	4.04	2.80	2.60	5.56	5.71	ns
8 mA	Std.	0.66	4.80	0.04	1.70	2.14	0.43	4.89	4.75	3.83	3.67	7.13	6.98	ns
	-1	0.56	4.09	0.04	1.44	1.82	0.36	4.16	4.04	3.26	3.12	6.06	5.94	ns
	-2	0.49	3.59	0.03	1.27	1.60	0.32	3.65	3.54	2.86	2.74	5.32	5.21	ns
12 mA	Std.	0.66	4.42	0.04	1.70	2.14	0.43	4.50	3.62	3.96	4.37	6.74	5.86	ns
	-1	0.56	3.76	0.04	1.44	1.82	0.36	3.83	3.08	3.37	3.72	5.73	4.98	ns
	-2	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



Table 2-130 • 1.5 V LVCMOS Low Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	12.78	0.04	1.31	0.43	12.81	12.78	3.40	2.64	15.05	15.02	ns
	<b>–</b> 1	0.56	10.87	0.04	1.11	0.36	10.90	10.87	2.89	2.25	12.80	12.78	ns
	-2	0.49	9.55	0.03	0.98	0.32	9.57	9.55	2.54	1.97	11.24	11.22	ns
4 mA	Std.	0.66	10.01	0.04	1.31	0.43	10.19	9.55	3.75	3.27	12.43	11.78	ns
	<b>–</b> 1	0.56	8.51	0.04	1.11	0.36	8.67	8.12	3.19	2.78	10.57	10.02	ns
	-2	0.49	7.47	0.03	0.98	0.32	7.61	7.13	2.80	2.44	9.28	8.80	ns
8 mA	Std.	0.66	9.33	0.04	1.31	0.43	9.51	8.89	3.83	3.43	11.74	11.13	ns
	<b>–</b> 1	0.56	7.94	0.04	1.11	0.36	8.09	7.56	3.26	2.92	9.99	9.47	ns
	-2	0.49	6.97	0.03	0.98	0.32	7.10	6.64	2.86	2.56	8.77	8.31	ns
12 mA	Std.	0.66	8.91	0.04	1.31	0.43	9.07	8.89	3.95	4.05	11.31	11.13	ns
	<b>–1</b>	0.56	7.58	0.04	1.11	0.36	7.72	7.57	3.36	3.44	9.62	9.47	ns
	-2	0.49	6.65	0.03	0.98	0.32	6.78	6.64	2.95	3.02	8.45	8.31	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Table 2-131 • 1.5 V LVCMOS High Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V Applicable to Advanced I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	8.36	0.04	1.44	0.43	6.82	8.36	3.39	2.77	9.06	10.60	ns
	-1	0.56	7.11	0.04	1.22	0.36	5.80	7.11	2.88	2.35	7.71	9.02	ns
	-2	0.49	6.24	0.03	1.07	0.32	5.10	6.24	2.53	2.06	6.76	7.91	ns
4 mA	Std.	0.66	5.31	0.04	1.44	0.43	4.85	5.31	3.74	3.40	7.09	7.55	ns
	-1	0.56	4.52	0.04	1.22	0.36	4.13	4.52	3.18	2.89	6.03	6.42	ns
	-2	0.49	3.97	0.03	1.07	0.32	3.62	3.97	2.79	2.54	5.29	5.64	ns
8 mA	Std.	0.66	4.67	0.04	1.44	0.43	4.55	4.67	3.82	3.56	6.78	6.90	ns
	-1	0.56	3.97	0.04	1.22	0.36	3.87	3.97	3.25	3.03	5.77	5.87	ns
	-2	0.49	3.49	0.03	1.07	0.32	3.40	3.49	2.85	2.66	5.07	5.16	ns
12 mA	Std.	0.66	4.08	0.04	1.44	0.43	4.15	3.58	3.94	4.20	6.39	5.81	ns
	-1	0.56	3.47	0.04	1.22	0.36	3.53	3.04	3.36	3.58	5.44	4.95	ns
	-2	0.49	3.05	0.03	1.07	0.32	3.10	2.67	2.95	3.14	4.77	4.34	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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## Table 2-132 • 1.5 V LVCMOS Low Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	12.33	0.04	1.42	0.43	11.79	12.33	2.45	2.32	ns
	-1	0.56	10.49	0.04	1.21	0.36	10.03	10.49	2.08	1.98	ns
	-2	0.49	9.21	0.03	1.06	0.32	8.81	9.21	1.83	1.73	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

# Table 2-133 • 1.5 V LVCMOS High Slew

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V Applicable to Standard I/Os

Drive Strength	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	Units
2 mA	Std.	0.66	7.65	0.04	1.42	0.43	6.31	7.65	2.45	2.45	ns
	-1	0.56	6.50	0.04	1.21	0.36	5.37	6.50	2.08	2.08	ns
	-2	0.49	5.71	0.03	1.06	0.32	4.71	5.71	1.83	1.83	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



## 3.3 V PCI, 3.3 V PCI-X

The Peripheral Component Interface for 3.3 V standard specifies support for 33 MHz and 66 MHz PCI Bus applications.

Table 2-134 • Minimum and Maximum DC Input and Output Levels

3.3 V PCI/PCI-X	V	IL	V	IH	VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μA <sup>4</sup>
Per PCI specification		Per PCI curves										10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

AC loadings are defined per the PCI/PCI-X specifications for the datapath; Microsemi loadings for enable path characterization are described in Figure 2-123.

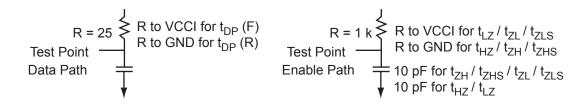


Figure 2-123 • AC Loading

AC loadings are defined per PCI/PCI-X specifications for the data path; Microsemi loading for tristate is described in Table 2-135.

Table 2-135 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C <sub>LOAD</sub> (pF)
0	3.3	0.285 * VCCI for t <sub>DP(R)</sub>	-	10
		0.615 * VCCI for t <sub>DP(F)</sub>		

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

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## **Timing Characteristics**

## Table 2-136 • 3.3 V PCI/PCI-X

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Pro I/Os

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zHS</sub>	Units
Std.	0.66	2.81	0.04	1.05	1.67	0.43	2.86	2.00	3.28	3.61	5.09	4.23	ns
<b>-</b> 1	0.56	2.39	0.04	0.89	1.42	0.36	2.43	1.70	2.79	3.07	4.33	3.60	ns
-2	0.49	2.09	0.03	0.78	1.25	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

## Table 2-137 • 3.3 V PCI/PCI-X

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Advanced I/Os

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.68	0.04	0.86	0.43	2.73	1.95	3.21	3.58	4.97	4.19	0.66	ns
<b>-</b> 1	0.56	2.28	0.04	0.73	0.36	2.32	1.66	2.73	3.05	4.22	3.56	0.56	ns
<b>-</b> 2	0.49	2.00	0.03	0.65	0.32	2.04	1.46	2.40	2.68	3.71	3.13	0.49	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# Voltage Referenced I/O Characteristics

3.3 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-138 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Min. Max. V V		Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
20 mA <sup>3</sup>	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20	181	268	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

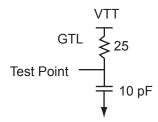


Figure 2-124 • AC Loading

Table 2-139 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.05	VREF + 0.05	0.8	0.8	1.2	10

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

### **Timing Characteristics**

Table 2-140 • 3.3 V GTL

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zHS</sub>	Units
Std.	0.66	2.08	0.04	2.93	0.43	2.04	2.08			4.27	4.31	ns
<b>–</b> 1	0.56	1.77	0.04	2.50	0.36	1.73	1.77			3.63	3.67	ns
-2	0.49	1.55	0.03	2.19	0.32	1.52	1.55			3.19	3.22	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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#### 2.5 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 2.5 V.

Table 2-141 • Minimum and Maximum DC Input and Output Levels

2.5 GTL		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μA <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
20 mA <sup>3</sup>	-0.3	VREF - 0.05	VREF + 0.05	3.6	0.4	-	20	20	124	169	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

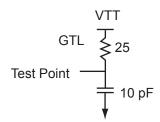


Figure 2-125 • AC Loading

Table 2-142 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.05	VREF + 0.05	0.8	0.8	1.2	10

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

## **Timing Characteristics**

Table 2-143 • 2.5 V GTL

Commercial Temperature Range Conditions: TJ =  $70^{\circ}$ C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 0.8 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.13	0.04	2.46	0.43	2.16	2.13			4.40	4.36	ns
<b>-1</b>	0.56	1.81	0.04	2.09	0.36	1.84	1.81			3.74	3.71	ns
-2	0.49	1.59	0.03	1.83	0.32	1.61	1.59			3.28	3.26	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



## 3.3 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-144 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL+	,	VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
35 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	_	35	35	181	268	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

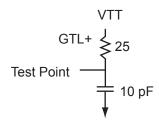


Figure 2-126 • AC Loading

Table 2-145 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	1.0	1.0	1.5	10

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

## **Timing Characteristics**

Table 2-146 • 3.3 V GTL+

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 1.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.06	0.04	1.59	0.43	2.09	2.06			4.33	4.29	ns
-1	0.56	1.75	0.04	1.35	0.36	1.78	1.75			3.68	3.65	ns
-2	0.49	1.53	0.03	1.19	0.32	1.56	1.53			3.23	3.20	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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#### 2.5 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 2.5 V.

Table 2-147 • Minimum and Maximum DC Input and Output Levels

2.5 V GTL+	VIL		VIH		VOL	VOH	IOL	ЮН	IOSL	юѕн	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μA <sup>4</sup>
33 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	_	33	33	124	169	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

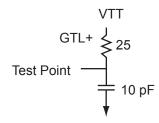


Figure 2-127 • AC Loading

Table 2-148 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	1.0	1.0	1.5	10

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

#### Timing Characteristics

Table 2-149 • 2.5 V GTL+

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V, VREF = 1.0 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
Std.	0.66	2.21	0.04	1.51	0.43	2.25	2.10			4.48	4.34	ns
-1	0.56	1.88	0.04	1.29	0.36	1.91	1.79			3.81	3.69	ns
-2	0.49	1.65	0.03	1.13	0.32	1.68	1.57			3.35	4.34	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



#### **HSTL Class I**

High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). Fusion devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-150 • Minimum and Maximum DC Input and Output Levels

HSTL Class I		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μA <sup>4</sup>
8 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	8	8	39	32	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

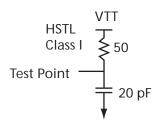


Figure 2-128 • AC Loading

Table 2-151 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF – 0.1	VREF + 0.1	0.75	0.75	0.75	20

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

#### **Timing Characteristics**

Table 2-152 • HSTL Class I

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V, VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	3.18	0.04	2.12	0.43	3.24	3.14			5.47	5.38	ns
<b>-</b> 1	0.56	2.70	0.04	1.81	0.36	2.75	2.67			4.66	4.58	ns
-2	0.49	2.37	0.03	1.59	0.32	2.42	2.35			4.09	4.02	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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#### **HSTL Class II**

High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-153 • Minimum and Maximum DC Input and Output Levels

HSTL Class II		VIL	VIH		VOL	VOL VOH		ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
15 mA <sup>3</sup>	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.4	VCCI - 0.4	15	15	55	66	10	10

#### Note:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Output drive strength is below JEDEC specification.

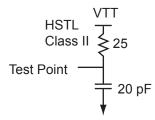


Figure 2-129 • AC Loading

Table 2-154 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.1	VREF + 0.1	0.75	0.75	0.75	20

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

## **Timing Characteristics**

Table 2-155 • HSTL Class II

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.4 V, VREF = 0.75 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	3.02	0.04	2.12	0.43	3.08	2.71			5.32	4.95	ns
<b>-1</b>	0.56	2.57	0.04	1.81	0.36	2.62	2.31			4.52	4.21	ns
-2	0.49	2.26	0.03	1.59	0.32	2.30	2.03			3.97	3.70	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



#### SSTL2 Class I

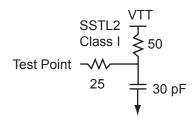
Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). Fusion devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-156 • Minimum and Maximum DC Input and Output Levels

SSTL2 Class I	lass I VIL		VIH	VIH		VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
15 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.54	VCCI - 0.62	15	15	87	83	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.



## Figure 2-130 • AC Loading

Table 2-157 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.25	1.25	1.25	30

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

# Timing Characteristics

Table 2-158 • SSTL 2 Class I

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V, VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.13	0.04	1.33	0.43	2.17	1.85			4.40	4.08	ns
<b>-1</b>	0.56	1.81	0.04	1.14	0.36	1.84	1.57			3.74	3.47	ns
-2	0.49	1.59	0.03	1.00	0.32	1.62	1.38			3.29	3.05	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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#### SSTL2 Class II

Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-159 • Minimum and Maximum DC Input and Output Levels

SSTL2 Class II		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
18 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.35	VCCI - 0.43	18	18	124	169	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.

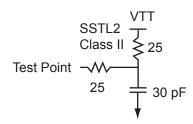


Figure 2-131 • AC Loading

Table 2-160 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.25	1.25	1.25	30

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

# **Timing Characteristics**

Table 2-161 • SSTL 2 Class II Commercial Temperature Range Conditions:  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.425 V,

Worst-Case VCCI = 2.3 V, VREF = 1.25 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>zhs</sub>	Units
Std.	0.66	2.17	0.04	1.33	0.43	2.21	1.77			4.44	4.01	ns
<b>-1</b>	0.56	1.84	0.04	1.14	0.36	1.88	1.51			3.78	3.41	ns
-2	0.49	1.62	0.03	1.00	0.32	1.65	1.32			3.32	2.99	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



#### SSTL3 Class I

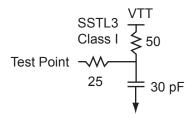
Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). Fusion devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-162 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class I		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
14 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.7	VCCI - 1.1	14	14	54	51	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.



#### Figure 2-132 • AC Loading

Table 2-163 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.5	1.5	1.485	30

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

# Timing Characteristics

Table 2-164 • SSTL3 Class I

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 1.5 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.31	0.04	1.25	0.43	2.35	1.84			4.59	4.07	ns
<b>-1</b>	0.56	1.96	0.04	1.06	0.36	2.00	1.56			3.90	3.46	ns
-2	0.49	1.72	0.03	0.93	0.32	1.75	1.37			3.42	3.04	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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#### SSTL3 Class II

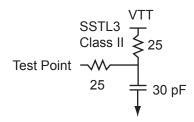
Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-165 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class II		VIL	VIH		VOL	VOH	IOL	ЮН	IOSL	IOSH	IIL <sup>1</sup>	IIH <sup>2</sup>
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA <sup>3</sup>	Max. mA <sup>3</sup>	μ <b>Α</b> <sup>4</sup>	μ <b>Α</b> <sup>4</sup>
21 mA	-0.3	VREF - 0.2	VREF + 0.2	3.6	0.5	VCCI - 0.9	21	21	109	103	10	10

#### Notes:

- 1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.
- 3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.



# Figure 2-133 • AC Loading

Table 2-166 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C <sub>LOAD</sub> (pF)
VREF - 0.2	VREF + 0.2	1.5	1.5	1.485	30

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

#### **Timing Characteristics**

Table 2-167 • SSTL3- Class II

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 1.5 V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.07	0.04	1.25	0.43	2.10	1.67			4.34	3.91	ns
<b>-1</b>	0.56	1.76	0.04	1.06	0.36	1.79	1.42			3.69	3.32	ns
-2	0.49	1.54	0.03	0.93	0.32	1.57	1.25			3.24	2.92	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# Differential I/O Characteristics

Configuration of the I/O modules as a differential pair is handled by the Microsemi Designer software when the user instantiates a differential I/O macro in the design.

Differential I/Os can also be used in conjunction with the embedded Input Register (InReg), Output Register (OutReg), Enable Register (EnReg), and Double Data Rate (DDR). However, there is no support for bidirectional I/Os or tristates with these standards.

#### **LVDS**

Low-Voltage Differential Signal (ANSI/TIA/EIA-644) is a high-speed differential I/O standard. It requires that one data bit be carried through two signal lines, so two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-134. The building blocks of the LVDS transmitter—receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVPECL implementation because the output standard specifications are different.

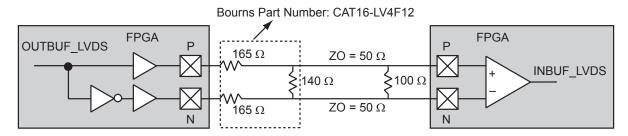


Figure 2-134 • LVDS Circuit Diagram and Board-Level Implementation

Table 2-168 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Тур.	Max.	Units
VCCI	Supply Voltage	2.375	2.5	2.625	V
VOL	Output Low Voltage	0.9	1.075	1.25	V
VOH	Input High Voltage	1.25	1.425	1.6	V
IOL <sup>1</sup>	Output Low Voltage	0.65	0.91	1.16	mA
IOH <sup>1</sup>	Output High Voltage	0.65	0.91	1.16	mA
VI	Input Voltage	0		2.925	V
IIL <sup>2,3</sup>	Input Low Voltage			10	μА
IIH <sup>2,4</sup>	Input High Voltage			10	μА
VODIFF	Differential Output Voltage	250	350	450	mV
VOCM	Output Common Mode Voltage	1.125	1.25	1.375	V
VICM	Input Common Mode Voltage	0.05	1.25	2.35	V
VIDIFF	Input Differential Voltage	100	350		mV

#### Notes:

- 1. IOL/IOH defined by VODIFF/(Resistor Network)
- 2. Currents are measured at 85°C junction temperature.
- 3. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.
- 4. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.

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Table 2-169 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)
1.075	1.325	Cross point	_

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

#### Timing Characteristics

Table 2-170 • LVDS

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V Applicable to Pro I/Os

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.66	2.10	0.04	1.82	ns
<b>-1</b>	0.56	1.79	0.04	1.55	ns
-2	0.49	1.57	0.03	1.36	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

#### **BLVDS/M-LVDS**

Bus LVDS (BLVDS) and Multipoint LVDS (M-LVDS) specifications extend the existing LVDS standard to high-performance multipoint bus applications. Multidrop and multipoint bus configurations can contain any combination of drivers, receivers, and transceivers. Microsemi LVDS drivers provide the higher drive current required by BLVDS and M-LVDS to accommodate the loading. The driver requires series terminations for better signal quality and to control voltage swing. Termination is also required at both ends of the bus, since the driver can be located anywhere on the bus. These configurations can be implemented using TRIBUF\_LVDS and BIBUF\_LVDS macros along with appropriate terminations. Multipoint designs using Microsemi LVDS macros can achieve up to 200 MHz with a maximum of 20 loads. A sample application is given in Figure 2-135. The input and output buffer delays are available in the LVDS section in Table 2-171.

Example: For a bus consisting of 20 equidistant loads, the following terminations provide the required differential voltage, in worst-case industrial operating conditions at the farthest receiver:  $R_S$  = 60  $\Omega$  and  $R_T$  = 70  $\Omega$ , given  $Z_0$  = 50  $\Omega$  (2") and  $Z_{stub}$  = 50  $\Omega$  (~1.5").

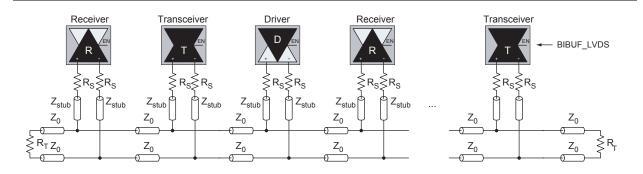


Figure 2-135 • BLVDS/M-LVDS Multipoint Application Using LVDS I/O Buffers



#### LVPECL

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit be carried through two signal lines. Like LVDS, two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-136. The building blocks of the LVPECL transmitter–receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVDS implementation because the output standard specifications are different.

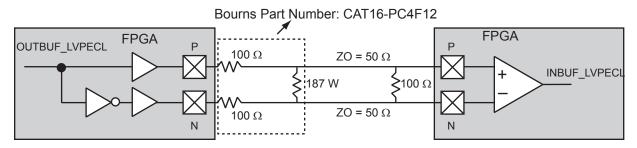


Figure 2-136 • LVPECL Circuit Diagram and Board-Level Implementation

Table 2-171 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Units
VCCI	Supply Voltage	3	3.0 3.3 3.6		3.6		V	
VOL	Output Low Voltage	0.96	1.27	1.06	1.43	1.30	1.57	V
VOH	Output High Voltage	1.8	2.11	1.92	2.28	2.13	2.41	V
VIL, VIH	Input Low, Input High Voltages	0	3.6	0	3.6	0	3.6	V
VODIFF	Differential Output Voltage	0.625	0.97	0.625	0.97	0.625	0.97	V
VOCM	Output Common Mode Voltage	1.762	1.98	1.762	1.98	1.762	1.98	V
VICM	Input Common Mode Voltage	1.01	2.57	1.01	2.57	1.01	2.57	V
VIDIFF	Input Differential Voltage	300		300		300		mV

Table 2-172 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)
1.64	1.94	Cross point	-

Note: \*Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

# **Timing Characteristics**

Table 2-173 • LVPECL

Commercial Temperature Range Conditions:  $T_J$  = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Pro I/Os

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.66	2.14	0.04	1.63	ns
<b>-1</b>	0.56	1.82	0.04	1.39	ns
-2	0.49	1.60	0.03	1.22	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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# I/O Register Specifications

# Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

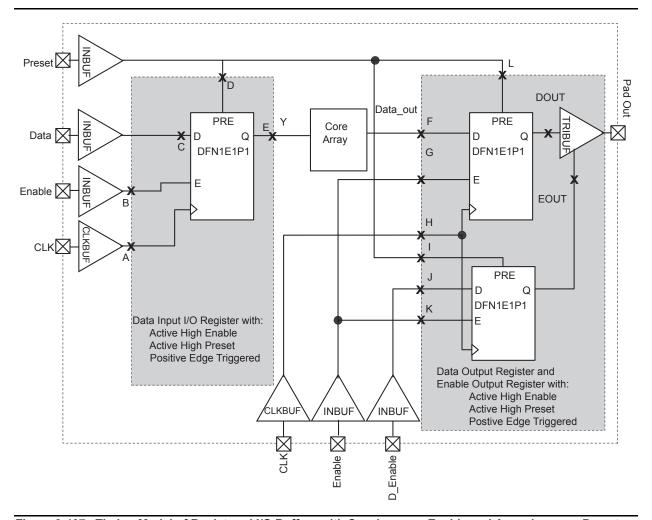


Figure 2-137 • Timing Model of Registered I/O Buffers with Synchronous Enable and Asynchronous Preset



Table 2-174 • Parameter Definitions and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	H, DOUT
tosup	Data Setup Time for the Output Data Register	F, H
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	F, H
t <sub>OSUE</sub>	Enable Setup Time for the Output Data Register	G, H
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	G, H
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	L,DOUT
t <sub>OREMPRE</sub>	Asynchronous Preset Removal Time for the Output Data Register	L, H
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery Time for the Output Data Register	L, H
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	H, EOUT
t <sub>OESUD</sub>	Data Setup Time for the Output Enable Register	J, H
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	J, H
t <sub>OESUE</sub>	Enable Setup Time for the Output Enable Register	K, H
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	K, H
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	I, EOUT
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal Time for the Output Enable Register	I, H
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery Time for the Output Enable Register	I, H
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	A, E
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	C, A
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	C, A
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	B, A
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	B, A
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	D, E
t <sub>IREMPRE</sub>	Asynchronous Preset Removal Time for the Input Data Register	D, A
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery Time for the Input Data Register	D, A

Note: \*See Figure 2-137 on page 2-212 for more information.

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# Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

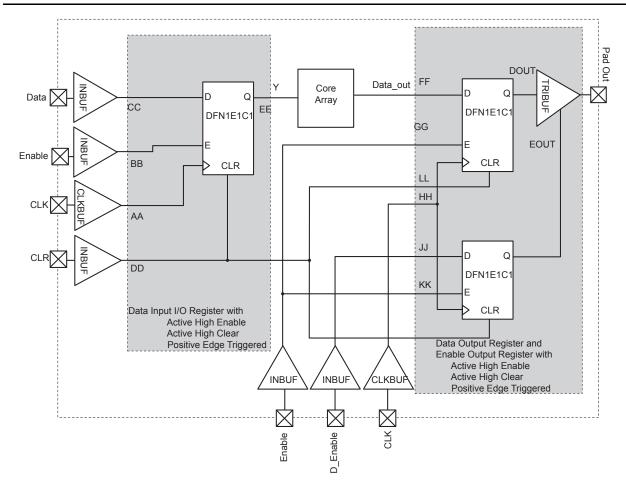


Figure 2-138 • Timing Model of the Registered I/O Buffers with Synchronous Enable and Asynchronous Clear



Table 2-175 • Parameter Definitions and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t <sub>oclk</sub> a	Clock-to-Q of the Output Data Register	HH, DOUT
tosup	Data Setup Time for the Output Data Register	FF, HH
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	FF, HH
t <sub>OSUE</sub>	Enable Setup Time for the Output Data Register	GG, HH
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	GG, HH
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	LL, DOUT
t <sub>OREMCLR</sub>	Asynchronous Clear Removal Time for the Output Data Register	LL, HH
t <sub>ORECCLR</sub>	Asynchronous Clear Recovery Time for the Output Data Register	LL, HH
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	HH, EOUT
t <sub>OESUD</sub>	Data Setup Time for the Output Enable Register	JJ, HH
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	JJ, HH
t <sub>OESUE</sub>	Enable Setup Time for the Output Enable Register	KK, HH
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	KK, HH
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	II, EOUT
t <sub>OEREMCLR</sub>	Asynchronous Clear Removal Time for the Output Enable Register	II, HH
t <sub>OERECCLR</sub>	Asynchronous Clear Recovery Time for the Output Enable Register	II, HH
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	AA, EE
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	CC, AA
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	CC, AA
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	BB, AA
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	BB, AA
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	DD, EE
t <sub>IREMCLR</sub>	Asynchronous Clear Removal Time for the Input Data Register	DD, AA
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery Time for the Input Data Register	DD, AA

Note: \*See Figure 2-138 on page 2-214 for more information.

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# Input Register

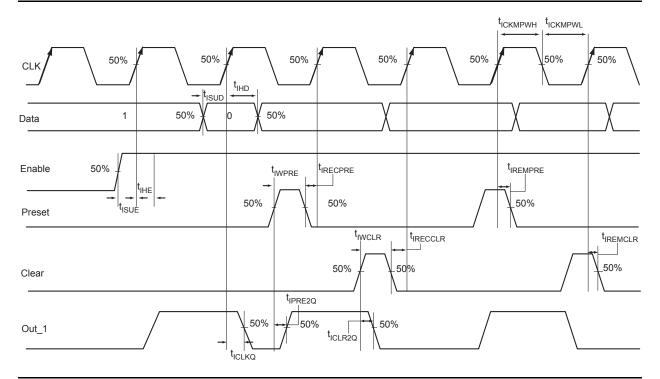


Figure 2-139 • Input Register Timing Diagram

**Timing Characteristics** 

Table 2-176 • Input Data Register Propagation Delays

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	<b>-1</b>	Std.	Units
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	0.24	0.27	0.32	ns
t <sub>ISUD</sub>	Data Setup Time for the Input Data Register	0.26	0.30	0.35	ns
t <sub>IHD</sub>	Data Hold Time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>ISUE</sub>	Enable Setup Time for the Input Data Register	0.37	0.42	0.50	ns
t <sub>IHE</sub>	Enable Hold Time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	0.45	0.52	0.61	ns
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	0.45	0.52	0.61	ns
t <sub>IREMCLR</sub>	Asynchronous Clear Removal Time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery Time for the Input Data Register	0.22	0.25	0.30	ns
t <sub>IREMPRE</sub>	Asynchronous Preset Removal Time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery Time for the Input Data Register	0.22	0.25	0.30	ns
t <sub>IWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.22	0.25	0.30	ns
t <sub>IWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.22	0.25	0.30	ns
t <sub>ICKMPWH</sub>	Clock Minimum Pulse Width High for the Input Data Register	0.36	0.41	0.48	ns
t <sub>ICKMPWL</sub>	Clock Minimum Pulse Width Low for the Input Data Register	0.32	0.37	0.43	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# **Output Register**

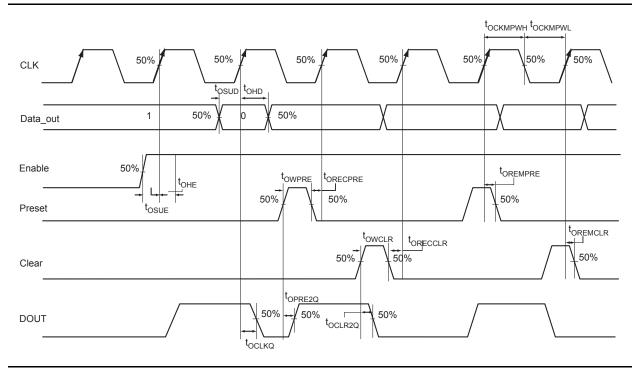


Figure 2-140 • Output Register Timing Diagram

# **Timing Characteristics**

Table 2-177 • Output Data Register Propagation Delays

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	0.59	0.67	0.79	ns
t <sub>OSUD</sub>	Data Setup Time for the Output Data Register	0.31	0.36	0.42	ns
t <sub>OHD</sub>	Data Hold Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>OSUE</sub>	Enable Setup Time for the Output Data Register	0.44	0.50	0.59	ns
t <sub>OHE</sub>	Enable Hold Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	0.80	0.91	1.07	ns
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	0.80	0.91	1.07	ns
t <sub>OREMCLR</sub>	Asynchronous Clear Removal Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>ORECCLR</sub>	Asynchronous Clear Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OREMPRE</sub>	Asynchronous Preset Removal Time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery Time for the Output Data Register	0.22	0.25	0.30	ns
towclr	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.22	0.25	0.30	ns
tockmpwh	Clock Minimum Pulse Width High for the Output Data Register	0.36	0.41	0.48	ns
t <sub>OCKMPWL</sub>	Clock Minimum Pulse Width Low for the Output Data Register	0.32	0.37	0.43	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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# **Output Enable Register**

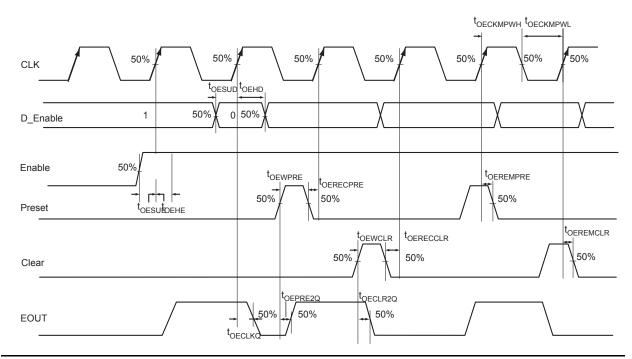


Figure 2-141 • Output Enable Register Timing Diagram

# **Timing Characteristics**

Table 2-178 • Output Enable Register Propagation Delays

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	0.44	0.51	0.59	ns
t <sub>OESUD</sub>	Data Setup Time for the Output Enable Register	0.31	0.36	0.42	ns
t <sub>OEHD</sub>	Data Hold Time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OESUE</sub>	Enable Setup Time for the Output Enable Register	0.44	0.50	0.58	ns
t <sub>OEHE</sub>	Enable Hold Time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	0.67	0.76	0.89	ns
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	0.67	0.76	0.89	ns
t <sub>OEREMCLR</sub>	Asynchronous Clear Removal Time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OERECCLR</sub>	Asynchronous Clear Recovery Time for the Output Enable Register	0.22	0.25	0.30	ns
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal Time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery Time for the Output Enable Register	0.22	0.25	0.30	ns
t <sub>OEWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.22	0.25	0.30	ns
t <sub>OEWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.22	0.25	0.30	ns
t <sub>OECKMPWH</sub>	Clock Minimum Pulse Width High for the Output Enable Register	0.36	0.41	0.48	ns
t <sub>OECKMPWL</sub>	Clock Minimum Pulse Width Low for the Output Enable Register	0.32	0.37	0.43	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# **DDR Module Specifications**

Input DDR Module

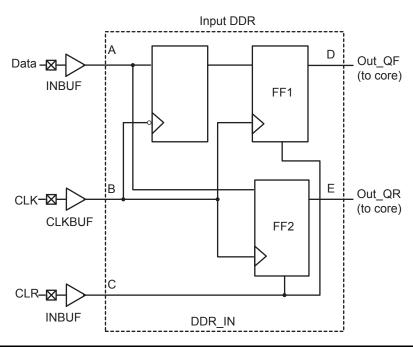


Figure 2-142 • Input DDR Timing Model

Table 2-179 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR	B, D
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF	B, E
t <sub>DDRISUD</sub>	Data Setup Time of DDR Input	A, B
t <sub>DDRIHD</sub>	Data Hold Time of DDR Input	A, B
t <sub>DDRICLR2Q1</sub>	Clear-to-Out Out_QR	C, D
t <sub>DDRICLR2Q2</sub>	Clear-to-Out Out_QF	C, E
t <sub>DDRIREMCLR</sub>	Clear Removal	C, B
t <sub>DDRIRECCLR</sub>	Clear Recovery	C, B

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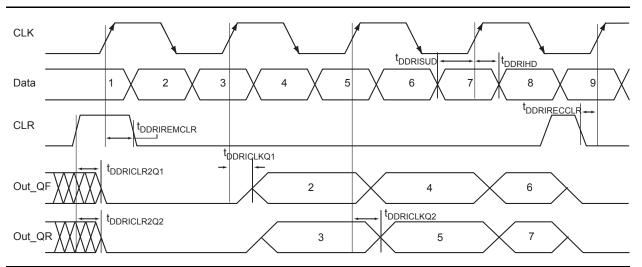


Figure 2-143 • Input DDR Timing Diagram

# **Timing Characteristics**

Table 2-180 • Input DDR Propagation Delays

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR for Input DDR	0.39	0.44	0.52	ns
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF for Input DDR	0.27	0.31	0.37	ns
t <sub>DDRISUD</sub>	Data Setup for Input DDR	0.28	0.32	0.38	ns
t <sub>DDRIHD</sub>	Data Hold for Input DDR	0.00	0.00	0.00	ns
t <sub>DDRICLR2Q1</sub>	Asynchronous Clear-to-Out Out_QR for Input DDR	0.57	0.65	0.76	ns
t <sub>DDRICLR2Q2</sub>	Asynchronous Clear-to-Out Out_QF for Input DDR	0.46	0.53	0.62	ns
t <sub>DDRIREMCLR</sub>	Asynchronous Clear Removal Time for Input DDR	0.00	0.00	0.00	ns
t <sub>DDRIRECCLR</sub>	Asynchronous Clear Recovery Time for Input DDR	0.22	0.25	0.30	ns
t <sub>DDRIWCLR</sub>	Asynchronous Clear Minimum Pulse Width for Input DDR	0.22	0.25	0.30	ns
t <sub>DDRICKMPWH</sub>	Clock Minimum Pulse Width High for Input DDR	0.36	0.41	0.48	ns
t <sub>DDRICKMPWL</sub>	Clock Minimum Pulse Width Low for Input DDR	0.32	0.37	0.43	ns
F <sub>DDRIMAX</sub>	Maximum Frequency for Input DDR	1404	1232	1048	MHz

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# **Output DDR**

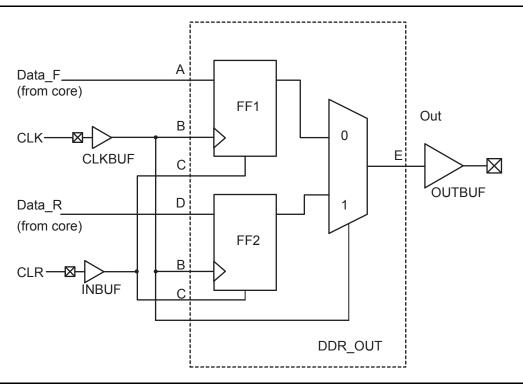


Figure 2-144 • Output DDR Timing Model

Table 2-181 • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (From, To)
t <sub>DDROCLKQ</sub>	Clock-to-Out	B, E
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out	C, E
t <sub>DDROREMCLR</sub>	Clear Removal	C, B
t <sub>DDRORECCLR</sub>	Clear Recovery	C, B
t <sub>DDROSUD1</sub>	Data Setup Data_F	A, B
t <sub>DDROSUD2</sub>	Data Setup Data_R	D, B
t <sub>DDROHD1</sub>	Data Hold Data_F	A, B
t <sub>DDROHD2</sub>	Data Hold Data_R	D, B

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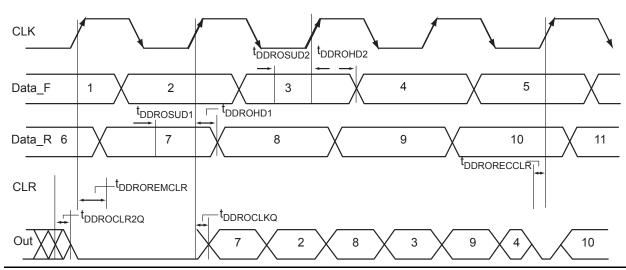


Figure 2-145 • Output DDR Timing Diagram

# **Timing Characteristics**

Table 2-182 • Output DDR Propagation Delays

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	<b>-1</b>	Std.	Units
t <sub>DDROCLKQ</sub>	Clock-to-Out of DDR for Output DDR	0.70	0.80	0.94	ns
t <sub>DDROSUD1</sub>	Data_F Data Setup for Output DDR	0.38	0.43	0.51	ns
t <sub>DDROSUD2</sub>	Data_R Data Setup for Output DDR	0.38	0.43	0.51	ns
t <sub>DDROHD1</sub>	Data_F Data Hold for Output DDR	0.00	0.00	0.00	ns
t <sub>DDROHD2</sub>	Data_R Data Hold for Output DDR	0.00	0.00	0.00	ns
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out for Output DDR	0.80	0.91	1.07	ns
t <sub>DDROREMCLR</sub>	Asynchronous Clear Removal Time for Output DDR	0.00	0.00	0.00	ns
t <sub>DDRORECCLR</sub>	Asynchronous Clear Recovery Time for Output DDR	0.22	0.25	0.30	ns
t <sub>DDROWCLR1</sub>	Asynchronous Clear Minimum Pulse Width for Output DDR	0.22	0.25	0.30	ns
t <sub>DDROCKMPWH</sub>	Clock Minimum Pulse Width High for the Output DDR	0.36	0.41	0.48	ns
t <sub>DDROCKMPWL</sub>	Clock Minimum Pulse Width Low for the Output DDR	0.32	0.37	0.43	ns
F <sub>DDOMAX</sub>	Maximum Frequency for the Output DDR	1404	1232	1048	MHz

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.



# **Pin Descriptions**

# **Supply Pins**

GND Ground

Ground supply voltage to the core, I/O outputs, and I/O logic.

GNDQ Ground (quiet)

Quiet ground supply voltage to input buffers of I/O banks. Within the package, the GNDQ plane is decoupled from the simultaneous switching noise originated from the output buffer ground domain. This minimizes the noise transfer within the package and improves input signal integrity. GNDQ needs to always be connected on the board to GND. Note: In FG256, FG484, and FG676 packages, GNDQ and GND pins are connected within the package and are labeled as GND pins in the respective package pin assignment tables.

ADCGNDREF Analog Reference Ground

Analog ground reference used by the ADC. This pad should be connected to a quiet analog ground.

GNDA Ground (analog)

Quiet ground supply voltage to the Analog Block of Fusion devices. The use of a separate analog ground helps isolate the analog functionality of the Fusion device from any digital switching noise. A 0.2 V maximum differential voltage between GND and GNDA/GNDQ should apply to system implementation.

GNDAQ Ground (analog quiet)

Quiet ground supply voltage to the analog I/O of Fusion devices. The use of a separate analog ground helps isolate the analog functionality of the Fusion device from any digital switching noise. A 0.2 V maximum differential voltage between GND and GNDA/GNDQ should apply to system implementation. Note: In FG256, FG484, and FG676 packages, GNDAQ and GNDA pins are connected within the package and are labeled as GNDA pins in the respective package pin assignment tables.

GNDNVM Flash Memory Ground

Ground supply used by the Fusion device's flash memory block module(s).

GNDOSC Oscillator Ground

Ground supply for both integrated RC oscillator and crystal oscillator circuit.

VCC15A Analog Power Supply (1.5 V)

1.5 V clean analog power supply input for use by the 1.5 V portion of the analog circuitry.

VCC33A Analog Power Supply (3.3 V)

3.3 V clean analog power supply input for use by the 3.3 V portion of the analog circuitry.

VCC33N Negative 3.3 V Output

This is the -3.3 V output from the voltage converter. A 2.2  $\mu$ F capacitor must be connected from this pin to ground.

VCC33PMP Analog Power Supply (3.3 V)

3.3 V clean analog power supply input for use by the analog charge pump. To avoid high current draw, VCC33PMP should be powered up simultaneously with or after VCC33A.

VCCNVM Flash Memory Block Power Supply (1.5 V)

1.5 V power supply input used by the Fusion device's flash memory block module(s). To avoid high current draw, VCC should be powered up before or simultaneously with VCCNVM.

VCCOSC Oscillator Power Supply (3.3 V)

Power supply for both integrated RC oscillator and crystal oscillator circuit. The internal 100 MHz oscillator, powered by the VCCOSC pin, is needed for device programming, operation of the VDDN33 pump, and eNVM operation. VCCOSC is off only when VCCA is off. VCCOSC must be powered whenever the Fusion device needs to function.

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#### VCC Core Supply Voltage

Supply voltage to the FPGA core, nominally 1.5 V. VCC is also required for powering the JTAG state machine, in addition to VJTAG. Even when a Fusion device is in bypass mode in a JTAG chain of interconnected devices, both VCC and VJTAG must remain powered to allow JTAG signals to pass through the Fusion device.

#### VCCIBx I/O Supply Voltage

Supply voltage to the bank's I/O output buffers and I/O logic. Bx is the I/O bank number. There are either four (AFS090 and AFS250) or five (AFS600 and AFS1500) I/O banks on the Fusion devices plus a dedicated VJTAG bank.

Each bank can have a separate VCCI connection. All I/Os in a bank will run off the same VCCIBx supply. VCCI can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VCCI pins tied to GND.

#### VCCPLA/B PLL Supply Voltage

Supply voltage to analog PLL, nominally 1.5 V, where A and B refer to the PLL. AFS090 and AFS250 each have a single PLL. The AFS600 and AFS1500 devices each have two PLLs. Microsemi recommends tying VCCPLX to VCC and using proper filtering circuits to decouple VCC noise from PLL. If unused, VCCPLA/B should be tied to GND.

#### VCOMPLA/B Ground for West and East PLL

VCOMPLA is the ground of the west PLL (CCC location F) and VCOMPLB is the ground of the east PLL (CCC location C).

#### VJTAG JTAG Supply Voltage

Fusion devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned to be used, the VJTAG pin together with the TRST pin could be tied to GND. It should be noted that VCC is required to be powered for JTAG operation; VJTAG alone is insufficient. If a Fusion device is in a JTAG chain of interconnected boards and it is desired to power down the board containing the Fusion device, this may be done provided both VJTAG and VCC to the Fusion part remain powered; otherwise, JTAG signals will not be able to transition the Fusion device, even in bypass mode.

#### VPUMP Programming Supply Voltage

Fusion devices support single-voltage ISP programming of the configuration flash and FlashROM. For programming, VPUMP should be in the 3.3 V +/-5% range. During normal device operation, VPUMP can be left floating or can be tied to any voltage between 0 V and 3.6 V.

When the VPUMP pin is tied to ground, it shuts off the charge pump circuitry, resulting in no sources of oscillation from the charge pump circuitry.

For proper programming, 0.01  $\mu$ F and 0.33  $\mu$ F capacitors (both rated at 16 V) are to be connected in parallel across VPUMP and GND, and positioned as close to the FPGA pins as possible.



# **User-Defined Supply Pins**

#### VREF I/O Voltage Reference

Reference voltage for I/O minibanks. Both AFS600 and AFS1500 (north bank only) support Microsemi Pro I/O. These I/O banks support voltage reference standard I/O. The VREF pins are configured by the user from regular I/Os, and any I/O in a bank, except JTAG I/Os, can be designated as the voltage reference I/O. Only certain I/O standards require a voltage reference—HSTL (I) and (II), SSTL2 (I) and (II), SSTL3 (I) and GTL/GTL+. One VREF pin can support the number of I/Os available in its minibank.

#### VAREF Analog Reference Voltage

The Fusion device can be configured to generate a 2.56 V internal reference voltage that can be used by the ADC. While using the internal reference, the reference voltage is output on the VAREF pin for use as a system reference. If a different reference voltage is required, it can be supplied by an external source and applied to this pin. The valid range of values that can be supplied to the ADC is 1.0 V to 3.3 V. When VAREF is internally generated by the Fusion device, a bypass capacitor must be connected from this pin to ground. The value of the bypass capacitor should be between 3.3 µF and 22 µF, which is based on the needs of the individual designs. The choice of the capacitor value has an impact on the settling time it takes the VAREF signal to reach the required specification of 2.56 V to initiate valid conversions by the ADC. If the lower capacitor value is chosen, the settling time required for VAREF to achieve 2.56 V will be shorter than when selecting the larger capacitor value. The above range of capacitor values supports the accuracy specification of the ADC, which is detailed in the datasheet. Designers choosing the smaller capacitor value will not obtain as much margin in the accuracy as that achieved with a larger capacitor value. Depending on the capacitor value selected in the Analog System Builder, a tool in Libero SoC, an automatic delay circuit will be generated using logic tiles available within the FPGA to ensure that VAREF has achieved the 2.56 V value. Microsemi recommends customers use 10 uF as the value of the bypass capacitor. Designers choosing to use an external VAREF need to ensure that a stable and clean VAREF source is supplied to the VAREF pin before initiating conversions by the ADC. Designers should also make sure that the ADCRESET signal is deasserted before initiating valid conversions.

If the user connects VAREF to external 3.3 V on their board, the internal VAREF driving OpAmp tries to bring the pin down to the nominal 2.56 V until the device is programmed and up/functional. Under this scenario, it is recommended to connect an external 3.3 V supply through a ~1 KOhm resistor to limit current, along with placing a 10-100nF capacitor between VAREF and GNDA.

# **User Pins**

#### I/O User Input/Output

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Input and output signal levels are compatible with the I/O standard selected. Unused I/O pins are configured as inputs with pull-up resistors.

During programming, I/Os become tristated and weakly pulled up to VCCI. With the VCCI and VCC supplies continuously powered up, when the device transitions from programming to operating mode, the I/Os get instantly configured to the desired user configuration.

Unused I/Os are configured as follows:

- Output buffer is disabled (with tristate value of high impedance)
- Input buffer is disabled (with tristate value of high impedance)
- · Weak pull-up is programmed

#### Axy Analog Input/Output

Analog I/O pin, where x is the analog pad type (C = current pad, G = Gate driver pad, T = Temperature pad, V = Voltage pad) and y is the Analog Quad number (0 to 9). There is a minimum 1 M $\Omega$  to ground on AV, AC, and AT. This pin can be left floating when it is unused.

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<sup>2.</sup> The ADC is functional with an external reference down to 1V, however to meet the performance parameters highlighted in the datasheet refer to the VAREF specification in Table 3-2 on page 3-3.



#### ATRTNx Temperature Monitor Return

AT returns are the returns for the temperature sensors. The cathode terminal of the external diodes should be connected to these pins. There is one analog return pin for every two Analog Quads. The x in the ATRTNx designator indicates the quad pairing (x = 0 for AQ1 and AQ2, x = 1 for AQ2 and AQ3, ..., x = 4 for AQ8 and AQ9). The signals that drive these pins are called out as ATRETURNxy in the software (where x and y refer to the quads that share the return signal). ATRTN is internally connected to ground. It can be left floating when it is unused. The maximum capacitance allowed across the AT pins is 500 pF.

#### GL Globals

GL I/Os have access to certain clock conditioning circuitry (and the PLL) and/or have direct access to the global network (spines). Additionally, the global I/Os can be used as Pro I/Os since they have identical capabilities. Unused GL pins are configured as inputs with pull-up resistors. See more detailed descriptions of global I/O connectivity in the "Clock Conditioning Circuits" section on page 2-22.

Refer to the "User I/O Naming Convention" section on page 2-158 for a description of naming of global pins.

# **JTAG Pins**

Fusion devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the Fusion part must be supplied to allow JTAG signals to transition the Fusion device.

Isolating the JTAG power supply in a separate I/O bank gives greater flexibility with supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned to be used, the VJTAG pin together with the TRST pin could be tied to GND.

#### TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND or VJTAG through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements. Refer to Table 2-183 for more information.

Table 2-183 • Recommended Tie-Off Values for the TCK and TRST Pins

VJTAG	Tie-Off Resistance <sup>2, 3</sup>
VJTAG at 3.3 V	200 $\Omega$ to 1 k $\Omega$
VJTAG at 2.5 V	200 $\Omega$ to 1 k $\Omega$
VJTAG at 1.8 V	500 $\Omega$ to 1 k $\Omega$
VJTAG at 1.5 V	500 Ω to 1 kΩ

#### Notes:

- 1. Equivalent parallel resistance if more than one device is on JTAG chain.
- 2. The TCK pin can be pulled up/down.
- 3. The TRST pin can only be pulled down.

## TDI Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

#### TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.



#### TMS Test Mode Select

The TMS pin controls the use of the IEEE1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

#### TRST Boundary Scan Reset Pin

The TRST pin functions as an active low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the TAP is held in reset mode. The resistor values must be chosen from Table 2-183 and must satisfy the parallel resistance value requirement. The values in Table 2-183 correspond to the resistor recommended when a single device is used and to the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entering an undesired JTAG state. In such cases, Microsemi recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all VJTAG voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements.

# **Special Function Pins**

#### NC No Connect

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

#### DC Don't Connect

This pin should not be connected to any signals on the PCB. These pins should be left unconnected.

#### NCAP Negative Capacitor

Negative Capacitor is where the negative terminal of the charge pump capacitor is connected. A capacitor, with a 2.2 µF recommended value, is required to connect between PCAP and NCAP.

#### PCAP Positive Capacitor

Positive Capacitor is where the positive terminal of the charge pump capacitor is connected. A capacitor, with a 2.2 µF recommended value, is required to connect between PCAP and NCAP.

#### PUB Push Button

*Push button* is the connection for the external momentary switch used to turn on the 1.5 V voltage regulator and can be floating if not used.

#### PTBASE Pass Transistor Base

Pass Transistor Base is the control signal of the voltage regulator. This pin should be connected to the base of the external pass transistor used with the 1.5 V internal voltage regulator and can be floating if not used.

#### PTEM Pass Transistor Emitter

Pass Transistor Emitter is the feedback input of the voltage regulator.

This pin should be connected to the emitter of the external pass transistor used with the 1.5 V internal voltage regulator and can be floating if not used.

#### XTAL1 Crystal Oscillator Circuit Input

Input to crystal oscillator circuit. Pin for connecting external crystal, ceramic resonator, RC network, or external clock input. When using an external crystal or ceramic oscillator, external capacitors are also recommended (Please refer to the crystal oscillator manufacturer for proper capacitor value).

If using external RC network or clock input, XTAL1 should be used and XTAL2 left unconnected. In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating.

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#### XTAL2 Crystal Oscillator Circuit Input

Input to crystal oscillator circuit. Pin for connecting external crystal, ceramic resonator, RC network, or external clock input. When using an external crystal or ceramic oscillator, external capacitors are also recommended (Please refer to the crystal oscillator manufacturer for proper capacitor value).

If using external RC network or clock input, XTAL1 should be used and XTAL2 left unconnected. In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating.

# Security

Fusion devices have a built-in 128-bit AES decryption core. The decryption core facilitates highly secure, in-system programming of the FPGA core array fabric and the FlashROM. The FlashROM and the FPGA core fabric can be programmed independently from each other, allowing the FlashROM to be updated without the need for change to the FPGA core fabric. The AES master key is stored in on-chip nonvolatile memory (flash). The AES master key can be preloaded into parts in a security-protected programming environment (such as the Microsemi in-house programming center), and then "blank" parts can be shipped to an untrusted programming or manufacturing center for final personalization with an AES-encrypted bitstream. Late stage product changes or personalization can be implemented easily and with high level security by simply sending a STAPL file with AES-encrypted data. Highly secure remote field updates over public networks (such as the Internet) are possible by sending and programming a STAPL file with AES-encrypted data. For more information, refer to the *Fusion Security* application note.

# 128-Bit AES Decryption

The 128-bit AES standard (FIPS-197) block cipher is the National Institute of Standards and Technology (NIST) replacement for DES (Data Encryption Standard FIPS46-2). AES has been designed to protect sensitive government information well into the 21st century. It replaces the aging DES, which NIST adopted in 1977 as a Federal Information Processing Standard used by federal agencies to protect sensitive, unclassified information. The 128-bit AES standard has  $3.4 \times 10^{38}$  possible 128-bit key variants, and it has been estimated that it would take 1,000 trillion years to crack 128-bit AES cipher text using exhaustive techniques. Keys are stored (protected with security) in Fusion devices in nonvolatile flash memory. All programming files sent to the device can be authenticated by the part prior to programming to ensure that bad programming data is not loaded into the part that may possibly damage it. All programming verification is performed on-chip, ensuring that the contents of Fusion devices remain as secure as possible.

AES decryption can also be used on the 1,024-bit FlashROM to allow for remote updates of the FlashROM contents. This allows for easy support of subscription model products and protects them with measures designed to provide the highest level of security available. See the application note *Fusion Security* for more details.

# AES for Flash Memory

AES decryption can also be used on the flash memory blocks. This provides the best available security during update of the flash memory blocks. During runtime, the encrypted data can be clocked in via the JTAG interface. The data can be passed through the internal AES decryption engine, and the decrypted data can then be stored in the flash memory block.

# **Programming**

Programming can be performed using various programming tools, such as Silicon Sculptor II (BP Micro Systems) or FlashPro3 (Microsemi).

The user can generate STP programming files from the Designer software and can use these files to program a device.

Fusion devices can be programmed in-system. During programming, VCCOSC is needed in order to power the internal 100 MHz oscillator. This oscillator is used as a source for the 20 MHz oscillator that is used to drive the charge pump for programming.



#### **ISP**

Fusion devices support IEEE 1532 ISP via JTAG and require a single VPUMP voltage of 3.3 V during programming. In addition, programming via a microcontroller in a target system can be achieved. Refer to the standard or the "In-System Programming (ISP) of Microsemi's Low Power Flash Devices Using FlashPro4/3/3X" chapter of the *Fusion FPGA Fabric User's Guide* for more details.

#### JTAG IEEE 1532

#### **Programming with IEEE 1532**

Fusion devices support the JTAG-based IEEE1532 standard for ISP. As part of this support, when a Fusion device is in an unprogrammed state, all user I/O pins are disabled. This is achieved by keeping the global IO\_EN signal deactivated, which also has the effect of disabling the input buffers. Consequently, the SAMPLE instruction will have no effect while the Fusion device is in this unprogrammed state—different behavior from that of the ProASICPLUS® device family. This is done because SAMPLE is defined in the IEEE1532 specification as a noninvasive instruction. If the input buffers were to be enabled by SAMPLE temporarily turning on the I/Os, then it would not truly be a noninvasive instruction. Refer to the standard or the "In-System Programming (ISP) of Microsemi's Low Power Flash Devices Using FlashPro4/3/3X" chapter of the Fusion FPGA Fabric User's Guide for more details.

#### **Boundary Scan**

Fusion devices are compatible with IEEE Standard 1149.1, which defines a hardware architecture and the set of mechanisms for boundary scan testing. The basic Fusion boundary scan logic circuit is composed of the test access port (TAP) controller, test data registers, and instruction register (Figure 2-146 on page 2-230). This circuit supports all mandatory IEEE 1149.1 instructions (EXTEST, SAMPLE/PRELOAD, and BYPASS) and the optional IDCODE instruction (Table 2-185 on page 2-230).

Each test section is accessed through the TAP, which has five associated pins: TCK (test clock input), TDI, TDO (test data input and output), TMS (test mode selector), and TRST (test reset input). TMS, TDI, and TRST are equipped with pull-up resistors to ensure proper operation when no input data is supplied to them. These pins are dedicated for boundary scan test usage. Refer to the "JTAG Pins" section on page 2-226 for pull-up/-down recommendations for TDO and TCK pins. The TAP controller is a 4-bit state machine (16 states) that operates as shown in Figure 2-146 on page 2-230. The 1s and 0s represent the values that must be present on TMS at a rising edge of TCK for the given state transition to occur. IR and DR indicate that the instruction register or the data register is operating in that state.

Table 2-184 • TRST and TCK Pull-Down Recommendations

VJTAG	Tie-Off Resistance*
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 $\Omega$ to 1 k $\Omega$
VJTAG at 1.8 V	500 $\Omega$ to 1 k $\Omega$
VJTAG at 1.5 V	500 Ω to 1 kΩ

Note: \*Equivalent parallel resistance if more than one device is on JTAG chain.

The TAP controller receives two control inputs (TMS and TCK) and generates control and clock signals for the rest of the test logic architecture. On power-up, the TAP controller enters the Test-Logic-Reset state. To guarantee a reset of the controller from any of the possible states, TMS must remain High for five TCK cycles. The TRST pin can also be used to asynchronously place the TAP controller in the Test-Logic-Reset state.

Fusion devices support three types of test data registers: bypass, device identification, and boundary scan. The bypass register is selected when no other register needs to be accessed in a device. This speeds up test data transfer to other devices in a test data path. The 32-bit device identification register is a shift register with four fields (LSB, ID number, part number, and version). The boundary scan register observes and controls the state of each I/O pin. Each I/O cell has three boundary scan register cells, each with a serial-in, serial-out, parallel-in, and parallel-out pin.

The serial pins are used to serially connect all the boundary scan register cells in a device into a boundary scan register chain, which starts at the TDI pin and ends at the TDO pin. The parallel ports are

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connected to the internal core logic I/O tile and the input, output, and control ports of an I/O buffer to capture and load data into the register to control or observe the logic state of each I/O.

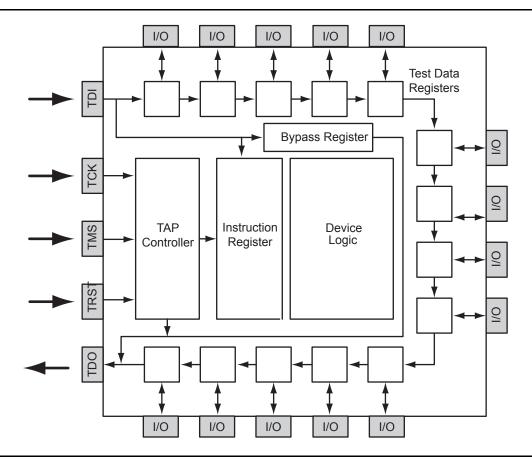


Figure 2-146 • Boundary Scan Chain in Fusion

Table 2-185 • Boundary Scan Opcodes

	Hex Opcode
EXTEST	00
HIGHZ	07
USERCODE	0E
SAMPLE/PRELOAD	01
IDCODE	0F
CLAMP	05
BYPASS	FF



# IEEE 1532 Characteristics

JTAG timing delays do not include JTAG I/Os. To obtain complete JTAG timing, add I/O buffer delays to the corresponding standard selected; refer to the I/O timing characteristics in the "User I/Os" section on page 2-132 for more details.

# **Timing Characteristics**

Table 2-186 • JTAG 1532

Commercial Temperature Range Conditions: T<sub>J</sub> = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>DISU</sub>	Test Data Input Setup Time	0.50	0.57	0.67	ns
t <sub>DIHD</sub>	Test Data Input Hold Time	1.00	1.13	1.33	ns
t <sub>TMSSU</sub>	Test Mode Select Setup Time	0.50	0.57	0.67	ns
t <sub>TMDHD</sub>	Test Mode Select Hold Time	1.00	1.13	1.33	ns
t <sub>TCK2Q</sub>	Clock to Q (data out)	6.00	6.80	8.00	ns
t <sub>RSTB2Q</sub>	Reset to Q (data out)	20.00	22.67	26.67	ns
F <sub>TCKMAX</sub>	TCK Maximum Frequency	25.00	22.00	19.00	MHz
t <sub>TRSTREM</sub>	ResetB Removal Time	0.00	0.00	0.00	ns
t <sub>TRSTREC</sub>	ResetB Recovery Time	0.20	0.23	0.27	ns
t <sub>TRSTMPW</sub>	ResetB Minimum Pulse	TBD	TBD	TBD	ns

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

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# 3 – DC and Power Characteristics

# **General Specifications**

# **Operating Conditions**

Stresses beyond those listed in Table 3-1 may cause permanent damage to the device.

Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Devices should not be operated outside the recommended operating ranges specified in Table 3-2 on page 3-3.

Table 3-1 • Absolute Maximum Ratings

Symbol	Parameter	Commercial	Industrial	Units
VCC	DC core supply voltage	-0.3 to 1.65	-0.3 to 1.65	V
VJTAG	JTAG DC voltage	-0.3 to 3.75	-0.3 to 3.75	V
VPUMP	Programming voltage	-0.3 to 3.75	-0.3 to 3.75	V
VCCPLL	Analog power supply (PLL)	-0.3 to 1.65	-0.3 to 1.65	V
VCCI	DC I/O output buffer supply voltage	-0.3 to 3.75	-0.3 to 3.75	V
VI	I/O input voltage <sup>1</sup>	<ul> <li>-0.3 V to 3.6 V (when I/O hot insertion mode is enabled)</li> <li>-0.3 V to (VCCI + 1 V) or 3.6 V, whichever voltage is lower (when I/O hot-insertion mode is disabled)</li> </ul>		
VCC33A	+3.3 V power supply	-0.3 to 3.75 <sup>2</sup>	–0.3 to 3.75 <sup>2</sup>	V
VCC33PMP	+3.3 V power supply	-0.3 to 3.75 <sup>2</sup>	-0.3 to 3.75 <sup>2</sup>	V
VAREF	Voltage reference for ADC	-0.3 to 3.75	-0.3 to 3.75	V
VCC15A	Digital power supply for the analog system	-0.3 to 1.65	-0.3 to 1.65	V
VCCNVM	Embedded flash power supply	-0.3 to 1.65	-0.3 to 1.65	V
vccosc	Oscillator power supply	-0.3 to 3.75	-0.3 to 3.75	V

#### Notes:

- 1. The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 3-4 on page 3-4.
- 2. Analog data not valid beyond 3.65 V.
- 3. The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.
- 4. For flash programming and retention maximum limits, refer to Table 3-5 on page 3-5. For recommended operating limits refer to Table 3-2 on page 3-3.



Table 3-1 • Absolute Maximum Ratings (continued)

Symbol	Parameter	Commercial	Industrial	Units
AV, AC	Unpowered, ADC reset asserted or unconfigured	-11.0 to 12.6	-11.0 to 12.0	V
	Analog input (+16 V to +2 V prescaler range)	–0.4 to 12.6	-0.4 to 12.0	V
	Analog input (+1 V to +0.125 V prescaler range)	-0.4 to 3.75	-0.4 to 3.75	V
	Analog input (–16 V to –2 V prescaler range)	-11.0 to 0.4	-11.0 to 0.4	V
	Analog input (–1 V to –0.125 V prescaler range)	-3.75 to 0.4	-3.75 to 0.4	V
	Analog input (direct input to ADC)	-0.4 to 3.75	-0.4 to 3.75	V
	Digital input	–0.4 to 12.6	-0.4 to 12.0	V
AG	Unpowered, ADC reset asserted or unconfigured	-11.0 to 12.6	-11.0 to 12.0	V
	Low Current Mode (1 μA, 3 μA, 10 μA, 30 μA)	–0.4 to 12.6	-0.4 to 12.0	V
	Low Current Mode (–1 μA, –3 μA, –10 μA, –30 μA)	-11.0 to 0.4	-11.0 to 0.4	V
	High Current Mode <sup>3</sup>	-11.0 to 12.6	-11.0 to 12.0	V
AT	Unpowered, ADC reset asserted or unconfigured	-0.4 to 16.0	-0.4 to 15.0	V
	Analog input (+16 V, 4 V prescaler range)	-0.4 to 16.0	-0.4 to 15.0	V
	Analog input (direct input to ADC)	–0.4 to 3.75	-0.4 to 3.75	V
	Digital input	-0.4 to 16.0	-0.4 to 15.0	V
T <sub>STG</sub> <sup>4</sup>	Storage temperature	<b>–</b> 65 t	to +150	°C
T <sub>J</sub> <sup>4</sup>	Junction temperature	+	125	°C

# Notes:

<sup>1.</sup> The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 3-4 on page 3-4.

<sup>2.</sup> Analog data not valid beyond 3.65 V.

<sup>3.</sup> The high current mode has a maximum power limit of 20 mW. Appropriate current limit resistors must be used, based on voltage on the pad.

<sup>4.</sup> For flash programming and retention maximum limits, refer to Table 3-5 on page 3-5. For recommended operating limits refer to Table 3-2 on page 3-3.



Table 3-2 • Recommended Operating Conditions<sup>1</sup>

Symbol	Parameter <sup>2</sup>		Commercial	Industrial	Units
T <sub>J</sub>	Junction temperature		0 to +85	-40 to +100	°C
VCC	1.5 V DC core supply voltage		1.425 to 1.575	1.425 to 1.575	V
VJTAG	JTAG DC voltage		1.4 to 3.6	1.4 to 3.6	V
VPUMP	Programming voltage	Programming mode <sup>3</sup>	3.15 to 3.45	3.15 to 3.45	V
		Operation <sup>4</sup>	0 to 3.6	0 to 3.6	V
VCCPLL	Analog power supply (PLL)		1.425 to 1.575	1.425 to 1.575	V
VCCI	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	LVDS differential I/O		2.375 to 2.625	2.375 to 2.625	V
	LVPECL differential I/O		3.0 to 3.6	3.0 to 3.6	V
VCC33A	+3.3 V power supply		2.97 to 3.63	2.97 to 3.63	V
VCC33PMP	+3.3 V power supply		2.97 to 3.63	2.97 to 3.63	V
VAREF	Voltage reference for ADC		2.527 to 2.593	2.527 to 2.593	V
VCC15A <sup>5</sup>	Digital power supply for the analog system		1.425 to 1.575	1.425 to 1.575	V
VCCNVM	Embedded flash power supply		1.425 to 1.575	1.425 to 1.575	V
VCCOSC	Oscillator power supply		2.97 to 3.63	2.97 to 3.63	V
AV, AC <sup>6</sup>	Unpowered, ADC reset asserted or unconfigured		-10.5 to 12.0	-10.5 to 11.6	V
	Analog input (+16 V to +2 V prescaler range)		-0.3 to 12.0	-0.3 to 11.6	V
	Analog input (+1 V to + 0.125 V prescaler range)		-0.3 to 3.6	-0.3 to 3.6	V
	Analog input (–16 V to –2 V prescaler range)		-10.5 to 0.3	-10.5 to 0.3	V
	Analog input (-1 V to -0.125 V prescaler range)		-3.6 to 0.3	-3.6 to 0.3	V
	Analog input (direct input to ADC)		-0.3 to 3.6	-0.3 to 3.6	V
	Digital input		-0.3 to 12.0	–0.3 to 11.6	V
AG <sup>6</sup>	Unpowered, ADC reset asserted or unconfigured		-10.5 to 12.0	-10.5 to 11.6	V
	Low Current Mode (1 μA, 3 μA, 10 μA, 30 μA)		-0.3 to 12.0	-0.3 to 11.6	V
	Low Current Mode (–1 μA, –3 μA, –10 μA, –30 μA)		-10.5 to 0.3	-10.5 to 0.3	V
	High Current Mode <sup>7</sup>		-10.5 to 12.0	-10.5 to 11.6	V
AT <sup>6</sup>	Unpowered, ADC reset asserted or unconfigured		-0.3 to 15.5	-0.3 to 14.5	V
	Analog input (+16 V, +4 V prescaler range)		-0.3 to 15.5	-0.3 to 14.5	V
	Analog input (direct input to ADC)		-0.3 to 3.6	-0.3 to 3.6	V
	Digital input		-0.3 to 15.5	-0.3 to 14.5	V

#### Notes:

- The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-85 on page 2-157.
- 2. All parameters representing voltages are measured with respect to GND unless otherwise specified.
- 3. The programming temperature range supported is  $T_{ambient}$  = 0°C to 85°C.
- 4. VPUMP can be left floating during normal operation (not programming mode).
- 5. Violating the V<sub>CC15A</sub> recommended voltage supply during an embedded flash program cycle can corrupt the page being programmed.
- 6. The input voltage may overshoot by up to 500 mV above the Recommended Maximum (150 mV in Direct mode), provided the duration of the overshoot is less than 50% of the operating lifetime of the device.
- 7. The AG pad should also conform to the limits as specified in Table 2-48 on page 2-114.

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Table 3-3 • Input Resistance of Analog Pads

Pads	Pad Configuration	Prescaler Range	Input Resistance to Ground
AV, AC	Analog Input (direct input to ADC)	-	2 kΩ (typical)
		-	> 10 MΩ
	Analog Input (positive prescaler)	+16 V to +2 V	1 MΩ (typical)
		+1 V to +0.125 V	> 10 MΩ
	Analog Input (negative prescaler)	–16 V to –2 V	1 MΩ (typical)
		–1 V to –0.125 V	> 10 MΩ
	Digital input	+16 V to +2 V	1 MΩ (typical)
	Current monitor	+16 V to +2 V	1 MΩ (typical)
		–16 V to –2 V	1 MΩ (typical)
AT	Analog Input (direct input to ADC)	-	1 MΩ (typical)
	Analog Input (positive prescaler)	+16 V, +4 V	1 MΩ (typical)
	Digital input	+16 V, +4 V	1 MΩ (typical)
	Temperature monitor	+16 V, +4 V	> 10 MΩ

Table 3-4 • Overshoot and Undershoot Limits <sup>1</sup>

VCCI	Average VCCI–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle <sup>2</sup>	Maximum Overshoot/ Undershoot <sup>2</sup> 1.4 V	
2.7 V or less	10%		
	5%	1.49 V	
3.0 V	10%	1.1 V	
	5%	1.19 V	
3.3 V	10%	0.79 V	
	5%	0.88 V	
3.6 V	10%	0.45 V	
	5%	0.54 V	

#### Notes:

- 1. Based on reliability requirements at a junction temperature of 85°C.
- 2. The duration is allowed at one cycle out of six clock cycle. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.



Table 3-5 • FPGA Programming, Storage, and Operating Limits

Product Grade	Storage Temperature	Element	Grade Programming Cycles	Retention
Commercial	Min. T <sub>J</sub> = 0°C	FPGA/FlashROM	500	20 years
	Max. T <sub>J</sub> = 85°C	Embedded Flash	< 1,000	20 years
			< 10,000	10 years
			< 15,000	5 years
Industrial	Min. $T_J = -40^{\circ}C$	FPGA/FlashROM	500	20 years
	Max. T <sub>J</sub> = 100°C	Embedded Flash	< 1,000	20 years
			< 10,000	10 years
			< 15,000	5 years

# I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every Fusion device. These circuits ensure easy transition from the powered off state to the powered up state of the device. The many different supplies can power up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 3-1 on page 3-6.

There are five regions to consider during power-up.

Fusion I/Os are activated only if ALL of the following three conditions are met:

- 1. VCC and VCCI are above the minimum specified trip points (Figure 3-1).
- 2. VCCI > VCC 0.75 V (typical).
- 3. Chip is in the operating mode.

#### **V<sub>CCI</sub> Trip Point:**

Ramping up: 0.6 V < trip\_point\_up < 1.2 V Ramping down: 0.5 V < trip\_point\_down < 1.1 V

**V<sub>CC</sub>** Trip Point:

Ramping up: 0.6 V < trip\_point\_up < 1.1 V Ramping down: 0.5 V < trip\_point\_down < 1 V

VCC and VCCI ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

- During programming, I/Os become tristated and weakly pulled up to VCCI.
- JTAG supply, PLL power supplies, and charge pump VPUMP supply have no influence on I/O behavior.

# Internal Power-Up Activation Sequence

- 1. Core
- 2. Input buffers
- 3. Output buffers, after 200 ns delay from input buffer activation

## PLL Behavior at Brownout Condition

Microsemi recommends using monotonic power supplies or voltage regulators to ensure proper power-up behavior. Power ramp-up should be monotonic at least until VCC and VCCPLX exceed brownout activation levels. The  $V_{CC}$  activation level is specified as 1.1 V worst-case (see Figure 3-1 on page 3-6 for more details).

When PLL power supply voltage and/or VCC levels drop below the VCC brownout levels  $(0.75~V\pm0.25~V)$ , the PLL output lock signal goes low and/or the output clock is lost.

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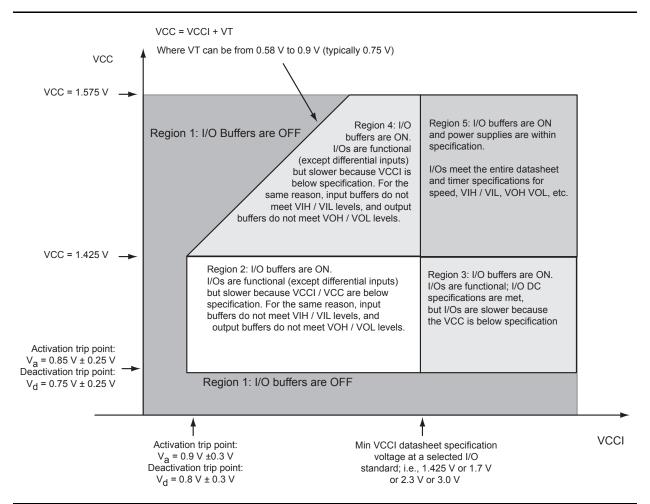


Figure 3-1 • I/O State as a Function of VCCI and VCC Voltage Levels



# **Thermal Characteristics**

## Introduction

The temperature variable in the Microsemi Designer software refers to the junction temperature, not the ambient, case, or board temperatures. This is an important distinction because dynamic and static power consumption will cause the chip's junction temperature to be higher than the ambient, case, or board temperatures. EQ 1 through EQ 3 give the relationship between thermal resistance, temperature gradient, and power.

$$\theta_{JA} = \frac{T_J - \theta_A}{P}$$

EQ 1

$$\theta_{JB} = \frac{T_J - T_B}{P}$$

EQ 2

$$\theta_{JC} = \frac{T_J - T_C}{P}$$

EQ3

where

 $\theta_{JA}$  = Junction-to-air thermal resistance

 $\theta_{JB}$  = Junction-to-board thermal resistance

 $\theta_{JC}$  = Junction-to-case thermal resistance

 $T_J$  = Junction temperature

T<sub>A</sub> = Ambient temperature

 $T_B$  = Board temperature (measured 1.0 mm away from the

package edge)

T<sub>C</sub> = Case temperature

P = Total power dissipated by the device

Table 3-6 • Package Thermal Resistance

		$\theta_{\sf JA}$				
Product	Still Air	1.0 m/s	2.5 m/s	θЈС	$\theta_{\sf JB}$	Units
AFS090-QN108	34.5	30.0	27.7	8.1	16.7	°C/W
AFS090-QN180	33.3	27.6	25.7	9.2	21.2	°C/W
AFS250-QN180	32.2	26.5	24.7	5.7	15.0	°C/W
AFS250-PQ208 <sup>1</sup>	42.1	38.4	37	20.5	36.3	°C/W
AFS600-PQ208 <sup>1</sup>	23.9	21.3	20.48	6.1	16.5	°C/W
AFS090-FG256	37.7	33.9	32.2	11.5	29.7	°C/W
AFS250-FG256	33.7	30.0	28.3	9.3	24.8	°C/W
AFS600-FG256	28.9	25.2	23.5	6.8	19.9	°C/W
AFS1500-FG256	23.3	19.6	18.0	4.3	14.2	°C/W
AFS600-FG484	21.8	18.2	16.7	7.7	16.8	°C/W
AFS1500-FG484	21.6	16.8	15.2	5.6	14.9	°C/W
AFS1500-FG676	TBD	TBD	TBD	TBD	TBD	°C/W

<sup>1.</sup> The package PQ208 is discontinued. For more information, see PDN 1407: Specific Part / Package Combinations.

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#### Theta-JA

Junction-to-ambient thermal resistance ( $\theta_{JA}$ ) is determined under standard conditions specified by JEDEC (JESD-51), but it has little relevance in actual performance of the product. It should be used with caution but is useful for comparing the thermal performance of one package to another.

A sample calculation showing the maximum power dissipation allowed for the AFS600-FG484 package under forced convection of 1.0 m/s and 75°C ambient temperature is as follows:

Maximum Power Allowed = 
$$\frac{T_{J(MAX)} - T_{A(MAX)}}{\theta_{JA}}$$

EQ4

where

 $\theta_{\text{JA}}$  = 19.00°C/W (taken from Table 3-6 on page 3-7).

 $T_A = 75.00^{\circ}C$ 

Maximum Power Allowed = 
$$\frac{100.00^{\circ}C - 75.00^{\circ}C}{19.00^{\circ}C/W} = 1.3 \text{ W}$$

EQ 5

The power consumption of a device can be calculated using the Microsemi power calculator. The device's power consumption must be lower than the calculated maximum power dissipation by the package. If the power consumption is higher than the device's maximum allowable power dissipation, a heat sink can be attached on top of the case, or the airflow inside the system must be increased.

#### Theta-JB

Junction-to-board thermal resistance ( $\theta_{JB}$ ) measures the ability of the package to dissipate heat from the surface of the chip to the PCB. As defined by the JEDEC (JESD-51) standard, the thermal resistance from junction to board uses an isothermal ring cold plate zone concept. The ring cold plate is simply a means to generate an isothermal boundary condition at the perimeter. The cold plate is mounted on a JEDEC standard board with a minimum distance of 5.0 mm away from the package edge.

### Theta-JC

Junction-to-case thermal resistance  $(\theta_{JC})$  measures the ability of a device to dissipate heat from the surface of the chip to the top or bottom surface of the package. It is applicable for packages used with external heat sinks. Constant temperature is applied to the surface in consideration and acts as a boundary condition. This only applies to situations where all or nearly all of the heat is dissipated through the surface in consideration.

#### Calculation for Heat Sink

For example, in a design implemented in an AFS600-FG484 package with 2.5 m/s airflow, the power consumption value using the power calculator is 3.00 W. The user-dependent  $T_a$  and  $T_j$  are given as follows:

 $T_{J} = 100.00^{\circ}C$ 

 $T_{\Delta} = 70.00^{\circ}C$ 

From the datasheet:

 $\theta_{JA} = 17.00$ °C/W

 $\theta_{\text{IC}} = 8.28^{\circ}\text{C/W}$ 

$$P = \frac{T_J - T_A}{\theta_{J\Delta}} = \frac{100^{\circ}C - 70^{\circ}C}{17.00 \text{ W}} = 1.76 \text{ W}$$

EQ6



The 1.76 W power is less than the required 3.00 W. The design therefore requires a heat sink, or the airflow where the device is mounted should be increased. The design's total junction-to-air thermal resistance requirement can be estimated by EQ 7:

$$\theta_{ja(total)} = \frac{T_J - T_A}{P} = \frac{100^{\circ}C - 70^{\circ}C}{3.00 \text{ W}} = 10.00^{\circ}C/W$$

EQ7

Determining the heat sink's thermal performance proceeds as follows:

$$\theta_{\text{JA(TOTAL)}} = \theta_{\text{JC}} + \theta_{\text{CS}} + \theta_{\text{SA}}$$

EQ8

where

 $\theta_{JA} = 0.37^{\circ}C/W$ 

= Thermal resistance of the interface material between the case and the heat sink, usually provided by the thermal interface manufacturer

 $\theta_{SA}$  = Thermal resistance of the heat sink in °C/W

$$\theta_{SA} = \theta_{JA(TOTAL)} - \theta_{JC} - \theta_{CS}$$

EQ9

$$\theta_{SA} = 13.33^{\circ}\text{C/W} - 8.28^{\circ}\text{C/W} - 0.37^{\circ}\text{C/W} = 5.01^{\circ}\text{C/W}$$

A heat sink with a thermal resistance of 5.01°C/W or better should be used. Thermal resistance of heat sinks is a function of airflow. The heat sink performance can be significantly improved with increased airflow.

Carefully estimating thermal resistance is important in the long-term reliability of an Microsemi FPGA. Design engineers should always correlate the power consumption of the device with the maximum allowable power dissipation of the package selected for that device.

Note: The junction-to-air and junction-to-board thermal resistances are based on JEDEC standard (JESD-51) and assumptions made in building the model. It may not be realized in actual application and therefore should be used with a degree of caution. Junction-to-case thermal resistance assumes that all power is dissipated through the case.

# Temperature and Voltage Derating Factors

Table 3-7 • Temperature and Voltage Derating Factors for Timing Delays (normalized to  $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.425 V)

Array Voltage	Junction Temperature (°C)							
VCC (V)	-40°C	0°C	25°C	70°C	85°C	100°C		
1.425	0.88	0.93	0.95	1.00	1.02	1.05		
1.500	0.83	0.88	0.90	0.95	0.96	0.99		
1.575	0.80	0.85	0.87	0.91	0.93	0.96		

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# **Calculating Power Dissipation**

# **Quiescent Supply Current**

Table 3-8 • AFS1500 Quiescent Supply Current Characteristics

Parameter	Description	Conditions	Temp.	Min.	Тур.	Max.	Unit
ICC <sup>1</sup>	1.5 V quiescent current	Operational standby <sup>4</sup> ,	$T_J = 25^{\circ}C$		20	40	mA
		VCC = 1.575 V	T <sub>J</sub> = 85°C		32	65	mA
			T <sub>J</sub> = 100°C		59	120	mA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VCC = 0 V			0	0	μA
ICC33 <sup>2</sup>	3.3 V analog supplies	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		9.8	13	mA
	current	VCC33 = 3.63 V	T <sub>J</sub> = 85°C		10.7	14	mA
			T <sub>J</sub> = 100°C		10.8	15	mA
		Operational standby, only Analog	T <sub>J</sub> = 25°C		0.31	2	mA
		VCC33 = 3.03 V	T <sub>J</sub> = 85°C		0.35	2	mA
			T <sub>J</sub> = 100°C		0.45	2	mA
		Standby mode <sup>5</sup> , VCC33 = 3.63 V	T <sub>J</sub> = 25°C		2.9	3.6	mA
			T <sub>J</sub> = 85°C		2.9	4	mA
			T <sub>J</sub> = 100°C		3.3	6	mA
		Sleep mode <sup>6</sup> , VCC33 = 3.63 V	T <sub>J</sub> = 25°C		17	19	μΑ
			T <sub>J</sub> = 85°C		18	20	μΑ
			T <sub>J</sub> = 100°C		24	25	μΑ
ICCI <sup>3</sup>	I/O quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		417	649	μΑ
		Standby mode, and Sleep Mode <sup>6</sup> , VCCIx = 3.63 V	T <sub>J</sub> = 85°C		417	649	μΑ
			T <sub>J</sub> = 100°C		417	649	μΑ

#### Notes:

- 1. ICC is the 1.5 V power supplies, ICC and ICC15A.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.



Table 3-8 • AFS1500 Quiescent Supply Current Characteristics (continued)

Parameter	Description	Conditions	Temp.	Min.	Тур.	Max.	Unit
IJTAG	JTAG I/O quiescent	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		80	100	μA
	current	VJTAG = 3.63 V	T <sub>J</sub> = 85°C		80	100	μΑ
			T <sub>J</sub> = 100°C		80	100	μΑ
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VJTAG = 0 V			0	0	μA
IPP	Programming supply	Non-programming mode,	T <sub>J</sub> = 25°C		39	80	μA
	current	VPUMP = 3.63 V	T <sub>J</sub> = 85°C		40	80	μA
			T <sub>J</sub> = 100°C		40	80	μΑ
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VPUMP = 0 V			0	0	μΑ
ICCNVM	Embedded NVM	Reset asserted, V <sub>CCNVM</sub> = 1.575 V	T <sub>J</sub> = 25°C		50	150	μΑ
	current		T <sub>J</sub> =85°C		50	150	μΑ
			T <sub>J</sub> = 100°C		50	150	μΑ
ICCPLL	1.5 V PLL quiescent	Operational standby	T <sub>J</sub> = 25°C		130	200	μΑ
	current	, VCCPLL = 1.575 V	T <sub>J</sub> = 85°C		130	200	μΑ
			T <sub>J</sub> = 100°C		130	200	μΑ

- 1. ICC is the 1.5 V power supplies, ICC and ICC15A.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.

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Table 3-9 • AFS600 Quiescent Supply Current Characteristics

Parameter	Description	Conditions	Temp.	Min	Тур	Max	Unit
ICC <sup>1</sup>	1.5 V quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		13	25	mA
		VCC = 1.575 V	T <sub>J</sub> = 85°C		20	45	mA
			T <sub>J</sub> =100°C		25	75	mA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VCC = 0 V			0	0	μA
ICC33 <sup>2</sup>	3.3 V analog supplies	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		9.8	13	mA
	current	VCC33 = 3.63 V	T <sub>J</sub> = 85°C		10.7	14	mA
			T <sub>J</sub> = 100°C		10.8	15	mA
		Operational standby,	T <sub>J</sub> = 25°C		0.31	2	mA
		only Analog Quad and -3.3 V output ON, VCC33 = 3.63 V	T <sub>J</sub> = 85°C		0.35	2	mA
			T <sub>J</sub> = 100°C		0.45	2	mA
		Standby mode <sup>5</sup> ,	T <sub>J</sub> = 25°C		2.8	3.6	mA
		VCC33 = 3.63 V	T <sub>J</sub> = 85°C		2.9	4	mA
			T <sub>J</sub> = 100°C		3.5	6	mA
		Sleep mode <sup>6</sup> , V <sub>CC33</sub> = 3.63 V	T <sub>J</sub> = 25°C		17	19	μΑ
			$T_J = 85^{\circ}C$		18	20	μΑ
			T <sub>J</sub> = 100°C		24	25	μΑ
ICCI <sup>3</sup>	I/O quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		417	648	μΑ
		VCCIx = 3.63 V	T <sub>J</sub> = 85°C		417	648	μΑ
			T <sub>J</sub> = 100°C		417	649	μΑ
IJTAG	JTAG I/O quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		80	100	μΑ
		VJTAG = 3.63 V	T <sub>J</sub> = 85°C		80	100	μΑ
			T <sub>J</sub> = 100°C		80	100	μΑ
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VJTAG = 0 V			0	0	μA

- 1. ICC is the 1.5 V power supplies, ICC and ICC15A.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.



Table 3-9 • AFS600 Quiescent Supply Current Characteristics (continued)

Parameter	Description	Conditions	Temp.	Min	Тур	Max	Unit
IPP	Programming supply	Non-programming mode,	T <sub>J</sub> = 25°C		36	80	μA
	current	VPUMP = 3.63 V	T <sub>J</sub> = 85°C		36	80	μA
			T <sub>J</sub> = 100°C		36	80	μA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VPUMP = 0 V			0	0	μA
ICCNVM	Embedded NVM current	Reset asserted,	$T_J = 25^{\circ}C$		22	80	μA
		VCCNVM = 1.575 V	T <sub>J</sub> = 85°C		24	80	μA
			T <sub>J</sub> = 100°C		25	80	μA
ICCPLL	1.5 V PLL quiescent current	ont Operational standby, VCCPLL = 1.575 V	$T_J = 25^{\circ}C$		130	200	μA
	VCCI		T <sub>J</sub> = 85°C		130	200	μA
			T <sub>J</sub> = 100°C		130	200	μA

- 1. ICC is the 1.5 V power supplies, ICC and ICC15A.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.

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Table 3-10 • AFS250 Quiescent Supply Current Characteristics

Parameter	Description	Conditions	Temp.	Min	Тур	Max	Unit
ICC <sup>1</sup>	1.5 V quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		4.8	10	mA
		VCC = 1.575 V	T <sub>J</sub> = 85°C		8.2	30	mA
			T <sub>J</sub> = 100°C		15	50	mA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VCC = 0 V			0	0	μA
ICC33 <sup>2</sup>	3.3 V analog supplies	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		9.8	13	mA
	current	VCC33 = 3.63 V	T <sub>J</sub> = 85°C		9.8	14	mA
			T <sub>J</sub> = 100°C		10.8	15	mA
		Operational standby, only	$T_J = 25^{\circ}C$		0.29	2	mA
		Analog Quad and –3.3 V output ON, VCC33 = 3.63 V	$T_J = 85^{\circ}C$		0.31	2	mA
			T <sub>J</sub> = 100°C		0.45	2	mA
		Standby mode <sup>5</sup> , VCC33 = 3.63V	$T_J = 25^{\circ}C$		2.9	3.0	mA
			T <sub>J</sub> = 85°C		2.9	3.1	mA
			T <sub>J</sub> = 100°C		3.5	6	mA
		Sleep mode <sup>6</sup> , VCC33 = 3.63 V	$T_J = 25^{\circ}C$		19	18	μΑ
			$T_J = 85^{\circ}C$		19	20	μΑ
			T <sub>J</sub> = 100°C		24	25	μΑ
ICCI <sup>3</sup>	I/O quiescent current	Operational standby <sup>6</sup> ,	$T_J = 25^{\circ}C$		266	437	μΑ
		VCCIx = 3.63 V	T <sub>J</sub> = 85°C		266	437	μΑ
			T <sub>J</sub> = 100°C		266	437	μA
IJTAG	JTAG I/O quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		80	100	μΑ
		VJTAG = 3.63 V	T <sub>J</sub> = 85°C		80	100	μΑ
			T <sub>J</sub> = 100°C		80	100	μΑ
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VJTAG = 0 V			0	0	μA

- 1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, and ICCI2.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTA G = VPUMP = 0 V.



Table 3-10 • AFS250 Quiescent Supply Current Characteristics (continued)

Parameter	Description	Conditions	Temp.	Min	Тур	Max	Unit
IPP	Programming supply	Non-programming mode,	T <sub>J</sub> = 25°C		37	80	μA
	current	VPUMP = 3.63 V	T <sub>J</sub> = 85°C		37	80	μA
			T <sub>J</sub> = 100°C		80	100	μA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VPUMP = 0 V			0	0	μA
ICCNVM	Embedded NVM current	Reset asserted,	$T_J = 25^{\circ}C$		10	40	μA
		VCCNVM = 1.575 V	T <sub>J</sub> = 85°C		14	40	μA
			T <sub>J</sub> = 100°C		14	40	μA
ICCPLL	1.5 V PLL quiescent current		$T_J = 25^{\circ}C$		65	100	μA
	VCCPLI	VCCPLL = 1.575 V	T <sub>J</sub> = 85°C		65	100	μA
			T <sub>J</sub> = 100°C		65	100	μA

- 1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, and ICCI2.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTA G = VPUMP = 0 V.

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Table 3-11 • AFS090 Quiescent Supply Current Characteristics

Parameter	Description	Conditions	Temp.	Min	Тур	Max	Unit
ICC <sup>1</sup>	1.5 V quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		5	7.5	mA
		VCC = 1.575 V	T <sub>J</sub> = 85°C		6.5	20	mA
			T <sub>J</sub> = 100°C		14	48	mA
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , V <sub>CC</sub> = 0 V			0	0	μA
ICC33 <sup>2</sup>	3.3 V analog supplies	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		9.8	12	mA
	current	VCC33 = 3.63 V	T <sub>J</sub> = 85°C		9.8	12	mA
			T <sub>J</sub> = 100°C		10.7	15	mA
		Operational standby, only	T <sub>J</sub> = 25°C		0.30	2	mA
		Analog Quad and –3.3 V output ON, VCC33 = 3.63 V	T <sub>J</sub> = 85°C		0.30	2	mA
			T <sub>J</sub> = 100°C		0.45	2	mA
		Standby mode <sup>5</sup> ,	T <sub>J</sub> = 25°C		2.9	2.9	mA
		VCC33 = 3.63 V	T <sub>J</sub> = 85°C		2.9	3.0	mA
			T <sub>J</sub> = 100°C		3.5	6	mA
		Sleep mode <sup>6</sup> , VCC33 = 3.63 V	T <sub>J</sub> = 25°C		17	18	μΑ
			T <sub>J</sub> = 85°C		18	20	μΑ
			T <sub>J</sub> = 100°C		24	25	μΑ
ICCI <sup>3</sup>	I/O quiescent current	Operational standby <sup>6</sup> , VCCIx = 3.63 V	T <sub>J</sub> = 25°C		260	437	μΑ
			T <sub>J</sub> = 85°C		260	437	μΑ
			T <sub>J</sub> = 100°C		260	437	μΑ
IJTAG	JTAG I/O quiescent current	Operational standby <sup>4</sup> ,	T <sub>J</sub> = 25°C		80	100	μΑ
		VJTAG = 3.63 V	T <sub>J</sub> = 85°C		80	100	μΑ
			T <sub>J</sub> = 100°C		80	100	μΑ
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VJTAG = 0 V			0	0	μA
IPP	Programming supply current	Non-programming mode, VPUMP = 3.63 V	T <sub>J</sub> = 25°C		37	80	μA
			T <sub>J</sub> = 85°C		37	80	μΑ
			T <sub>J</sub> = 100°C		80	100	μΑ
		Standby mode <sup>5</sup> or Sleep mode <sup>6</sup> , VPUMP = 0 V			0	0	μA

- 1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, and ICCI2.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.



Table 3-11 • AFS090 Quiescent Supply Current Characteristics (continued)

Parameter	Description	Conditions	Temp.	Min	Тур	Max	Unit
ICCNVM	Embedded NVM current	Reset asserted,	T <sub>J</sub> = 25°C		10	40	μΑ
		VCCNVM = 1.575 V	T <sub>J</sub> = 85°C		14	40	μΑ
			T <sub>J</sub> = 100°C		14	40	μΑ
ICCPLL	1.5 V PLL quiescent current		T <sub>J</sub> = 25°C		65	100	μΑ
		VCCPLL = 1.575 V	T <sub>J</sub> = 85°C		65	100	μΑ
			T <sub>J</sub> = 100°C		65	100	μA

- 1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.
- 2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
- 3. ICCI includes all ICCI0, ICCI1, and ICCI2.
- 4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
- 5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
- 6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.

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# Power per I/O Pin

Table 3-12 • Summary of I/O Input Buffer Power (per pin)—Default I/O Software Settings

	VCCI (V)	Static Power PDC7 (mW) <sup>1</sup>	Dynamic Power PAC9 (μW/MHz) <sup>2</sup>
Applicable to Pro I/O Banks	1		l
Single-Ended			
3.3 V LVTTL/LVCMOS	3.3	_	17.39
3.3 V LVTTL/LVCMOS – Schmitt trigger	3.3	_	25.51
2.5 V LVCMOS	2.5	_	5.76
2.5 V LVCMOS – Schmitt trigger	2.5	_	7.16
1.8 V LVCMOS	1.8	_	2.72
1.8 V LVCMOS – Schmitt trigger	1.8	_	2.80
1.5 V LVCMOS (JESD8-11)	1.5	_	2.08
1.5 V LVCMOS (JESD8-11) – Schmitt trigger	1.5	_	2.00
3.3 V PCI	3.3	_	18.82
3.3 V PCI – Schmitt trigger	3.3	_	20.12
3.3 V PCI-X	3.3	_	18.82
3.3 V PCI-X – Schmitt trigger	3.3	_	20.12
Voltage-Referenced			-
3.3 V GTL	3.3	2.90	8.23
2.5 V GTL	2.5	2.13	4.78
3.3 V GTL+	3.3	2.81	4.14
2.5 V GTL+	2.5	2.57	3.71
HSTL (I)	1.5	0.17	2.03
HSTL (II)	1.5	0.17	2.03
SSTL2 (I)	2.5	1.38	4.48
SSTL2 (II)	2.5	1.38	4.48
SSTL3 (I)	3.3	3.21	9.26
SSTL3 (II)	3.3	3.21	9.26
Differential	•		•
LVDS	2.5	2.26	1.50
LVPECL	3.3	5.71	2.17

# Notes:

<sup>1.</sup> PDC7 is the static power (where applicable) measured on VCCI.

<sup>2.</sup> PAC9 is the total dynamic power measured on VCC and VCCI.



Table 3-12 • Summary of I/O Input Buffer Power (per pin)—Default I/O Software Settings (continued)

	VCCI (V)	Static Power PDC7 (mW) <sup>1</sup>	Dynamic Power PAC9 (µW/MHz) <sup>2</sup>
Applicable to Advanced I/O Banks	1223(1,		(,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
Single-Ended			
3.3 V LVTTL/LVCMOS	3.3	_	16.69
2.5 V LVCMOS	2.5	_	5.12
1.8 V LVCMOS	1.8	_	2.13
1.5 V LVCMOS (JESD8-11)	1.5	_	1.45
3.3 V PCI	3.3	_	18.11
3.3 V PCI-X	3.3	_	18.11
Differential			
LVDS	2.5	2.26	1.20
LVPECL	3.3	5.72	1.87
Applicable to Standard I/O Banks			
3.3 V LVTTL/LVCMOS	3.3	_	16.79
2.5 V LVCMOS	2.5	_	5.19
1.8 V LVCMOS	1.8	_	2.18
1.5 V LVCMOS (JESD8-11)	1.5	_	1.52

- 1. PDC7 is the static power (where applicable) measured on VCCI.
- 2. PAC9 is the total dynamic power measured on VCC and VCCI.

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Table 3-13 • Summary of I/O Output Buffer Power (per pin)—Default I/O Software Settings<sup>1</sup>

	C <sub>LOAD</sub> (pF)	VCCI (V)	Static Power PDC8 (mW) <sup>2</sup>	Dynamic Power PAC10 (μW/MHz) <sup>3</sup>
Applicable to Pro I/O Banks	L			
Single-Ended				
3.3 V LVTTL/LVCMOS	35	3.3	_	474.70
2.5 V LVCMOS	35	2.5	-	270.73
1.8 V LVCMOS	35	1.8	-	151.78
1.5 V LVCMOS (JESD8-11)	35	1.5	-	104.55
3.3 V PCI	10	3.3	-	204.61
3.3 V PCI-X	10	3.3	-	204.61
Voltage-Referenced	1			1
3.3 V GTL	10	3.3	-	24.08
2.5 V GTL	10	2.5	-	13.52
3.3 V GTL+	10	3.3	-	24.10
2.5 V GTL+	10	2.5	-	13.54
HSTL (I)	20	1.5	7.08	26.22
HSTL (II)	20	1.5	13.88	27.22
SSTL2 (I)	30	2.5	16.69	105.56
SSTL2 (II)	30	2.5	25.91	116.60
SSTL3 (I)	30	3.3	26.02	114.87
SSTL3 (II)	30	3.3	42.21	131.76
Differential			•	•
LVDS	_	2.5	7.70	89.62
LVPECL	_	3.3	19.42	168.02
Applicable to Advanced I/O Bar	nks		•	•
Single-Ended				
3.3 V LVTTL / 3.3 V LVCMOS	35	3.3	_	468.67
2.5 V LVCMOS	35	2.5	-	267.48
1.8 V LVCMOS	35	1.8	-	149.46
1.5 V LVCMOS (JESD8-11)	35	1.5	-	103.12
3.3 V PCI	10	3.3	-	201.02
3.3 V PCI-X	10	3.3	_	201.02

- 1. Dynamic power consumption is given for standard load and software-default drive strength and output slew.
- 2. PDC8 is the static power (where applicable) measured on VCCI.
- 3. PAC10 is the total dynamic power measured on VCC and VCCI.



Table 3-13 • Summary of I/O Output Buffer Power (per pin)—Default I/O Software Settings<sup>1</sup> (continued)

	C <sub>LOAD</sub> (pF)	VCCI (V)	Static Power PDC8 (mW) <sup>2</sup>	Dynamic Power PAC10 (μW/MHz) <sup>3</sup>			
Differential							
LVDS	_	2.5	7.74	88.92			
LVPECL	_	3.3	19.54	166.52			
Applicable to Standard I/O Ban	Applicable to Standard I/O Banks						
Single-Ended							
3.3 V LVTTL / 3.3 V LVCMOS	35	3.3	_	431.08			
2.5 V LVCMOS	35	2.5	_	247.36			
1.8 V LVCMOS	35	1.8	_	128.46			
1.5 V LVCMOS (JESD8-11)	35	1.5	_	89.46			

- 1. Dynamic power consumption is given for standard load and software-default drive strength and output slew.
- 2. PDC8 is the static power (where applicable) measured on VCCI.
- 3. PAC10 is the total dynamic power measured on VCC and VCCI.

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# **Dynamic Power Consumption of Various Internal Resources**

Table 3-14 • Different Components Contributing to the Dynamic Power Consumption in Fusion Devices

		Power Supply		Device-Specific Dynamic Contributions				
Parameter	Definition	Name	Setting	AFS1500	AFS600	AFS250	AFS090	Units
PAC1	Clock contribution of a Global Rib	VCC	1.5 V	14.5	12.8	11	11	μW/MHz
PAC2	Clock contribution of a Global Spine	VCC	1.5 V	2.5	1.9	1.6	0.8	μW/MHz
PAC3	Clock contribution of a VersaTile row	VCC	1.5 V		0.8	1		μW/MHz
PAC4	Clock contribution of a VersaTile used as a sequential module	VCC	1.5 V		0.1	1		μW/MHz
PAC5	First contribution of a VersaTile used as a sequential module	VCC	1.5 V		0.0	7		μW/MHz
PAC6	Second contribution of a VersaTile used as a sequential module		1.5 V		0.2	9		µW/MHz
PAC7	Contribution of a VersaTile used as a combinatorial module	VCC	1.5 V		0.2	9		μW/MHz
PAC8	Average contribution of a routing net	VCC	1.5 V	0.70			μW/MHz	
PAC9	Contribution of an I/O input pin (standard dependent)	VCCI		See Table 3-12 on page 3-18				
PAC10	Contribution of an I/O output pin (standard dependent)	VCCI		See	Table 3-13	on page 3	-20	
PAC11	Average contribution of a RAM block during a read operation	VCC	1.5 V		25	j		μW/MHz
PAC12	Average contribution of a RAM block during a write operation	VCC	1.5 V		30	)		μW/MHz
PAC13	Dynamic Contribution for PLL	VCC	1.5 V		2.6	3		µW/MHz
PAC15	Contribution of NVM block during a read operation (F < 33MHz)	VCC	1.5 V		358	8		μW/MHz
PAC16	1st contribution of NVM block during a read operation (F > 33 MHz)		1.5 V	5 V 12.88			mW	
PAC17	2nd contribution of NVM block during a read operation (F > 33 MHz)		1.5 V	V 4.8		µW/MHz		
PAC18	Crystal Oscillator contribution	VCC33A	3.3 V	V 0.63			mW	
PAC19	RC Oscillator contribution	VCC33A	3.3 V		3.3	3		mW
PAC20	Analog Block dynamic power contribution of ADC	VCC	1.5 V		3			mW



# **Static Power Consumption of Various Internal Resources**

Table 3-15 • Different Components Contributing to the Static Power Consumption in Fusion Devices

		Power		Device-S	pecific St	atic Contr	ibutions	
Parameter	Definition	Supply		AFS1500	AFS600	AFS250	AFS090	Units
PDC1	Core static power contribution in operating mode	VCC	1.5 V	18	7.5	4.50	3.00	mW
PDC2	Device static power contribution in standby mode	VCC33A	3.3 V		0.0	66		mW
PDC3	Device static power contribution in sleep mode	VCC33A	3A 3.3 V 0.03				mW	
PDC4	NVM static power contribution	VCC	1.5 V 1.19				mW	
PDC5	Analog Block static power contribution of ADC	VCC33A	3.3 V	8.25			mW	
PDC6	Analog Block static power contribution per Quad	VCC33A	3.3 V		3.	.3		mW
PDC7	Static contribution per input pin – standard dependent contribution	VCCI		See	Table 3-12	2 on page 3	3-18	
PDC8	Static contribution per input pin – standard dependent contribution	VCCI	CI See Table 3-13 on page 3-20		3-20			
PDC9	Static contribution for PLL	VCC	1.5 V	V 2.55			mW	

# **Power Calculation Methodology**

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in the Libero SoC software.

The power calculation methodology described below uses the following variables:

- · The number of PLLs as well as the number and the frequency of each output clock generated
- · The number of combinatorial and sequential cells used in the design
- · The internal clock frequencies
- The number and the standard of I/O pins used in the design
- · The number of RAM blocks used in the design
- · The number of NVM blocks used in the design
- · The number of Analog Quads used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in Table 3-16 on page 3-27.
- Enable rates of output buffers—guidelines are provided for typical applications in Table 3-17 on page 3-27.
- Read rate and write rate to the RAM—guidelines are provided for typical applications in Table 3-17 on page 3-27.
- · Read rate to the NVM blocks

The calculation should be repeated for each clock domain defined in the design.

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# Methodology

# Total Power Consumption—P<sub>TOTAL</sub>

#### Operating Mode, Standby Mode, and Sleep Mode

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

P<sub>STAT</sub> is the total static power consumption.

P<sub>DYN</sub> is the total dynamic power consumption.

# Total Static Power Consumption—P<sub>STAT</sub>

#### **Operating Mode**

$$P_{STAT} = PDC1 + (N_{NVM\text{-}BLOCKS} * PDC4) + PDC5 + (N_{QUADS} * PDC6) + (N_{INPUTS} * PDC7) + (N_{OUTPUTS} * PDC8) + (N_{PLLS} * PDC9)$$

 $\ensuremath{N_{\text{NVM-BLOCKS}}}$  is the number of NVM blocks available in the device.

N<sub>QUADS</sub> is the number of Analog Quads used in the design.

 $N_{\mbox{\footnotesize{INPUTS}}}$  is the number of I/O input buffers used in the design.

 $N_{\mbox{\scriptsize OUTPUTS}}$  is the number of I/O output buffers used in the design.

N<sub>PLLS</sub> is the number of PLLs available in the device.

#### Standby Mode

 $P_{STAT} = PDC2$ 

#### Sleep Mode

 $P_{STAT} = PDC3$ 

#### Total Dynamic Power Consumption—P<sub>DYN</sub>

#### **Operating Mode**

# Standby Mode

 $P_{DYN} = P_{XTL-OSC}$ 

# Sleep Mode

 $P_{DYN} = 0 W$ 

# Global Clock Dynamic Contribution—P<sub>CLOCK</sub>

#### **Operating Mode**

N<sub>SPINE</sub> is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the *Fusion and Extended Temperature Fusion FPGA Fabric User's Guide*.

N<sub>ROW</sub> is the number of VersaTile rows used in the design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the *Fusion and Extended Temperature Fusion FPGA Fabric User*'s *Guide*.

F<sub>CLK</sub> is the global clock signal frequency.

 $N_{S\text{-}CELL}$  is the number of VersaTiles used as sequential modules in the design.

#### Standby Mode and Sleep Mode

P<sub>CLOCK</sub> = 0 W

# Sequential Cells Dynamic Contribution—P<sub>S-CELL</sub>

#### **Operating Mode**



$$P_{S-CELL} = N_{S-CELL} * (PAC5 + (\alpha_1 / 2) * PAC6) * F_{CLK}$$

N<sub>S-CELL</sub> is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 3-16 on page 3-27.

F<sub>CLK</sub> is the global clock signal frequency.

## Standby Mode and Sleep Mode

P<sub>S-CELL</sub> = 0 W

# Combinatorial Cells Dynamic Contribution—P<sub>C-CELL</sub>

## **Operating Mode**

 $P_{C-CELL} = N_{C-CELL} * (\alpha_1 / 2) * PAC7 * F_{CLK}$ 

 $N_{\text{C-CELL}}$  is the number of VersaTiles used as combinatorial modules in the design.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 3-16 on page 3-27.

F<sub>CLK</sub> is the global clock signal frequency.

# Standby Mode and Sleep Mode

 $P_{C-CELL} = 0 W$ 

Routing Net Dynamic Contribution—P<sub>NET</sub>

## **Operating Mode**

 $P_{NET} = (N_{S-CELL} + N_{C-CELL}) * (\alpha_1 / 2) * PAC8 * F_{CLK}$ 

N<sub>S-CELL</sub> is the number VersaTiles used as sequential modules in the design.

N<sub>C-CELL</sub> is the number of VersaTiles used as combinatorial modules in the design.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 3-16 on page 3-27.

F<sub>CLK</sub> is the global clock signal frequency.

#### Standby Mode and Sleep Mode

 $P_{NET} = 0 W$ 

## I/O Input Buffer Dynamic Contribution—PINPUTS

#### **Operating Mode**

 $P_{INPUTS} = N_{INPUTS} * (\alpha_2 / 2) * PAC9 * F_{CLK}$ 

N<sub>INPUTS</sub> is the number of I/O input buffers used in the design.

 $\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 3-16 on page 3-27.

F<sub>CLK</sub> is the global clock signal frequency.

#### Standby Mode and Sleep Mode

P<sub>INPUTS</sub> = 0 W

# I/O Output Buffer Dynamic Contribution—POUTPUTS

#### Operating Mode

 $P_{OUTPUTS} = N_{OUTPUTS} * (\alpha_2 / 2) * \beta_1 * PAC10 * F_{CLK}$ 

N<sub>OUTPUTS</sub> is the number of I/O output buffers used in the design.

 $\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 3-16 on page 3-27.

 $\beta_1$  is the I/O buffer enable rate—guidelines are provided in Table 3-17 on page 3-27.

F<sub>CLK</sub> is the global clock signal frequency.

## Standby Mode and Sleep Mode

P<sub>OUTPUTS</sub> = 0 W

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# RAM Dynamic Contribution—P<sub>MEMORY</sub>

### **Operating Mode**

 $P_{MEMORY} = (N_{BLOCKS} * PAC11 * \beta_2 * F_{READ-CLOCK}) + (N_{BLOCKS} * PAC12 * \beta_3 * F_{WRITE-CLOCK})$ 

N<sub>BLOCKS</sub> is the number of RAM blocks used in the design.

F<sub>READ-CLOCK</sub> is the memory read clock frequency.

 $\beta_2$  is the RAM enable rate for read operations—guidelines are provided in Table 3-17 on page 3-27.

 $\beta_3$  the RAM enable rate for write operations—guidelines are provided in Table 3-17 on page 3-27.

F<sub>WRITE-CLOCK</sub> is the memory write clock frequency.

## Standby Mode and Sleep Mode

 $P_{MEMORY} = 0 W$ 

## PLL/CCC Dynamic Contribution—Pp. 1

#### **Operating Mode**

P<sub>PLL</sub> = PAC13 \* F<sub>CLKOUT</sub>

F<sub>CLKIN</sub> is the input clock frequency.

F<sub>CLKOUT</sub> is the output clock frequency. <sup>1</sup>

#### Standby Mode and Sleep Mode

 $P_{PLL} = 0 W$ 

# Nonvolatile Memory Dynamic Contribution—P<sub>NVM</sub>

## **Operating Mode**

The NVM dynamic power consumption is a piecewise linear function of frequency.

 $P_{NVM} = N_{NVM-BLOCKS} * \beta_4 * PAC15 * F_{READ-NVM}$  when  $F_{READ-NVM} \le 33$  MHz,

 $P_{NVM} = N_{NVM-BLOCKS} * \beta_4 * (PAC16 + PAC17 * F_{READ-NVM} when F_{READ-NVM} > 33 MHz$ 

N<sub>NVM-BLOCKS</sub> is the number of NVM blocks used in the design (2 inAFS600).

 $\beta_4$  is the NVM enable rate for read operations. Default is 0 (NVM mainly in idle state).

F<sub>READ-NVM</sub> is the NVM read clock frequency.

## Standby Mode and Sleep Mode

P<sub>NVM</sub> = 0 W

#### Crystal Oscillator Dynamic Contribution—P<sub>XTL-OSC</sub>

#### Operating Mode

P<sub>XTL-OSC</sub> = PAC18

## Standby Mode

 $P_{XTL-OSC} = PAC18$ 

### Sleep Mode

 $P_{XTL-OSC} = 0 W$ 

The PLL dynamic contribution depends on the input clock frequency, the number of output clock signals generated by the PLL, and the frequency of each output clock. If a PLL is used to generate more than one output clock, include each output clock in the formula output clock by adding its corresponding contribution (P<sub>AC14</sub> \* F<sub>CLKOUT</sub> product) to the total PLL contribution.



# RC Oscillator Dynamic Contribution—P<sub>RC-OSC</sub>

## **Operating Mode**

P<sub>RC-OSC</sub> = PAC19

## Standby Mode and Sleep Mode

 $P_{RC-OSC} = 0 W$ 

## Analog System Dynamic Contribution—PAR

## **Operating Mode**

 $P_{AB} = PAC20$ 

#### Standby Mode and Sleep Mode

 $P_{AB} = 0 W$ 

# Guidelines

#### **Toggle Rate Definition**

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that the net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100%, as all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
  - Bit 0 (LSB) = 100%
  - Bit 1 = 50%
  - Bit 2 = 25%
  - ..
  - Bit 7 (MSB) = 0.78125%
  - Average toggle rate = (100% + 50% + 25% + 12.5% +... 0.78125%) / 8.

#### **Enable Rate Definition**

Output enable rate is the average percentage of time during which tristate outputs are enabled. When non-tristate output buffers are used, the enable rate should be 100%.

Table 3-16 • Toggle Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
$\alpha_1$	Toggle rate of VersaTile outputs	
$\alpha_2$	I/O buffer toggle rate	10%

#### Table 3-17 • Enable Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
$\beta_1$	I/O output buffer enable rate	100%
$\beta_2$	RAM enable rate for read operations	12.5%
$\beta_3$	RAM enable rate for write operations	12.5%
$\beta_4$	NVM enable rate for read operations	0%

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# **Example of Power Calculation**

This example considers a shift register with 5,000 storage tiles, including a counter and memory that stores analog information. The shift register is clocked at 50 MHz and stores and reads information from a RAM.

The device used is a commercial AFS600 device operating in typical conditions.

The calculation below uses the power calculation methodology previously presented and shows how to determine the dynamic and static power consumption of resources used in the application.

Also included in the example is the calculation of power consumption in operating, standby, and sleep modes to illustrate the benefit of power-saving modes.

# Global Clock Contribution—P<sub>CLOCK</sub>

 $F_{CLK} = 50 \text{ MHz}$ 

Number of sequential VersaTiles: N<sub>S-CELL</sub> = 5,000

Estimated number of Spines:  $N_{SPINES} = 5$ Estimated number of Rows:  $N_{ROW} = 313$ 

#### **Operating Mode**

```
P_{CLOCK} = (PAC1 + N_{SPINE} * PAC2 + N_{ROW} * PAC3 + N_{S-CELL} * PAC4) * F_{CLK} P_{CLOCK} = (0.0128 + 5 * 0.0019 + 313 * 0.00081 + 5,000 * 0.00011) * 50 P_{CLOCK} = 41.28 mW
```

# Standby Mode and Sleep Mode

P<sub>CLOCK</sub> = 0 W

# Logic—Sequential Cells, Combinational Cells, and Routing Net Contributions— $P_{S-CELL}$ , $P_{C-CELL}$ , and $P_{NET}$

 $F_{CLK} = 50 \text{ MHz}$ 

Number of sequential VersaTiles: N<sub>S-CELL</sub> = 5,000 Number of combinatorial VersaTiles: N<sub>C-CELL</sub> = 6,000 Estimated toggle rate of VersaTile outputs:  $\alpha_1$  = 0.1 (10%)

# **Operating Mode**

```
\begin{split} & P_{S\text{-CELL}} = 5,000 * (0.00007 + (0.1 \, / \, 2) * 0.00029) * 50 \\ & P_{S\text{-CELL}} = 21.13 \text{ mW} \\ \\ & P_{C\text{-CELL}} = N_{C\text{-CELL}} * (\alpha_1 \, / \, 2) * PAC7 * F_{CLK} \\ & P_{C\text{-CELL}} = 6,000 * (0.1 \, / \, 2) * 0.00029 * 50 \\ & P_{C\text{-CELL}} = 4.35 \text{ mW} \\ \\ & P_{NET} = (N_{S\text{-CELL}} + N_{C\text{-CELL}}) * (\alpha_1 \, / \, 2) * PAC8 * F_{CLK} \\ & P_{NET} = (5,000 + 6,000) * (0.1 \, / \, 2) * 0.0007 * 50 \\ & P_{NET} = 19.25 \text{ mW} \\ \\ & P_{LOGIC} = P_{S\text{-CELL}} + P_{C\text{-CELL}} + P_{NET} \\ & P_{LOGIC} = 21.13 \text{ mW} + 4.35 \text{ mW} + 19.25 \text{ mW} \end{split}
```

 $P_{S-CELL} = N_{S-CELL} * (P_{AC5} + (\alpha_1 / 2) * PAC6) * F_{CLK}$ 

#### Standby Mode and Sleep Mode

 $P_{LOGIC} = 44.73 \text{ mW}$ 



 $P_{S-CFII} = 0 W$ 

 $P_{C-CFII} = 0 W$ 

 $P_{NET} = 0 W$ 

P<sub>LOGIC</sub> = 0 W

#### I/O Input and Output Buffer Contribution—P<sub>I/O</sub>

This example uses LVTTL 3.3~V~I/O cells. The output buffers are 12~mA–capable, configured with high output slew and driving a 35~pF output load.

 $F_{CLK} = 50 \text{ MHz}$ 

Number of input pins used:  $N_{INPUTS} = 30$ Number of output pins used:  $N_{OUTPUTS} = 40$ Estimated I/O buffer toggle rate:  $\alpha_2 = 0.1$  (10%) Estimated IO buffer enable rate:  $\beta_1 = 1$  (100%)

#### **Operating Mode**

 $P_{INPUTS} = N_{INPUTS} * (\alpha_2 / 2) * PAC9 * F_{CLK}$ 

 $P_{INPUTS} = 30 * (0.1 / 2) * 0.01739 * 50$ 

 $P_{INPUTS} = 1.30 \text{ mW}$ 

 $P_{OUTPUTS} = N_{OUTPUTS} * (\alpha_2 / 2) * \beta_1 * PAC10 * F_{CLK}$ 

P<sub>OUTPUTS</sub> = 40 \* (0.1 / 2) \* 1 \* 0.4747 \* 50

 $P_{OUTPUTS} = 47.47 \text{ mW}$ 

 $P_{I/O} = P_{INPUTS} + P_{OUTPUTS}$ 

 $P_{I/O} = 1.30 \text{ mW} + 47.47 \text{ mW}$ 

 $P_{I/O} = 48.77 \text{ mW}$ 

#### Standby Mode and Sleep Mode

P<sub>INPUTS</sub> = 0 W

P<sub>OUTPUTS</sub> = 0 W

 $P_{I/O} = 0 W$ 

# RAM Contribution—P<sub>MEMORY</sub>

Frequency of Read Clock:  $F_{READ-CLOCK} = 10 \text{ MHz}$ 

Frequency of Write Clock:  $F_{WRITE-CLOCK} = 10 \text{ MHz}$ 

Number of RAM blocks:  $N_{BLOCKS} = 20$ 

Estimated RAM Read Enable Rate:  $\beta_2$  = 0.125 (12.5%) Estimated RAM Write Enable Rate:  $\beta_3$  = 0.125 (12.5%)

#### Operating Mode

 $P_{MEMORY} = (N_{BLOCKS} * PAC11 * \beta_2 * F_{READ-CLOCK}) + (N_{BLOCKS} * PAC12 * \beta_3 * F_{WRITE-CLOCK})$ 

P<sub>MEMORY</sub> = (20 \* 0.025 \* 0.125 \* 10) + (20 \* 0.030 \* 0.125 \* 10)

 $P_{MEMORY} = 1.38 \text{ mW}$ 

#### Standby Mode and Sleep Mode

 $P_{MEMORY} = 0 W$ 



# PLL/CCC Contribution—P<sub>PLL</sub>

PLL is not used in this application.

$$P_{PLL} = 0 W$$

# Nonvolatile Memory—P<sub>NVM</sub>

Nonvolatile memory is not used in this application.

$$P_{NVM} = 0 W$$

# Crystal Oscillator—PXTL-OSC

The application utilizes standby mode. The crystal oscillator is assumed to be active.

## **Operating Mode**

 $P_{XTL-OSC} = PAC18$ 

 $P_{XTL-OSC} = 0.63 \text{ mW}$ 

#### Standby Mode

 $P_{XTL-OSC} = PAC18$ 

 $P_{XTL-OSC} = 0.63 \text{ mW}$ 

#### Sleep Mode

 $P_{XTL-OSC} = 0 W$ 

## RC Oscillator—PRC-OSC

## **Operating Mode**

 $P_{RC-OSC} = PAC19$ 

 $P_{RC-OSC} = 3.30 \text{ mW}$ 

#### Standby Mode and Sleep Mode

 $P_{RC-OSC} = 0 W$ 

## Analog System—PAR

Number of Quads used: N<sub>QUADS</sub> = 4

### **Operating Mode**

 $P_{AB} = PAC20$ 

 $P_{AB} = 3.00 \text{ mW}$ 

# Standby Mode and Sleep Mode

 $P_{AB} = 0 W$ 

# Total Dynamic Power Consumption—PDYN

#### **Operating Mode**

PDYN = PCLOCK + PS-CELL + PC-CELL + PNET + PINPUTS + POUTPUTS + PMEMORY + PPLL + PNVM+ PXTL-OSC + PRC-OSC + PAB

 $P_{\rm DYN}$  = 41.28 mW + 21.1 mW + 4.35 mW + 19.25 mW + 1.30 mW + 47.47 mW + 1.38 mW + 0 + 0 + 0.63 mW + 3.30 mW + 3.00 mW

 $P_{DYN} = 143.06 \text{ mW}$ 

#### Standby Mode

 $P_{DYN} = P_{XTL-OSC}$ 

 $P_{DYN} = 0.63 \text{ mW}$ 

## Sleep Mode

 $P_{DYN} = 0 W$ 



# Total Static Power Consumption—P<sub>STAT</sub>

Number of Quads used: N<sub>QUADS</sub> = 4

Number of NVM blocks available (AFS600): N<sub>NVM-BLOCKS</sub> = 2

Number of input pins used:  $N_{INPUTS} = 30$ Number of output pins used:  $N_{OUTPUTS} = 40$ 

## **Operating Mode**

P<sub>STAT</sub> = PDC1 + (N<sub>NVM-BLOCKS</sub> \* PDC4) + PDC5 + (N<sub>QUADS</sub> \* PDC6) + (N<sub>INPUTS</sub> \* PDC7) +

(N<sub>OUTPUTS</sub> \* PDC8)

 $P_{STAT}$  = 7.50 mW + (2 \* 1.19 mW) + 8.25 mW + (4 \* 3.30 mW) + (30 \* 0.00) + (40 \* 0.00)

 $P_{STAT} = 31.33 \text{ mW}$ 

#### Standby Mode

 $P_{STAT} = PDC2$ 

 $P_{STAT} = 0.03 \text{ mW}$ 

#### Sleep Mode

 $P_{STAT} = PDC3$ 

 $P_{STAT} = 0.03 \text{ mW}$ 

# Total Power Consumption—P<sub>TOTAL</sub>

In operating mode, the total power consumption of the device is 174.39 mW:

 $P_{TOTAL} = P_{STAT} + P_{DYN}$ 

 $P_{TOTAL} = 143.06 \text{ mW} + 31.33 \text{ mW}$ 

P<sub>TOTAL</sub> = 174.39 mW

In standby mode, the total power consumption of the device is limited to 0.66 mW:

 $P_{TOTAL} = P_{STAT} + P_{DYN}$ 

 $P_{TOTAL} = 0.03 \text{ mW} + 0.63 \text{ mW}$ 

 $P_{TOTAL} = 0.66 \text{ mW}$ 

In sleep mode, the total power consumption of the device drops as low as 0.03 mW:

 $P_{TOTAL} = P_{STAT} + P_{DYN}$ 

 $P_{TOTAL} = 0.03 \text{ mW}$ 



# **Power Consumption**

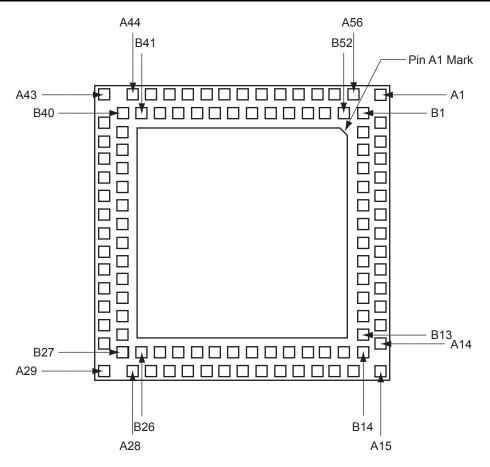
Table 3-18 • Power Consumption

Parameter	Description	Condition	Min.	Typical	Max.	Units
Crystal Oscilla	tor			•	•	•
ISTBXTAL	Standby Current of Crystal Oscillator			10		μΑ
IDYNXTAL	Operating Current	RC		0.6		mA
		0.032-0.2		0.19		mA
		0.2-2.0		0.6		mA
		2.0–20.0		0.6		mA
RC Oscillator						
IDYNRC	Operating Current			1		mA
ACM						
	Operating Current (fixed clock)			200		μA/MHz
	Operating Current (user clock)			30		μΑ
NVM System				•	•	
	NVM Array Operating Power	Idle		795		μA
		Read operation		See Table 3-15 on page 3-23.		See Table 3-15 on page 3-23.
		Erase		900		μΑ
		Write		900		μΑ
PNVMCTRL	NVM Controller Operating Power			20		μW/MHz



# 4 – Package Pin Assignments

# **QN108**



Note: The die attach paddle center of the package is tied to ground (GND).

# Note

For more information on package drawings, see PD3068: Package Mechanical Drawings.



QN108			
Pin Number	AFS090 Function		
A1	NC		
A2	GNDQ		
A3	GAA2/IO52PDB3V0		
A4	GND		
A5	GFA1/IO47PDB3V0		
A6	GEB1/IO45PDB3V0		
A7	VCCOSC		
A8	XTAL2		
A9	GEA1/IO44PPB3V0		
A10	GEA0/IO44NPB3V0		
A11	GEB2/IO42PDB3V0		
A12	VCCNVM		
A13	VCC15A		
A14	PCAP		
A15	NC		
A16	GNDA		
A17	AV0		
A18	AG0		
A19	ATRTN0		
A20	AT1		
A21	AC1		
A22	AV2		
A23	AG2		
A24	AT2		
A25	AT3		
A26	AC3		
A27	GNDAQ		
A28	ADCGNDREF		
A29	NC		
A30	GNDA		
A31	PTEM		
A32	GNDNVM		
A33	VPUMP		
A34	TCK		
A35	TMS		
A36	TRST		
A37	GDB1/IO39PSB1V0		
A38	GDC1/IO38PDB1V0		

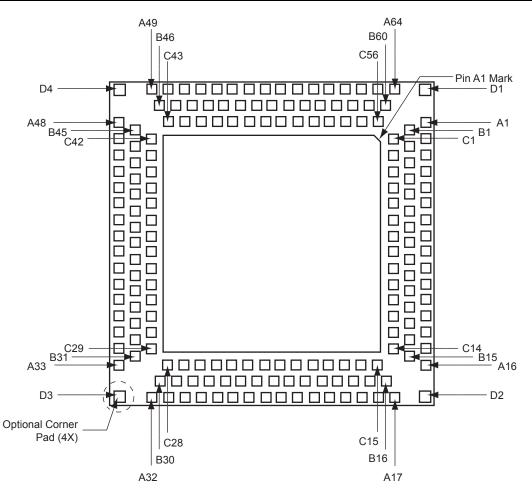
QN108			
Pin Number	AFS090 Function		
A39	GND		
A40	GCB1/IO35PDB1V0		
A41	GCB2/IO33PDB1V0		
A42	GBA2/IO31PDB1V0		
A43	NC		
A44	GBA1/IO30RSB0V0		
A45	GBB1/IO28RSB0V0		
A46	GND		
A47	VCC		
A48	GBC1/IO26RSB0V0		
A49	IO21RSB0V0		
A50	IO19RSB0V0		
A51	IO09RSB0V0		
A52	GAC0/IO04RSB0V0		
A53	VCCIB0		
A54	GND		
A55	GAB0/IO02RSB0V0		
A56	GAA0/IO00RSB0V0		
B1	VCOMPLA		
B2	VCCIB3		
В3	GAB2/IO52NDB3V0		
B4	VCCIB3		
B5	GFA0/IO47NDB3V0		
B6	GEB0/IO45NDB3V0		
B7	XTAL1		
B8	GNDOSC		
B9	GEC2/IO43PSB3V0		
B10	GEA2/IO42NDB3V0		
B11	VCC		
B12	GNDNVM		
B13	NCAP		
B14	VCC33PMP		
B15	VCC33N		
B16	GNDAQ		
B17	AC0		
B18	AT0		
B19	AG1		
B20	AV1		
	l .		

QN108			
Pin Number	AFS090 Function		
B21	AC2		
B22	ATRTN1		
B23	AG3		
B24	AV3		
B25	VCC33A		
B26	VAREF		
B27	PUB		
B28	VCC33A		
B29	PTBASE		
B30	VCCNVM		
B31	VCC		
B32	TDI		
B33	TDO		
B34	VJTAG		
B35	GDC0/IO38NDB1V 0		
B36	VCCIB1		
B37	GCB0/IO35NDB1V0		
B38	GCC2/IO33NDB1V 0		
B39	GBB2/IO31NDB1V0		
B40	VCCIB1		
B41	GNDQ		
B42	GBA0/IO29RSB0V0		
B43	VCCIB0		
B44	GBB0/IO27RSB0V0		
B45	GBC0/IO25RSB0V0		
B46	IO20RSB0V0		
B47	IO10RSB0V0		
B48	GAC1/IO05RSB0V0		
B49	GAB1/IO03RSB0V0		
B50	VCC		
B51	GAA1/IO01RSB0V0		
B52	VCCPLA		

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# **QN180**



Note: The die attach paddle center of the package is tied to ground (GND).

# Note

For more information on package drawings, see PD3068: Package Mechanical Drawings.

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	QN180	
Pin Number	AFS090 Function	AFS250 Function
A1	GNDQ	GNDQ
A2	VCCIB3	VCCIB3
A3	GAB2/IO52NDB3V0	IO74NDB3V0
A4	GFA2/IO51NDB3V0	IO71NDB3V0
A5	GFC2/IO50NDB3V0	IO69NPB3V0
A6	VCCIB3	VCCIB3
A7	GFA1/IO47PPB3V0	GFB1/IO67PPB3V0
A8	GEB0/IO45NDB3V0	NC
A9	XTAL1	XTAL1
A10	GNDOSC	GNDOSC
A11	GEC2/IO43PPB3V0	GEA1/IO61PPB3V0
A12	IO43NPB3V0	GEA0/IO61NPB3V0
A13	NC	VCCIB3
A14	GNDNVM	GNDNVM
A15	PCAP	PCAP
A16	VCC33PMP	VCC33PMP
A17	NC	NC
A18	AV0	AV0
A19	AG0	AG0
A20	ATRTN0	ATRTN0
A21	AG1	AG1
A22	AC1	AC1
A23	AV2	AV2
A24	AT2	AT2
A25	AT3	AT3
A26	AC3	AC3
A27	AV4	AV4
A28	AC4	AC4
A29	AT4	AT4
A30	NC	AG5
A31	NC	AV5
A32	ADCGNDREF	ADCGNDREF
A33	VCC33A	VCC33A
A34	GNDA	GNDA
A35	PTBASE	PTBASE
A36	VCCNVM	VCCNVM

	QN180	
Pin Number	AFS090 Function	AFS250 Function
A37	VPUMP	VPUMP
A38	TDI	TDI
A39	TDO	TDO
A40	VJTAG	VJTAG
A41	GDB1/IO39PPB1V0	GDA1/IO54PPB1V0
A42	GDC1/IO38PDB1V0	GDB1/IO53PDB1V0
A43	VCC	VCC
A44	GCB0/IO35NPB1V0	GCB0/IO48NPB1V0
A45	GCC1/IO34PDB1V0	GCC1/IO47PDB1V0
A46	VCCIB1	VCCIB1
A47	GBC2/IO32PPB1V0	GBB2/IO41PPB1V0
A48	VCCIB1	VCCIB1
A49	NC	NC
A50	GBA0/IO29RSB0V0	GBB1/IO37RSB0V0
A51	VCCIB0	VCCIB0
A52	GBB0/IO27RSB0V0	GBC0/IO34RSB0V0
A53	GBC1/IO26RSB0V0	IO33RSB0V0
A54	IO24RSB0V0	IO29RSB0V0
A55	IO21RSB0V0	IO26RSB0V0
A56	VCCIB0	VCCIB0
A57	IO15RSB0V0	IO21RSB0V0
A58	IO10RSB0V0	IO13RSB0V0
A59	IO07RSB0V0	IO10RSB0V0
A60	GAC0/IO04RSB0V0	IO06RSB0V0
A61	GAB1/IO03RSB0V0	GAC1/IO05RSB0V0
A62	VCC	VCC
A63	GAA1/IO01RSB0V0	GAB0/IO02RSB0V0
A64	NC	NC
B1	VCOMPLA	VCOMPLA
B2	GAA2/IO52PDB3V0	GAC2/IO74PDB3V0
B3	GAC2/IO51PDB3V0	GFA2/IO71PDB3V0
B4	GFB2/IO50PDB3V0	GFB2/IO70PSB3V0
B5	VCC	VCC
B6	GFC0/IO49NDB3V0	GFC0/IO68NDB3V0
B7	GEB1/IO45PDB3V0	NC
B8	VCCOSC	VCCOSC

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QN180		
Pin Number	AFS090 Function	AFS250 Function
В9	XTAL2	XTAL2
B10	GEA0/IO44NDB3V0	GFA0/IO66NDB3V0
B11	GEB2/IO42PDB3V0	IO60NDB3V0
B12	VCC	VCC
B13	VCCNVM	VCCNVM
B14	VCC15A	VCC15A
B15	NCAP	NCAP
B16	VCC33N	VCC33N
B17	GNDAQ	GNDAQ
B18	AC0	AC0
B19	AT0	AT0
B20	AT1	AT1
B21	AV1	AV1
B22	AC2	AC2
B23	ATRTN1	ATRTN1
B24	AG3	AG3
B25	AV3	AV3
B26	AG4	AG4
B27	ATRTN2	ATRTN2
B28	NC	AC5
B29	VCC33A	VCC33A
B30	VAREF	VAREF
B31	PUB	PUB
B32	PTEM	PTEM
B33	GNDNVM	GNDNVM
B34	VCC	VCC
B35	TCK	TCK
B36	TMS	TMS
B37	TRST	TRST
B38	GDB2/IO41PSB1V0	GDA2/IO55PSB1V0
B39	GDC0/IO38NDB1V0	GDB0/IO53NDB1V0
B40	VCCIB1	VCCIB1
B41	GCA1/IO36PDB1V0	GCA1/IO49PDB1V0
B42	GCC0/IO34NDB1V0	GCC0/IO47NDB1V0
B43	GCB2/IO33PSB1V0	GBC2/IO42PSB1V0
B44	VCC	VCC

QN180		
Pin Number	AFS090 Function	AFS250 Function
B45	GBA2/IO31PDB1V0	GBA2/IO40PDB1V0
B46	GNDQ	GNDQ
B47	GBA1/IO30RSB0V0	GBA0/IO38RSB0V0
B48	GBB1/IO28RSB0V0	GBC1/IO35RSB0V0
B49	VCC	VCC
B50	GBC0/IO25RSB0V0	IO31RSB0V0
B51	IO23RSB0V0	IO28RSB0V0
B52	IO20RSB0V0	IO25RSB0V0
B53	VCC	VCC
B54	IO11RSB0V0	IO14RSB0V0
B55	IO08RSB0V0	IO11RSB0V0
B56	GAC1/IO05RSB0V0	IO08RSB0V0
B57	VCCIB0	VCCIB0
B58	GAB0/IO02RSB0V0	GAC0/IO04RSB0V0
B59	GAA0/IO00RSB0V0	GAA1/IO01RSB0V0
B60	VCCPLA	VCCPLA
C1	NC	NC
C2	NC	VCCIB3
C3	GND	GND
C4	NC	GFC2/IO69PPB3V0
C5	GFC1/IO49PDB3V0	GFC1/IO68PDB3V0
C6	GFA0/IO47NPB3V0	GFB0/IO67NPB3V0
C7	VCCIB3	NC
C8	GND	GND
C9	GEA1/IO44PDB3V0	GFA1/IO66PDB3V0
C10	GEA2/IO42NDB3V0	GEC2/IO60PDB3V0
C11	NC	GEA2/IO58PSB3V0
C12	NC	NC
C13	GND	GND
C14	NC	NC
C15	NC	NC
C16	GNDA	GNDA
C17	NC	NC
C18	NC	NC
C19	NC	NC
C20	NC	NC



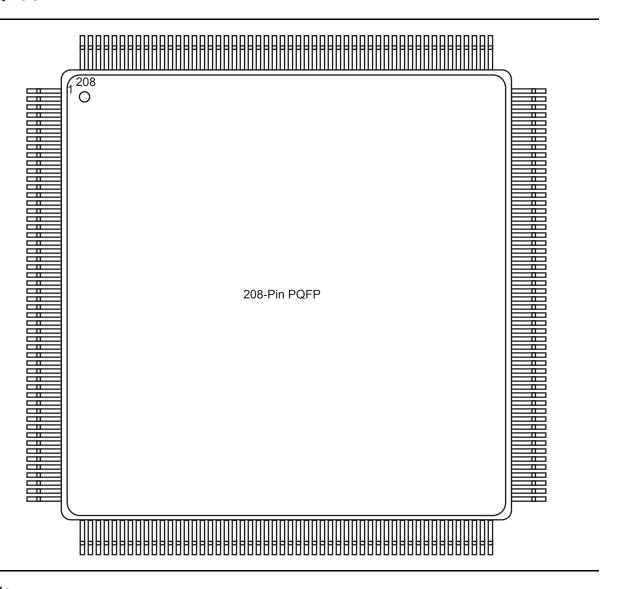
QN180		
Pin Number	AFS090 Function	AFS250 Function
C21	AG2	AG2
C22	NC	NC
C23	NC	NC
C24	NC	NC
C25	NC	AT5
C26	GNDAQ	GNDAQ
C27	NC	NC
C28	NC	NC
C29	NC	NC
C30	NC	NC
C31	GND	GND
C32	NC	NC
C33	NC	NC
C34	NC	NC
C35	GND	GND
C36	GDB0/IO39NPB1V0	GDA0/IO54NPB1V0
C37	GDA1/IO37NSB1V0	GDC0/IO52NSB1V0
C38	GCA0/IO36NDB1V0	GCA0/IO49NDB1V0
C39	GCB1/IO35PPB1V0	GCB1/IO48PPB1V0
C40	GND	GND
C41	GCA2/IO32NPB1V0	IO41NPB1V0
C42	GBB2/IO31NDB1V0	IO40NDB1V0
C43	NC	NC
C44	NC	GBA1/IO39RSB0V0
C45	NC	GBB0/IO36RSB0V0
C46	GND	GND
C47	NC	IO30RSB0V0
C48	IO22RSB0V0	IO27RSB0V0
C49	GND	GND
C50	IO13RSB0V0	IO16RSB0V0
C51	IO09RSB0V0	IO12RSB0V0
C52	IO06RSB0V0	IO09RSB0V0
C53	GND	GND
C54	NC	GAB1/IO03RSB0V0
C55	NC	GAA0/IO00RSB0V0
C56	NC	NC

QN180		
Pin Number	AFS090 Function	AFS250 Function
D1	NC	NC
D2	NC	NC
D3	NC	NC
D4	NC	NC

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# **PQ208**



# Note

- 1. Package PQ208 is discontinued.
- 2. For more information on package drawings, see *PD3068: Package Mechanical Drawings*.

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	PQ208		
Pin Number	AFS250 Function	AFS600 Function	
1	VCCPLA	VCCPLA	
2	VCOMPLA	VCOMPLA	
3	GNDQ	GAA2/IO85PDB4V0	
4	VCCIB3	IO85NDB4V0	
5	GAA2/IO76PDB3V0	GAB2/IO84PDB4V0	
6	IO76NDB3V0	IO84NDB4V0	
7	GAB2/IO75PDB3V0	GAC2/IO83PDB4V0	
8	IO75NDB3V0	IO83NDB4V0	
9	NC	IO77PDB4V0	
10	NC	IO77NDB4V0	
11	VCC	IO76PDB4V0	
12	GND	IO76NDB4V0	
13	VCCIB3	VCC	
14	IO72PDB3V0	GND	
15	IO72NDB3V0	VCCIB4	
16	GFA2/IO71PDB3V0	GFA2/IO75PDB4V0	
17	IO71NDB3V0	IO75NDB4V0	
18	GFB2/IO70PDB3V0	GFC2/IO73PDB4V0	
19	IO70NDB3V0	IO73NDB4V0	
20	GFC2/IO69PDB3V0	VCCOSC	
21	IO69NDB3V0	XTAL1	
22	VCC	XTAL2	
23	GND	GNDOSC	
24	VCCIB3	GFC1/IO72PDB4V0	
25	GFC1/IO68PDB3V0	GFC0/IO72NDB4V0	
26	GFC0/IO68NDB3V0	GFB1/IO71PDB4V0	
27	GFB1/IO67PDB3V0	GFB0/IO71NDB4V0	
28	GFB0/IO67NDB3V0	GFA1/IO70PDB4V0	
29	VCCOSC	GFA0/IO70NDB4V0	
30	XTAL1	IO69PDB4V0	
31	XTAL2	IO69NDB4V0	
32	GNDOSC	VCC	
33	GEB1/IO62PDB3V0	GND	
34	GEB0/IO62NDB3V0	VCCIB4	
35	GEA1/IO61PDB3V0	GEC1/IO63PDB4V0	
36	GEA0/IO61NDB3V0	GEC0/IO63NDB4V0	
37	GEC2/IO60PDB3V0	GEB1/IO62PDB4V0	

PQ208		
Pin Number	AFS250 Function	AFS600 Function
38	IO60NDB3V0	GEB0/IO62NDB4V0
39	GND	GEA1/IO61PDB4V0
40	VCCIB3	GEA0/IO61NDB4V0
41	GEB2/IO59PDB3V0	GEC2/IO60PDB4V0
42	IO59NDB3V0	IO60NDB4V0
43	GEA2/IO58PDB3V0	VCCIB4
44	IO58NDB3V0	GNDQ
45	VCC	VCC
45	VCC	VCC
46	VCCNVM	VCCNVM
47	GNDNVM	GNDNVM
48	GND	GND
49	VCC15A	VCC15A
50	PCAP	PCAP
51	NCAP	NCAP
52	VCC33PMP	VCC33PMP
53	VCC33N	VCC33N
54	GNDA	GNDA
55	GNDAQ	GNDAQ
56	NC	AV0
57	NC	AC0
58	NC	AG0
59	NC	AT0
60	NC	ATRTN0
61	NC	AT1
62	NC	AG1
63	NC	AC1
64	NC	AV1
65	AV0	AV2
66	AC0	AC2
67	AG0	AG2
68	AT0	AT2
69	ATRTN0	ATRTN1
70	AT1	AT3
71	AG1	AG3
72	AC1	AC3
73	AV1	AV3

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PQ208		
Pin Number	AFS250 Function	AFS600 Function
74	AV2	AV4
75	AC2	AC4
76	AG2	AG4
77	AT2	AT4
78	ATRTN1	ATRTN2
79	AT3	AT5
80	AG3	AG5
81	AC3	AC5
82	AV3	AV5
83	AV4	AV6
84	AC4	AC6
85	AG4	AG6
86	AT4	AT6
87	ATRTN2	ATRTN3
88	AT5	AT7
89	AG5	AG7
90	AC5	AC7
91	AV5	AV7
92	NC	AV8
93	NC	AC8
94	NC	AG8
95	NC	AT8
96	NC	ATRTN4
97	NC	AT9
98	NC	AG9
99	NC	AC9
100	NC	AV9
101	GNDAQ	GNDAQ
102	VCC33A	VCC33A
103	ADCGNDREF	ADCGNDREF
104	VAREF	VAREF
105	PUB	PUB
106	VCC33A	VCC33A
107	GNDA	GNDA
108	PTEM	PTEM
109	PTBASE	PTBASE
110	GNDNVM	GNDNVM

PQ208		
Pin Number	AFS250 Function	AFS600 Function
111	VCCNVM	VCCNVM
112	VCC	VCC
112	VCC	VCC
113	VPUMP	VPUMP
114	GNDQ	NC
115	VCCIB1	TCK
116	TCK	TDI
117	TDI	TMS
118	TMS	TDO
119	TDO	TRST
120	TRST	VJTAG
121	VJTAG	IO57NDB2V0
122	IO57NDB1V0	GDC2/IO57PDB2V0
123	GDC2/IO57PDB1V0	IO56NDB2V0
124	IO56NDB1V0	GDB2/IO56PDB2V0
125	GDB2/IO56PDB1V0	IO55NDB2V0
126	VCCIB1	GDA2/IO55PDB2V0
127	GND	GDA0/IO54NDB2V0
128	IO55NDB1V0	GDA1/IO54PDB2V0
129	GDA2/IO55PDB1V0	VCCIB2
130	GDA0/IO54NDB1V0	GND
131	GDA1/IO54PDB1V0	VCC
132	GDB0/IO53NDB1V0	GCA0/IO45NDB2V0
133	GDB1/IO53PDB1V0	GCA1/IO45PDB2V0
134	GDC0/IO52NDB1V0	GCB0/IO44NDB2V0
135	GDC1/IO52PDB1V0	GCB1/IO44PDB2V0
136	IO51NSB1V0	GCC0/IO43NDB2V 0
137	VCCIB1	GCC1/IO43PDB2V0
138	GND	IO42NDB2V0
139	VCC	IO42PDB2V0
140	IO50NDB1V0	IO41NDB2V0
141	IO50PDB1V0	GCC2/IO41PDB2V0
142	GCA0/IO49NDB1V0	VCCIB2
143	GCA1/IO49PDB1V0	GND
144	GCB0/IO48NDB1V0	VCC
145	GCB1/IO48PDB1V0	IO40NDB2V0
146	GCC0/IO47NDB1V0	GCB2/IO40PDB2V0



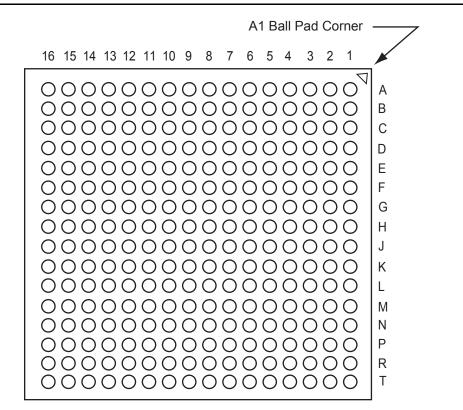
	PQ208			
Pin Number	AFS250 Function	AFS600 Function		
147	GCC1/IO47PDB1V0	IO39NDB2V0		
148	IO42NDB1V0	GCA2/IO39PDB2V0		
149	GBC2/IO42PDB1V0	IO31NDB2V0		
150	VCCIB1	GBB2/IO31PDB2V0		
151	GND	IO30NDB2V0		
152	VCC	GBA2/IO30PDB2V0		
153	IO41NDB1V0	VCCIB2		
154	GBB2/IO41PDB1V0	GNDQ		
155	IO40NDB1V0	VCOMPLB		
156	GBA2/IO40PDB1V0	VCCPLB		
157	GBA1/IO39RSB0V0	VCCIB1		
158	GBA0/IO38RSB0V0	GNDQ		
159	GBB1/IO37RSB0V0	GBB1/IO27PPB1V1		
160	GBB0/IO36RSB0V0	GBA1/IO28PPB1V1		
161	GBC1/IO35RSB0V0	GBB0/IO27NPB1V1		
162	VCCIB0	GBA0/IO28NPB1V1		
163	GND	VCCIB1		
164	VCC	GND		
165	GBC0/IO34RSB0V0	VCC		
166	IO33RSB0V0	GBC1/IO26PDB1V1		
167	IO32RSB0V0	GBC0/IO26NDB1V1		
168	IO31RSB0V0	IO24PPB1V1		
169	IO30RSB0V0	IO23PPB1V1		
170	IO29RSB0V0	IO24NPB1V1		
171	IO28RSB0V0	IO23NPB1V1		
172	IO27RSB0V0	IO22PPB1V0		
173	IO26RSB0V0	IO21PPB1V0		
174	IO25RSB0V0	IO22NPB1V0		
175	VCCIB0	IO21NPB1V0		
176	GND	IO20PSB1V0		
177	VCC	IO19PSB1V0		
178	IO24RSB0V0	IO14NSB0V1		
179	IO23RSB0V0	IO12PDB0V1		
180	IO22RSB0V0	IO12NDB0V1		
181	IO21RSB0V0	VCCIB0		
182	IO20RSB0V0	GND		
183	IO19RSB0V0	VCC		

	PQ208			
Pin Number	AFS250 Function	AFS600 Function		
184	IO18RSB0V0	IO10PPB0V1		
185	IO17RSB0V0	IO09PPB0V1		
186	IO16RSB0V0	IO10NPB0V1		
187	IO15RSB0V0	IO09NPB0V1		
188	VCCIB0	IO08PPB0V1		
189	GND	IO07PPB0V1		
190	VCC	IO08NPB0V1		
191	IO14RSB0V0	IO07NPB0V1		
192	IO13RSB0V0	IO06PPB0V0		
193	IO12RSB0V0	IO05PPB0V0		
194	IO11RSB0V0	IO06NPB0V0		
195	IO10RSB0V0	IO04PPB0V0		
196	IO09RSB0V0	IO05NPB0V0		
197	IO08RSB0V0	IO04NPB0V0		
198	IO07RSB0V0	GAC1/IO03PDB0V0		
199	IO06RSB0V0	GAC0/IO03NDB0V0		
200	GAC1/IO05RSB0V0	VCCIB0		
201	VCCIB0	GND		
202	GND	VCC		
203	VCC	GAB1/IO02PDB0V0		
204	GAC0/IO04RSB0V0	GAB0/IO02NDB0V0		
205	GAB1/IO03RSB0V0	GAA1/IO01PDB0V0		
206	GAB0/IO02RSB0V0	GAA0/IO01NDB0V0		
207	GAA1/IO01RSB0V0	GNDQ		
208	GAA0/IO00RSB0V0	VCCIB0		

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## **FG256**



#### Note

For more information on package drawings, see PD3068: Package Mechanical Drawings.



FG256				
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
A1	GND	GND	GND	GND
A2	VCCIB0	VCCIB0	VCCIB0	VCCIB0
A3	GAB0/IO02RSB0V0	GAA0/IO00RSB0V0	GAA0/IO01NDB0V0	GAA0/IO01NDB0V0
A4	GAB1/IO03RSB0V0	GAA1/IO01RSB0V0	GAA1/IO01PDB0V0	GAA1/IO01PDB0V0
A5	GND	GND	GND	GND
A6	IO07RSB0V0	IO11RSB0V0	IO10PDB0V1	IO07PDB0V1
A7	IO10RSB0V0	IO14RSB0V0	IO12PDB0V1	IO13PDB0V2
A8	IO11RSB0V0	IO15RSB0V0	IO12NDB0V1	IO13NDB0V2
A9	IO16RSB0V0	IO24RSB0V0	IO22NDB1V0	IO24NDB1V0
A10	IO17RSB0V0	IO25RSB0V0	IO22PDB1V0	IO24PDB1V0
A11	IO18RSB0V0	IO26RSB0V0	IO24NDB1V1	IO29NDB1V1
A12	GND	GND	GND	GND
A13	GBC0/IO25RSB0V0	GBA0/IO38RSB0V0	GBA0/IO28NDB1V1	GBA0/IO42NDB1V2
A14	GBA0/IO29RSB0V0	IO32RSB0V0	IO29NDB1V1	IO43NDB1V2
A15	VCCIB0	VCCIB0	VCCIB1	VCCIB1
A16	GND	GND	GND	GND
B1	VCOMPLA	VCOMPLA	VCOMPLA	VCOMPLA
B2	VCCPLA	VCCPLA	VCCPLA	VCCPLA
В3	GAA0/IO00RSB0V0	IO07RSB0V0	IO00NDB0V0	IO00NDB0V0
B4	GAA1/IO01RSB0V0	IO06RSB0V0	IO00PDB0V0	IO00PDB0V0
B5	NC	GAB1/IO03RSB0V0	GAB1/IO02PPB0V0	GAB1/IO02PPB0V0
В6	IO06RSB0V0	IO10RSB0V0	IO10NDB0V1	IO07NDB0V1
В7	VCCIB0	VCCIB0	VCCIB0	VCCIB0
B8	IO12RSB0V0	IO16RSB0V0	IO18NDB1V0	IO22NDB1V0
В9	IO13RSB0V0	IO17RSB0V0	IO18PDB1V0	IO22PDB1V0
B10	VCCIB0	VCCIB0	VCCIB1	VCCIB1
B11	IO19RSB0V0	IO27RSB0V0	IO24PDB1V1	IO29PDB1V1
B12	GBB0/IO27RSB0V0	GBC0/IO34RSB0V0	GBC0/IO26NPB1V1	GBC0/IO40NPB1V2
B13	GBC1/IO26RSB0V0	GBA1/IO39RSB0V0	GBA1/IO28PDB1V1	GBA1/IO42PDB1V2
B14	GBA1/IO30RSB0V0	IO33RSB0V0	IO29PDB1V1	IO43PDB1V2
B15	NC	NC	VCCPLB	VCCPLB
B16	NC	NC	VCOMPLB	VCOMPLB
C1	VCCIB3	V <b>CCI</b> B3	VCCIB4	VCCIB4
C2	GND	GND	GND	GND
C3	VCCIB3	VCCIB3	VCCIB4	VCCIB4
C4	NC	NC	VCCIB0	VCCIB0
C5	VCCIB0	VCCIB0	VCCIB0	VCCIB0
C6	GAC1/IO05RSB0V0	GAC1/IO05RSB0V0	GAC1/IO03PDB0V0	GAC1/IO03PDB0V0



		FG256		
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
C7	IO09RSB0V0	IO12RSB0V0	IO06NDB0V0	IO09NDB0V1
C8	IO14RSB0V0	IO22RSB0V0	IO16PDB1V0	IO23PDB1V0
C9	IO15RSB0V0	IO23RSB0V0	IO16NDB1V0	IO23NDB1V0
C10	IO22RSB0V0	IO30RSB0V0	IO25NDB1V1	IO31NDB1V1
C11	IO20RSB0V0	IO31RSB0V0	IO25PDB1V1	IO31PDB1V1
C12	VCCIB0	VCCIB0	VCCIB1	VCCIB1
C13	GBB1/IO28RSB0V0	GBC1/IO35RSB0V0	GBC1/IO26PPB1V1	GBC1/IO40PPB1V2
C14	VCCIB1	VCCIB1	VCCIB2	VCCIB2
C15	GND	GND	GND	GND
C16	VCCIB1	VCCIB1	VCCIB2	VCCIB2
D1	GFC2/IO50NPB3V0	IO75NDB3V0	IO84NDB4V0	IO124NDB4V0
D2	GFA2/IO51NDB3V0	GAB2/IO75PDB3V0	GAB2/IO84PDB4V0	GAB2/IO124PDB4V0
D3	GAC2/IO51PDB3V0	IO76NDB3V0	IO85NDB4V0	IO125NDB4V0
D4	GAA2/IO52PDB3V0	GAA2/IO76PDB3V0	GAA2/IO85PDB4V0	GAA2/IO125PDB4V0
D5	GAB2/IO52NDB3V0	GAB0/IO02RSB0V0	GAB0/IO02NPB0V0	GAB0/IO02NPB0V0
D6	GAC0/IO04RSB0V0	GAC0/IO04RSB0V0	GAC0/IO03NDB0V0	GAC0/IO03NDB0V0
D7	IO08RSB0V0	IO13RSB0V0	IO06PDB0V0	IO09PDB0V1
D8	NC	IO20RSB0V0	IO14NDB0V1	IO15NDB0V2
D9	NC	IO21RSB0V0	IO14PDB0V1	IO15PDB0V2
D10	IO21RSB0V0	IO28RSB0V0	IO23PDB1V1	IO37PDB1V2
D11	IO23RSB0V0	GBB0/IO36RSB0V0	GBB0/IO27NDB1V1	GBB0/IO41NDB1V2
D12	NC	NC	VCCIB1	VCCIB1
D13	GBA2/IO31PDB1V0	GBA2/IO40PDB1V0	GBA2/IO30PDB2V0	GBA2/IO44PDB2V0
D14	GBB2/IO31NDB1V0	IO40NDB1V0	IO30NDB2V0	IO44NDB2V0
D15	GBC2/IO32PDB1V0	GBB2/IO41PDB1V0	GBB2/IO31PDB2V0	GBB2/IO45PDB2V0
D16	GCA2/IO32NDB1V0	IO41NDB1V0	IO31NDB2V0	IO45NDB2V0
E1	GND	GND	GND	GND
E2	GFB0/IO48NPB3V0	IO73NDB3V0	IO81NDB4V0	IO118NDB4V0
E3	GFB2/IO50PPB3V0	IO73PDB3V0	IO81PDB4V0	IO118PDB4V0
E4	VCCIB3	VCCIB3	VCCIB4	VCCIB4
E5	NC	IO74NPB3V0	IO83NPB4V0	IO123NPB4V0
E6	NC	IO08RSB0V0	IO04NPB0V0	IO05NPB0V1
E7	GND	GND	GND	GND
E8	NC	IO18RSB0V0	IO08PDB0V1	IO11PDB0V1
E9	NC	NC	IO20NDB1V0	IO27NDB1V1
E10	GND	GND	GND	GND
E11	IO24RSB0V0	GBB1/IO37RSB0V0	GBB1/IO27PDB1V1	GBB1/IO41PDB1V2
E12	NC	IO50PPB1V0	IO33PSB2V0	IO48PSB2V0

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FG256				
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
E13	VCCIB1	VCCIB1	VCCIB2	VCCIB2
E14	GCC2/IO33NDB1V0	IO42NDB1V0	IO32NDB2V0	IO46NDB2V0
E15	GCB2/IO33PDB1V0	GBC2/IO42PDB1V0	GBC2/IO32PDB2V0	GBC2/IO46PDB2V0
E16	GND	GND	GND	GND
F1	NC	NC	IO79NDB4V0	IO111NDB4V0
F2	NC	NC	IO79PDB4V0	IO111PDB4V0
F3	GFB1/IO48PPB3V0	IO72NDB3V0	IO76NDB4V0	IO112NDB4V0
F4	GFC0/IO49NDB3V0	IO72PDB3V0	IO76PDB4V0	IO112PDB4V0
F5	NC	NC	IO82PSB4V0	IO120PSB4V0
F6	GFC1/IO49PDB3V0	GAC2/IO74PPB3V0	GAC2/IO83PPB4V0	GAC2/IO123PPB4V0
F7	NC	IO09RSB0V0	IO04PPB0V0	IO05PPB0V1
F8	NC	IO19RSB0V0	IO08NDB0V1	IO11NDB0V1
F9	NC	NC	IO20PDB1V0	IO27PDB1V1
F10	NC	IO29RSB0V0	IO23NDB1V1	IO37NDB1V2
F11	NC	IO43NDB1V0	IO36NDB2V0	IO50NDB2V0
F12	NC	IO43PDB1V0	IO36PDB2V0	IO50PDB2V0
F13	NC	IO44NDB1V0	IO39NDB2V0	IO59NDB2V0
F14	NC	GCA2/IO44PDB1V0	GCA2/IO39PDB2V0	GCA2/IO59PDB2V0
F15	GCC1/IO34PDB1V0	GCB2/IO45PDB1V0	GCB2/IO40PDB2V0	GCB2/IO60PDB2V0
F16	GCC0/IO34NDB1V0	IO45NDB1V0	IO40NDB2V0	IO60NDB2V0
G1	GEC0/IO46NPB3V0	IO70NPB3V0	IO74NPB4V0	IO109NPB4V0
G2	VCCIB3	VCCIB3	VCCIB4	VCCIB4
G3	GEC1/IO46PPB3V0	GFB2/IO70PPB3V0	GFB2/IO74PPB4V0	GFB2/IO109PPB4V0
G4	GFA1/IO47PDB3V0	GFA2/IO71PDB3V0	GFA2/IO75PDB4V0	GFA2/IO110PDB4V0
G5	GND	GND	GND	GND
G6	GFA0/IO47NDB3V0	IO71NDB3V0	IO75NDB4V0	IO110NDB4V0
G7	GND	GND	GND	GND
G8	VCC	VCC	VCC	VCC
G9	GND	GND	GND	GND
G10	VCC	VCC	VCC	VCC
G11	GDA1/IO37NDB1V0	GCC0/IO47NDB1V0	GCC0/IO43NDB2V0	GCC0/IO62NDB2V0
G12	GND	GND	GND	GND
G13	IO37PDB1V0	GCC1/IO47PDB1V0	GCC1/IO43PDB2V0	GCC1/IO62PDB2V0
G14	GCB0/IO35NPB1V0	IO46NPB1V0	IO41NPB2V0	IO61NPB2V0
G15	VCCIB1	VCCIB1	VCCIB2	VCCIB2
G16	GCB1/IO35PPB1V0	GCC2/IO46PPB1V0	GCC2/IO41PPB2V0	GCC2/IO61PPB2V0
H1	GEB1/IO45PDB3V0	GFC2/IO69PDB3V0	GFC2/IO73PDB4V0	GFC2/IO108PDB4V0
H2	GEB0/IO45NDB3V0	IO69NDB3V0	IO73NDB4V0	IO108NDB4V0



FG256				
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
Н3	XTAL2	XTAL2	XTAL2	XTAL2
H4	XTAL1	XTAL1	XTAL1	XTAL1
H5	GNDOSC	GNDOSC	GNDOSC	GNDOSC
H6	VCCOSC	VCCOSC	VCCOSC	VCCOSC
H7	VCC	VCC	VCC	VCC
H8	GND	GND	GND	GND
H9	VCC	VCC	VCC	VCC
H10	GND	GND	GND	GND
H11	GDC0/IO38NDB1V0	IO51NDB1V0	IO47NDB2V0	IO69NDB2V0
H12	GDC1/IO38PDB1V0	IO51PDB1V0	IO47PDB2V0	IO69PDB2V0
H13	GDB1/IO39PDB1V0	GCA1/IO49PDB1V0	GCA1/IO45PDB2V0	GCA1/IO64PDB2V0
H14	GDB0/IO39NDB1V0	GCA0/IO49NDB1V0	GCA0/IO45NDB2V0	GCA0/IO64NDB2V0
H15	GCA0/IO36NDB1V0	GCB0/IO48NDB1V0	GCB0/IO44NDB2V0	GCB0/IO63NDB2V0
H16	GCA1/IO36PDB1V0	GCB1/IO48PDB1V0	GCB1/IO44PDB2V0	GCB1/IO63PDB2V0
J1	GEA0/IO44NDB3V0	GFA0/IO66NDB3V0	GFA0/IO70NDB4V0	GFA0/IO105NDB4V
J2	GEA1/IO44PDB3V0	GFA1/IO66PDB3V0	GFA1/IO70PDB4V0	GFA1/IO105PDB4V0
J3	IO43NDB3V0	GFB0/IO67NDB3V0	GFB0/IO71NDB4V0	GFB0/IO106NDB4V
J4	GEC2/IO43PDB3V0	GFB1/IO67PDB3V0	GFB1/IO71PDB4V0	GFB1/IO106PDB4V0
J5	NC	GFC0/IO68NDB3V0	GFC0/IO72NDB4V0	GFC0/IO107NDB4V
J6	NC	GFC1/IO68PDB3V0	GFC1/IO72PDB4V0	GFC1/IO107PDB4V
J7	GND	GND	GND	GND
J8	VCC	VCC	VCC	VCC
J9	GND	GND	GND	GND
J10	VCC	VCC	VCC	VCC
J11	GDC2/IO41NPB1V0	IO56NPB1V0	IO56NPB2V0	IO83NPB2V0
J12	NC	GDB0/IO53NPB1V0	GDB0/IO53NPB2V0	GDB0/IO80NPB2V0
J13	NC	GDA1/IO54PDB1V0	GDA1/IO54PDB2V0	GDA1/IO81PDB2V0
J14	GDA0/IO40PDB1V0	GDC1/IO52PPB1V0	GDC1/IO52PPB2V0	GDC1/IO79PPB2V0
J15	NC	IO50NPB1V0	IO51NSB2V0	IO77NSB2V0
J16	GDA2/IO40NDB1V0	GDC0/IO52NPB1V0	GDC0/IO52NPB2V0	GDC0/IO79NPB2V0
K1	NC	IO65NPB3V0	IO67NPB4V0	IO92NPB4V0
K2	VCCIB3	VCCIB3	VCCIB4	VCCIB4
K3	NC	IO65PPB3V0	IO67PPB4V0	IO92PPB4V0
K4	NC	IO64PDB3V0	IO65PDB4V0	IO96PDB4V0
K5	GND	GND	GND	GND
K6	NC	IO64NDB3V0	IO65NDB4V0	IO96NDB4V0
K7	VCC	VCC	VCC	VCC
K8	GND	GND	GND	GND

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FG256				
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
K9	VCC	VCC	VCC	VCC
K10	GND	GND	GND	GND
K11	NC	GDC2/IO57PPB1V0	GDC2/IO57PPB2V0	GDC2/IO84PPB2V0
K12	GND	GND	GND	GND
K13	NC	GDA0/IO54NDB1V0	GDA0/IO54NDB2V0	GDA0/IO81NDB2V0
K14	NC	GDA2/IO55PPB1V0	GDA2/IO55PPB2V0	GDA2/IO82PPB2V0
K15	VCCIB1	VCCIB1	VCCIB2	VCCIB2
K16	NC	GDB1/IO53PPB1V0	GDB1/IO53PPB2V0	GDB1/IO80PPB2V0
L1	NC	GEC1/IO63PDB3V0	GEC1/IO63PDB4V0	GEC1/IO90PDB4V0
L2	NC	GEC0/IO63NDB3V0	GEC0/IO63NDB4V0	GEC0/IO90NDB4V0
L3	NC	GEB1/IO62PDB3V0	GEB1/IO62PDB4V0	GEB1/IO89PDB4V0
L4	NC	GEB0/IO62NDB3V0	GEB0/IO62NDB4V0	GEB0/IO89NDB4V
L5	NC	IO60NDB3V0	IO60NDB4V0	IO87NDB4V0
L6	NC	GEC2/IO60PDB3V0	GEC2/IO60PDB4V0	GEC2/IO87PDB4V
L7	GNDA	GNDA	GNDA	GNDA
L8	AC0	AC0	AC2	AC2
L9	AV2	AV2	AV4	AV4
L10	AC3	AC3	AC5	AC5
L11	PTEM	PTEM	PTEM	PTEM
L12	TDO	TDO	TDO	TDO
L13	VJTAG	VJTAG	VJTAG	VJTAG
L14	NC	IO57NPB1V0	IO57NPB2V0	IO84NPB2V0
L15	GDB2/IO41PPB1V0	GDB2/IO56PPB1V0	GDB2/IO56PPB2V0	GDB2/IO83PPB2V
L16	NC	IO55NPB1V0	IO55NPB2V0	IO82NPB2V0
M1	GND	GND	GND	GND
M2	NC	GEA1/IO61PDB3V0	GEA1/IO61PDB4V0	GEA1/IO88PDB4V
M3	NC	GEA0/IO61NDB3V0	GEA0/IO61NDB4V0	GEA0/IO88NDB4V
M4	VCCIB3	VCCIB3	VCCIB4	VCCIB4
M5	NC	IO58NPB3V0	IO58NPB4V0	IO85NPB4V0
M6	NC	NC	AV0	AV0
M7	NC	NC	AC1	AC1
M8	AG1	AG1	AG3	AG3
M9	AC2	AC2	AC4	AC4
M10	AC4	AC4	AC6	AC6
M11	NC	AG5	AG7	AG7
M12	VPUMP	VPUMP	VPUMP	VPUMP
M13	VCCIB1	VCCIB1	VCCIB2	VCCIB2
M14	TMS	TMS	TMS	TMS



FG256				
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
M15	TRST	TRST	TRST	TRST
M16	GND	GND	GND	GND
N1	GEB2/IO42PDB3V0	GEB2/IO59PDB3V0	GEB2/IO59PDB4V0	GEB2/IO86PDB4V0
N2	GEA2/IO42NDB3V0	IO59NDB3V0	IO59NDB4V0	IO86NDB4V0
N3	NC	GEA2/IO58PPB3V0	GEA2/IO58PPB4V0	GEA2/IO85PPB4V0
N4	VCC33PMP	VCC33PMP	VCC33PMP	VCC33PMP
N5	VCC15A	VCC15A	VCC15A	VCC15A
N6	NC	NC	AG0	AG0
N7	AC1	AC1	AC3	AC3
N8	AG3	AG3	AG5	AG5
N9	AV3	AV3	AV5	AV5
N10	AG4	AG4	AG6	AG6
N11	NC	NC	AC8	AC8
N12	GNDA	GNDA	GNDA	GNDA
N13	VCC33A	VCC33A	VCC33A	VCC33A
N14	VCCNVM	VCCNVM	VCCNVM	VCCNVM
N15	TCK	TCK	TCK	TCK
N16	TDI	TDI	TDI	TDI
P1	VCCNVM	VCCNVM	VCCNVM	VCCNVM
P2	GNDNVM	GNDNVM	GNDNVM	GNDNVM
P3	GNDA	GNDA	GNDA	GNDA
P4	NC	NC	AC0	AC0
P5	NC	NC	AG1	AG1
P6	NC	NC	AV1	AV1
P7	AG0	AG0	AG2	AG2
P8	AG2	AG2	AG4	AG4
P9	GNDA	GNDA	GNDA	GNDA
P10	NC	AC5	AC7	AC7
P11	NC	NC	AV8	AV8
P12	NC	NC	AG8	AG8
P13	NC	NC	AV9	AV9
P14	ADCGNDREF	ADCGNDREF	ADCGNDREF	ADCGNDREF
P15	PTBASE	PTBASE	PTBASE	PTBASE
P16	GNDNVM	GNDNVM	GNDNVM	GNDNVM
R1	VCCIB3	VCCIB3	VCCIB4	VCCIB4
R2	PCAP	PCAP	PCAP	PCAP
R3	NC	NC	AT1	AT1
R4	NC	NC	AT0	AT0

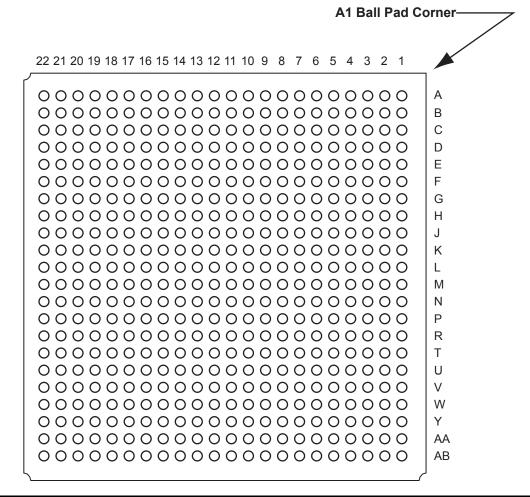
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	FG256			
Pin Number	AFS090 Function	AFS250 Function	AFS600 Function	AFS1500 Function
R5	AV0	AV0	AV2	AV2
R6	AT0	AT0	AT2	AT2
R7	AV1	AV1	AV3	AV3
R8	AT3	AT3	AT5	AT5
R9	AV4	AV4	AV6	AV6
R10	NC	AT5	AT7	AT7
R11	NC	AV5	AV7	AV7
R12	NC	NC	AT9	AT9
R13	NC	NC	AG9	AG9
R14	NC	NC	AC9	AC9
R15	PUB	PUB	PUB	PUB
R16	VCCIB1	VCCIB1	VCCIB2	VCCIB2
T1	GND	GND	GND	GND
T2	NCAP	NCAP	NCAP	NCAP
T3	VCC33N	VCC33N	VCC33N	VCC33N
T4	NC	NC	ATRTN0	ATRTN0
T5	AT1	AT1	AT3	AT3
T6	ATRTN0	ATRTN0	ATRTN1	ATRTN1
T7	AT2	AT2	AT4	AT4
T8	ATRTN1	ATRTN1	ATRTN2	ATRTN2
Т9	AT4	AT4	AT6	AT6
T10	ATRTN2	ATRTN2	ATRTN3	ATRTN3
T11	NC	NC	AT8	AT8
T12	NC	NC	ATRTN4	ATRTN4
T13	GNDA	GNDA	GNDA	GNDA
T14	VCC33A	VCC33A	VCC33A	VCC33A
T15	VAREF	VAREF	VAREF	VAREF
T16	GND	GND	GND	GND



## **FG484**



#### Note

For more information on package drawings, see PD3068: Package Mechanical Drawings.

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	FG484			
Pin Number	AFS600 Function	AFS1500 Function		
A1	GND	GND		
A2	VCC	NC		
A3	GAA1/IO01PDB0V0	GAA1/IO01PDB0V0		
A4	GAB0/IO02NDB0V0	GAB0/IO02NDB0V0		
A5	GAB1/IO02PDB0V0	GAB1/IO02PDB0V0		
A6	IO07NDB0V1	IO07NDB0V1		
A7	IO07PDB0V1	IO07PDB0V1		
A8	IO10PDB0V1	IO09PDB0V1		
A9	IO14NDB0V1	IO13NDB0V2		
A10	IO14PDB0V1	IO13PDB0V2		
A11	IO17PDB1V0	IO24PDB1V0		
A12	IO18PDB1V0	IO26PDB1V0		
A13	IO19NDB1V0	IO27NDB1V1		
A14	IO19PDB1V0	IO27PDB1V1		
A15	IO24NDB1V1	IO35NDB1V2		
A16	IO24PDB1V1	IO35PDB1V2		
A17	GBC0/IO26NDB1V1	GBC0/IO40NDB1V2		
A18	GBA0/IO28NDB1V1	GBA0/IO42NDB1V2		
A19	IO29NDB1V1	IO43NDB1V2		
A20	IO29PDB1V1	IO43PDB1V2		
A21	VCC	NC		
A22	GND	GND		
AA1	VCC	NC		
AA2	GND	GND		
AA3	VCCIB4	VCCIB4		
AA4	VCCIB4	VCCIB4		
AA5	PCAP	PCAP		
AA6	AG0	AG0		
AA7	GNDA	GNDA		
AA8	AG1	AG1		
AA9	AG2	AG2		
AA10	GNDA	GNDA		
AA11	AG3	AG3		
AA12	AG6	AG6		
AA13	GNDA	GNDA		

	FG484				
Pin Number	AFS600 Function	AFS1500 Function			
AA14	AG7	AG7			
AA15	AG8	AG8			
AA16	GNDA	GNDA			
AA17	AG9	AG9			
AA18	VAREF	VAREF			
AA19	VCCIB2	VCCIB2			
AA20	PTEM	PTEM			
AA21	GND	GND			
AA22	VCC	NC			
AB1	GND	GND			
AB2	VCC	NC			
AB3	NC	IO94NSB4V0			
AB4	GND	GND			
AB5	VCC33N	VCC33N			
AB6	AT0	AT0			
AB7	ATRTN0	ATRTN0			
AB8	AT1	AT1			
AB9	AT2	AT2			
AB10	ATRTN1	ATRTN1			
AB11	AT3	AT3			
AB12	AT6	AT6			
AB13	ATRTN3	ATRTN3			
AB14	AT7	AT7			
AB15	AT8	AT8			
AB16	ATRTN4	ATRTN4			
AB17	AT9	AT9			
AB18	VCC33A	VCC33A			
AB19	GND	GND			
AB20	NC	IO76NPB2V0			
AB21	VCC	NC			
AB22	GND	GND			
B1	VCC	NC			
B2	GND	GND			
В3	GAA0/IO01NDB0V0	GAA0/IO01NDB0V0			
B4	GND	GND			

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	FG484				
Pin Number	AFS600 Function	AFS1500 Function			
B5	IO05NDB0V0	IO04NDB0V0			
B6	IO05PDB0V0	IO04PDB0V0			
В7	GND	GND			
B8	IO10NDB0V1	IO09NDB0V1			
В9	IO13PDB0V1	IO11PDB0V1			
B10	GND	GND			
B11	IO17NDB1V0	IO24NDB1V0			
B12	IO18NDB1V0	IO26NDB1V0			
B13	GND	GND			
B14	IO21NDB1V0	IO31NDB1V1			
B15	IO21PDB1V0	IO31PDB1V1			
B16	GND	GND			
B17	GBC1/IO26PDB1V1	GBC1/IO40PDB1V2			
B18	GBA1/IO28PDB1V1	GBA1/IO42PDB1V2			
B19	GND	GND			
B20	VCCPLB	VCCPLB			
B21	GND	GND			
B22	VCC	NC			
C1	IO82PDB4V0	IO121PDB4V0			
C2	NC	IO122PSB4V0			
С3	IO00NDB0V0	IO00NDB0V0			
C4	IO00PDB0V0	IO00PDB0V0			
C5	VCCIB0	VCCIB0			
C6	IO06NDB0V0	IO05NDB0V1			
C7	IO06PDB0V0	IO05PDB0V1			
C8	VCCIB0	VCCIB0			
С9	IO13NDB0V1	IO11NDB0V1			
C10	IO11PDB0V1	IO14PDB0V2			
C11	VCCIB0	VCCIB0			
C12	VCCIB1	VCCIB1			
C13	IO20NDB1V0	IO29NDB1V1			
C14	IO20PDB1V0	IO29PDB1V1			
C15	VCCIB1	VCCIB1			
C16	IO25NDB1V1	IO37NDB1V2			
C17	GBB0/IO27NDB1V1	GBB0/IO41NDB1V2			

FG484			
Pin Number	AFS600 Function	AFS1500 Function	
C18	VCCIB1	VCCIB1	
C19	VCOMPLB	VCOMPLB	
C20	GBA2/IO30PDB2V0	GBA2/IO44PDB2V0	
C21	NC	IO48PSB2V0	
C22	GBB2/IO31PDB2V0	GBB2/IO45PDB2V0	
D1	IO82NDB4V0	IO121NDB4V0	
D2	GND	GND	
D3	IO83NDB4V0	IO123NDB4V0	
D4	GAC2/IO83PDB4V0	GAC2/IO123PDB4V0	
D5	GAA2/IO85PDB4V0	GAA2/IO125PDB4V0	
D6	GAC0/IO03NDB0V0	GAC0/IO03NDB0V0	
D7	GAC1/IO03PDB0V0	GAC1/IO03PDB0V0	
D8	IO09NDB0V1	IO10NDB0V1	
D9	IO09PDB0V1	IO10PDB0V1	
D10	IO11NDB0V1	IO14NDB0V2	
D11	IO16NDB1V0	IO23NDB1V0	
D12	IO16PDB1V0	IO23PDB1V0	
D13	NC	IO32NPB1V1	
D14	IO23NDB1V1	IO34NDB1V1	
D15	IO23PDB1V1	IO34PDB1V1	
D16	IO25PDB1V1	IO37PDB1V2	
D17	GBB1/IO27PDB1V1	GBB1/IO41PDB1V2	
D18	VCCIB2	VCCIB2	
D19	NC	IO47PPB2V0	
D20	IO30NDB2V0	IO44NDB2V0	
D21	GND	GND	
D22	IO31NDB2V0	IO45NDB2V0	
E1	IO81NDB4V0	IO120NDB4V0	
E2	IO81PDB4V0	IO120PDB4V0	
E3	VCCIB4	VCCIB4	
E4	GAB2/IO84PDB4V0	GAB2/IO124PDB4V0	
E5	IO85NDB4V0	IO125NDB4V0	
E6	GND	GND	
E7	VCCIB0	VCCIB0	
E8	NC	IO08NDB0V1	

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FG484		
Pin Number	AFS600 Function	AFS1500 Function
E9	NC	IO08PDB0V1
E10	GND	GND
E11	IO15NDB1V0	IO22NDB1V0
E12	IO15PDB1V0	IO22PDB1V0
E13	GND	GND
E14	NC	IO32PPB1V1
E15	NC	IO36NPB1V2
E16	VCCIB1	VCCIB1
E17	GND	GND
E18	NC	IO47NPB2V0
E19	IO33PDB2V0	IO49PDB2V0
E20	VCCIB2	VCCIB2
E21	IO32NDB2V0	IO46NDB2V0
E22	GBC2/IO32PDB2V0	GBC2/IO46PDB2V0
F1	IO80NDB4V0	IO118NDB4V0
F2	IO80PDB4V0	IO118PDB4V0
F3	NC	IO119NSB4V0
F4	IO84NDB4V0	IO124NDB4V0
F5	GND	GND
F6	VCOMPLA	VCOMPLA
F7	VCCPLA	VCCPLA
F8	VCCIB0	VCCIB0
F9	IO08NDB0V1	IO12NDB0V1
F10	IO08PDB0V1	IO12PDB0V1
F11	VCCIB0	VCCIB0
F12	VCCIB1	VCCIB1
F13	IO22NDB1V0	IO30NDB1V1
F14	IO22PDB1V0	IO30PDB1V1
F15	VCCIB1	VCCIB1
F16	NC	IO36PPB1V2
F17	NC	IO38NPB1V2
F18	GND	GND
F19	IO33NDB2V0	IO49NDB2V0
F20	IO34PDB2V0	IO50PDB2V0
F21	IO34NDB2V0	IO50NDB2V0

FG484			
Pin Number	AFS600 Function	AFS1500 Function	
F22	IO35PDB2V0	IO51PDB2V0	
G1	IO77PDB4V0	IO115PDB4V0	
G2	GND	GND	
G3	IO78NDB4V0	IO116NDB4V0	
G4	IO78PDB4V0	IO116PDB4V0	
G5	VCCIB4	VCCIB4	
G6	NC	IO117PDB4V0	
G7	VCCIB4	VCCIB4	
G8	GND	GND	
G9	IO04NDB0V0	IO06NDB0V1	
G10	IO04PDB0V0	IO06PDB0V1	
G11	IO12NDB0V1	IO16NDB0V2	
G12	IO12PDB0V1	IO16PDB0V2	
G13	NC	IO28NDB1V1	
G14	NC	IO28PDB1V1	
G15	GND	GND	
G16	NC	IO38PPB1V2	
G17	NC	IO53PDB2V0	
G18	VCCIB2	VCCIB2	
G19	IO36PDB2V0	IO52PDB2V0	
G20	IO36NDB2V0	IO52NDB2V0	
G21	GND	GND	
G22	IO35NDB2V0	IO51NDB2V0	
H1	IO77NDB4V0	IO115NDB4V0	
H2	IO76PDB4V0	IO113PDB4V0	
НЗ	VCCIB4	VCCIB4	
H4	IO79NDB4V0	IO114NDB4V0	
H5	IO79PDB4V0	IO114PDB4V0	
H6	NC	IO117NDB4V0	
H7	GND	GND	
H8	VCC	VCC	
H9	VCCIB0	VCCIB0	
H10	GND	GND	
H11	VCCIB0	VCCIB0	
H12	VCCIB1	VCCIB1	

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	FG484		
Pin Number	AFS600 Function	AFS1500 Function	
H13	GND	GND	
H14	VCCIB1	VCCIB1	
H15	GND	GND	
H16	GND	GND	
H17	NC	IO53NDB2V0	
H18	IO38PDB2V0	IO57PDB2V0	
H19	GCA2/IO39PDB2V0	GCA2/IO59PDB2V0	
H20	VCCIB2	VCCIB2	
H21	IO37NDB2V0	IO54NDB2V0	
H22	IO37PDB2V0	IO54PDB2V0	
J1	NC	IO112PPB4V0	
J2	IO76NDB4V0	IO113NDB4V0	
J3	GFB2/IO74PDB4V0	GFB2/IO109PDB4V0	
J4	GFA2/IO75PDB4V0	GFA2/IO110PDB4V0	
J5	NC	IO112NPB4V0	
J6	NC	IO104PDB4V0	
J7	NC	IO111PDB4V0	
J8	VCCIB4	VCCIB4	
J9	GND	GND	
J10	VCC	VCC	
J11	GND	GND	
J12	VCC	VCC	
J13	GND	GND	
J14	VCC	VCC	
J15	VCCIB2	VCCIB2	
J16	GCB2/IO40PDB2V0	GCB2/IO60PDB2V0	
J17	NC	IO58NDB2V0	
J18	IO38NDB2V0	IO57NDB2V0	
J19	IO39NDB2V0	IO59NDB2V0	
J20	GCC2/IO41PDB2V0	GCC2/IO61PDB2V0	
J21	NC	IO55PSB2V0	
J22	IO42PDB2V0	IO56PDB2V0	
K1	GFC2/IO73PDB4V0	GFC2/IO108PDB4V0	
K2	GND	GND	
K3	IO74NDB4V0	IO109NDB4V0	

FG484			
Pin Number	AFS600 Function	AFS1500 Function	
K4	IO75NDB4V0	IO110NDB4V0	
K5	GND	GND	
K6	NC	IO104NDB4V0	
K7	NC	IO111NDB4V0	
K8	GND	GND	
K9	VCC	VCC	
K10	GND	GND	
K11	VCC	VCC	
K12	GND	GND	
K13	VCC	VCC	
K14	GND	GND	
K15	GND	GND	
K16	IO40NDB2V0	IO60NDB2V0	
K17	NC	IO58PDB2V0	
K18	GND	GND	
K19	NC	IO68NPB2V0	
K20	IO41NDB2V0	IO61NDB2V0	
K21	GND	GND	
K22	IO42NDB2V0	IO56NDB2V0	
L1	IO73NDB4V0	IO108NDB4V0	
L2	VCCOSC	VCCOSC	
L3	VCCIB4	VCCIB4	
L4	XTAL2	XTAL2	
L5	GFC1/IO72PDB4V0	GFC1/IO107PDB4V0	
L6	VCCIB4	VCCIB4	
L7	GFB1/IO71PDB4V0	GFB1/IO106PDB4V0	
L8	VCCIB4	VCCIB4	
L9	GND	GND	
L10	VCC	VCC	
L11	GND	GND	
L12	VCC	VCC	
L13	GND	GND	
L14	VCC	VCC	
L15	VCCIB2	VCCIB2	
L16	IO48PDB2V0	IO70PDB2V0	

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FG484		
Pin Number	AFS600 Function AFS1500 Function	
L17	VCCIB2	VCCIB2
L18	IO46PDB2V0	IO69PDB2V0
L19	GCA1/IO45PDB2V0	GCA1/IO64PDB2V0
L20	VCCIB2	VCCIB2
L21	GCC0/IO43NDB2V0	GCC0/IO62NDB2V0
L22	GCC1/IO43PDB2V0	GCC1/IO62PDB2V0
M1	NC	IO103PDB4V0
M2	XTAL1	XTAL1
М3	VCCIB4	VCCIB4
M4	GNDOSC	GNDOSC
M5	GFC0/IO72NDB4V0	GFC0/IO107NDB4V0
M6	VCCIB4	VCCIB4
M7	GFB0/IO71NDB4V0	GFB0/IO106NDB4V0
M8	VCCIB4	VCCIB4
M9	VCC	VCC
M10	GND	GND
M11	VCC	VCC
M12	GND	GND
M13	VCC	VCC
M14	GND	GND
M15	VCCIB2	VCCIB2
M16	IO48NDB2V0	IO70NDB2V0
M17	VCCIB2	VCCIB2
M18	IO46NDB2V0	IO69NDB2V0
M19	GCA0/IO45NDB2V0	GCA0/IO64NDB2V0
M20	VCCIB2	VCCIB2
M21	GCB0/IO44NDB2V0	GCB0/IO63NDB2V0
M22	GCB1/IO44PDB2V0	GCB1/IO63PDB2V0
N1	NC	IO103NDB4V0
N2	GND	GND
N3	IO68PDB4V0	IO101PDB4V0
N4	NC	IO100NPB4V0
N5	GND	GND
N6	NC	IO99PDB4V0
N7	NC	IO97PDB4V0

FG484			
Pin Number	AFS600 Function	AFS1500 Function	
N8	GND	GND	
N9	GND	GND	
N10	VCC	VCC	
N11	GND	GND	
N12	VCC	VCC	
N13	GND	GND	
N14	VCC	VCC	
N15	GND	GND	
N16	GDB2/IO56PDB2V0	GDB2/IO83PDB2V0	
N17	NC	IO78PDB2V0	
N18	GND	GND	
N19	IO47NDB2V0	IO72NDB2V0	
N20	IO47PDB2V0	IO72PDB2V0	
N21	GND	GND	
N22	IO49PDB2V0	IO71PDB2V0	
P1	GFA1/IO70PDB4V0	GFA1/IO105PDB4V0	
P2	GFA0/IO70NDB4V0	GFA0/IO105NDB4V0	
P3	IO68NDB4V0	IO101NDB4V0	
P4	IO65PDB4V0	IO96PDB4V0	
P5	IO65NDB4V0	IO96NDB4V0	
P6	NC	IO99NDB4V0	
P7	NC	IO97NDB4V0	
P8	VCCIB4	VCCIB4	
P9	VCC	VCC	
P10	GND	GND	
P11	VCC	VCC	
P12	GND	GND	
P13	VCC	VCC	
P14	GND	GND	
P15	VCCIB2	VCCIB2	
P16	IO56NDB2V0	IO83NDB2V0	
P17	NC	IO78NDB2V0	
P18	GDA1/IO54PDB2V0	GDA1/IO81PDB2V0	
P19	GDB1/IO53PDB2V0	GDB1/IO80PDB2V0	
P20	IO51NDB2V0	IO73NDB2V0	

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FG484		
Pin Number	AFS600 Function	AFS1500 Function
P21	IO51PDB2V0	IO73PDB2V0
P22	IO49NDB2V0	IO71NDB2V0
R1	IO69PDB4V0	IO102PDB4V0
R2	IO69NDB4V0	IO102NDB4V0
R3	VCCIB4	VCCIB4
R4	IO64PDB4V0	IO91PDB4V0
R5	IO64NDB4V0	IO91NDB4V0
R6	NC	IO92PDB4V0
R7	GND	GND
R8	GND	GND
R9	VCC33A	VCC33A
R10	GNDA	GNDA
R11	VCC33A	VCC33A
R12	GNDA	GNDA
R13	VCC33A	VCC33A
R14	GNDA	GNDA
R15	VCC	VCC
R16	GND	GND
R17	NC	IO74NDB2V0
R18	GDA0/IO54NDB2V0	GDA0/IO81NDB2V0
R19	GDB0/IO53NDB2V0	GDB0/IO80NDB2V0
R20	VCCIB2	VCCIB2
R21	IO50NDB2V0	IO75NDB2V0
R22	IO50PDB2V0	IO75PDB2V0
T1	NC	IO100PPB4V0
T2	GND	GND
Т3	IO66PDB4V0	IO95PDB4V0
T4	IO66NDB4V0	IO95NDB4V0
T5	VCCIB4	VCCIB4
Т6	NC	IO92NDB4V0
T7	GNDNVM	GNDNVM
Т8	GNDA	GNDA
Т9	NC	NC
T10	AV4	AV4
T11	NC	NC

FG484		
Pin Number	AFS600 Function	AFS1500 Function
T12	AV5	AV5
T13	AC5	AC5
T14	NC	NC
T15	GNDA	GNDA
T16	NC	IO77PPB2V0
T17	NC	IO74PDB2V0
T18	VCCIB2	VCCIB2
T19	IO55NDB2V0	IO82NDB2V0
T20	GDA2/IO55PDB2V0	GDA2/IO82PDB2V0
T21	GND	GND
T22	GDC1/IO52PDB2V0	GDC1/IO79PDB2V0
U1	IO67PDB4V0	IO98PDB4V0
U2	IO67NDB4V0	IO98NDB4V0
U3	GEC1/IO63PDB4V0	GEC1/IO90PDB4V0
U4	GEC0/IO63NDB4V0	GEC0/IO90NDB4V0
U5	GND	GND
U6	VCCNVM	VCCNVM
U7	VCCIB4	VCCIB4
U8	VCC15A	VCC15A
U9	GNDA	GNDA
U10	AC4	AC4
U11	VCC33A	VCC33A
U12	GNDA	GNDA
U13	AG5	AG5
U14	GNDA	GNDA
U15	PUB	PUB
U16	VCCIB2	VCCIB2
U17	TDI	TDI
U18	GND	GND
U19	IO57NDB2V0	IO84NDB2V0
U20	GDC2/IO57PDB2V0	GDC2/IO84PDB2V0
U21	NC	IO77NPB2V0
U22	GDC0/IO52NDB2V0	GDC0/IO79NDB2V0
V1	GEB1/IO62PDB4V0	GEB1/IO89PDB4V0
V2	GEB0/IO62NDB4V0	GEB0/IO89NDB4V0

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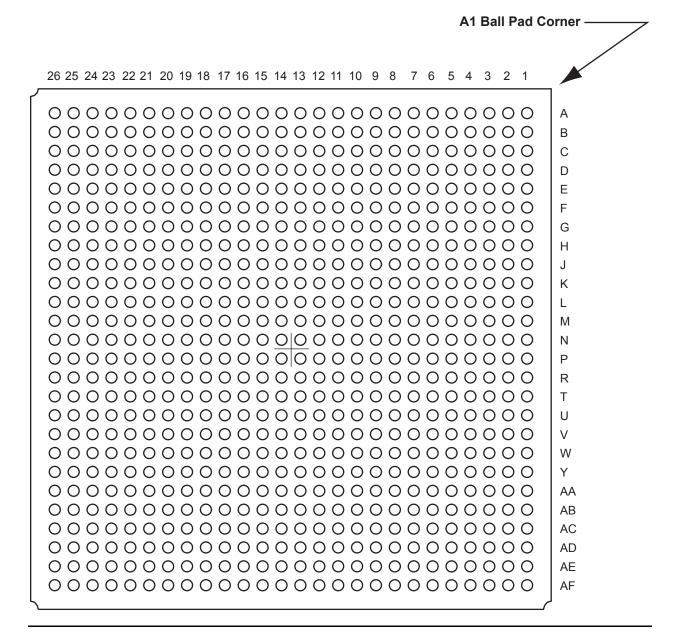
FG484		
Pin Number AFS600 Function AFS		AFS1500 Function
V3	VCCIB4	VCCIB4
V4	GEA1/IO61PDB4V0	GEA1/IO88PDB4V0
V5	GEA0/IO61NDB4V0	GEA0/IO88NDB4V0
V6	GND	GND
V7	VCC33PMP	VCC33PMP
V8	NC	NC
V9	VCC33A	VCC33A
V10	AG4	AG4
V11	AT4	AT4
V12	ATRTN2	ATRTN2
V13	AT5	AT5
V14	VCC33A	VCC33A
V15	NC	NC
V16	VCC33A	VCC33A
V17	GND	GND
V18	TMS	TMS
V19	VJTAG	VJTAG
V20	VCCIB2	VCCIB2
V21	TRST	TRST
V22	TDO	TDO
W1	NC	IO93PDB4V0
W2	GND	GND
W3	NC	IO93NDB4V0
W4	GEB2/IO59PDB4V0	GEB2/IO86PDB4V0
W5	IO59NDB4V0	IO86NDB4V0
W6	AV0	AV0
W7	GNDA	GNDA
W8	AV1	AV1
W9	AV2	AV2
W10	GNDA	GNDA
W11	AV3	AV3
W12	AV6	AV6
W13	GNDA	GNDA
W14	AV7	AV7
W15	AV8	AV8

FG484			
Pin Number	AFS600 Function	AFS1500 Function	
W16	GNDA	GNDA	
W17	AV9	AV9	
W18	VCCIB2	VCCIB2	
W19	NC	IO68PPB2V0	
W20	TCK	TCK	
W21	GND	GND	
W22	NC	IO76PPB2V0	
Y1	GEC2/IO60PDB4V0	GEC2/IO87PDB4V0	
Y2	IO60NDB4V0	IO87NDB4V0	
Y3	GEA2/IO58PDB4V0	GEA2/IO85PDB4V0	
Y4	IO58NDB4V0	IO85NDB4V0	
Y5	NCAP	NCAP	
Y6	AC0	AC0	
Y7	VCC33A	VCC33A	
Y8	AC1	AC1	
Y9	AC2	AC2	
Y10	VCC33A	VCC33A	
Y11	AC3	AC3	
Y12	AC6	AC6	
Y13	VCC33A	VCC33A	
Y14	AC7	AC7	
Y15	AC8	AC8	
Y16	VCC33A	VCC33A	
Y17	AC9	AC9	
Y18	ADCGNDREF	ADCGNDREF	
Y19	PTBASE	PTBASE	
Y20	GNDNVM	GNDNVM	
Y21	VCCNVM	VCCNVM	
Y22	VPUMP	VPUMP	

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### **FG676**



#### Note

For more information on package drawings, see PD3068: Package Mechanical Drawings.



Pin Number         AFS1500 Function           A1         NC           A2         GND           A3         NC           A4         NC           A5         GND           A6         NC           A7         NC           A8         GND           A9         IO17NDB0V2           A10         IO17PDB0V2           A11         GND           A12         IO18NDB0V2           A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0		FG676
A2         GND           A3         NC           A4         NC           A5         GND           A6         NC           A7         NC           A8         GND           A9         IO17NDB0V2           A10         IO17PDB0V2           A11         GND           A12         IO18NDB0V2           A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0	Pin Number	AFS1500 Function
A3         NC           A4         NC           A5         GND           A6         NC           A7         NC           A8         GND           A9         IO17NDB0V2           A10         IO17PDB0V2           A11         GND           A12         IO18NDB0V2           A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0	A1	NC
A4         NC           A5         GND           A6         NC           A7         NC           A8         GND           A9         IO17NDB0V2           A10         IO17PDB0V2           A11         GND           A12         IO18NDB0V2           A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA <td>A2</td> <td>GND</td>	A2	GND
A5 GND A6 NC A7 NC A8 GND A9 IO17NDB0V2 A10 IO17PDB0V2 A11 GND A12 IO18NDB0V2 A13 IO18PDB0V2 A14 IO20NDB0V2 A15 IO20PDB0V2 A16 GND A17 IO21PDB0V2 A18 IO21NDB0V2 A19 GND A20 IO39NDB1V2 A21 IO39PDB1V2 A22 GND A23 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA8 AV0 AA9 GNDA	A3	NC
A6 NC A7 NC A8 GND A9 IO17NDB0V2 A10 IO17PDB0V2 A11 GND A12 IO18NDB0V2 A13 IO18PDB0V2 A14 IO20NDB0V2 A15 IO20PDB0V2 A16 GND A17 IO21PDB0V2 A18 IO21NDB0V2 A19 GND A20 IO39NDB1V2 A21 IO39PDB1V2 A22 GND A23 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA8 AV0 AA8 AV0 AA8 GNDA	A4	NC
A7         NC           A8         GND           A9         IO17NDB0V2           A10         IO17PDB0V2           A11         GND           A12         IO18NDB0V2           A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A5	GND
A8 GND A9 IO17NDB0V2 A10 IO17PDB0V2 A11 GND A12 IO18NDB0V2 A13 IO18PDB0V2 A14 IO20NDB0V2 A15 IO20PDB0V2 A16 GND A17 IO21PDB0V2 A18 IO21NDB0V2 A19 GND A20 IO39NDB1V2 A21 IO39PDB1V2 A22 GND A23 NC A24 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA8 AV0 AA8 AV0 AA8 AV0 AA8 GNDA	A6	NC
A9 IO17NDB0V2 A10 IO17PDB0V2 A11 GND A12 IO18NDB0V2 A13 IO18PDB0V2 A14 IO20NDB0V2 A15 IO20PDB0V2 A16 GND A17 IO21PDB0V2 A18 IO21NDB0V2 A19 GND A20 IO39NDB1V2 A21 IO39PDB1V2 A22 GND A23 NC A24 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA8 AV0 AA9 GNDA	A7	NC
A10       IO17PDB0V2         A11       GND         A12       IO18NDB0V2         A13       IO18PDB0V2         A14       IO20NDB0V2         A15       IO20PDB0V2         A16       GND         A17       IO21PDB0V2         A18       IO21NDB0V2         A19       GND         A20       IO39NDB1V2         A21       IO39PDB1V2         A22       GND         A23       NC         A24       NC         A25       GND         A26       NC         AA1       NC         AA2       VCCIB4         AA3       IO93PDB4V0         AA4       GND         AA5       IO93NDB4V0         AA6       GEB2/IO86PDB4V0         AA7       IO86NDB4V0         AA8       AV0         AA9       GNDA	A8	GND
A11         GND           A12         IO18NDB0V2           A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A9	IO17NDB0V2
A12       IO18NDB0V2         A13       IO18PDB0V2         A14       IO20NDB0V2         A15       IO20PDB0V2         A16       GND         A17       IO21PDB0V2         A18       IO21NDB0V2         A19       GND         A20       IO39NDB1V2         A21       IO39PDB1V2         A22       GND         A23       NC         A24       NC         A25       GND         A26       NC         AA1       NC         AA2       VCCIB4         AA3       IO93PDB4V0         AA4       GND         AA5       IO93NDB4V0         AA6       GEB2/IO86PDB4V0         AA7       IO86NDB4V0         AA8       AV0         AA9       GNDA	A10	IO17PDB0V2
A13         IO18PDB0V2           A14         IO20NDB0V2           A15         IO20PDB0V2           A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A11	GND
A14 IO20NDB0V2 A15 IO20PDB0V2 A16 GND A17 IO21PDB0V2 A18 IO21NDB0V2 A19 GND A20 IO39NDB1V2 A21 IO39PDB1V2 A22 GND A23 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA8 AV0 AA9 GNDA	A12	IO18NDB0V2
A15 IO20PDB0V2 A16 GND A17 IO21PDB0V2 A18 IO21NDB0V2 A19 GND A20 IO39NDB1V2 A21 IO39PDB1V2 A22 GND A23 NC A24 NC A25 GND A26 NC AA1 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	A13	IO18PDB0V2
A16         GND           A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A14	IO20NDB0V2
A17         IO21PDB0V2           A18         IO21NDB0V2           A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A15	IO20PDB0V2
A18       IO21NDB0V2         A19       GND         A20       IO39NDB1V2         A21       IO39PDB1V2         A22       GND         A23       NC         A24       NC         A25       GND         A26       NC         AA1       NC         AA2       VCCIB4         AA3       IO93PDB4V0         AA4       GND         AA5       IO93NDB4V0         AA6       GEB2/IO86PDB4V0         AA7       IO86NDB4V0         AA8       AV0         AA9       GNDA	A16	GND
A19         GND           A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A17	IO21PDB0V2
A20         IO39NDB1V2           A21         IO39PDB1V2           A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A18	IO21NDB0V2
A21 IO39PDB1V2 A22 GND A23 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	A19	GND
A22         GND           A23         NC           A24         NC           A25         GND           A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A20	IO39NDB1V2
A23 NC A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	A21	IO39PDB1V2
A24 NC A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	A22	GND
A25 GND A26 NC AA1 NC AA2 VCCIB4 AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	A23	NC
A26         NC           AA1         NC           AA2         VCCIB4           AA3         IO93PDB4V0           AA4         GND           AA5         IO93NDB4V0           AA6         GEB2/IO86PDB4V0           AA7         IO86NDB4V0           AA8         AV0           AA9         GNDA	A24	NC
AA1 NC  AA2 VCCIB4  AA3 IO93PDB4V0  AA4 GND  AA5 IO93NDB4V0  AA6 GEB2/IO86PDB4V0  AA7 IO86NDB4V0  AA8 AV0  AA9 GNDA	A25	GND
AA2 VCCIB4  AA3 IO93PDB4V0  AA4 GND  AA5 IO93NDB4V0  AA6 GEB2/IO86PDB4V0  AA7 IO86NDB4V0  AA8 AV0  AA9 GNDA	A26	NC
AA3 IO93PDB4V0 AA4 GND AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	AA1	NC
AA4 GND  AA5 IO93NDB4V0  AA6 GEB2/IO86PDB4V0  AA7 IO86NDB4V0  AA8 AV0  AA9 GNDA	AA2	VCCIB4
AA5 IO93NDB4V0 AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	AA3	IO93PDB4V0
AA6 GEB2/IO86PDB4V0 AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	AA4	GND
AA7 IO86NDB4V0 AA8 AV0 AA9 GNDA	AA5	IO93NDB4V0
AA8 AV0 AA9 GNDA	AA6	GEB2/IO86PDB4V0
AA9 GNDA	AA7	IO86NDB4V0
	AA8	AV0
AA10 AV1	AA9	GNDA
	AA10	AV1

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Din Number	FG676 AFS1500 Function
Pin Number	
AA11	AV2
AA12	GNDA
AA13	AV3
AA14	AV6
AA15	GNDA
AA16	AV7
AA17	AV8
AA18	GNDA
AA19	AV9
AA20	VCCIB2
AA21	IO68PPB2V0
AA22	TCK
AA23	GND
AA24	IO76PPB2V0
AA25	VCCIB2
AA26	NC
AB1	GND
AB2	NC
AB3	GEC2/IO87PDB4V0
AB4	IO87NDB4V0
AB5	GEA2/IO85PDB4V0
AB6	IO85NDB4V0
AB7	NCAP
AB8	AC0
AB9	VCC33A
AB10	AC1
AB11	AC2
AB12	VCC33A
AB13	AC3
AB14	AC6
AB15	VCC33A
AB16	AC7
AB17	AC8
AB18	VCC33A
AB19	AC9
AB20	ADCGNDREF
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	FG676
Pin Number	AFS1500 Function
AB21	PTBASE
AB22	GNDNVM
AB23	VCCNVM
AB24	VPUMP
AB25	NC
AB26	GND
AC1	NC
AC2	NC
AC3	NC
AC4	GND
AC5	VCCIB4
AC6	VCCIB4
AC7	PCAP
AC8	AG0
AC9	GNDA
AC10	AG1
AC11	AG2
AC12	GNDA
AC13	AG3
AC14	AG6
AC15	GNDA
AC16	AG7
AC17	AG8
AC18	GNDA
AC19	AG9
AC20	VAREF
AC21	VCCIB2
AC22	PTEM
AC23	GND
AC24	NC
AC25	NC
AC26	NC
AD1	NC
AD2	NC
AD3	GND
AD4	NC

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Pin Number         AF\$1500 Function           AD5         IO94NPB4V0           AD6         GND           AD7         VCC33N           AD8         AT0           AD9         ATRTN0           AD10         AT1           AD11         AT2           AD12         ATRTN1           AD13         AT3           AD14         AT6           AD15         ATRTN3           AD16         AT7           AD17         AT8           AD18         ATRTN4           AD19         AT9           AD20         VCC33A           AD21         GND           AD22         IO76NPB2V0           AD23         NC           AD24         GND           AD25         NC           AD26         NC           AE1         GND           AE2         GND           AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10	FG676	
AD6 GND AD7 VCC33N AD8 AT0 AD9 ATRTN0 AD10 AT1 AD11 AT2 AD12 ATRTN1 AD13 AT3 AD14 AT6 AD15 ATRTN3 AD16 AT7 AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE6 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE10 NC AE11 NC AE11 NC AE11 NC AE12 GNDA AE11 NC AE12 GNDA AE11 NC AE12 GNDA AE11 NC AE12 GNDA	Pin Number	AFS1500 Function
AD7         VCC33N           AD8         AT0           AD9         ATRTN0           AD10         AT1           AD11         AT2           AD12         ATRTN1           AD13         AT3           AD14         AT6           AD15         ATRTN3           AD16         AT7           AD17         AT8           AD18         ATRTN4           AD19         AT9           AD20         VCC33A           AD21         GND           AD22         IO76NPB2V0           AD23         NC           AD24         GND           AD25         NC           AD26         NC           AE1         GND           AE2         GND           AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC     <	AD5	IO94NPB4V0
AD8         AT0           AD9         ATRTN0           AD10         AT1           AD11         AT2           AD12         ATRTN1           AD13         AT3           AD14         AT6           AD15         ATRTN3           AD16         AT7           AD17         AT8           AD18         ATRTN4           AD19         AT9           AD20         VCC33A           AD21         GND           AD22         IO76NPB2V0           AD23         NC           AD24         GND           AD25         NC           AD26         NC           AE1         GND           AE2         GND           AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AD6	GND
AD9         ATRTNO           AD10         AT1           AD11         AT2           AD12         ATRTN1           AD13         AT3           AD14         AT6           AD15         ATRTN3           AD16         AT7           AD17         AT8           AD18         ATRTN4           AD19         AT9           AD20         VCC33A           AD21         GND           AD22         IO76NPB2V0           AD23         NC           AD24         GND           AD25         NC           AD26         NC           AE1         GND           AE2         GND           AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AD7	VCC33N
AD10 AT1 AD11 AT2 AD12 ATRTN1 AD13 AT3 AD14 AT6 AD15 ATRTN3 AD16 AT7 AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE10 NC AE11 NC AE11 NC AE12 GNDA AE11 NC AE12 GNDA AE11 NC AE12 GNDA AE11 NC AE11 NC AE12 GNDA AE11 NC AE12 GNDA AE11 NC AE12 GNDA AE11 NC	AD8	AT0
AD11 AT2 AD12 ATRTN1 AD13 AT3 AD14 AT6 AD15 ATRTN3 AD16 AT7 AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE10 NC AE11 NC	AD9	ATRTN0
AD12 ATRTN1 AD13 AT3 AD14 AT6 AD15 ATRTN3 AD16 AT7 AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE11 NC	AD10	AT1
AD13 AT3 AD14 AT6 AD15 ATRTN3 AD16 AT7 AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE10 NC AE11 NC	AD11	AT2
AD14         AT6           AD15         ATRTN3           AD16         AT7           AD17         AT8           AD18         ATRTN4           AD19         AT9           AD20         VCC33A           AD21         GND           AD22         IO76NPB2V0           AD23         NC           AD24         GND           AD25         NC           AD26         NC           AE1         GND           AE2         GND           AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AD12	ATRTN1
AD15 ATRTN3 AD16 AT7 AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE10 NC AE11 NC	AD13	AT3
AD16         AT7           AD17         AT8           AD18         ATRTN4           AD19         AT9           AD20         VCC33A           AD21         GND           AD22         IO76NPB2V0           AD23         NC           AD24         GND           AD25         NC           AD26         NC           AE1         GND           AE2         GND           AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AD14	AT6
AD17 AT8 AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE11 NC AE11 NC AE11 NC AE11 NC AE11 NC AE11 NC AE12 GNDA AE12 GNDA AE11 NC	AD15	ATRTN3
AD18 ATRTN4 AD19 AT9 AD20 VCC33A AD21 GND AD22 IO76NPB2V0 AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE11 NC AE12 GNDA AE12 GNDA AE11 NC AE12 GNDA AE11 NC	AD16	AT7
AD19 AT9  AD20 VCC33A  AD21 GND  AD22 IO76NPB2V0  AD23 NC  AD24 GND  AD25 NC  AD26 NC  AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE12 GNDA  AE12 GNDA  AE12 GNDA  AE12 GNDA  AE11 NC	AD17	AT8
AD20 VCC33A  AD21 GND  AD22 IO76NPB2V0  AD23 NC  AD24 GND  AD25 NC  AD26 NC  AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE11 NC  AE11 NC  AE11 NC  AE11 NC  AE12 GNDA  AE12 GNDA  AE13 NC	AD18	ATRTN4
AD21 GND  AD22 IO76NPB2V0  AD23 NC  AD24 GND  AD25 NC  AD26 NC  AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE11 NC  AE12 GNDA  AE12 GNDA  AE12 GNDA  AE13 NC	AD19	AT9
AD22 IO76NPB2V0  AD23 NC  AD24 GND  AD25 NC  AD26 NC  AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE11 NC  AE12 GNDA  AE12 GNDA  AE12 GNDA  AE13 NC	AD20	VCC33A
AD23 NC AD24 GND AD25 NC AD26 NC AE1 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE11 NC AE11 NC AE11 NC AE12 GNDA AE12 GNDA AE13 NC	AD21	GND
AD24 GND  AD25 NC  AD26 NC  AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE10 NC  AE11 NC  AE11 NC  AE12 GNDA  AE12 GNDA  AE13 NC	AD22	IO76NPB2V0
AD25 NC AD26 NC AE1 GND AE2 GND AE3 NC AE4 NC AE5 NC AE6 NC AE7 NC AE8 NC AE9 GNDA AE10 NC AE11 NC AE12 GNDA AE12 GNDA AE12 GNDA AE13 NC	AD23	NC
AD26 NC  AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE10 NC  AE11 NC  AE12 GNDA  AE13 NC	AD24	GND
AE1 GND  AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE10 NC  AE11 NC  AE12 GNDA  AE13 NC	AD25	NC
AE2 GND  AE3 NC  AE4 NC  AE5 NC  AE6 NC  AE7 NC  AE8 NC  AE9 GNDA  AE10 NC  AE11 NC  AE12 GNDA  AE13 NC	AD26	NC
AE3         NC           AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE1	GND
AE4         NC           AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE2	GND
AE5         NC           AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE3	NC
AE6         NC           AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE4	NC
AE7         NC           AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE5	NC
AE8         NC           AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE6	NC
AE9         GNDA           AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE7	NC
AE10         NC           AE11         NC           AE12         GNDA           AE13         NC	AE8	NC
AE11 NC AE12 GNDA AE13 NC	AE9	GNDA
AE12 GNDA AE13 NC	AE10	NC
AE13 NC	AE11	NC
	AE12	GNDA
AE14 NC	AE13	NC
	AE14	NC

	FG676
Pin Number	AFS1500 Function
AE15	GNDA
AE16	NC NC
AE17	NC
AE18	GNDA
AE19	NC
AE20	NC
AE21	NC
AE22	NC
AE23	NC
AE24	NC
AE25	GND
AE26	GND
AF1	NC
AF2	GND
AF3	NC
AF4	NC
AF5	NC
AF6	NC
AF7	NC
AF8	NC
AF9	VCC33A
AF10	NC
AF11	NC
AF12	VCC33A
AF13	NC
AF14	NC
AF15	VCC33A
AF16	NC
AF17	NC
AF18	VCC33A
AF19	NC
AF20	NC
AF21	NC
AF22	NC
AF23	NC
AF24	NC

FG676	
Pin Number	AFS1500 Function
AF25	GND
AF26	NC
B1	GND
B2	GND
В3	NC
B4	NC
B5	NC
В6	VCCIB0
В7	NC
B8	NC
В9	VCCIB0
B10	IO15NDB0V2
B11	IO15PDB0V2
B12	VCCIB0
B13	IO19NDB0V2
B14	IO19PDB0V2
B15	VCCIB1
B16	IO25NDB1V0
B17	IO25PDB1V0
B18	VCCIB1
B19	IO33NDB1V1
B20	IO33PDB1V1
B21	VCCIB1
B22	NC
B23	NC
B24	NC
B25	GND
B26	GND
C1	NC
C2	NC
C3	GND
C4	NC
C5	GAA1/IO01PDB0V0
C6	GAB0/IO02NDB0V0
C7	GAB1/IO02PDB0V0
C8	IO07NDB0V1

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Pin Number         AFS1500 Function           C9         IO07PDB0V1           C10         IO09PDB0V1           C11         IO13NDB0V2           C12         IO13PDB0V2           C13         IO24PDB1V0           C14         IO26PDB1V0           C15         IO27NDB1V1           C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND		FG676	
C10   IO09PDB0V1   C11   IO13NDB0V2   C12   IO13PDB0V2   C13   IO24PDB1V0   C14   IO26PDB1V0   C15   IO27NDB1V1   C16   IO27PDB1V1   C17   IO35NDB1V2   C18   IO35PDB1V2   C19   GBC0/IO40NDB1V2   C20   GBA0/IO42NDB1V2   C21   IO43NDB1V2   C22   IO43PDB1V2   C23   NC   C24   GND   C25   NC   C26   NC   D1   NC   D2   NC   D3   NC   D4   GND   D5   GAA0/IO01NDB0V0   D6   GND   D7   IO04NDB0V0   D8   IO04PDB0V0   D9   GND   D10   IO09NDB0V1   D11   IO11PDB0V1   D12   GND   D13   IO24NDB1V0   D14   IO26NDB1V0   D15   GND   D16   IO31NDB1V1   D17   IO31PDB1V1	Pin Number	AFS1500 Function	
C11         IO13NDB0V2           C12         IO13PDB0V2           C13         IO24PDB1V0           C14         IO26PDB1V0           C15         IO27NDB1V1           C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND <td< td=""><td>C9</td><td>IO07PDB0V1</td></td<>	C9	IO07PDB0V1	
C12         IO13PDB0V2           C13         IO24PDB1V0           C14         IO26PDB1V0           C15         IO27NDB1V1           C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1 <td< td=""><td>C10</td><td>IO09PDB0V1</td></td<>	C10	IO09PDB0V1	
C13         IO24PDB1V0           C14         IO26PDB1V0           C15         IO27NDB1V1           C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C11	IO13NDB0V2	
C14         IO26PDB1V0           C15         IO27NDB1V1           C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C12	IO13PDB0V2	
C15         IO27NDB1V1           C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C13	IO24PDB1V0	
C16         IO27PDB1V1           C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C14	IO26PDB1V0	
C17         IO35NDB1V2           C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C15	IO27NDB1V1	
C18         IO35PDB1V2           C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C16	IO27PDB1V1	
C19         GBC0/IO40NDB1V2           C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C17	IO35NDB1V2	
C20         GBA0/IO42NDB1V2           C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C18	IO35PDB1V2	
C21         IO43NDB1V2           C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C19	GBC0/IO40NDB1V2	
C22         IO43PDB1V2           C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C20	GBA0/IO42NDB1V2	
C23         NC           C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C21	IO43NDB1V2	
C24         GND           C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C22	IO43PDB1V2	
C25         NC           C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C23	NC	
C26         NC           D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C24	GND	
D1         NC           D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C25	NC	
D2         NC           D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	C26	NC	
D3         NC           D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D1	NC	
D4         GND           D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D2	NC	
D5         GAA0/IO01NDB0V0           D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D3	NC	
D6         GND           D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D4	GND	
D7         IO04NDB0V0           D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D5	GAA0/IO01NDB0V0	
D8         IO04PDB0V0           D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D6	GND	
D9         GND           D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D7	IO04NDB0V0	
D10         IO09NDB0V1           D11         IO11PDB0V1           D12         GND           D13         IO24NDB1V0           D14         IO26NDB1V0           D15         GND           D16         IO31NDB1V1           D17         IO31PDB1V1	D8	IO04PDB0V0	
D11 IO11PDB0V1 D12 GND D13 IO24NDB1V0 D14 IO26NDB1V0 D15 GND D16 IO31NDB1V1 D17 IO31PDB1V1	D9	GND	
D12 GND  D13 IO24NDB1V0  D14 IO26NDB1V0  D15 GND  D16 IO31NDB1V1  D17 IO31PDB1V1	D10	IO09NDB0V1	
D13 IO24NDB1V0 D14 IO26NDB1V0 D15 GND D16 IO31NDB1V1 D17 IO31PDB1V1	D11	IO11PDB0V1	
D14 IO26NDB1V0 D15 GND D16 IO31NDB1V1 D17 IO31PDB1V1	D12	GND	
D15 GND  D16 IO31NDB1V1  D17 IO31PDB1V1	D13	IO24NDB1V0	
D16 IO31NDB1V1 D17 IO31PDB1V1	D14	IO26NDB1V0	
D17 IO31PDB1V1	D15	GND	
	D16	IO31NDB1V1	
D18 GND	D17	IO31PDB1V1	
	D18	GND	

	FG676
Pin Number	AFS1500 Function
D19	GBC1/IO40PDB1V2
D20	GBA1/IO42PDB1V2
D21	GND
D22	VCCPLB
D23	GND
D24	NC
D25	NC
D26	NC
E1	GND
E2	IO122NPB4V0
E3	IO121PDB4V0
E4	IO122PPB4V0
E5	IO00NDB0V0
E6	IO00PDB0V0
E7	VCCIB0
E8	IO05NDB0V1
E9	IO05PDB0V1
E10	VCCIB0
E11	IO11NDB0V1
E12	IO14PDB0V2
E13	VCCIB0
E14	VCCIB1
E15	IO29NDB1V1
E16	IO29PDB1V1
E17	VCCIB1
E18	IO37NDB1V2
E19	GBB0/IO41NDB1V2
E20	VCCIB1
E21	VCOMPLB
E22	GBA2/IO44PDB2V0
E23	IO48PPB2V0
E24	GBB2/IO45PDB2V0
E25	NC
E26	GND
F1	NC
F2	VCCIB4

	FG676
Pin Number	AFS1500 Function
F3	IO121NDB4V0
F4	GND
F5	IO123NDB4V0
F6	GAC2/IO123PDB4V0
F7	GAA2/IO125PDB4V0
F8	GAC0/IO03NDB0V0
F9	GAC1/IO03PDB0V0
F10	IO10NDB0V1
F11	IO10PDB0V1
F12	IO14NDB0V2
F13	IO23NDB1V0
F14	IO23PDB1V0
F15	IO32NPB1V1
F16	IO34NDB1V1
F17	IO34PDB1V1
F18	IO37PDB1V2
F19	GBB1/IO41PDB1V2
F20	VCCIB2
F21	IO47PPB2V0
F22	IO44NDB2V0
F23	GND
F24	IO45NDB2V0
F25	VCCIB2
F26	NC
G1	NC
G2	IO119PPB4V0
G3	IO120NDB4V0
G4	IO120PDB4V0
G5	VCCIB4
G6	GAB2/IO124PDB4V0
G7	IO125NDB4V0
G8	GND
G9	VCCIB0
G10	IO08NDB0V1
G11	IO08PDB0V1
G12	GND

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	FG676	
Pin Number	AFS1500 Function	
G13	IO22NDB1V0	
G14	IO22PDB1V0	
G15	GND	
G16	IO32PPB1V1	
G17	IO36NPB1V2	
G18	VCCIB1	
G19	GND	
G20	IO47NPB2V0	
G21	IO49PDB2V0	
G22	VCCIB2	
G23	IO46NDB2V0	
G24	GBC2/IO46PDB2V0	
G25	IO48NPB2V0	
G26	NC	
H1	GND	
H2	NC	
Н3	IO118NDB4V0	
H4	IO118PDB4V0	
H5	IO119NPB4V0	
H6	IO124NDB4V0	
H7	GND	
Н8	VCOMPLA	
H9	VCCPLA	
H10	VCCIB0	
H11	IO12NDB0V1	
H12	IO12PDB0V1	
H13	VCCIB0	
H14	VCCIB1	
H15	IO30NDB1V1	
H16	IO30PDB1V1	
H17	VCCIB1	
H18	IO36PPB1V2	
H19	IO38NPB1V2	
H20	GND	
H21	IO49NDB2V0	
H22	IO50PDB2V0	

	FG676
Pin Number	AFS1500 Function
H23	IO50NDB2V0
H24	IO51PDB2V0
H25	NC
H26	GND
J1	NC
J2	VCCIB4
J3	IO115PDB4V0
J4	GND
J5	IO116NDB4V0
J6	IO116PDB4V0
J7	VCCIB4
J8	IO117PDB4V0
J9	VCCIB4
J10	GND
J11	IO06NDB0V1
J12	IO06PDB0V1
J13	IO16NDB0V2
J14	IO16PDB0V2
J15	IO28NDB1V1
J16	IO28PDB1V1
J17	GND
J18	IO38PPB1V2
J19	IO53PDB2V0
J20	VCCIB2
J21	IO52PDB2V0
J22	IO52NDB2V0
J23	GND
J24	IO51NDB2V0
J25	VCCIB2
J26	NC
K1	NC
K2	NC
K3	IO115NDB4V0
K4	IO113PDB4V0
K5	VCCIB4
K6	IO114NDB4V0

FG676	
Pin Number	AFS1500 Function
K7	IO114PDB4V0
K8	IO117NDB4V0
K9	GND
K10	VCC
K11	VCCIB0
K12	GND
K13	VCCIB0
K14	VCCIB1
K15	GND
K16	VCCIB1
K17	GND
K18	GND
K19	IO53NDB2V0
K20	IO57PDB2V0
K21	GCA2/IO59PDB2V0
K22	VCCIB2
K23	IO54NDB2V0
K24	IO54PDB2V0
K25	NC
K26	NC
L1	GND
L2	NC
L3	IO112PPB4V0
L4	IO113NDB4V0
L5	GFB2/IO109PDB4V0
L6	GFA2/IO110PDB4V0
L7	IO112NPB4V0
L8	IO104PDB4V0
L9	IO111PDB4V0
L10	VCCIB4
L11	GND
L12	VCC
L13	GND
L14	VCC
L15	GND
L16	VCC

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Pin Number         AF\$1500 Function           L17         VCCIB2           L18         GCB2/IO60PDB2V0           L19         IO58NDB2V0           L20         IO57NDB2V0           L21         IO59NDB2V0           L22         GCC2/IO61PDB2V0           L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M20         GND	FG676	
L18         GCB2/IO60PDB2V0           L19         IO58NDB2V0           L20         IO57NDB2V0           L21         IO59NDB2V0           L22         GCC2/IO61PDB2V0           L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24 <th>Pin Number</th> <th>AFS1500 Function</th>	Pin Number	AFS1500 Function
L19         IO58NDB2V0           L20         IO57NDB2V0           L21         IO59NDB2V0           L22         GCC2/IO61PDB2V0           L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25	L17	VCCIB2
L20         IO57NDB2V0           L21         IO59NDB2V0           L22         GCC2/IO61PDB2V0           L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L18	GCB2/IO60PDB2V0
L21         IO59NDB2V0           L22         GCC2/IO61PDB2V0           L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO61NDB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L19	IO58NDB2V0
L22         GCC2/IO61PDB2V0           L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L20	IO57NDB2V0
L23         IO55PPB2V0           L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L21	IO59NDB2V0
L24         IO56PDB2V0           L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L22	GCC2/IO61PDB2V0
L25         IO55NPB2V0           L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L23	IO55PPB2V0
L26         GND           M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L24	IO56PDB2V0
M1         NC           M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L25	IO55NPB2V0
M2         VCCIB4           M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	L26	GND
M3         GFC2/IO108PDB4V0           M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M1	NC
M4         GND           M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M2	VCCIB4
M5         IO109NDB4V0           M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	М3	GFC2/IO108PDB4V0
M6         IO110NDB4V0           M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M4	GND
M7         GND           M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M5	IO109NDB4V0
M8         IO104NDB4V0           M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M6	IO110NDB4V0
M9         IO111NDB4V0           M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M7	GND
M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M8	IO104NDB4V0
M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M9	IO111NDB4V0
M12       GND         M13       VCC         M14       GND         M15       VCC         M16       GND         M17       GND         M18       IO60NDB2V0         M19       IO58PDB2V0         M20       GND         M21       IO68NPB2V0         M22       IO61NDB2V0         M23       GND         M24       IO56NDB2V0         M25       VCCIB2	M10	GND
M13         VCC           M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M11	∨cc
M14         GND           M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M12	GND
M15         VCC           M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M13	VCC
M16         GND           M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M14	GND
M17         GND           M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M15	VCC
M18         IO60NDB2V0           M19         IO58PDB2V0           M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M16	GND
M19 IO58PDB2V0 M20 GND M21 IO68NPB2V0 M22 IO61NDB2V0 M23 GND M24 IO56NDB2V0 M25 VCCIB2	M17	GND
M20         GND           M21         IO68NPB2V0           M22         IO61NDB2V0           M23         GND           M24         IO56NDB2V0           M25         VCCIB2	M18	IO60NDB2V0
M21 IO68NPB2V0 M22 IO61NDB2V0 M23 GND M24 IO56NDB2V0 M25 VCCIB2	M19	IO58PDB2V0
M22 IO61NDB2V0 M23 GND M24 IO56NDB2V0 M25 VCCIB2	M20	GND
M23 GND M24 IO56NDB2V0 M25 VCCIB2	M21	IO68NPB2V0
M24 IO56NDB2V0 M25 VCCIB2	M22	IO61NDB2V0
M25 VCCIB2	M23	GND
	M24	IO56NDB2V0
M26 IO65PDB2V0	M25	VCCIB2
	M26	IO65PDB2V0

	FG676
Pin Number	AFS1500 Function
N1	NC
N2	NC
N3	IO108NDB4V0
N4	VCCOSC
N5	VCCIB4
N6	XTAL2
N7	GFC1/IO107PDB4V0
N8	VCCIB4
N9	GFB1/IO106PDB4V0
N10	VCCIB4
N11	GND
N12	VCC
N13	GND
N14	VCC
N15	GND
N16	VCC
N17	VCCIB2
N18	IO70PDB2V0
N19	VCCIB2
N20	IO69PDB2V0
N21	GCA1/IO64PDB2V0
N22	VCCIB2
N23	GCC0/IO62NDB2V0
N24	GCC1/IO62PDB2V0
N25	IO66PDB2V0
N26	IO65NDB2V0
P1	NC
P2	NC
P3	IO103PDB4V0
P4	XTAL1
P5	VCCIB4
P6	GNDOSC
P7	GFC0/IO107NDB4V0
P8	VCCIB4
P9	GFB0/IO106NDB4V0
P10	VCCIB4
l	

	FG676
Pin Number	AFS1500 Function
P11	VCC
P12	GND
P13	VCC
P14	GND
P15	VCC
P16	GND
P17	VCCIB2
P18	IO70NDB2V0
P19	VCCIB2
P20	IO69NDB2V0
P21	GCA0/IO64NDB2V0
P22	VCCIB2
P23	GCB0/IO63NDB2V0
P24	GCB1/IO63PDB2V0
P25	IO66NDB2V0
P26	IO67PDB2V0
R1	NC
R2	VCCIB4
R3	IO103NDB4V0
R4	GND
R5	IO101PDB4V0
R6	IO100NPB4V0
R7	GND
R8	IO99PDB4V0
R9	IO97PDB4V0
R10	GND
R11	GND
R12	VCC
R13	GND
R14	VCC
R15	GND
R16	VCC
R17	GND
R18	GDB2/IO83PDB2V0
R19	IO78PDB2V0
R20	GND

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Pin Number         AF\$1500 Function           R21         IO72NDB2V0           R22         IO72PDB2V0           R23         GND           R24         IO71PDB2V0           R25         VCCIB2           R26         IO67NDB2V0           T1         GND           T2         NC           T3         GFA1/IO105PDB4V0           T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T9         IO97NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC		FG676
R22   IO72PDB2V0   R23   GND   R24   IO71PDB2V0   R25   VCCIB2   R26   IO67NDB2V0   T1   GND   T2   NC   T3   GFA1/IO105PDB4V0   T4   GFA0/IO105NDB4V0   T5   IO101NDB4V0   T6   IO96PDB4V0   T7   IO96NDB4V0   T8   IO99NDB4V0   T9   IO97NDB4V0   T10   VCCIB4   T11   VCC   T12   GND   T13   VCC   T14   GND   T15   VCC   T16   GND   T17   VCCIB2   T18   IO83NDB2V0   T19   IO78NDB2V0   T20   GDA1/IO81PDB2V0   T21   GDB1/IO80PDB2V0   T22   IO73NDB2V0   T23   IO73PDB2V0   T24   IO71NDB2V0   T25   NC   T26   GND   U1   NC   U2   NC   U3   IO102PDB4V0	Pin Number	AFS1500 Function
R23         GND           R24         IO71PDB2V0           R25         VCCIB2           R26         IO67NDB2V0           T1         GND           T2         NC           T3         GFA1/IO105PDB4V0           T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3	R21	IO72NDB2V0
R24         IO71PDB2V0           R25         VCCIB2           R26         IO67NDB2V0           T1         GND           T2         NC           T3         GFA1/IO105PDB4V0           T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3<	R22	IO72PDB2V0
R25         VCCIB2           R26         IO67NDB2V0           T1         GND           T2         NC           T3         GFA1/IO105PDB4V0           T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	R23	GND
R26         IO67NDB2V0           T1         GND           T2         NC           T3         GFA1/IO105PDB4V0           T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	R24	IO71PDB2V0
T1         GND           T2         NC           T3         GFA1/IO105PDB4V0           T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	R25	VCCIB2
T2 NC T3 GFA1/IO105PDB4V0 T4 GFA0/IO105NDB4V0 T5 IO101NDB4V0 T6 IO96PDB4V0 T7 IO96NDB4V0 T8 IO99NDB4V0 T9 IO97NDB4V0 T10 VCCIB4 T11 VCC T12 GND T13 VCC T14 GND T15 VCC T16 GND T17 VCCIB2 T18 IO83NDB2V0 T19 IO78NDB2V0 T20 GDA1/IO81PDB2V0 T21 GDB1/IO80PDB2V0 T22 IO73NDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	R26	IO67NDB2V0
T3 GFA1/IO105PDB4V0 T4 GFA0/IO105NDB4V0 T5 IO101NDB4V0 T6 IO96PDB4V0 T7 IO96NDB4V0 T8 IO99NDB4V0 T9 IO97NDB4V0 T10 VCCIB4 T11 VCC T12 GND T13 VCC T14 GND T15 VCC T16 GND T17 VCCIB2 T18 IO83NDB2V0 T19 IO78NDB2V0 T20 GDA1/IO81PDB2V0 T21 GDB1/IO80PDB2V0 T22 IO73NDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC	T1	GND
T4         GFA0/IO105NDB4V0           T5         IO101NDB4V0           T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T2	NC
T5   IO101NDB4V0   T6   IO96PDB4V0   T7   IO96NDB4V0   T8   IO99NDB4V0   T9   IO97NDB4V0   T10   VCCIB4   T11   VCC   T12   GND   T13   VCC   T14   GND   T15   VCC   T16   GND   T17   VCCIB2   T18   IO83NDB2V0   T19   IO78NDB2V0   T20   GDA1/IO81PDB2V0   T21   GDB1/IO80PDB2V0   T22   IO73NDB2V0   T23   IO73PDB2V0   T24   IO71NDB2V0   T25   NC   T26   GND   U1   NC   U2   NC   U3   IO102PDB4V0	Т3	GFA1/IO105PDB4V0
T6         IO96PDB4V0           T7         IO96NDB4V0           T8         IO99NDB4V0           T9         IO97NDB4V0           T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T4	GFA0/IO105NDB4V0
T7 IO96NDB4V0 T8 IO99NDB4V0 T9 IO97NDB4V0 T10 VCCIB4 T11 VCC T12 GND T13 VCC T14 GND T15 VCC T16 GND T17 VCCIB2 T18 IO83NDB2V0 T19 IO78NDB2V0 T20 GDA1/IO81PDB2V0 T21 GDB1/IO80PDB2V0 T22 IO73NDB2V0 T23 IO73PDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T5	IO101NDB4V0
T8	T6	IO96PDB4V0
T9	T7	IO96NDB4V0
T10         VCCIB4           T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T8	IO99NDB4V0
T11         VCC           T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	Т9	IO97NDB4V0
T12         GND           T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T10	VCCIB4
T13         VCC           T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T11	VCC
T14         GND           T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T12	GND
T15         VCC           T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T13	VCC
T16         GND           T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T14	GND
T17         VCCIB2           T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T15	VCC
T18         IO83NDB2V0           T19         IO78NDB2V0           T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T16	GND
T19 IO78NDB2V0 T20 GDA1/IO81PDB2V0 T21 GDB1/IO80PDB2V0 T22 IO73NDB2V0 T23 IO73PDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T17	VCCIB2
T20         GDA1/IO81PDB2V0           T21         GDB1/IO80PDB2V0           T22         IO73NDB2V0           T23         IO73PDB2V0           T24         IO71NDB2V0           T25         NC           T26         GND           U1         NC           U2         NC           U3         IO102PDB4V0	T18	IO83NDB2V0
T21 GDB1/IO80PDB2V0 T22 IO73NDB2V0 T23 IO73PDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T19	IO78NDB2V0
T22 IO73NDB2V0 T23 IO73PDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T20	GDA1/IO81PDB2V0
T23 IO73PDB2V0 T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T21	GDB1/IO80PDB2V0
T24 IO71NDB2V0 T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T22	IO73NDB2V0
T25 NC T26 GND U1 NC U2 NC U3 IO102PDB4V0	T23	IO73PDB2V0
T26 GND  U1 NC  U2 NC  U3 IO102PDB4V0	T24	IO71NDB2V0
U1 NC U2 NC U3 IO102PDB4V0	T25	NC
U2 NC U3 IO102PDB4V0	T26	GND
U3 IO102PDB4V0	U1	NC
	U2	NC
U4 IO102NDB4V0	U3	IO102PDB4V0
	U4	IO102NDB4V0

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Pin Number	AFS1500 Function
U5	VCCIB4
U6	IO91PDB4V0
U7	IO91NDB4V0
U8	IO92PDB4V0
U9	GND
U10	GND
U11	VCC33A
U12	GNDA
U13	VCC33A
U14	GNDA
U15	VCC33A
U16	GNDA
U17	VCC
U18	GND
U19	IO74NDB2V0
U20	GDA0/IO81NDB2V0
U21	GDB0/IO80NDB2V0
U22	VCCIB2
U23	IO75NDB2V0
U24	IO75PDB2V0
U25	NC
U26	NC
V1	NC
V2	VCCIB4
V3	IO100PPB4V0
V4	GND
V5	IO95PDB4V0
V6	IO95NDB4V0
V7	VCCIB4
V8	IO92NDB4V0
V9	GNDNVM
V10	GNDA
V11	NC
V12	AV4
V13	NC
V14	AV5

	FG676
Pin Number	AFS1500 Function
V15	AC5
V16	NC
V17	GNDA
V18	IO77PPB2V0
V19	IO74PDB2V0
V20	VCCIB2
V21	IO82NDB2V0
V22	GDA2/IO82PDB2V0
V23	GND
V24	GDC1/IO79PDB2V0
V25	VCCIB2
V26	NC
W1	GND
W2	IO94PPB4V0
W3	IO98PDB4V0
W4	IO98NDB4V0
W5	GEC1/IO90PDB4V0
W6	GEC0/IO90NDB4V0
W7	GND
W8	VCCNVM
W9	VCCIB4
W10	VCC15A
W11	GNDA
W12	AC4
W13	VCC33A
W14	GNDA
W15	AG5
W16	GNDA
W17	PUB
W18	VCCIB2
W19	TDI
W20	GND
W21	IO84NDB2V0
W22	GDC2/IO84PDB2V0
W23	IO77NPB2V0
W24	GDC0/IO79NDB2V0

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	FG676
Pin Number	AFS1500 Function
W25	NC
W26	GND
Y1	NC
Y2	NC
Y3	GEB1/IO89PDB4V0
Y4	GEB0/IO89NDB4V0
Y5	VCCIB4
Y6	GEA1/IO88PDB4V0
Y7	GEA0/IO88NDB4V0
Y8	GND
Y9	VCC33PMP
Y10	NC
Y11	VCC33A
Y12	AG4
Y13	AT4
Y14	ATRTN2
Y15	AT5
Y16	VCC33A
Y17	NC
Y18	VCC33A
Y19	GND
Y20	TMS
Y21	VJTAG
Y22	VCCIB2
Y23	TRST
Y24	TDO
Y25	NC
Y26	NC

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## 5 - Datasheet Information

# **List of Changes**

The following table lists critical changes that were made in each revision of the Fusion datasheet.

Revision	Changes	Table
Revision 8 (May 2018)	In "Specifying I/O States During Programming", the version of the software, v9.0 is removed to write Libero SoC, as Fusion family is supported in the Libero SoC (SAR 73296).	1-9
	In tables, Table 2-78, Table 2-79 and Table 2-80, "3" is edited to a tick mark, to show the I/O standards with available drive and slew settings (SAR 70900).	2-152
	The description for "LOCKREQUEST" is edited in "LOCKREQUEST" section (SAR 25423).	2-44
	A note is added to explain data corruption in SRAM block, when setup and hold requirements are violated on address inputs under "Clocking" (SAR 93618).	2-61
	A note is added where ever it is applicable in the datasheet that the package PQ208 is discontinued (SAR 76873).	
	A note is added in "Package Pin Assignments" to direct the user to PD3068: Package Mechanical Drawings (SAR 76874)	4-1
Revision 7 (May 2016)	Note added for discontinuance of PQ208 package to the "Package I/Os: Single-/Double-Ended (Analog)" table, "Product Ordering Codes", and "Temperature Grade Offerings" table (SAR).	1-II, 1-III, and 1-IV
	Updated Figure 2-42 (SAR 61872).	2-51
Revision 6 (March 2014)	Note added for the discontinuance of QN108 and QN180 packages to the "Package I/Os: Single-/Double-Ended (Analog)" table and the "Temperature Grade Offerings" table (SAR 55113, PDN 1306).	II and IV
	Updated details about page programming time in the "Program Operation" section (SAR 49291).	2-46
	ADC_START changed to ADCSTART in the "ADC Operation" section (SAR 44104).	2-104
Revision 5 (January 2014)	Calibrated offset values (AFS090, AFS250) of the external temperature monitor in Table 2-49 • Analog Channel Specifications have been updated (SAR 51464).	2-117
	Specifications for the internal temperature monitor in Table 2-49 • Analog Channel Specifications have been updated (SAR 50870).	2-117



Revision	Changes	Table
Revision 4 (January 2013)	The "Product Ordering Codes" section has been updated to mention "Y" as "Blank" mentioning "Device Does Not Include License to Implement IP Based on the Cryptography Research, Inc. (CRI) Patent Portfolio" (SAR 43177).	III
	The note in Table 2-12 • Fusion CCC/PLL Specification referring the reader to SmartGen was revised to refer instead to the online help associated with the core (SAR 42563).	2-28
	Table 2-49 • Analog Channel Specifications was modified to update the uncalibrated offset values (AFS250) of the external and internal temperature monitors (SAR 43134).	2-117
	In Table 2-57 • Prescaler Control Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3), changed the column heading from 'Full-Scale Voltage' to 'Full Scale Voltage in 10-Bit Mode', and added and updated Notes as required (SAR 20812).	2-130
	The values for the Speed Grade (-1 and Std.) for FDDRIMAX (Table 2-180 • Input DDR Propagation Delays) and values for the Speed Grade (-2 and Std.) for FDDOMAX (Table 2-182 • Output DDR Propagation Delays) had been inadvertently interchanged. This has been rectified (SAR 38514).	2-220, 2-222
	Added description about what happens if a user connects VAREF to an external 3.3 V on their board to the "V <sub>AREF</sub> Analog Reference Voltage" section (SAR 35188).	2-225
	Added a note to Table 3-2 • Recommended Operating Conditions <sup>1</sup> (SAR 43429): The programming temperature range supported is T <sub>ambient</sub> = 0°C to 85°C.	3-3
	Added the Package Thermal details for AFS600-PQ208 and AFS250-PQ208 to Table 3-6 • Package Thermal Resistance (SAR 37816). Deleted the Die Size column from the table (SAR 43503).	3-7
	Libero Integrated Design Environment (IDE) was changed to Libero System-on-Chip (SoC) throughout the document (SAR 42495).	NA
	Live at Power-Up (LAPU) has been replaced with Instant On'.	
Revision 3	Microblade U1AFS250 and U1AFS1500 devices were added to the product tables.	I – IV
(August 2012)	A sentence pertaining to the analog I/Os was added to the "Specifying I/O States During Programming" section (SAR 34831).	1-9

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Revision	Changes	Table
Revision 3 (continued)	The "RC Oscillator" section was revised to correct a sentence that did not differentiate accuracy for commercial and industrial temperature ranges, which is given in Table 2-9 • Electrical Characteristics of RC Oscillator (SAR 33722).	2-19
	Figure 2-57 • FIFO Read and Figure 2-58 • FIFO Write are new (SAR 34840).	2-72
	The first paragraph of the "Offset" section was removed; it was intended to be replaced by the paragraph following it (SAR 22647).	2-95
	IOL and IOH values for 3.3 V GTL+ and 2.5 V GTL+ were corrected in Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions (SAR 39813).	2-164
	The drive strength, IOL, and IOH for 3.3 V GTL and 2.5 V GTL were changed from 25 mA to 20 mA in the following tables (SAR 37373):	
	Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions,	2-164
	Table 2-92 • Summary of I/O Timing Characteristics – Software Default Settings	2-167
	Table 2-96 • I/O Output Buffer Maximum Resistances <sup>1</sup>	2-169
	Table 2-138 • Minimum and Maximum DC Input and Output Levels	2-199
	Table 2-141 • Minimum and Maximum DC Input and Output Levels	2-200
	The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34800): "It uses a 5 V-tolerant input buffer and push-pull output buffer."	2-181
	Corrected the inadvertent error in maximum values for LVPECL VIH and VIL and revised them to "3.6" in Table 2-171 • Minimum and Maximum DC Input and Output Levels, making these consistent with Table 3-1 • Absolute Maximum Ratings, and Table 3-4 • Overshoot and Undershoot Limits <sup>1</sup> (SAR 37687).	2-211
	The maximum frequency for global clock parameter was removed from Table 2-5 • AFS1500 Global Resource Timing through Table 2-8 • AFS090 Global Resource Timing because a frequency on the global is only an indication of what the global network can do. There are other limiters such as the SRAM, I/Os, and PLL. SmartTime software should be used to determine the design frequency (SAR 36955).	2-16 to 2-17
Revision 2 (March 2012)	The phrase "without debug" was removed from the "Soft ARM Cortex-M1 Fusion Devices (M1)" section (SAR 21390).	1
	The "In-System Programming (ISP) and Security" section, "Security" section, "Flash Advantages" section, and "Security" section were revised to clarify that although no existing security measures can give an absolute guarantee, Microsemi FPGAs implement the best security available in the industry (SAR 34679).	l, 1-2, 2-228
	The Y security option and Licensed DPA Logo was added to the "Product Ordering Codes" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 34721).	III
	The "Specifying I/O States During Programming" section is new (SAR 34693).	1-9
	The following information was added before Figure 2-17 • XTLOSC Macro:	2-20
	In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating (SAR 24119).	
	Table 2-12 • Fusion CCC/PLL Specification was updated. A note was added indicating that when the CCC/PLL core is generated by Microsemi core generator software, not all delay values of the specified delay increments are available (SAR 34814).	2-28

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Revision	Changes	Table
Revision 2 (continued)	A note was added to Figure 2-27 • Real-Time Counter System (not all the signals are shown for the AB macro) stating that the user is only required to instantiate the VRPSM macro if the user wishes to specify PUPO behavior of the voltage regulator to be different from the default, or employ user logic to shut the voltage regulator off (SAR 21773).	2-31
	VPUMP was incorrectly represented as VPP in several places. This was corrected to VPUMP in the "Standby and Sleep Mode Circuit Implementation" section and Table 3-8 • AFS1500 Quiescent Supply Current Characteristics through Table 3-11 • AFS090 Quiescent Supply Current Characteristics (21963).	2-32, 3-10
	Additional information was added to the Flash Memory Block "Write Operation" section, including an explanation of the fact that a copy-page operation takes no less than 55 cycles (SAR 26338).	2-45
	The "FlashROM" section was revised to refer to Figure 2-46 • FlashROM Timing Diagram and Table 2-26 • FlashROM Access Time rather than stating 20 MHz as the maximum FlashROM access clock and 10 ns as the time interval for D0 to become valid or invalid (SAR 22105).	2-53, 2-54
	The following figures were deleted (SAR 29991). Reference was made to a new application note, <i>Simultaneous Read-Write Operations in Dual-Port SRAM for Flash-Based cSoCs and FPGAs</i> , which covers these cases in detail (SAR 34862).	
	Figure 2-55 • Write Access after Write onto Same Address	
	Figure 2-56 • Read Access after Write onto Same Address	
	Figure 2-57 • Write Access after Read onto Same Address	
	The port names in the SRAM "Timing Waveforms", "Timing Characteristics", SRAM tables, Figure 2-55 • RAM Reset. Applicable to both RAM4K9 and RAM512x18., and the FIFO "Timing Characteristics" tables were revised to ensure consistency with the software names (SAR 35753).	2-63, 2-66, 2-65, 2-7
	In several places throughout the datasheet, GNDREF was corrected to ADCGNDREF (SAR 20783):	
	Figure 2-64 • Analog Block Macro	2-77
	Table 2-36 • Analog Block Pin Description	2-78
	"ADC Operation" section	2-104
	The following note was added below Figure 2-78 • Timing Diagram for the Temperature Monitor Strobe Signal:	2-93
	When the IEEE 1149.1 Boundary Scan EXTEST instruction is executed, the AG pad drive strength ceases and becomes a 1 $\mu$ A sink into the Fusion device. (SAR 24796).	
	The "Analog-to-Digital Converter Block" section was extensively revised, reorganizing the information and adding the "ADC Theory of Operation" section and "Acquisition Time or Sample Time Control" section. The "ADC Example" section was reworked and corrected (SAR 20577).	2-96
	Table 2-49 • Analog Channel Specifications was modified to include calibrated and uncalibrated values for offset (AFS090 and AFS250) for the external and internal temperature monitors. The "Offset" section was revised accordingly and now references Table 2-49 • Analog Channel Specifications (SARs 22647, 27015).	2-95, 2-117
	The "Intra-Conversion" section and "Injected Conversion" section had definitions incorrectly interchanged and have been corrected. Figure 2-92 • Intra-Conversion Timing Diagram and Figure 2-93 • Injected Conversion Timing Diagram were also incorrectly interchanged and have been replaced correctly. Reference in the figure notes to EQ 10 has been corrected to EQ 23 (SAR 20547).	2-110, 2-113, 2-113

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Revision	Changes	Table
Revision 2 (continued)	The prescalar range for the 'Analog Input (direct input to ADC)" configurations was removed as inapplicable for direct inputs. The input resistance for direct inputs is covered in Table 2-50 • ADC Characteristics in Direct Input Mode (SAR 31201).	2-120
	The "Examples" for calibrating accuracy for ADC channels were revised and corrected to make them consistent with terminology in the associated tables (SARs 36791, 36773).	2-124
	A note was added to Table 2-56 • Analog Quad ACM Byte Assignment and the introductory text for Table 2-66 • Internal Temperature Monitor Control Truth Table, stating that for the internal temperature monitor to function, Bit 0 of Byte 2 for all 10 Quads must be set (SAR 34418).	2-129, 2-131
	t <sub>DOUT</sub> was corrected to t <sub>DIN</sub> in Figure 2-116 • Input Buffer Timing Model and Delays (example) (SAR 37115).	2-161
	The formulas in the table notes for Table 2-97 • I/O Weak Pull-Up/Pull-Down Resistances were corrected (SAR 34751).	2-171
	The AC Loading figures in the "Single-Ended I/O Characteristics" section were updated to match tables in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section (SAR 34877).	2-175
	The following notes were removed from Table 2-168 • Minimum and Maximum DC Input and Output Levels (SAR 34808): ±5% Differential input voltage = ±350 mV	2-209
	An incomplete, duplicate sentence was removed from the end of the "GNDAQ Ground (analog quiet)" pin description (SAR 30185).	2-223
	Information about configuration of unused I/Os was added to the "User Pins" section (SAR 32642).	2-225
	The following information was added to the pin description for "XTAL1 Crystal Oscillator Circuit Input" and "XTAL2 Crystal Oscillator Circuit Input" (SAR 24119).	2-227
	The input resistance to ground value in Table 3-3 • Input Resistance of Analog Pads for Analog Input (direct input to ADC), was corrected from 1 M $\Omega$ (typical) to 2 k $\Omega$ (typical) (SAR 34371).	3-4
	The Storage Temperature column in Table 3-5 • FPGA Programming, Storage, and Operating Limits stated Min. T <sub>J</sub> twice for commercial and industrial product grades and has been corrected to Min. T <sub>J</sub> and Max. T <sub>J</sub> (SAR 29416).	3-5
	The reference to guidelines for global spines and VersaTile rows, given in the "Global Clock Dynamic Contribution—P <sub>CLOCK</sub> " section, was corrected to the "Spine Architecture" section of the Global Resources chapter in the <i>Fusion FPGA Fabric User's Guide</i> (SAR 34741).	3-24
	Package names used in the "Package Pin Assignments" section were revised to match standards given in <i>Package Mechanical Drawings</i> (SAR 36612).	4-1
July 2010	The versioning system for data-sheets has been changed. Datasheets are assigned a revision number that increments each time the datasheet is revised. The "Fusion Device Status" table indicates the status for each device in the device family.	N/A

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Revision	Changes	Table
v2.0, Revision 1 (July 2009)	The MicroBlade and Fusion datasheets have been combined. Pigeon Point information is new.	N/A
	CoreMP7 support was removed since it is no longer offered.	
	–F was removed from the datasheet since it is no longer offered.	
	The operating temperature was changed from ambient to junction to better reflect actual conditions of operations.  Commercial: 0°C to 85°C	
	Industrial: –40°C to 100°C	
	The version number category was changed from Preliminary to Production, which means the datasheet contains information based on final characterization. The version number changed from Preliminary v1.7 to v2.0.	
	The "Integrated Analog Blocks and Analog I/Os" section was updated to include a reference to the "Analog System Characteristics" section in the <i>Device Architecture</i> chapter of the datasheet, which includes Table 2-46 • Analog Channel Specifications and specific voltage data.	1-4
	The phrase "Commercial-Case Conditions" in timing table titles was changed to "Commercial Temperature Range Conditions."	N/A
	The "Crystal Oscillator" section was updated significantly. Please review carefully.	2-20
	The "Real-Time Counter (part of AB macro)" section was updated significantly. Please review carefully.	2-33
	There was a typo in Table 2-19 • Flash Memory Block Pin Names for the ERASEPAGE description; it was the same as DISCARDPAGE. As as a result, the ERASEPAGE description was updated.	2-40
	The $t_{\mbox{\scriptsize FMAXCLKNVM}}$ parameter was updated in Table 2-25 • Flash Memory Block Timing.	2-52
	Table 2-31 • RAM4K9 and Table 2-32 • RAM512X18 were updated.	2-66
	In Table 2-36 • Analog Block Pin Description, the Function description for PWRDWN was changed from "Comparator power-down if 1" to	2-78
	"ADC comparator power-down if 1. When asserted, the ADC will stop functioning, and the digital portion of the analog block will continue operating. This may result in invalid status flags from the analog block. Therefore, Microsemi does not recommend asserting the PWRDWN pin."	
	Figure 2-75 • Gate Driver Example was updated.	2-91
	The "ADC Operation" section was updated. Please review carefully.	2-104
	Figure 2-92 • Intra-Conversion Timing Diagram and Figure 2-93 • Injected Conversion Timing Diagram are new.	2-113
	The "Typical Performance Characteristics" section is new.	2-115
	Table 2-49 • Analog Channel Specifications was significantly updated.	2-117
	Table 2-50 • ADC Characteristics in Direct Input Mode was significantly updated.	2-120
	In Table 2-52 • Calibrated Analog Channel Accuracy 1,2,3, note 2 was updated.	2-123
	In Table 2-53 • Analog Channel Accuracy: Monitoring Standard Positive Voltages, note 1 was updated.	2-124
	In Table 2-54 • ACM Address Decode Table for Analog Quad, bit 89 was removed.	2-126

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Revision	Changes	Table
v2.0, Revision 1 (continued)	The data in the 2.5 V LCMOS and LVCMOS 2.5 V / 5.0 V rows were updated in Table 2-75 • Fusion Standard and Advanced I/O – Hot-Swap and 5 V Input Tolerance Capabilities.	2-143
	In Table 2-78 • Fusion Standard I/O Standards—OUT_DRIVE Settings, LVCMOS 1.5 V, for OUT_DRIVE 2, was changed from a dash to a check mark.	2-152
	The "VCC15A Analog Power Supply (1.5 V)" definition was changed from "A 1.5 V analog power supply input should be used to provide this input" to "1.5 V clean analog power supply input for use by the 1.5 V portion of the analog circuitry."	2-223
	In the "VCC33PMP Analog Power Supply (3.3 V)" pin description, the following text was changed from "VCC33PMP should be powered up before or simultaneously with VCC33A" to "VCC33PMP should be powered up simultaneously with or after VCC33A."	2-223
	The "VCCOSC Oscillator Power Supply (3.3 V)" section was updated to include information about when to power the pin.	2-223
	In the "128-Bit AES Decryption" section, FIPS-192 was incorrect and changed to FIPS-197.	2-228
	The note in Table 2-84 • Fusion Standard and Advanced I/O Attributes vs. I/O Standard Applications was updated.	2-156
	For 1.5 V LVCMOS, the VIL and VIH parameters, 0.30 * VCCI was changed to 0.35 * VCCI and 0.70 * VCCI was changed to 0.65 * VCCI in Table 2-86 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions, Table 2-87 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions, and Table 2-88 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions.	2-164 to 2-165
	In Table 2-87 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions, the VIH max column was updated.	
	Table 2-89 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions was updated to include notes 3 and 4. The temperature ranges were also updated in notes 1 and 2.	2-165
	The titles in Table 2-92 • Summary of I/O Timing Characteristics – Software Default Settings to Table 2-94 • Summary of I/O Timing Characteristics – Software Default Settings were updated to "VCCI = I/O Standard Dependent."	2-167 to 2-168
	Below Table 2-98 • I/O Short Currents IOSH/IOSL, the paragraph was updated to change 110°C to 100°C and three months was changed to six months.	2-172
	Table 2-99 • Short Current Event Duration before Failure was updated to remove 110°C data.	2-174
	In Table 2-101 • I/O Input Rise Time, Fall Time, and Related I/O Reliability, LVTTL/LVCMOS rows were changed from 110°C to 100°C.	2-174
	VCC33PMP was added to Table 3-1 • Absolute Maximum Ratings. In addition, conditions for AV, AC, AG, and AT were also updated.	3-1
	VCC33PMP was added to Table 3-2 • Recommended Operating Conditions <sup>1</sup> . In addition, conditions for AV, AC, AG, and AT were also updated.	3-3
	Table 3-5 • FPGA Programming, Storage, and Operating Limits was updated to include new data and the temperature ranges were changed. The notes were removed from the table.	3-5

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Revision	Changes	Table
v2.0, Revision 1 (continued)	Table 3-6 • Package Thermal Resistance was updated to include new data.	3-7
	In EQ 4 to EQ 6, the junction temperature was changed from 110°C to 100°C.	3-8 to 3-8
	Table 3-8 • AFS1500 Quiescent Supply Current Characteristics through Table 3-11 • AFS090 Quiescent Supply Current Characteristics are new and have replaced the Quiescent Supply Current Characteristics (IDDQ) table.	3-10 to 3-16
	In Table 3-14 • Different Components Contributing to the Dynamic Power Consumption in Fusion Devices, the power supply for PAC9 and PAC10 were changed from VMV/VCC to VCCI.	3-22
	In Table 3-15 • Different Components Contributing to the Static Power Consumption in Fusion Devices, the power supply for PDC7 and PDC8 were changed from VMV/VCC to VCCI. PDC1 was updated from TBD to 18.	3-23
	The "QN108" table was updated to remove the duplicates of pins B12 and B34.	4-2
Preliminary v1.7 (October 2008)	The version number category was changed from Advance to Preliminary, which means the datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.	
	For the VIL and VIH parameters, 0.30 * VCCI was changed to 0.35 * VCCI and 0.70 * VCCI was changed to 0.65 * VCCI in Table 2-126 • Minimum and Maximum DC Input and Output Levels.	2-193
	The version number category was changed from Advance to Preliminary, which means the datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.	N/A
	The following updates were made to Table 2-141 • Minimum and Maximum DC Input and Output Levels:	2-200
	Temperature Digital Output	
	213 00 1111 1101	
	283 01 0001 1011 358 01 0110 - only the digital output was updated. Temperature 358 remains in the temperature column.	
	In Advance v1.2, the "V <sub>AREF</sub> Analog Reference Voltage" pin description was significantly updated but the change was not noted in the change table.	2-225
Advance v1.6 (August 2008)	The title of the datasheet changed from Actel Programmable System Chips to Actel Fusion Mixed Signal FPGAs. In addition, all instances of programmable system chip were changed to mixed signal FPGA.	N/A
	The references to the <i>Peripherals User's Guide</i> in the "No-Glitch MUX (NGMUX)" section and "Voltage Regulator Power Supply Monitor (VRPSM)" section were changed to <i>Fusion Handbook</i> .	2-32, 2-42
Advance v1.5 (July 2008)	The following bullet was updated from High-Voltage Input Tolerance: ±12 V to High-Voltage Input Tolerance: 10.5 V to 12 V.	I
	The following bullet was updated from Programmable 1, 3, 10, 30 $\mu$ A and 25 mA Drive Strengths to Programmable 1, 3, 10, 30 $\mu$ A and 20 mA Drive Strengths.	I

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Revision	Changes	Table
Advance v1.5 (continued)	This bullet was added to the "Integrated A/D Converter (ADC) and Analog I/O" section: ADC Accuracy is Better than 1%	I
	In the "Integrated Analog Blocks and Analog I/Os" section, ±4 LSB was changed to 0.72. The following sentence was deleted:	1-4
	The input range for voltage signals is from $-12\ V$ to $+12\ V$ with full-scale output values from $0.125\ V$ to $16\ V$ .	
	In addition, 2°C was changed to 3°C:	
	"One analog input in each quad can be connected to an external temperature monitor diode and achieves detection accuracy of ±3°C."	
	The following sentence was deleted:	
	The input range for voltage signals is from $-12~V$ to $+12~V$ with full-scale output values from 0.125 V to 16 V.	
	The title of the datasheet changed from Actel Programmable System Chips to Actel Fusion Mixed Signal FPGAs. In addition, all instances of programmable system chip were changed to mixed signal FPGA.	N/A
Advance v1.4 (July 2008)	In Table 3-8 · Quiescent Supply Current Characteristics (IDDQ)1, footnote references were updated for I <sub>DC2</sub> and I <sub>DC3</sub> .  Footnote 3 and 4 were updated and footnote 5 is new.	3-11
Advance v1.3 (July 2008)	The "ADC Description" section was significantly updated. Please review carefully.	2-102
Advance v1.2 (May 2008)	Table 2-25 • Flash Memory Block Timing was significantly updated.	2-55
	The "V <sub>AREF</sub> Analog Reference Voltage" pin description section was significantly update. Please review it carefully.	2-226
	Table 2-45 • ADC Interface Timing was significantly updated.	2-110
	Table 2-56 • Direct Analog Input Switch Control Truth Table—AV $(x = 0)$ , AC $(x = 1)$ , and AT $(x = 3)$ was significantly updated.	2-131
	The following sentence was deleted from the "Voltage Monitor" section: The Analog Quad inputs are tolerant up to 12 V + 10%.	2-86
	The "180-Pin QFN" figure was updated. D1 to D4 are new and the figure was changed to bottom view. The note below the figure is new.	3-3
Advance v1.1	The following text was incorrect and therefore deleted:	2-204
(May 2008)	VCC33A Analog Power Filter	
	Analog power pin for the analog power supply low-pass filter. An external 100 pF capacitor should be connected between this pin and ground.	
	There is still a description of V <sub>CC33A</sub> on page 2-224.	

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Revision	Changes	Table
Advance v1.0 (January 2008)	All Timing Characteristics tables were updated. For the Differential I/O Standards, the Standard I/O support tables are new.	N/A
	Table 2-3 • Array Coordinates was updated to change the max x and y values	2-9
	Table 2-12 • Fusion CCC/PLL Specification was updated.	2-31
	A note was added to Table 2-16 · RTC ACM Memory Map.	2-37
	A reference to the Peripheral's User's Guide was added to the "Voltage Regulator Power Supply Monitor (VRPSM)" section.	2-42
	In Table 2-25 • Flash Memory Block Timing, the commercial conditions were updated.	2-55
	In Table 2-26 • FlashROM Access Time, the commercial conditions were missing and have been added below the title of the table.	2-58
	In Table 2-36 • Analog Block Pin Description, the function description was updated for the ADCRESET.	2-82
	In the "Voltage Monitor" section, the following sentence originally had $\pm$ 10% and it was changed to +10%.	2-86
	The Analog Quad inputs are tolerant up to 12 V + 10%.	
	In addition, this statement was deleted from the datasheet:  Each I/O will draw power when connected to power (3 mA at 3 V).	
	The "Terminology" section is new.	2-88
	The "Current Monitor" section was significantly updated. Figure 2-72 • Timing Diagram for Current Monitor Strobe to Figure 2-74 • Negative Current Monitor and Table 2-37 • Recommended Resistor for Different Current Range Measurement are new.	2-90
	The "ADC Description" section was updated to add the "Terminology" section.	2-93
	In the "Gate Driver" section, 25 mA was changed to 20 mA and 1.5 MHz was changed to 1.3 MHz. In addition, the following sentence was deleted:  The maximum AG pad switching frequency is 1.25 MHz.	2-94
	The "Temperature Monitor" section was updated to rewrite most of the text and add Figure 2-78, Figure 2-79, and Table 2-38 • Temperature Data Format.	2-96
	In Table 2-38 • Temperature Data Format, the temperature K column was changed for 85°C from 538 to 358.	2-98
	In Table 2-45 • ADC Interface Timing, "Typical-Case" was changed to "Worst-Case."	2-110
	The "ADC Interface Timing" section is new.	2-110
	Table 2-46 • Analog Channel Specifications was updated.	2-118
	The "V <sub>CC15A</sub> Analog Power Supply (1.5 V)" section was updated.	2-224
	The "V <sub>CCPLA/B</sub> PLL Supply Voltage" section is new.	2-225
	In "V <sub>CCNVM</sub> Flash Memory Block Power Supply (1.5 V)" section, supply was changed to supply input.	2-224
	The "V <sub>CCPLA/B</sub> PLL Supply Voltage" pin description was updated to include the following statement:	2-225
	Actel recommends tying VCCPLX to VCC and using proper filtering circuits to decouple V <sub>CC</sub> noise from PLL.	
	The "V <sub>COMPLA/B</sub> Ground for West and East PLL" section was updated.	2-225

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Revision	Changes	Table
Advance 1.0 (continued)	In Table 2-47 • ADC Characteristics in Direct Input Mode, the commercial conditions were updated and note 2 is new.	2-121
	The $V_{\text{CC33ACAP}}$ signal name was changed to "XTAL1 Crystal Oscillator Circuit Input".	2-228
	Table 2-48 • Uncalibrated Analog Channel Accuracy* is new.	2-123
	Table 2-49 • Calibrated Analog Channel Accuracy 1,2,3 is new.	2-124
	Table 2-50 • Analog Channel Accuracy: Monitoring Standard Positive Voltages is new.	2-125
	In Table 2-57 • Voltage Polarity Control Truth Table—AV $(x = 0)$ , AC $(x = 1)$ , and AT $(x = 3)^*$ , the following I/O Bank names were changed:	2-131
	Hot-Swap changed to Standard LVDS changed to Advanced	
	In Table 2-58 • Prescaler Op Amp Power-Down Truth Table—AV (x = 0), AC (x = 1), and AT (x = 3), the following I/O Bank names were changed:  Hot-Swap changed to Standard  LVDS changed to Advanced	2-132
	In the title of Table 2-64 • I/O Standards Supported by Bank Type, LVDS I/O was changed to Advanced I/O.	2-134
	The title was changed from "Fusion Standard, LVDS, and Standard plus Hot-Swap I/O" to Table 2-68 • Fusion Standard and Advanced I/O Features. In addition, the table headings were all updated. The heading used to be Standard and LVDS I/O and was changed to Advanced I/O. Standard Hot-Swap was changed to just Standard.	2-136
	This sentence was deleted from the "Slew Rate Control and Drive Strength" section: The Standard hot-swap I/Os do not support slew rate control. In addition, these references were changed:	2-152
	<ul> <li>From: Fusion hot-swap I/O (Table 2-69 on page 2-122) To: Fusion Standard I/O</li> <li>From: Fusion LVDS I/O (Table 2-70 on page 2-122) To: Fusion Advanced I/O</li> </ul>	
	The "Cold-Sparing Support" section was significantly updated.	2-143
	In the title of Table 2-75 • Fusion Standard I/O Standards—OUT_DRIVE Settings, Hot-Swap was changed to Standard.	2-153
	In the title of Table 2-76 • Fusion Advanced I/O Standards—SLEW and OUT_DRIVE Settings, LVDS was changed to Advanced.	2-153
	In the title of Table 2-81 • Fusion Standard and Advanced I/O Attributes vs. I/O Standard Applications, LVDS was changed to Advanced.	2-157
	In Figure 2-111 • Naming Conventions of Fusion Devices with Three Digital I/O Banks and Figure 2-112 • Naming Conventions of Fusion Devices with Four I/O Banks the following names were changed:	2-160
	Hot-Swap changed to Standard	
	LVDS changed to Advanced  The Figure 2 112 a Timing Medal was undeted	2.464
	The Figure 2-113 • Timing Model was updated.  In the notes for Table 2-86 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions, T <sub>J</sub> was changed to T <sub>A</sub> .	2-161 2-166

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Revision	Changes	Table
Advance v1.0 (continued)	This change table states that in the "208-Pin PQFP" table listed under the Advance v0.8 changes, the AFS090 device had a pin change. That is incorrect. Pin 102 was updated for AFS250 and AFS600. The function name changed from $V_{CC33ACAP}$ to $V_{CC33A}$ .	3-8
Advance v0.9 (October 2007)	In the "Package I/Os: Single-/Double-Ended (Analog)" table, the AFS1500/M7AFS1500 I/O counts were updated for the following devices: FG484: 223/109 FG676: 252/126	II
	In the "108-Pin QFN" table, the function changed from $V_{CC33ACAP}$ to $V_{CC33A}$ for the following pin: B25	3-2
	In the "180-Pin QFN" table, the function changed from V <sub>CC33ACAP</sub> to V <sub>CC33A</sub> for the following pins:  AFS090: B29  AFS250: B29	3-4
	In the "208-Pin PQFP" table, the function changed from $V_{CC33ACAP}$ to $V_{CC33A}$ for the following pins: AFS090: 102 AFS250: 102	3-8
	In the "256-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to $V_{CC33A}$ for the following pins: AFS090: T14 AFS250: T14 AFS1500: T14 AFS1500: T14	3-12
Advance v0.9 (continued)	In the "484-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to $V_{CC33A}$ for the following pins: AFS600: AB18 AFS1500: AB18	3-20
	In the "676-Pin FBGA" table, the function changed from $V_{CC33ACAP}$ to $V_{CC33A}$ for the following pins: AFS1500: AD20	3-28
Advance v0.8 (June 2007)	Figure 2-16 • Fusion Clocking Options and the "RC Oscillator" section were updated to change GND_OSC and VCC_OSC to GNDOSC and VCCOSC.	2-20, 2-21
	Figure 2-19 • Fusion CCC Options: Global Buffers with the PLL Macro was updated to change the positions of OADIVRST and OADIVHALF, and a note was added.	2-25
	The "Crystal Oscillator" section was updated to include information about controlling and enabling/disabling the crystal oscillator.	2-22
	Table 2-11 $\cdot$ Electrical Characteristics of the Crystal Oscillator was updated to change the typical value of I <sub>DYNXTAL</sub> for 0.032–0.2 MHz to 0.19.	2-24
	The "1.5 V Voltage Regulator" section was updated to add "or floating" in the paragraph stating that an external pull-down is required on TRST to power down the VR.	2-41
	The "1.5 V Voltage Regulator" section was updated to include information on powering down with the VR.	2-41



Revision	Changes	Table
Advance v0.8 (continued)	This sentence was updated in the "No-Glitch MUX (NGMUX)" section to delete GLA:	2-32
	The GLMUXCFG[1:0] configuration bits determine the source of the CLK inputs (i.e., internal signal or GLC).	
	In Table 2-13 • NGMUX Configuration and Selection Table, 10 and 11 were deleted.	2-32
	The method to enable sleep mode was updated for bit 0 in Table 2-16 • RTC Control/Status Register.	2-38
	S2 was changed to D2 in Figure 2-39 • Read Waveform (Pipe Mode, 32-bit access) for RD[31:0] was updated.	2-51
	The definitions for bits 2 and 3 were updated in Table 2-24 • Page Status Bit Definition.	2-52
	Figure 2-46 • FlashROM Timing Diagram was updated.	2-58
	Table 2-26 • FlashROM Access Time is new.	2-58
	Figure 2-55 • Write Access After Write onto Same Address, Figure 2-56 • Read	2-68-
	Access After Write onto Same Address, and Figure 2-57 • Write Access After Read onto Same Address are new.	2-70
	Table 2-31 • RAM4K9 and Table 2-32 • RAM512X18 were updated.	2-71, 2-72
	The VAREF and SAMPLE functions were updated in Table 2-36 • Analog Block Pin Description.	2-82
	The title of Figure 2-72 • Timing Diagram for Current Monitor Strobe was updated to add the word "positive."	2-91
	The "Gate Driver" section was updated to give information about the switching rate in High Current Drive mode.	2-94
	The "ADC Description" section was updated to include information about the SAMPLE and BUSY signals and the maximum frequencies for SYSCLK and ADCCLK. EQ 2 was updated to add parentheses around the entire expression in the denominator.	2-102
	Table 2-46 · Analog Channel Specifications and Table 2-47 · ADC Characteristics in Direct Input Mode were updated.	2-118, 2-121
	The note was removed from Table 2-55 • Analog Multiplexer Truth Table—AV $(x = 0)$ , AC $(x = 1)$ , and AT $(x = 3)$ .	2-131
	Table 2-63 • Internal Temperature Monitor Control Truth Table is new.	2-132
	The "Cold-Sparing Support" section was updated to add information about cases where current draw can occur.	2-143
	Figure 2-104 • Solution 4 was updated.	2-147
	Table 2-75 • Fusion Standard I/O Standards—OUT_DRIVE Settings was updated.	2-153
	The "GNDA Ground (analog)" section and "GNDAQ Ground (analog quiet)" section were updated to add information about maximum differential voltage.	2-224
	The "V <sub>AREF</sub> Analog Reference Voltage" section and "VPUMP Programming Supply Voltage" section were updated.	2-226
	The "V <sub>CCPLA/B</sub> PLL Supply Voltage" section was updated to include information about the east and west PLLs.	2-225
	The V <sub>COMPLF</sub> pin description was deleted.	N/A
	The "Axy Analog Input/Output" section was updated with information about grounding and floating the pin.	2-226

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Revision	Changes	Table
Advance v0.8 (continued)	The voltage range in the "VPUMP Programming Supply Voltage" section was updated. The parenthetical reference to "pulled up" was removed from the statement, "VPUMP can be left floating or can be tied (pulled up) to any voltage between 0 V and 3.6 V."	2-225
	The "ATRTNx Temperature Monitor Return" section was updated with information about grounding and floating the pin.	2-226
	The following text was deleted from the "VREF I/O Voltage Reference" section: (all digital I/O).	2-225
	The "NCAP Negative Capacitor" section and "PCAP Positive Capacitor" section were updated to include information about the type of capacitor that is required to connect the two.	2-228
	1 μF was changed to 100 pF in the "XTAL1 Crystal Oscillator Circuit Input".	2-228
	The "Programming" section was updated to include information about V <sub>CCOSC</sub> .	2-229
	The VMV pins have now been tied internally with the V <sub>CCI</sub> pins.	N/A
	The AFS090"108-Pin QFN" table was updated.	3-2
	The AFS090 and AFS250 devices were updated in the "108-Pin QFN" table.	3-2
	The AFS250 device was updated in the "208-Pin PQFP" table.	3-8
	The AFS600 device was updated in the "208-Pin PQFP" table.	3-8
	The AFS090, AFS250, AFS600, and AFS1500 devices were updated in the "256-Pin FBGA" table.	3-12
	The AFS600 and AFS1500 devices were updated in the "484-Pin FBGA" table.	3-20
Advance v0.7	The AFS600 device was updated in the "676-Pin FBGA" table.	3-28
(January 2007)	The AFS1500 digital I/O count was updated in the "Fusion Family" table.	1
	The AFS1500 digital I/O count was updated in the "Package I/Os: Single-/Double-Ended (Analog)" table.	II
Advance v0.6 (October 2006)	The second paragraph of the "PLL Macro" section was updated to include information about POWERDOWN.	2-30
	The description for bit 0 was updated in Table 2-17 · RTC Control/Status Register.	2-38
	3.9 was changed to 7.8 in the "Crystal Oscillator (Xtal Osc)" section.	2-40.
	All function descriptions in Table 2-18 · Signals for VRPSM Macro.	2-42
	In Table 2-19 • Flash Memory Block Pin Names, the RD[31:0] description was updated.	2-43
	The "RESET" section was updated.	2-61
	The "RESET" section was updated.	2-64
	Table 2-35 • FIFO was updated.	2-79
	The VAREF function description was updated in Table 2-36 • Analog Block Pin Description.	2-82
	The "Voltage Monitor" section was updated to include information about low power mode and sleep mode.	2-86
	The text in the "Current Monitor" section was changed from 2 mV to 1 mV.	2-90
	The "Gate Driver" section was updated to include information about forcing 1 V on the drain.	2-94



Revision	Changes	Table
Advance v0.6 (continued)	The "Analog-to-Digital Converter Block" section was updated with the following statement:  "All results are MSB justified in the ADC."	2-99
	The information about the ADCSTART signal was updated in the "ADC Description" section.	2-102
	Table 2-46 · Analog Channel Specifications was updated.	2-118
	Table 2-47 · ADC Characteristics in Direct Input Mode was updated.	2-121
	Table 2-51 • ACM Address Decode Table for Analog Quad was updated.	2-127
	In Table 2-53 • Analog Quad ACM Byte Assignment, the Function and Default Setting for Bit 6 in Byte 3 was updated.	2-130
	The "Introduction" section was updated to include information about digital inputs, outputs, and bibufs.	2-133
	In Table 2-69 • Fusion Pro I/O Features, the programmable delay descriptions were updated for the following features:	2-137
	Single-ended receiver	
	Voltage-referenced differential receiver	
	LVDS/LVPECL differential receiver features	
	The "User I/O Naming Convention" section was updated to include "V" and "z" descriptions	2-159
	The "VCC33PMP Analog Power Supply (3.3 V)" section was updated to include information about avoiding high current draw.	2-224
	The "VCCNVM Flash Memory Block Power Supply (1.5 V)" section was updated to include information about avoiding high current draw.	2-224
	The "VMVx I/O Supply Voltage (quiet)" section was updated to include this statement: VMV and VCCI must be connected to the same power supply and $V_{\rm CCI}$ pins within a given I/O bank.	2-185
	The "PUB Push Button" section was updated to include information about leaving the pin floating if it is not used.	2-228
	The "PTBASE Pass Transistor Base" section was updated to include information about leaving the pin floating if it is not used.	2-228
	The "PTEM Pass Transistor Emitter" section was updated to include information about leaving the pin floating if it is not used.	2-228
	The heading was incorrect in the "208-Pin PQFP" table. It should be AFS250 and not AFS090.	3-8

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Revision	Changes	Table
Advance v0.5 (June 2006)	The low power modes of operation were updated and clarified.	N/A
	The AFS1500 digital I/O count was updated in Table 1 • Fusion Family.	i
	The AFS1500 digital I/O count was updated in the "Package I/Os: Single-/Double-Ended (Analog)" table.	ii
	The "Voltage Regulator Power Supply Monitor (VRPSM)" was updated.	2-36
	Figure 2-45 • FlashROM Timing Diagram was updated.	2-53
	The "256-Pin FBGA" table for the AFS1500 is new.	3-12
Advance v0.4 (April 2006)	The G was moved in the "Product Ordering Codes" section.	III
Advance v0.3	The "Features and Benefits" section was updated.	I
(April 2006)	The "Fusion Family" table was updated.	I
	The "Package I/Os: Single-/Double-Ended (Analog)" table was updated.	II
	The "Product Ordering Codes" table was updated.	III
	The "Temperature Grade Offerings" table was updated.	IV
	The "General Description" section was updated to include ARM information.	1-1
	Figure 2-46 • FlashROM Timing Diagram was updated.	2-58
	The "FlashROM" section was updated.	2-57
	The "RESET" section was updated.	2-61
	The "RESET" section was updated.	2-64
	Figure 2-27 · Real-Time Counter System was updated.	2-35
	Table 2-19 • Flash Memory Block Pin Names was updated.	2-43
	Figure 2-33 • Flash Memory Block Diagram was updated to include AUX block information.	2-45
	Figure 2-34 • Flash Memory Block Organization was updated to include AUX block information.	2-46
	The note in the "Program Operation" section was updated.	2-48
	Figure 2-76 • Gate Driver Example was updated.	2-95
	The "Analog Quad ACM Description" section was updated.	2-130
	Information about the maximum pad input frequency was added to the "Gate Driver" section.	2-94
	Figure 2-65 • Analog Block Macro was updated.	2-81
	Figure 2-65 • Analog Block Macro was updated.	2-81
	The "Analog Quad" section was updated.	2-84
	The "Voltage Monitor" section was updated.	2-86
	The "Direct Digital Input" section was updated.	2-89
	The "Current Monitor" section was updated.	2-90
	Information about the maximum pad input frequency was added to the "Gate Driver" section.	2-94



Revision	Changes	Table
Advance v0.3 (continued)	The "Temperature Monitor" section was updated.	2-96
	EQ 2 is new.	2-103
	The "ADC Description" section was updated.	2-102
	Figure 2-16 • Fusion Clocking Options was updated.	2-20
	Table 2-46 · Analog Channel Specifications was updated.	2-118
	The notes in Table 2-72 • Fusion Standard and Advanced I/O – Hot-Swap and 5 V Input Tolerance Capabilities were updated.	2-144
	The "Simultaneously Switching Outputs and PCB Layout" section is new.	2-149
	LVPECL and LVDS were updated in Table 2-81 • Fusion Standard and Advanced I/O Attributes vs. I/O Standard Applications.	2-157
	LVPECL and LVDS were updated in Table 2-82 • Fusion Pro I/O Attributes vs. I/O Standard Applications.	2-158
	The "Timing Model" was updated.	2-161
	All voltage-referenced Minimum and Maximum DC Input and Output Level tables were updated.	N/A
	All Timing Characteristic tables were updated	N/A
	Table 2-83 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions was updated.	2-165
	Table 2-79 • Summary of I/O Timing Characteristics – Software Default Settings was updated.	2-134
	Table 2-93 • I/O Output Buffer Maximum Resistances <sup>1</sup> was updated.	2-171
	The "BLVDS/M-LVDS" section is new. BLVDS and M-LVDS are two new I/O standards included in the datasheet.	2-211
	The "CoreMP7 and Cortex-M1 Software Tools" section is new.	2-257
	Table 2-83 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions was updated.	2-165
	Table 2-79 • Summary of I/O Timing Characteristics – Software Default Settings was updated.	2-134
	Table 2-93 • I/O Output Buffer Maximum Resistances <sup>1</sup> was updated.	2-171
	The "BLVDS/M-LVDS" section is new. BLVDS and M-LVDS are two new I/O standards included in the datasheet.	2-211
	The "108-Pin QFN" table for the AFS090 device is new.	3-2
	The "180-Pin QFN" table for the AFS090 device is new.	3-4
	The "208-Pin PQFP" table for the AFS090 device is new.	3-8
	The "256-Pin FBGA" table for the AFS090 device is new.	3-12
	The "256-Pin FBGA" table for the AFS250 device is new.	3-12

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## **Datasheet Categories**

## **Categories**

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "Fusion Device Status" table, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

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The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

#### Advance

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

## **Preliminary**

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#### **Production**

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